

Surface Mount Ceramic Capacitor Products





IMPORTANT INFORMATION/DISCLAIMER

All product specifications, statements, information and data (collectively, the "Information") in this datasheet or made available on the website are subject to change. The customer is responsible for checking and verifying the extent to which the Information contained in this publication is applicable to an order at the time the order is placed. All Information given herein is believed to be accurate and reliable, but it is presented without guarantee, warranty, or responsibility of any kind, expressed or implied.

Statements of suitability for certain applications are based on KYOCERA AVX's knowledge of typical operating conditions for such applications, but are not intended to constitute and KYOCERA AVX specifically disclaims any warranty concerning suitability for a specific customer application or use.

ANY USE OF PRODUCT OUTSIDE OF SPECIFICATIONS OR ANY STORAGE OR INSTALLATION INCONSISTENT WITH PRODUCT GUIDANCE VOIDS ANY WARRANTY.

The Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by KYOCERA AVX with reference to the use of KYOCERA AVX's products is given without regard, and KYOCERA AVX assumes no obligation or liability for the advice given or results obtained.

Although KYOCERA AVX designs and manufactures its products to the most stringent quality and safety standards, given the current state of the art, isolated component failures may still occur. Accordingly, customer applications which require a high degree of reliability or safety should employ suitable designs or other safeguards (such as installation of protective circuitry or redundancies) in order to ensure that the failure of an electrical component does not result in a risk of personal injury or property damage.

Unless specifically agreed to in writing, KYOCERA AVX has not tested or certified its products, services or deliverables for use in high risk applications including medical life support, medical device, direct physical patient contact, water treatment, nuclear facilities, weapon systems, mass and air transportation control, flammable environments, or any other potentially life critical uses. Customer understands and agrees that KYOCERA AVX makes no assurances that the products, services or deliverables are suitable for any highrisk uses. Under no circumstances does KYOCERA AVX warrant or guarantee suitability for any customer design or manufacturing process.

Although all product-related warnings, cautions and notes must be observed, the customer should not assume that all safety measures are indicted or that other measures may not be required.

Surface Mount Ceramic Capacitor Products





How to (Automotive MLCC	
Part Num	ber Explanation	1 General Specifications	54
		Capacitance Range	<u>5</u> 6
COG (NF	P0) Dielectric		
General S	pecifications	3 APS for COTS+ High Reliability Applications	
Specificat	tions and Test Methods	4 General Specifications	59
Capacitar	nce Range	5 Capacitance Range	60
U Dielec	etric	MLCC with FLEXITERM®	
RF/Microv	wave COG (NP0) Capacitors (RoHS)	General Specifications	63
	wave COG (NPO) Capacitors (Sn/Pb)	Specifications and Test Methods	64
RF/Microv	wave Automotive COG (NP0) Capacitors (RoHS) 200 Qualified Ultra Low ESR	Capacitance Range	66
Designer	Kits	15 FLEXISAFE MLC Chips	
		General Specifications and Capacitance Range	68
X8R/X8I	L Dielectric	3.	
General S	pecifications	16 Capacitor Array	
Specificat	tions and Test Methods		69
•		Automotive Capacitor Array (IPC)	
X7R Die	lectric	Part & Pad Layout Dimensions	
General S	pecifications		
	tions and Test Methods		
•	nce Range		75
o apaona.	g	LICC (Low Inductance Chip Capacitors)	
X7S Die	lectric	IDC (InterDigitated Capacitors)	
	pecifications	23 LGA Low Inductance Capacitors	
	tions and Test Methods		63
•	nce Range		
Capacitai	ice Nange	AT Series – 200°C & 250°C Rated	0.0
X5R Die	lectric	AT Series - 200°C & 200 C Rateu	00
	pecifications	26 High Voltage MI C Chine	
	tions and Test Methods		0.4
	nce Range		
Capacitai	ice Range		
Y5V Die	lootrio	FLEXITERM® - 600V to 5000V Applications	
		For 600V to 3000V Automotive Applications - AEC-Q200	106
	pecifications		
•	tions and Test Methods		
Capacitar	nce Range		
MICCO	ald Tarmination All Carias	CDR31 thru CDR35	110
	old Termination — AU Series		
	pecifications	The state of the s	
Capacitar	nce Range	34 MM Series	
	in/Lead Termination "B" (LD Series)	Packaging of Chip Components	119
COG (NPO) – General Specifications		
	Specifications and Test Methods		120
VOD	Capacitance Range		
X8R	General Specifications		121
	Specifications and Test Methods	45	
X7R	Capacitance Range		122
A/1\	Specifications and Test Methods	······································	
	Capacitance Range		123
X5R	General Specifications	•	123
AJR	Coc. ar openination o		
AJK	Specifications and Test Methods	52 Surface Mounting Guide	120

How to Order

Part Number Explanation



Commercial Surface Mount Chips EXAMPLE: 08055A101JAT2A

0805	5	Α	101	J*	Α	<u>T</u>	2	A **
Size (L" x W") 0101* 0201 0402 0603 0805 1206 1210 1812 1825 2220 2225	Voltage 4 = 4V 6 = 6.3V Z = 10V Y = 16V 3 = 25V D = 35V 5 = 50V 1 = 100V 2 = 200V 7 = 500V	Dielectric A = NP0(C0G) C = X7R D = X5R F = X8R G = Y5V U = U Series W = X6S Z = X7S	Capacitance 2 Sig. Fig + No. of Zeros Examples: 100 = 10 pF 101 = 100 pF 102 = 1000 pF 223 = 22000 pF 224 = 220000 pF 105 = 1μF 106 = 10μF 107 = 100μF For values below 10 pF. use "R"	Tolerance B = ±.10 pF C = ±.25 pF D = ±.50 pF F = ±1% (≥ 10 pF G = ±2% (≥ 10 pF J = ±5% K = ±10% M = ±20% Z = +80%, -20% P = +100%, -0%	-)	Terminations T = Plated Ni and Sn T = Gold Plated U = Conductive Expoxy for Hybrid Applications Z = FLEXITERM® *X = FLEXITERM® with 5% min lead (X7R & X8R only)	Packaging Available 2 = 7" Reel 4 = 13" Reel U = 4mm TR (01005) Contact Factory For Multiples	Special Code A = Std K = 30K (0603 2mm pitch) 22K (0805/1206 <0.030"/ 0.76mm) H = 18K (0603/0805/1206 <0.037" / 0.94mm) J = 15K (0805/1206 <0.050" / 1.27mm) 1 = 12K (0805/1206 <0.055 / 1.4mm) **Non std options upon approval from the factory
*EIA 01005	Special F = 63V E = 150V V = 250V	Voltages 9 = 300V 8 = 400V	in place of Decimal point, e.g., 9.1 pF = 9R1.		1	Contact Factory For = Pd/Ag Term		,

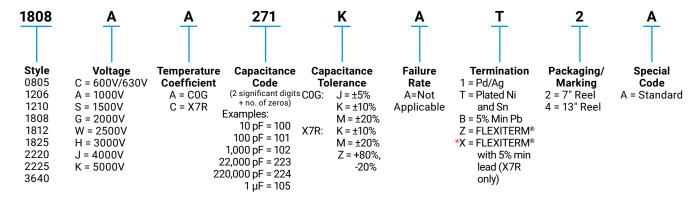
* B, C & D tolerance for ≤10 pF values.

Standard Tape and Reel material (Paper/Embossed) depends upon chip size and thickness. See individual part tables for tape material type for each capacitance value.

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. For Tin/Lead Terminations, please refer to LD Series

High Voltage MLC Chips

EXAMPLE: 1808AA271KAT2A



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. For Tin/Lead Terminations, please refer to LD Series

Not RoHS Compliant



For RoHS compliant products, please select correct termination style.

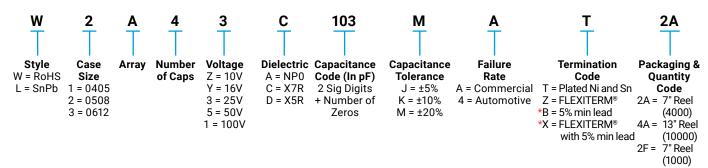
How to Order

Part Number Explanation



Capacitor Array

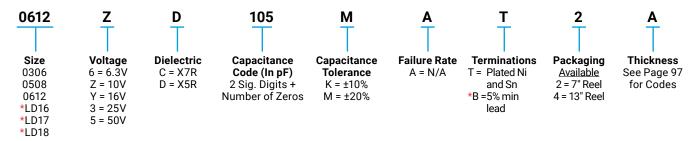
EXAMPLE: W2A43C103MAT2A



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

Low Inductance Capacitors (LICC)

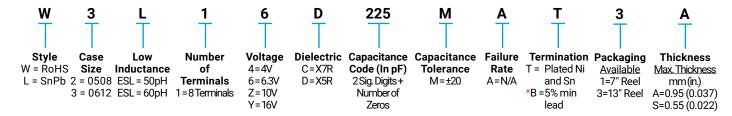
EXAMPLE: 0612ZD105MAT2A



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

Interdigitated Capacitors (IDC)

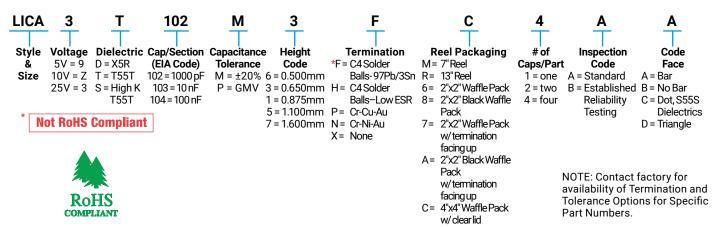
EXAMPLE: W3L16D225MAT3A



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

Low Inductance Decoupling Capacitor Arrays (LICA)

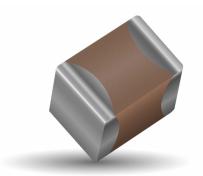
EXAMPLE: LICA3T183M3FC4AA



COG (NPO) Dielectric

General Specifications

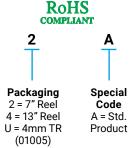


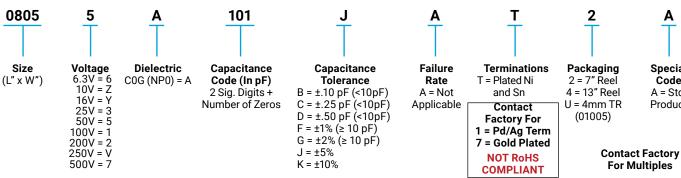


COG (NPO) is the most popular formulation of the "temperature-compensating," EIA Class I ceramic materials. Modern COG (NPO) formulations contain neodymium, samarium and other rare earth oxides.

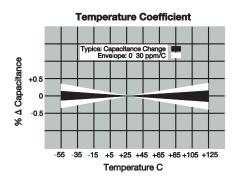
COG (NP0) ceramics offer one of the most stable capacitor dielectrics available. Capacitance change with temperature is 0 ±30ppm/°C which is less than ±0.3% C from -55°C to +125°C. Capacitance drift or hysteresis for COG (NPO) ceramics is negligible at less than ±0.05% versus up to ±2% for films. Typical capacitance change with life is less than ±0.1% for COG (NPO), one-fifth that shown by most other dielectrics. COG (NPO) formulations show no aging characteristics.

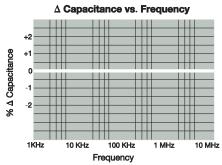
PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

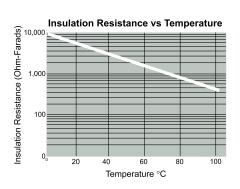


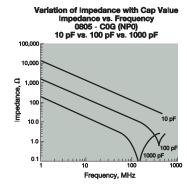


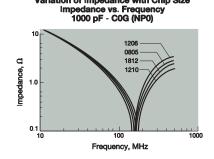
NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.



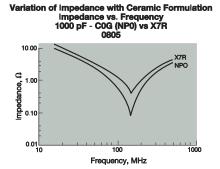








Variation of Impedance with Chip Size



COG (NP0) Dielectric





Parame	ter/Test	NP0 Specification Limits	Measuring (Conditions	
	perature Range	-55°C to +125°C	Temperature C		
	itance Q	Within specified tolerance <30 pF: Q≥ 400+20 x Cap Value ≥30 pF: Q≥ 1000	Freq.: 1.0 MHz ± 10% 1.0 kHz ± 10% fo Voltage: 1.0	r cap > 1000 pF	
Insulation	Resistance	100,000MΩ or 1000MΩ - μ F, whichever is less	Charge device with rated @ room tem		
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250% seconds, w/charge and d to 50 mA Note: Charge device with for 500V	ischarge current limited A (max) n 150% of rated voltage	
	Appearance	No defects			
Resistance to	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Deflectio Test Time: 3		
Flexure	Q	Meets Initial Values (As Above)	V		
Stresses	Insulation Resistance	≥ Initial Value x 0.3	90 n	nm	
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic sold 0.5 sec		
	Appearance	No defects, <25% leaching of either end terminal			
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Dip device in eutectic	solder at 260°C for	
Resistance to Solder Heat	Q	Meets Initial Values (As Above)	60sec- onds. Store at		
Soluel Heat	Insulation Resistance	Meets Initial Values (As Above)	for 24 ± 2hours before measuring electr properties.		
	Dielectric Strength	Meets Initial Values (As Above)			
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes	
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp	≤ 3 minutes	
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes	
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes	
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 hours at roor		
	Appearance	No visual defects	-		
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twic chamber set at		
Load Life	Q (C=Nominal Cap)	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	for 1000 hou Remove from test cha	rs (+48, -0).	
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	room temperatu before me	re for 24 hours	
	Dielectric Strength	Meets Initial Values (As Above)		- -	
	Appearance	No visual defects			
	Capacitance Variation	≤ ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber s	et at 85°C ± 2°C/ 85% +	
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	5% relative humidi (+48, -0) with rated	ty for 1000 hours I voltage applied.	
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature for 24 ± 2 ho		
	Dielectric Strength	Meets Initial Values (As Above)			

COG (NP0) Dielectric

Capacitance Range



PREFERRED SIZES ARE SHADED

SIZE		0101*	020			0402				0603						0805						1206			
Solderin		Reflow Only	Reflow			low/Wa				eflow/W			Reflow/Wave								eflow/W				
Packagir	ng mm	All Paper 0.40 ± 0.02	All Pa 0.60 ±			II Pape 00 ± 0.1				All Pape .60 ± 0.						/Emboss 01 ± 0.20	ea					per/Embo 3.20 ± 0.			
(L) Length	(in.)	(0.016 ± 0.0008)	(0.024 ±			40 ± 0.0		(0.063 ± 0					(0.079 ± 0.008)							.126 ± 0.					
W) Width	mm (in.)	0.20 ± 0.02 (0.008 ± 0.0008)	0.30 ± (0.011 ±			50 ± 0.1 20 ± 0.0				0.81 ± 0. 032 ± 0.						25 ± 0.20 19 ± 0.00	8)					1.60 ± 0. .063 ± 0.			
(t) Tarrainal	mm	0.10 ± 0.04	0.15 ±		_	25 ± 0.1				0.35 ± 0.						50 ± 0.25	<u>, </u>					0.50 ± 0.			
(t) Terminal	(in.)	(0.004 ± 0.0016)	(0.006 ±			10 ± 0.0				014 ± 0.						20 ± 0.01						.020 ± 0.			
Con	WVDC 0.5	16	25 A	50 A	16 C	25 C	50 C	16 G	25 G	50 G	100 G	200	16 J	25 J	50 J	100 J	200 J	250 J	16 J	25 J	50 J	100 J	200 J	250 J	500 J
(pF)	1.0	В	A	A	C	C	C	G	G	G	G		J	J	J	J	J	J	J	J	J	J	J	J	J
"	1.2	В	Α	Α	С	С	С	G	G	G	G	İ	J	J	J	J	J	J	J	J	J	J	J	J	J
	1.5 1.8	B B	A	A	C	C	C	G	G	G G	G G		J	J	J	J	J	J	J	J	J	J	J	J	J
	2.2	В	Â	Â	c	C	c	G	G	G	G		J	J	J	J	J	J	J	J	J	J	J	J	J
	2.7	В	A	A	С	С	С	G	G	G	G		J	J	J	J	J	J	J	J	J	J	J	J	J
	3.3 3.9	B B	A A	A	C	C	C	G G	G G	G G	G G		J	J	J	J	J	J	J	J	J	J	J	J	J
	4.7	В	A	A	c	C	c	G	G	G	G		Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ
	5.6	В	A	A	С	С	С	G	G	G	G		٦.	٦.	J	J	J	J	J	J	J	J	J	J	J
	6.8 8.2	B B	A	A	C	C	C	G G	G G	G G	G G		J	J	J	J	J	J	J	J	J	J	J	J	J J
	10	В	A	A	С	С	С	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J
	12	В	A	A	С	С	C	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J
	15 18	B B	A	A	C	C	C	G G	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J	J	J
	22	В	Α	Α	С	С	С	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J
	27 33	B B	A	A	C	C	C	G	G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J	J	J
	39	В	A	A	C	C	C	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J
	47	В	Α	Α	С	С	С	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J
	56 68	B B	A A	A	C	CC	C	G G	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J	J	J J
	82	В	Â	A	C	C	c	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J
	100	В	Α	Α	С	С	С	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J
	120 150				C	C	C	G G	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J	J	J
	180				С	С	C	G	G	G	G	G	J	J	J	J	J	N	J	J	J	J	J	J	J
	220				С	С	С	G	G	G	G	G	J	J	J	J	N	N	J	J	J	J	J	J	J
	270 330				C	C	C	G	G G	G G	G G		J	J	J	J	N N	N N	J	J	J	J	J	J	J
	390				С	С	c	G	G	G	G		J	J	Ĵ	J	N	N	J	J	J	J	J	J	J
	470				C	C	C	G	G	G	G G		J	J	J	J	N N	N N	J	J	J	J	J	J	J
	560 680				С	C	C	G G	G	G G	G		J	J	J	J	N	N N	J	J	J	J	J	J	J
	750				С	С	С	G	G	G	G		J	J	J	J	N	N	J	J	J	J	J	J	J
	820 1000				C	C	C	G	G G	G G	G G		J	J	J	J	N N	N N	J	J	J	J	J	J	J
	1200				C	U		G	G	G	U		J	J	J	J	P	P	J	J	J	J	J	Ĵ	J
	1500							G	G	G			J	J	J	J	P	Р	J	J	J	М	Q	Р	P
	1800 2200							G G	G G	G G			J P	J P	J P	J P	P P	P P	J	J	M	P P	Q Q	P P	P P
	2700							G	G	G			Р	Р	Р	Р	Р	Р	J	J	М	Р	Q	Р	Р
	3300							G	G	G			Р	Р	Р	Р	Р	Р	J	J	M	Р	Q	X	P
	3900 4700							G G	G G	G G			P P	P P	P P	P P	P P	P P	J	J	M	P P	X	X	X
	5600												Р	Р	Р				J	J	М	Р	Х	Х	Х
	6800 8200												P P	P P	P P				M P	M P	M P	P P	X	X	Х
Сар	0.010							 					P	P	P				P	P	P	P	X	X	
(μF)	0.012												Р	Р	Р				Х	Х	Х	Х			
	0.015 0.018	<u> </u>	>		[← 1Λ/		'—							-					X	X	X	X			
	0.018	- L				2													X	X	X	X			
	0.027	^		\)) ÎT													X	X	X				
	0.033 0.039			1_	سلر	_	-												X	X	X	Х			
	0.039		$\overline{}$				_	L							L				×	X	x				
	0.068		4 ∱	•															Х	Х	Х				
	0.082 0.1		' 1	ĺ			I												Х	X	X				
WVDC		16	25	50	16	25	50	16	25	50	100	200	16	25	50	100	200	250	16	25	50	100	200	250	500
SIZE		0101*	020	01		0402				0603						0805						1206			

Letter	Α	В	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max. Thickness	0.33 (0.013)	0.22 (0.009)	0.56 (0.022)	0.71 (0.028)	0.90 (0.035)	0.94 (0.037)	1.02 (0.040)	1.27 (0.050)	1.40 (0.05 5)	1.52 (0.060)	1.78 (0.070)	2.29 (0.090)	2.54 (0.100)	2.79 (0.110)
	PAPER									EMB	OSSED			

COG (NP0) Dielectric





PREFERRED SIZES ARE SHADED

SIZE				1210					1812				1825			2220			2225	
Soldering				Reflow Only					Reflow Only				Reflow Onl			Reflow Onl			eflow Only	
Packaging				per/Embos					II Embosse				All Embosse			II Embosse			Embossed	
(L) Length	mm (in.)			3.20 ± 0.20 0.126 ± 0.00					4.50 ± 0.30 1.177 ± 0.01				4.50 ± 0.30 0.177 ± 0.01			5.70 ± 0.40 .225 ± 0.01			5.72 ± 0.25 225 ± 0.010	
W) Width	mm			2.50 ± 0.20					3.20 ± 0.20				6.40 ± 0.40)		5.00 ± 0.40)	6	.35 ± 0.25	
w) width	(in.)			0.098 ± 0.00					.126 ± 0.00				0.252 ± 0.01			.197 ± 0.01			250 ± 0.010	
(t) Terminal	mm (in.)			0.50 ± 0.25 0.020 ± 0.01					0.61 ± 0.36 0.024 ± 0.01				0.61 ± 0.36 0.024 ± 0.01			0.64 ± 0.39 .025 ± 0.01			0.64 ± 0.39 025 ± 0.01	
	WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	50	100	200
Сар	3.9																			
(pF)	4.7 5.6																			
	6.8																			
	8.2																			
	10	М	М	М	М	М	Р	Р	Р	Р	Р						>		٨/-	
	12	М	M	M	M	M	P	P P	P	P	P					L			5	
	15 18	M	M M	M M	M M	M M	P P	P	P P	P P	P P					+ `(-	,)	J.Į⊤-	\vdash
	22	М	M	M	М	М	P	P	P	P	P					_	\sim 1,			
	27	М	М	М	М	М	Р	Р	Р	Р	Р					L				
	33	М	М	М	М	М	P	P	P	P	P						_	l		
	39 47	M P	M P	M P	M P	M P	P P	P P	P P	P P	P P									
	56	P	P	P	P	P	P	P	P	P	P									\vdash
	68	Р	Р	Р	Р	Р	Р	Р	Р	Р	Р									
	82	Р	Р	Р	Р	Р	Р	Р	Р	Р	Р									
	100	P	P	P	P	Р	Р	P	P	P	P									
	120 150	P P	P P	P P	P P	P P	P P	P P	P P	P P	P P									
	180	P	P	P	P	P	P	P	P	P	P									
	220	Р	Р	Р	Р	Р	Р	Р	Р	Р	Р									
	270	Р	P	P	P	Р	Р	P	P	Р	Р									
	330 390	P P	P P	P P	P P	P P	P P	P P	P P	P	P P									
	470	P	P	P	P	P	P	P	P	P P	P									
	560	P	Р	P	P	P	P	P	P	P	P									
	680	Р	Р	Р	Р	Р	Р	Р	Р	Р	Р									
	820	P	P	P	P	P	P	P	P	P	P									
	1000 1200	P P	P P	P P	P P	P P	P P	P P	P P	P P	P P	M M	M M	M M				M M	M M	P P
	1500	P	P	P	P P	P P	P	P	P	P	P	M	M	M				M	M	P
	1800	Р	Р	Р	Р	Р	Р	Р	Р	Р	Р	М	М	М				М	М	Р
	2200	P	P	P	P	P	P	P	P	P	P	X	X	М				М	М	P
	2700 3300	P P	P P	P P	P P	P P	P P	P P	P P	P P	Q Q	X	X	M X		-	X	M M	M M	P P
	3900	P	P	P	P	P	P	P	P	P	Q	X	×	×			×	M	M	P
	4700	P	Р	Р	P	P	Р	Р	P	Р	Υ	X	Х	Х	Х	Х	X	М	М	P
	5600	P	P	P	P	P	P	P	Р	Р	Υ	Х	Х	Х	Х	Х	Х	М	М	P
	6800	P P	P	P P	X	X	P	P P	Q	Q	Y	X	X	X	X	X	X	M	M	P
Сар	8200 0.010	P P	P P	X	X	X	P P	P	Q	Q Q	Y	X	X	X	X	X	X	M M	M M	P P
(pF)	0.012	X	×	x	x	x	P	P	Q	x	Y	x	X	X	X	×	x	M	М	P
	0.015	Х	Х	Х	Z	Z	Р	Р	Q	Х	Y	Х	Х	Х	Х	Х	Х	М	М	Υ
	0.018	X	X	Z	Z		P	P	X	X	Y	X	X	X	X	X	Х	М	M	Y
	0.022 0.027	X X	X Z	Z Z	Z Z		P Q	P X	X	X Z		X X	X X	X	X X	X		M P	Y	Y
	0.027	X	Z	Z	Z		Q	X	X	Z		X	X	,	X	X		X	Y	Y
	0.039	Z	Z	Z			х	X	Z	Z		Х			Y			X	Y	Y
	0.047	Z	Z	Z			X	X	Z	Z		Х			Y			X	Z	
	0.068 0.082						Z Z	Z Z	Z Z						Z Z			X X	Z Z	
	0.082						Z	Z	Z						Z			X Z	Z	
	WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200	50	100	200
	SIZE			1210					1812				1825			2220			2225	

Letter	Α	В	С	E	G	J	K	М	N	Р	Q	Х	Υ	Z
Max. Thickness	0.33 (0.013)	0.22 (0.009)	0.56 (0.022)	0.71 (0.028)	0.90 (0.035)	0.94 (0.037)	1.02 (0.040)	1.27 (0.050)	1.40 (0.055)	1.52 (0.060)	1.78 (0.070)	2.29 (0.090)	2.54 (0.100)	2.79 (0.110)
	PAPER					EMBOSSED								

U Dielectric

RF/Microwave C0G (NP0) Capacitors (RoHS)

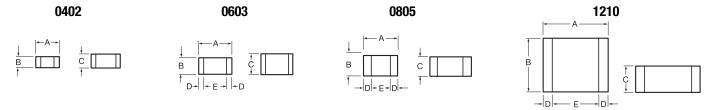
Ultra Low ESR, "U" Series, COG (NP0) Chip Capacitors



GENERAL INFORMATION

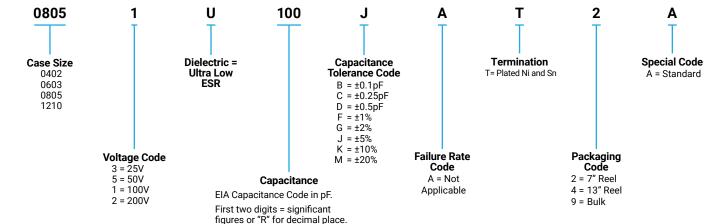
"U" Series capacitors are C0G (NP0) chip capacitors specially designed for "Ultra" low ESR for applications in the communications market. Max ESR and effective capacitance are met on each value producing lot to lot uniformity. Sizes available are EIA chip sizes 0603, 0805, and 1210.

DIMENSIONS: inches (millimeters)



Size	A	В	С	D	E
0402	0.039±0.004 (1.00±0.1)	0.020±0.004 (0.50±0.1)	0.024 (0.6) max	0.010 ± 0.006 (0.25 ± 0.15)	0.014 (0.36) min
0603	0.060±0.010 (1.52±0.25)	0.030±0.010 (0.76±0.25)	0.036 (0.91) max	0.010 ± 0.005 (0.25 ± 0.13)	0.030 (0.76) min
0805	0.079±0.008 (2.01±0.2)	0.049±0.008 (1.25±0.2)	0.045 (1.15mm) max	0.020 ± 0.010 (0.51 ± 0.254)	0.020 (0.51) min
1210	0.126±0.008 (3.2±0.2)	0.098±0.008 (2.49±0.2)	0.055 (1.40mm) max	0.025 ± 0.015 (0.635 ± 0.381)	0.040 (1.02) min

HOW TO ORDER



Third digit = number of zeros or after "R" significant figures.

ELECTRICAL CHARACTERISTICS

Capacitance Values and Tolerances:

Size 0402 - 0.2 pF to 22 pF @ 1 MHz Size 0603 - 1.0 pF to 100 pF @ 1 MHz Size 0805 - 1.6 pF to 160 pF @ 1 MHz Size 1210 - 2.4 pF to 1000 pF @ 1 MHz

Temperature Coefficient of Capacitance (TC):

0±30 ppm/°C (-55° to +125°C)

Insulation Resistance (IR):

 $10^{12}\,\Omega$ min. @ $25^{\circ}C$ and rated WVDC $10^{11} \Omega$ min. @ 125° C and rated WVDC

Working Voltage (WVDC):

Size Working Voltage 0402 50, 25 WVDC 0603 200, 100, 50 WVDC 0805 200, 100 WVDC 1210 200, 100 WVDC

Dielectric Working Voltage (DWV):

250% of rated WVDC

Equivalent Series Resistance Typical (ESR):

0402 - See Performance Curve, page 300 0603 - See Performance Curve, page 300 0805 - See Performance Curve, page 300 1210 - See Performance Curve, page 300

Marking

Laser marking EIA J marking standard (except 0603) (capacitance code and tolerance upon request).

LEAD-FREE

LEAD-FREE COMPATIBLE COMPONENT

RoHS

COMPLIANT

MILITARY SPECIFICATIONS

Meets or exceeds the requirements of MIL-C-55681

U Dielectric

On Anallable

RF/Microwave C0G (NP0) Capacitors (RoHS)



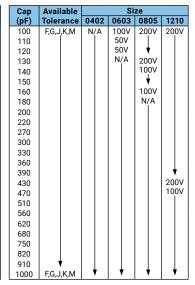


CAPACITANCE RANGE

Сар	Available		- 51	ze	
(pF)	Tolerance	0402	0603	0805	1210
0.2	B,C	50V	N/A	N/A	N/A
0.3					
0.4	♦				
0.5	B,C				
0.6	B,Ç,D				
0.7					
0.8	🔻				l I I
0.9	B,C,D	♦	♦	♦	🕈

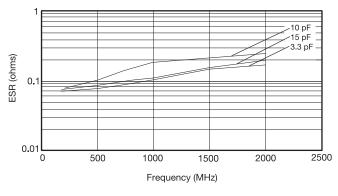
Cap	Available	le Size					
(pF)	Tolerance	0402	0603	0805	1210		
1.0	B,C,D	50V	200V	200V	200V		
1.1							
1.2							
1.3							
1.4							
1.5							
1.6							
1.7							
1.8							
1.9							
2.0							
2.1							
2.2							
2.4							
2.7							
3.0							
3.3							
3.6							
3.9							
4.3							
4.7							
5.1	l 1						
5.6	. ▼.						
6.2	B,C,D	↓	↓	↓	↓		
6.8	B,C,J,K,M	'	"	"	'		

Cap	Available						
(pF)	Tolerance	0402	0603	0805	1210		
7.5	B,C,J,K,M	50V	200V	200V	200V		
8.2	♦						
9.1	B,C,J,K,M						
10	F,G,J,K,M						
11							
12							
13							
15			♦				
18			200V				
20			100V				
22							
24							
27		♦					
30		50V					
33		N/A					
36							
39							
43							
47							
51							
56							
68							
75							
82	1 1	1 1			1		
91	▼	_ ▼	▼	- ▼	■ ▼		

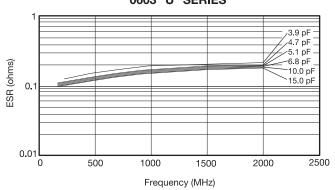


ULTRA LOW ESR, "U" SERIES

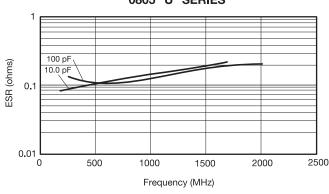
TYPICAL ESR vs. FREQUENCY 0402 "U" SERIES



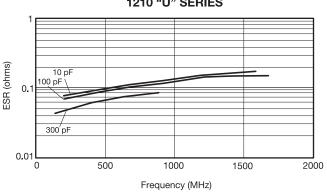
TYPICAL ESR vs. FREQUENCY 0603 "U" SERIES



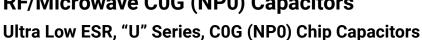
TYPICAL ESR vs. FREQUENCY 0805 "U" SERIES



TYPICAL ESR vs. FREQUENCY 1210 "U" SERIES

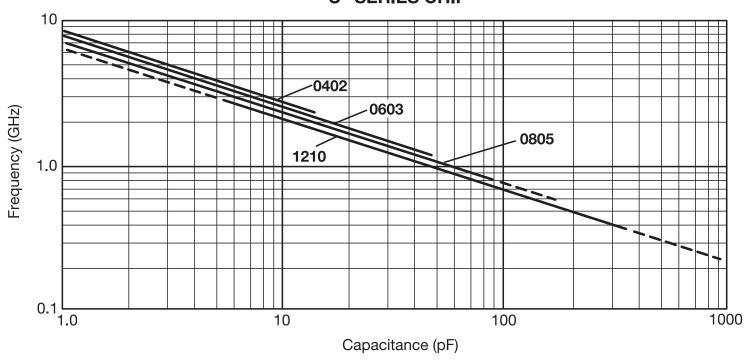


ESR Measured on the Boonton 34A





TYPICAL SERIES RESONANT FREQUENCY "U" SERIES CHIP



U Dielectric

RF/Microwave C0G (NP0) Capacitors (Sn/Pb)

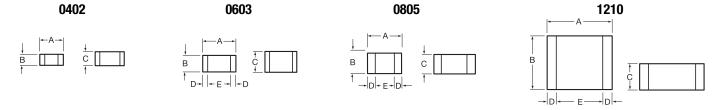
Ultra Low ESR, "U" Series, COG (NP0) Chip Capacitors



GENERAL INFORMATION

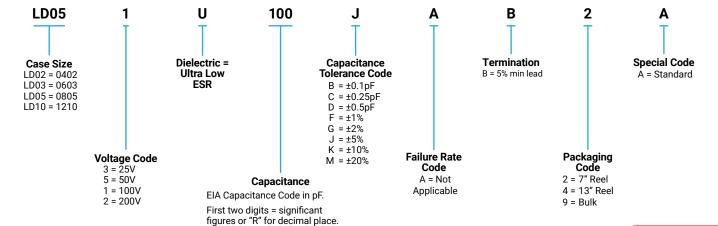
"U" Series capacitors are C0G (NP0) chip capacitors specially designed for "Ultra" low ESR for applications in the communications market. Max ESR and effective capacitance are met on each value producing lot to lot uniformity. Sizes available are EIA chip sizes 0603, 0805, and 1210.

DIMENSIONS: inches (millimeters)



Size	A	В	С	D	E
0402	0.039±0.004 (1.00±0.1)	0.020±0.004 (0.50±0.1)	0.024 (0.6) max	0.010 ± 0.006 (0.25 ± 0.15)	0.014 (0.36) min
0603	0.060±0.010 (1.52±0.25)	0.030±0.010 (0.76±0.25)	0.036 (0.91) max	0.010±0.005 (0.25±0.13)	0.030 (0.76) min
0805	0.079±0.008 (2.01±0.2)	0.049±0.008 (1.25±0.2)	0.045 (1.15mm) max	0.020±0.010 (0.51±0.254)	0.020 (0.51) min
1210	0.126±0.008 (3.2±0.2)	0.098±0.008 (2.49±0.2)	0.055 (1.40mm) max	0.025±0.015 (0.635±0.381)	0.040 (1.02) min

HOW TO ORDER



Third digit = number of zeros or after "R" significant figures.

Not RoHS Compliant

ELECTRICAL CHARACTERISTICS

Capacitance Values and Tolerances:

Size 0402 - 0.2 pF to 22 pF @ 1 MHz Size 0603 - 1.0 pF to 100 pF @ 1 MHz

Size 0805 - 1.6 pF to 160 pF @ 1 MHz Size 1210 - 2.4 pF to 1000 pF @ 1 MHz

Temperature Coefficient of Capacitance (TC):

0±30 ppm/°C (-55° to +125°C)

Insulation Resistance (IR):

 $10^{12}\,\Omega$ min. @ 25° C and rated WVDC $10^{11} \Omega$ min. @ 125° C and rated WVDC

Working Voltage (WVDC):

Size Working Voltage 0402 - 50, 25 WVDC 0603 - 200, 100, 50 WVDC 0805 - 200, 100 WVDC 1210 - 200, 100 WVDC

Dielectric Working Voltage (DWV):

250% of rated WVDC

Equivalent Series Resistance Typical (ESR):

040 - See Performance Curve, page 306

0603 - See Performance Curve, page 306

0805 - See Performance Curve, page 306

1210 - See Performance Curve, page 306

Laser marking EIA J marking standard (except 0603) (capacitance code and tolerance upon request).

Military Specifications

Meets or exceeds the requirements of MIL-C-55681



U Dielectric

RF/Microwave C0G (NP0) Capacitors (Sn/Pb)



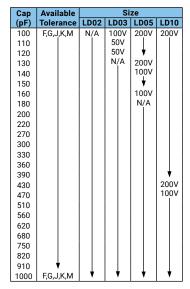


CAPACITANCE RANGE

	Cap	Available	Size						
I	(pF)	Tolerance	LD02	LD03	LD05	LD10			
ĺ	0.2	B,C	50V	N/A	N/A	N/A			
l	0.3								
١	0.4	♦							
l	0.5	B,C							
l	0.6	B,Ç,D							
İ	0.7								
İ	0.8	▼							
ĺ	0.9	B,C,D	♦	♦	♦	♦			
l	0.9	5,0,5	_ '						

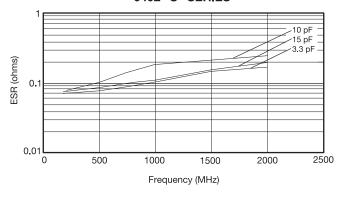
Сар	Available		Si	ze		
(pF)	Tolerance	LD02	LD03	LD05	LD10	
1.0	B,C,D	50V	200V	200V	200V	
1.1						
1.2						
1.3						
1.4						
1.5						
1.6						
1.7						
1.8						
1.9						
2.0						
2.1						
2.2						
2.4						
2.7						
3.0						
3.3						
3.6						
3.9						
4.3						
4.7						
5.1						
5.6	🔻					
6.2	B,C,D	1	I	1	ΙŢ	
6.8	B,C,J,K,M	▼	■ *	▼	▼	

Сар	Available	Size				
(pF)	Tolerance	LD02	LD03	LD05	LD10	
7.5	B,C,J,K,M	50V	200V	200V	200V	
8.2	♦					
9.1	B,C,J,K,M					
10	F,G,J,K,M					
11						
12						
13						
15			♦			
18			200V			
20			100V			
22						
24						
27		♦				
30		50V				
33		N/A				
36						
39						
43						
47						
51						
56						
68						
75						
82						
91	▼	♥	♥	♥	♦	

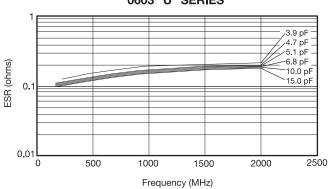


ULTRA LOW ESR, "U" SERIES

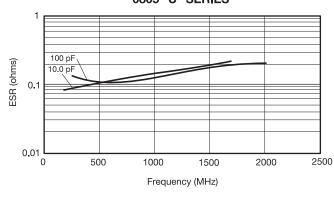
TYPICAL ESR vs. FREQUENCY 0402 "U" SERIES



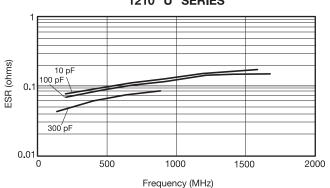
TYPICAL ESR vs. FREQUENCY 0603 "U" SERIES



TYPICAL ESR vs. FREQUENCY 0805 "U" SERIES



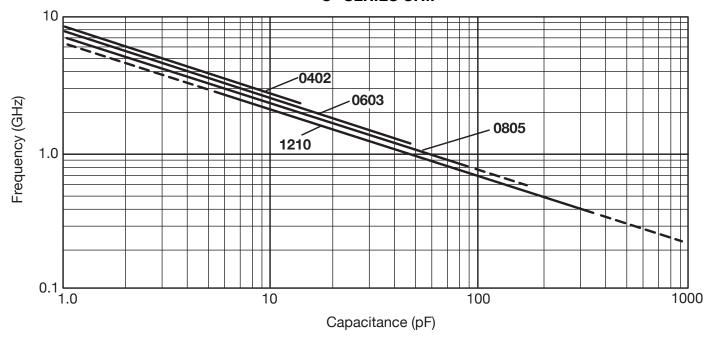
TYPICAL ESR vs. FREQUENCY 1210 "U" SERIES



ESR Measured on the Boonton 34A



TYPICAL SERIES RESONANT FREQUENCY "U" SERIES CHIP



U Dielectric

RF/Microwave Automotive C0G (NP0) Capacitors (RoHS)



AEC Q200 Qualified Ultra Low ESR, "U" Series, C0G (NP0) Chip Capacitors

GENERAL INFORMATION

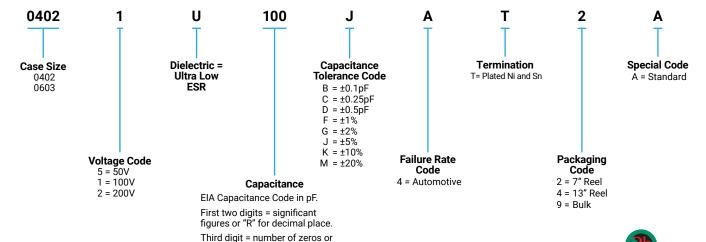
Automotive "U" Series capacitors are COG (NPO) chip capacitors specially designed for "Ultra" low ESR for applications in the automotive market. Max ESR and effective capacitance are met on each value producing lot to lot uniformity. Sizes available are EIA chip sizes 0402 and 0603.



inches (mm)

Size	Α	В	С	D	Е
0402	0.039±0.004 (1.00±0.1)	0.020±0.004 (0.50±0.1)	0.024 max (0.6)	N/A	N/A
0603	0.060±0.010 (1.52±0.25)	0.030±0.010 (0.76±0.25)	0.036 max (0.91)	0.010±0.005 (0.25±0.13)	0.030 min (0.76)

HOW TO ORDER



ELECTRICAL CHARACTERISTICS

Capacitance Values and Tolerances:

Size 0402 - 0.2 pF to 22 pF @ 1 MHz Size 0603 - 1.0 pF to 100 pF @ 1 MHz

Temperature Coefficient of Capacitance (TC):

0±30 ppm/°C (-55° to +125°C)

Insulation Resistance (IR):

 $10^{12} \Omega$ min. @ 25° C and rated WVDC $10^{11} \Omega$ min. @ 125° C and rated WVDC

Working Voltage (WVDC):

Working Voltage 0402 - 100, 50, 25 WVDC 0603 - 200, 100, 50 WVDC

Dielectric Working Voltage (DWV):

250% of rated WVDC

after "R" significant figures.

Equivalent Series Resistance Typical (ESR):

0402 See Performance Curve, page 303 0603 See Performance Curve, page 303

Automotive Specifications

Meets or exceeds the requirements of AEC Q200



LEAD-FREE

LEAD-FREE COMPATIBLE COMPONENT

120216

U Dielectric

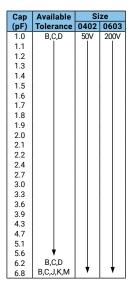
RF/Microwave Automotive C0G (NP0) Capacitors (RoHS)



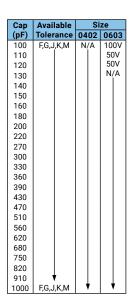
AEC Q200 Qualified, Ultra Low ESR, "U" Series, C0G (NP0) Chip Capacitors

CAPACITANCE RANGE

Cap	Available	Si	ze	
(pF)	Tolerance	0402	0603	
0.2	B,C	50V	N/A	
0.3				
0.4	♦			
0.5	B,C			
0.6	B,C,D			
0.7				
0.8	▼			
0.9	B,C,D	♦	🔻	

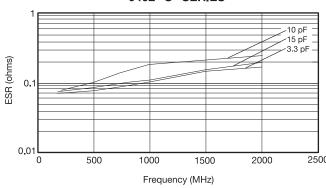


Cap	Available	Size		
(pF)	Tolerance	0402	0603	
7.5	B,C,J,K,M	50V	200V	
8.2	♦			
9.1	B,C,J,K,M			
10	F,G,J,K,M			
11				
12				
13				
15			🕈	
18			200V	
20			100V	
22				
24				
27		▼		
30		50V		
33		N/A		
36				
39				
43				
47				
51				
56				
68				
75				
82		ΙĹ		
91	▼	_ ▼	■	

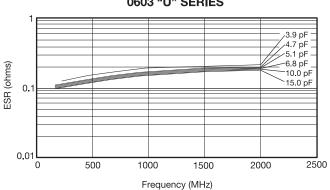


ULTRA LOW ESR, "U" SERIES

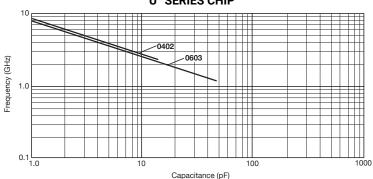
TYPICAL ESR vs. FREQUENCY 0402 "U" SERIES



TYPICAL ESR vs. FREQUENCY 0603 "U" SERIES



TYPICAL SERIES RESONANT FREQUENCY "U" SERIES CHIP





0402

	Kit 5000 UZ							
Cap. Value PF	Tolerance	Cap. Value pF	Tolerance					
0.5		4.7						
1.0		5.6	B (± 0.1pF)					
1.5		6.8	в (± 0.1pr)					
1.8	B (±0.1pF)	8.2						
2.2	в (±0.1µг)	10.0						
2.4		12.0	J (±5%)					
3.0		15.0	J (±5%)					
3.6								

^{***25} each of 15 values

0805

Kit 3000 UZ							
Cap. Value PF	Tolerance	Cap. Value pF	Tolerance				
1.0		15.0					
1.5		18.0					
2.2	D (10.125)	22.0					
2.4		24.0					
2.7		27.0					
3.0		33.0					
3.3	B (±0.1pF)	36.0	J (±5%)				
3.9		39.0	3 (±3%)				
4.7		47.0					
5.6		56.0					
7.5		68.0					
8.2		82.0					
10.0	J (±5 %)	100.0					
12.0	3 (±3 %)	130.0					

^{***25} each of 30 values

0603

Kit 4000 UZ							
Cap. Value Tolerance PF		Dierance Cap. Value To					
1.0		6.8					
1.2		7.5	B (±0.1pF)				
1.5		8.2					
1.8		10.0					
2.0		12.0					
2.4	B (±0.1pF)	15.0					
2.7	Б (±0.1рі)	18.0					
3.0		22.0	J (±5%)				
3.3		27.0					
3.9		33.0					
4.7		39.0					
5.6		47.0					

^{***25} each of 24 values

1210

	Kit 3500 UZ						
Cap. Value PF	Tolerance	Cap. Value pF	Tolerance				
2.2	B (±0.1pF)	36.0					
2.7		39.0					
4.7		47.0					
5.1		51.0					
6.8		56.0					
8.2		68.0					
9.1		82.0					
10.0		100.0	J (±5%)				
13.0		120.0					
15.0		130.0					
18.0	1/+ 5 %)	240.0					
20.0	J (± 5 %)	300.0					
24.0		390.0					
27.0		470.0					
30.0		680.0					

^{***25} each of 30 values

X8R/X8L Dielectric

General Specifications





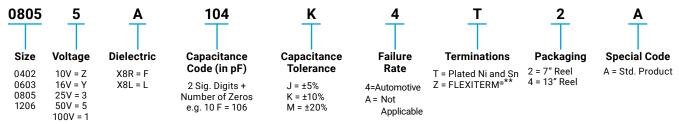
KYOCERA AVX has developed a range of multilayer ceramic capacitors designed for use in applications up to 150°C. These capacitors are manufactured with an X8R and an X8L dielectric material. X8R material has capacitance variation of ± 15% between -55°C and +150°C. The X8L material has capacitance variation of ±15% between -55°C to 125°C to 125°C and +15/40% from +125°C to +150°C.

The need for X8R and X8L performance has been driven by customer requirements for parts that operate at elevated temperatures. They provide a highly reliable capacitor with low loss and stable capacitance over temperature.

They are ideal for automotive under the hood sensors, and various industrial applications. Typical industrial application would be drilling monitoring system. They can also be used as bulk capacitors for high temperature camera modules.



Both X8R and X8L dielectric capacitors are automotive AEC-Q200 qualified. Optional termination systems, tin, FLEXITERM® and conductive epoxy for hybrid applications are available. Providing this series with our FLEXITERM® termination system provides further advantage to customers by way of enhanced resistance to both, temperature cycling and mechanical



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

Style			0603			0805		12	06
S	oldering	Ref	flow/W	ave	Ref	flow/W	ave	Reflow	/Wave
	WVDC	25V	50V	100V	25V	50V	100V	25V	50V
221	220				J	J	J		
271	270	G	G		J	J	J		
331	pF 330	G	G		J	J	J		
471	470	G	G	G	J	J	J		
681	680	G	G	G	J	J	J		
102	1000	G	G	G	J	J	J	J	J
152	1500	G	G	G	J	J	J	J	J
222	2200	G	G	G	J	J	J	J	J
332	3300	G	G	G	J	J	J	J	J
472	4700	G	G	G	J	J	J	J	J
682	6800	G	G	G	J	J	J	J	J
103	uF 0.01	G	G	G	J	J	J	J	J
153	0.015	G	G		J	J	N	J	J
223	0.022	G	G		J	J	N	J	J
333	0.033	G	G		J	J		J	J
473	0.047	G	G		J	J		J	J
683	0.068	G			N	N		М	М
104	0.1				N	N		М	М
154	0.15				N	N		М	М
224	0.22				N			М	М
334	0.33							М	М
474	0.47							М	Q
684	0.68							Q	Q
105	uF 1							Q	Q
	WVDC	25V	50V	100V	25V	50V	100V	25V	50V
	Style		0603			0805		12	06

Size		0603	0805	1206	1210
Solderin	g	Reflow/Wave	Reflow/Wave	Reflow/Wave	Reflow/Wave
Packagii	ng	All Paper	Paper/Embossed	Paper/Embossed	Paper/Embossed
(L) Length	mm	1.60 ± 0.15	2.01 ± 0.20	3.20 ± 0.20	3.30 ± 0.4
	(in)	(0.063 ± 0.006)	(0.079 ± 0.008)	(0.126 ± 0.008)	(0.130 ± 0.016)
(W) Width	mm	0.81 ± 0.15	1.25 ± 0.20	1.60 ± 0.20	2.50 ± 0.20
	(in)	(0.032 ± 0.006)	(0.049 ± 0.008)	(0.063 ± 0.008)	(0.098 ± 0.008)
(t) Terminal	mm	0.35 ± 0.15	0.50 ± 0.25	0.50 ± 0.25	0.50 ± 0.25
	(in)	(0.014 ± 0.006)	(0.020 ± 0.010)	(0.020 ± 0.010)	(0.020 ± 0.010)

X₈L

	Size			0603			0805			12	06			1210	
-	Solderin	na	Ref	flow/W	ave	Ref	flow/W	ave		Reflow			Ref	low/W	ave
<u> </u>		WVDC	25V	50V	100V	25V	50V	100V	16V	25V		100V	10V	50V	100V
271	Cap	270	G	G	1001	201		1001		201	00.				
331	(pF)	330	G	G	G	J	J	J							
471	\F-/_	470	G	G	G	J	J	Ĵ							
681		680	G	G	G	J	J	J							
102		1000	G	G	G	J	Ĵ	Ĵ		J	J				
152		1500	G	G	G	J	J	J		J	J	J			
182		1800	G	G	G	J	J	J		J	J	J			
222		2200	G	G	G	J	J	J		J	J	J			
272		2700	G	G	G	J	J	J		J	J	J			
332		3300	G	G	G	J	J	J		J	J	J			
392		3900	G	G	G	J	J	J		J	J	J			
472		4700	G	G	G	J	J	J		J	J	J			
562		5600	G	G	G	J	J	J		J	J	J			
682		6800	G	G	G	J	J	J		J	J	J			
822		8200	G	G	G	J	J	J		J	J	J			
103	Cap	0.01	G	G	G	J	J	J		J	J	J			
123		0.012	G	G		J	J	J		J	J	J			
153		0.015	G	G		J	J	J		J	J	J			
183		0.018	G	G		J	J	J		J	J	J			
223		0.022	G	G		J	J	J		J	J	J			
273		0.027	G	G		J	J	J		J	J	J			
333		0.033	G	G		J	J	N		J	J	J			
393		0.039	G	G		J	J	N		J	J	J			
473		0.047	G	G		J	J	N		J	J	J			
563		0.056	G	G		J	J	N		J	J	J			
683		0.068	G	G		J	J	N		J	J	J			
823		0.082	G	G		J	J	N		J	J	J			
104		0.1	G	G		J	J	N		J	J	М			
124		0.12				J	N			J	J	M			
154		0.15				J	N		J	J	J	Q			
184		0.18		-		N N	N N	<u> </u>	J	J	J	Q		-	
224 274		0.22				N	IN		J	J M	J M	Q			_
334		0.27		-		N		-	J	M	M	Q			-
394	<u> </u>	0.33		-		N	-	-	M	M	P	Q		-	-
474	_	0.39				N	<u> </u>	<u> </u>	M	M	P	Q			
684		0.47				N	_	 	M	M	P	Q			<u> </u>
824		0.82				N		_	M	M	P	Q			\vdash
105		1				N			M	M	P	Q			
155		1.5				14			M	M		٧			
225		2.2							M	M				Z	Z
475		۷.۷								141				Z	
106													Z		
	· · ·	WVDC	25V	50V	100V	25V	50V	100V	16V	25V	50V	100V	10V	50V	100V
	SIZE			0603	, ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		0805	, ,,,,,,,			06	, ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,		1210	

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max. Thickness	0.33 (-0.013)	0.56 (-0.022)	0.71 (-0.028)	0.9 (-0.035)	0.94 (-0.037)	1.02 (-0.04)	1.27 (-0.05)	1.4 (-0.055)	1.52 (-0.06)	1.78 (-0.07)	2.29 (-0.09)	2.54 (-0.1)	2.79 (-0.11)
			PAPER						FMB0:	SSFD			



X8R/X8L Dielectric

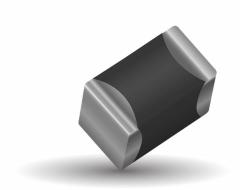
General Specifications



APPLICATIONS FOR X8R AND X8L CAPACITORS

- All market sectors with a 150°C requirement
- Automotive on engine applications
- Oil exploration applications
- · Hybrid automotive applications
 - Battery control
 - Inverter / converter circuits
 - Motor control applications
 - Water pump
- Hybrid commercial applications
 - Emergency circuits
 - Sensors
 - Temperature regulation





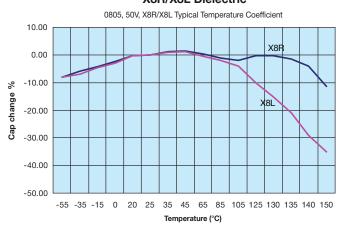
ADVANTAGES OF X8R AND X8L MLC CAPACI-TORS

- Both ranges are qualified to the highest automotive AEC-Q200 standards
- Excellent reliability compared to other capacitor technologies
- RoHS compliant
- Low ESR / ESL compared to other technologies
- Tin solder finish
- FLEXITERM® available
- Epoxy termination for hybrid available
- 100V range available

ENGINEERING TOOLS FOR HIGH VOLTAGE MLC CAPACITORS

- Samples
- **Technical Articles**
- **Application Engineering**
- **Application Support**

X8R/X8L Dielectric



X8R/X8L Dielectric





Parame	ter/Test	X8R/X8L Specification Limits	Measuring (Conditions
Operating Tem	perature Range	-55°C to +150°C	Temperature C	ycle Chamber
Capac	itance	Within specified tolerance	Freg.: 1.0 k	Hz + 10%
Dissipati	on Factor	≤ 2.5% for ≥ 50V DC rating ≤ 3.5% for 25V DC and 16V DC rating	Voltage: 1.0	
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with rated @ room tem	
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250 1-5 seconds, w/charge limited to 50 Note: Charge device with for 500V	and discharge current mA (max) n 150% of rated voltage
	Appearance	No defects	Deflectio	n: 2mm
Resistance to	Capacitance Variation Dissipation Factor Insulation Resistance Solderability Appearance Capacitance Variation Dissipation Factor Insulation Factor Insulation Factor Insulation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Dissipation Factor Insulation Resistance Dielectric Strength Appearance Capacitance Variation Dissipation Factor	≤ ±12%	Test Time: 3	
Flexure Stresses		Meets Initial Values (As Above)		
		≥ Initial Value x 0.3	90 r	mm ————
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic solo 0.5 sec	
	Appearance	No defects, <25% leaching of either end terminal		
		≤ ±7.5%	Din dovice in cute eti	a colder at 26000 for
Resistance to Solder Heat		Meets Initial Values (As Above)	Dip device in eutection 60 seconds. Store at 24 ± 2 hours before r	room temperature for
		Meets Initial Values (As Above)	properties.	J
		Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
		≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock		Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro	
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 r test chamber set	
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hou	
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test chamb temperature for 24 ± 2 h	
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Store in a test chamber s 5% relative humidi	ty for 1000 hours
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated	voltage applied.
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature and humidity measu	for 24 ± 2 hours before
	Dielectric Strength	Meets Initial Values (As Above)	ineasu	y

100917

General Specifications





X7R formulations are called "temperature stable" ceramics and fall into EIA Class II materials. X7R is the most popular of these intermediate dielectric constant materials. Its temperature variation of capacitance is within ±15% from -55°C to +125°C. This capacitance change is non-linear.

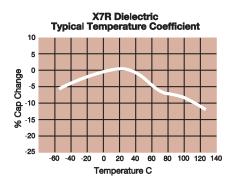
Capacitance for X7R varies under the influence of electrical operating con-ditions such as voltage and frequency.

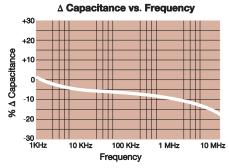
X7R dielectric chip usage covers the broad spectrum of industrial applications where known changes in capacitance due to applied voltages are acceptable.

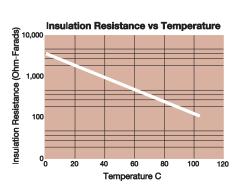
PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

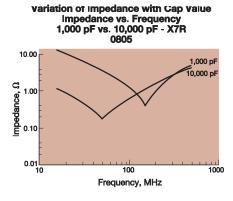
0805	<u>5</u>	C	103	M	A	<u>T</u>	2	A
Size (L" x W")	Voltage 4V = 4 6.3V = 6 10V = Z 16V = Y 25V = 3 50V = 5	Dielectric X7R = C	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance $J = \pm 5\%^*$ $K = \pm 10\%$ $M = \pm 20\%$	Failure Rate A = Not Applicable	Terminations T = Plated Ni and Sn Z= FLEXITERM®** *Optional termination **See FLEXITERM®	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples	Special Code A = Std. Product
	100V = 1 200V = 2 500V = 7			*≤1μF only, contact factory fo additional values		X7R section	a.a.piec	

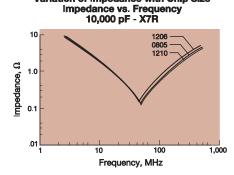
Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.



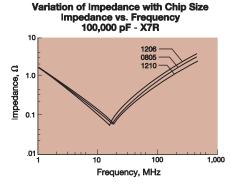








Variation of Impedance with Chip Size







Paramete	er/Test	X7R Specification Limits	М	easuring Conditions
Operating Tempo		-55°C to +125°C	Temp	perature Cycle Chamber
Capacit Dissipation		Within specified tolerance ≤ 10% for ≥ 50V DC rating≤ 12.5% for 25V DC rating ≤ 12.5% for 25V and 16V DC rating ≤ 12.5% for ≤ 10V DC rating Contact Factory for DF by PN	Vo	Freq.: 1.0 kHz ± 10% oltage: 1.0Vrms ± .2V o > 10μF, 0.5Vrm @ 120Hz
Insulation R	esistance	100,000MΩ or 1000MΩ - μF, whichever is less		levice with rated voltage for ecs @ room temp/humidity
Dielectric S	Strength	No breakdown or visual defects	charge and disch	50% of rated voltage for 1-5 seconds, w/ arge current limited to 50 mA (max) th 150% of rated voltage for 500V devices.
	Appearance	No defects		
Resistance to	Capacitance Variation	≤ ±12%		Deflection: 2mm
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	T€	est Time: 30 seconds
	Insulation Resistance	≥ Initial Value x 0.3		
Soldera	bility	≥ 95% of each terminal should be covered with fresh solder		in eutectic solder at 230 ± 5°C or 5.0 ± 0.5 seconds
	Appearance	No defects, <25% leaching of either end terminal		
	Capacitance Variation	≤ ±7.5%		
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic room temperature for	solder at 260°C for 60 seconds. Store at 24 ± 2hours before measuring electrical
Solder Heat	Insulation Resistance	Meets Initial Values (As Above)		properties.
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	,	and measure after 24 ± 2 hours at room temperature
	Appearance Capacitance Variation	No visual defects ≤ ±12.5%	Pre-treatment: After m 10C for 2 hour, then	ounting, perform heat treatment 150+0/- stabilise for 24+/-2 hour at room temp, then measure.
	Dissipation Factor	≤ Initial Value x 2.0 (See Above)		≥ rated voltage in test chamber set at
Load Life	Insulation Resistance	≥ Initial Value x 0.3 (See Above)		2°C for 1000 hours (+48, -0).
	Dielectric Strength	Meets Initial Values (As Above)	treatment 150+0/-100 at roo	emove from test chamber, perform heat of or 2 hour, then stabilise for 24+/-2 hour om temp, then measure. A AVX for datasheet of specific parts.
	Appearance	No visual defects	Pre-treatment: After m	ounting, perform heat treatment 150+0/-
	Capacitance Variation	≤ ±12.5%	10C for 2 hour, then	stabilise for 24+/-2 hour at room temp, then measure.
Load	Dissipation Factor	≤ Initial Value x 2.0 (See Above)		per set at 85°C ± 2°C/ 85% ± 5% relative
Humidity	Insulation Resistance	≥ Initial Value x 0.3 (See Above)		emove from test chamber, perform heat
	Dielectric Strength	Meets Initial Values (As Above)	treatment 150+0/-100	for 2 hour, then stabilise for 24+/-2 hour om temp, then measure.





PREFERRED SIZES ARE SHADED

SIZE		0101*			0201					04	102						06	603							ns	05								1206				
Soldering	\dashv	Reflow Only			flow (1		Reflo		Ve		\vdash			Reflow		/e			\vdash		R		//Wav	/e							ow/V		—		-
Packaging		Paper/ Embossed			II Pap						Paper							aper								mbos						-			osse	 d	_	
	mm (in.)	0.40 ± 0.02 (0.016 ± 0.0008)			50 ± 0 24 ± 0					1.00							1.60									± 0.20								20 ± 0 26 ± 0		_		
W) Width	mm	0.20 ± 0.02 (0.008 ± 0.0008)		0.3	30 ± 0	.09				0.50	± 0.1	0					0.81	± 0.1	5						1.25	± 0.20)						1.6	60 ± 0				
ì	mm	0.10± 0.04			15 ± 0			1	<u> </u>	0.25				\vdash			0.35									± 0.25							_	50 ± 0				-
		(0.004 ± 0.0016)			06 ± 0					0.010							.014									± 0.01								20 ± 0				
WVDC		16	6.3	10	16	25	50	6.3	10	16	25	50	100	6.3	10	16	25	50	100	200	250	6.3	10	16	25	50	100	200	250	6.3	10	16	25	50	100	200	250	500
Cap 100 1	101	В	Α	Α	Α	Α	Α	С	С	С	С	С	С	G	G	G	G	G	G	J	J													G	G	N	Ν	N
(pF) 150 1	151	В	Α	Α	Α	Α	Α	С	С	С	С	С	С	G	G	G	G	G	G	J	J									G	G	G	G	G	G	N	Ν	N
220 2	221	В	Α	Α	Α	Α	Α	С	С	С	С	С	С	G	G	G	G	G	G	J	J	Е	Е	Е	Е	Е	Е	Е	J	J	J	J	J	J	J	N	N	Р
	331	В	Α	Α	Α	Α	Α	С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	J	J	J	J	J	J	J	J	N	Ν	Р
470 4	171	В	Α	Α	Α	Α	Α	С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	J	J	J	J	J	J	J	J	N	Ν	Р
	81	В	Α	Α	Α	Α	Α	С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	J	J	J	J	J	J	J	J	N	N	Р
	102	В	Α	Α	Α	Α	Α	С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	J	J	J	J	J	J	J	J	N	Ν	Р
	52	·	Α	Α	Α	Α		С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	J	J	J	J	J	J	J	J	Z	Ζ	Р
	222		Α	Α	Α	Α		С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	J	J	J	J	J	J	J	J	N	Ν	Р
	332		Α	Α	Α	Α		С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	J	J	J	J	J	J	J	J	N	N	Р
	392		Α	Α	Α	Α						_																										ш
	172		Α	Α	Α	Α		С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	J	J	J	J	J	J	J	J	N	N	Р
	562		Α	Α	Α	Α																																ш
	582		Α	Α	Α	Α		С	С	С	C	С	С	G	G	G	G	G	G	J	J	<u> </u>	J	J	J	J	J	Р	Р	J	J	J	J	J	J	N	N	Р
	103		Α	Α	Α	Α		С	С	С	С	С	С	G	G	G	G	G	G	J	J		J	J	J	J	J	Р	Р	J	J	J	J	J	J	N	N	Р
. ,	123																																					ш
	153				_			С	С	С	С	E	_	G	G	G	G	G	J	J	J		J	J	J	J	J	Р	Р	J	J	J	J	J	J	N	N	Q
	183											-								١.									_								_	
	223		Α	Α	Α			С	С	С	С	E	_	G	G	G	G	G	J	J	J		J	J	J	J	J	Р	Р	J	J	J	J	J	J	Р	Р	Q
	273											-						١.	١.		-						_	_	-								_	
	333		_	_	\vdash		_	С	С	С	С	E	-	G	G	G	G	J	J	-	-		J	J	J	J	Р	Р	Р	J	J	J	J	J	J	Q	Q	Q
	173		_	_	-			С	С	С	С	Е		G	G	G	G	J	J		-	_	J	J	J		Р	Р	Р	J	J	J	J	J	J		0	Q
	683		_	_	\vdash		_	С	С	C	-	E	_	G	G	G	-	-	-	_	-		_	-	J	J	Р	P	Р	J	J		J	J	P	Q Q	Q	Ų
	323		-	\vdash	\vdash	-	\vdash	U	U	U	С	=	-	G	G	G	G	J	J	-	\vdash	\vdash	J	J	J	J	Р	Р	-	J	J	J	J	J	P	Ų	Q	\vdash
	04		Α					С	С	С	С	Е		G	G	G	G	J	J				J	J	J	J	Р	Р		J	J	J	J	J	Р	Q	Q	\vdash
0.12 1	\rightarrow		-		\vdash		-				+	-			0	-	0	3	1		\vdash		3	3	3	3		'		3	3	3	3	3	i.	ų.	Q	\vdash
0.12	_				\vdash			+	\vdash		+	+	\vdash	G	G	G	J	J		\vdash	\vdash	\vdash	N	N	N	N	Р			K	K	K	K	K	Q	Q	Q	\dashv
	224				1			С	С	С	С			G	G	J	J	J		<u> </u>	1		N	N	N	N	P			K	K	K	K	K	Q	Q	ν	\dashv
	334				\vdash								\vdash	J	J	J	J	J			\vdash		P	Р	P	P	P			K	K	K	K	N	Q			\dashv
0.47 4	\rightarrow				\vdash			С	С		1		\vdash	J	J	J	J	J			\vdash		P	P	P	P	P			М	М	М	М	X	X			\neg
	584				1						t			J	J	J					1		P	P	Р					М	М	М	М	Х	Х			\neg
1.0 1								С		t	T			J	J	J	J	K		T	1		Р	P	Р	Р				М	М	М	М	Х	Х			\neg
2.2 2	\rightarrow				t					T		1	t	J	J	К			1	l	t		Р	Р	Р	Р				М	М	М	Х	Х	Х			П
4.7 4								1						K									Р	Р	Р					Х	Х	Х	Х	Z				\neg
10 1											1											Р	Р	Р						Х	Х	Х	Х					\neg
22 2	226																													Х	Х							\Box
	176				i i										İ						İ																	\neg
100 1	107				i i			1							İ						İ									Ì								\neg
WVDC		16	6.3	10	16	25	50	6.3	10	16	25	50	100	6.3	10	16	25	50	100	200	250	6.3	10	16	25	50	100	200	250	6.3	10	16	25	50	100	200	250	500
SIZE		0101*			0201					04	102						06	03							90	05								1206	5			
								•																														

Letter	Α	В	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max. Thickness	0.33 (0.013)	0.22 (0.009)	0.56 (0.022)	0.71 (0.028)	0.90 (0.035)	0.94 (0.037)	1.02 (0.040)	1.27 (0.050)	1.40 (0.055)	1.52 (0.060)	1.78 (0.070)	2.29 (0.090)	2.54 (0.100)	2.79 (0.110)
			PAI	PER						EMBO	SSED			

NOTE: Contact factory for non-specified capacitance values

^{*}EIA 01005

^{**}Contact Factory for Specifications





PREFERRED SIZES ARE SHADED

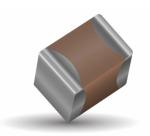
	SIZE					1210						18	12				1825				2220				2225	
	Soldering				R	eflow Or	nly					Reflo	w Only			R	eflow Or	nly		R	eflow Or	nly		R	eflow On	lly
	Packaging					er/Embo							bossed				I Embos:				Embos				Emboss	,
(L) Ler	ngth	mm (in.)				3.30 ± 0. 130± 0.0							± 0.40 ± 0.016)				1.50 ± 0.4 177 ± 0.0				5.70 ± 0.9 224 ± 0.0				.70 ± 0.4 224 ± 0.0	
W) Wid	dth	mm (in.)				.50 ± 0.3 .98 ± 0.0						3.20 (0.126	± 0.40 ± 0.016)				5.40 ± 0.4 252 ± 0.0				5.00 ± 0.4 197 ± 0.0				.30 ± 0.4 248 ± 0.0	
(t) Ter	minal	mm (in.)				.50 ± 0.2 020 ± 0.0							± 0.36 ± 0.014)				0.61 ± 0.3 024 ± 0.0				0.64 ± 0.0 025 ± 0.0				.64 ± 0.3)25 ± 0.0	
	V	VVDC	10	16	25	50	100	200	500	16	25	50	100	200	500	50	100	200	25	50	100	200	500	50	100	200
Cap	100	101																					ļ	>	~ N	, _
(pF)	150	151																					4		7	1
	220	221				K	K	K	М														(7) <u>1</u>
	330	331				K	K	K	М			N	N	N	N								_	$\overline{}$		
	470	471				K	K	K	М			N	N	N	N								Ţ	a-t		
	680	681				K	K	K	М			N	N	N	N									1 000		
	1000	102	K	K	K	K	K	K	М	N	N	N	N	N	N	Х	Х	X		Х	Х	Х	X	Х	Х	Х
	1500	152	K	K	K	K	K	K	М	N	N	N	N	N	N	Х	Х	Х		Х	Х	X	Х	Х	Х	Х
	2200	222	K	K	K	K	K	K	М	N	N	N	N	N	N	Х	X	Х		Х	Х	Х	Х	Х	Х	Х
	3300	332	K	K	K	K	K	K	Р	N	N	N	N	N	N	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	4700	472	K	K	K	K	K	K	Р	N	N	N	N	N	Р	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	6800	682	K	K	K	K	K	K	P	N	N	N	N	N	Р	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
Cap	0.01	103	K	K	K	K	K	K	P	N	N	N	N	N	Р	Х	Х	Х		Х	Х	Х	Х	Х	Х	X
(µF)	0.015	153	K	K	K	K	K	K	P	N	N	N	N	N	Р	Х	Х	Х		Х	Х	Х	Х	Х	Х	X
	0.022	223	K	K	K	K	K	Р	Q	N	N	N	N	N	Р	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.033	333	K	K	K	K	K	Р	Х	N	N	N	N	N	Х	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.047	473	K	K	K	K	K	Р	Х	Ν	N	N	N	Р	Х	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.068	683	K	K	K	K	K	P	Х	Ν	N	N	N	Р	Х	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.1	104	K	K	K	K	K	Р	Х	Ν	N	N	P	Р	Х	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.15	154	K	K	K	М	Р	Z	Z	Ν	N	N	Р	Р	Z	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.22	224	K	K	K	М	Р	Z		Ν	N	N	Р	Q	Z	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.33	334	K	K	K	М	Q	Z		N	N	N	Р	Х	Z	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.47	474	М	М	М	Р	Q	Z		N	N	N	Q	Х	Z	Х	Х	Х		Х	Х	Х	Х	Х	Х	Х
	0.68	684	М	М	Р	Х	Х	Z		Q	Q	Q	Q	Z		Х	Х	Х		Х	Х	Х	Z	Х	Х	Х
	1.0	105	Р	Р	Р	Х	Z			Q	Q	Q	Х	Z		Х	Х	Х		Х	Х	Х	7	Х	Х	Х
	1.5	155	N	N	Z	Z	Z				Z	Z	Z			Х	Х	Z		Х	Х	Z		Х	Х	Z
	2.2	225	Х	Х	Z	Z	Z				Z	Z	Z			Х	Х	Z		Х	Х	Z		Х	Х	Z
	3.3	335	Х	Х	Z	Z	Z				Z	Z	Z			Х	Х			Х	Z			Х	Х	
	4.7	475	Z	Z	Z	Z	Z				Z	Z	Z			Х	Х			Z	Z			Х	Х	
	10	106	Z	Z	Z	Z				Z	Z	Z				Z	Z			Z	Z			Z	Z	
	22	226	Z	Z	Z														Z							
	47	476	Z																							
	100	107																								
	WVDC		10	16	25	50	100	200	500	16	25	50	100	200	500	50	100	200	25	50	100	200	500	50	100	200
	SIZE					1210						18	12				1825				2220				2225	

Letter	Α	В	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z	7
Max.	0.33	0.22	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79	3.30
Thickness							(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)	(0.130)
			PAI	PER							MBOSSEI)			

NOTE: Contact factory for non-specified capacitance values

General Specifications





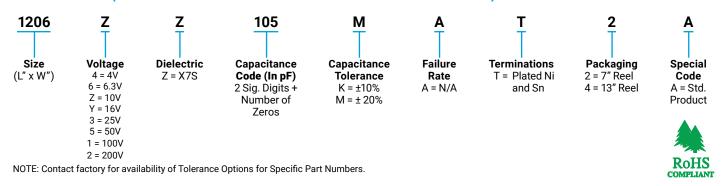
GENERAL DESCRIPTION

X7S formulations are called "temperature stable" ceramics and fall into EIA Class II materials. Its temperature variation of capacitances within ±22% from -55°C to +125°C. This capacitance change is non-linear.

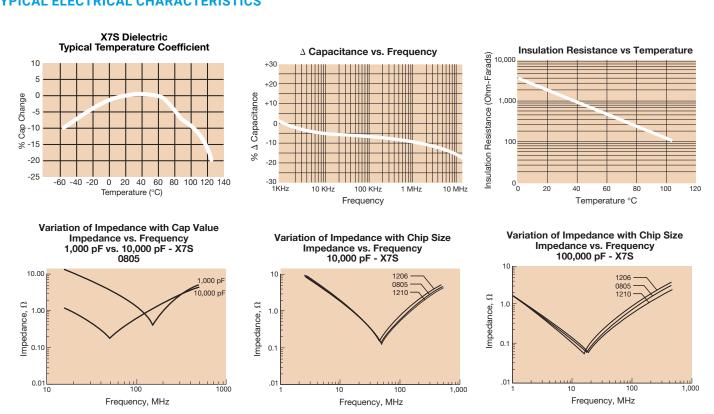
Capacitance for X7S varies under the influence of electrical operating conditions such as voltage and frequency.

X7S dielectric chip usage covers the broad spectrum of industrial applications where known changes in capacitance due to applied voltages are acceptable.

PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)



TYPICAL ELECTRICAL CHARACTERISTICS







Parame	ter/Test	X7S Specification Limits	Measuring	Conditions
	perature Range	-55°C to +125°C	Temperature C	ycle Chamber
	on Factor	Within specified tolerance ≤ 5.0% for ≥ 100V DC rating ≤ 5.0% for ≥ 25V DC rating ≤ 10.0% for ≥ 10V DC rating ≤ 10.0% for ≤ 10V DC rating Contact Factory for DF by PN	Freq.: 1.0 k Voltage: 1.0 For Cap > 10 μF, 0	Vrms ± .2V
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with 120 ± 5 secs @ roo	
Dielectric	Strength	No breakdown or visual defects	Charge device with 250 1-5 seconds, w/charge limited to 50	and discharge current
	Appearance	No defects	Deflection	
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3	-
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)		
	Insulation Resistance	≥ Initial Value x 0.3	90 1	mm —
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutection for 5.0 ± 0.	
	Appearance	No defects, <25% leaching of either end terminal		
	Capacitance Variation	≤ ±7.5%		
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room	temperature for 24 ± 2
	Insulation Resistance	Meets Initial Values (As Above)	hours before measurin	g electrical properties.
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro	and measure after oom temperature
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5	
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	test chamber se for 1000 hou	rat 125°C ± 2°C urs (+48, -0)
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test chamb temperature for 24 ± 2 h	
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Store in a test chamber s 5% relative humidi	
Load	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rate	d voltage applied.
Humidity	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature ar	nd humidity for
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 hours bef	ore measuring.

Capacitance Range



PREFERRED SIZES ARE SHADED

				=					
SIZ	E	0	402	0603	0805		1206		1210
Solder		Reflo	w/Wave	Reflow/Wave	Reflow/Wave	Ref	low/W	ave	Reflow Only
Packa			Paper	All Paper	Paper/Embossed		r/Embo		Paper/Embossed
	mm) ± 0.10	1.60 ± 0.15	2.01 ± 0.20		20 ± 0.		3.20 ± 0.20
(L) Length	(in.)		± 0.004)	(0.063 ± 0.006)	(0.079 ± 0.008)		26 ± 0.		(0.126 ± 0.008)
140 140 141	mm		± 0.10	0.81 ± 0.15	1.25 ± 0.20		60 ± 0.:		2.50 ± 0.20
W) Width	(in.)	(0.020	± 0.004)	(0.032 ± 0.006)	(0.049 ± 0.008)	(0.0	63 ± 0.	(800	(0.098 ± 0.008)
(t)	mm		± 0.15	0.35 ± 0.15	0.50 ± 0.25		50 ± 0.:		0.50 ± 0.25
Terminal	(in.)	(0.010	± 0.006)	(0.014 ± 0.006)	(0.020 ± 0.010)	(0.0	20 ± 0.	010)	(0.020 ± 0.010)
	WVDC	4	6.3	6.3	4	10	50	100	6.3
Сар	100								
(pF)	150		İ			İ			
[220						_	I	
	330					Ī	1-	1	\sim W \sim
	470					*			
	680					1	_		J ↓T
	1000					١ ١	_		
	1500							<u> </u>	
	2200							4	
	3300					Ī		111	
	4700								
İ	6800		İ						
Сар	0.010								
(μF)	0.015								
" /	0.022		İ			İ			
	0.033		С						
	0.047		С						
	0.068		С						
	0.10		C						
	0.15								
	0.22								
	0.33			G					
	0.47			G					
	0.68			G		ĺ			
	1.0	Е		G					
[1.5		1		N	ĺ		l	
[2.2	E			N	l		Q	
	3.3				N				
	4.7				N	Q			
	10		ĺ						
	22								Z
	47								
	100								
	WVDC	4	6.3	6.3	4	10	50	100	6.3
	SIZE	0	402	0603	0805		1206	•	1210

Letter	Α	С	E	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.90	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.075)	(0.090)	(0.100)	(0.110)
			PAPER						EMBO	SSED			

^{*}Contact Factory for Specifications

General Specifications





GENERAL DESCRIPTION

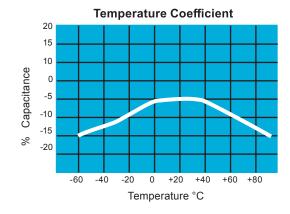
- · General Purpose Dielectric for Ceramic Capacitors
- EIA Class II Dielectric
- Temperature variation of capacitance is within ±15% from -55°C to +85°C
- Well suited for decoupling and filtering applications
- Available in High Capacitance values (up to 100μF)

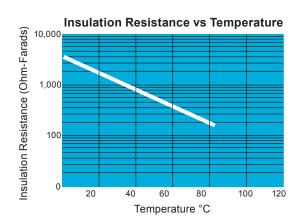
PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

1210	4	D	107	M	Α	T	2	Α
	T	T	T	T	T	T	T	T
Size	Voltage	Dielectric	Capacitance	Capacitance	Failure	Terminations	Packaging	Special
(L" x W")	4 = 4V	D = X5R	Code (In pF)	Tolerance	Rate	T = Plated Ni	2 = 7" Reel	Code
0101**	6 = 6.3V		2 Sig. Digits +	$K = \pm 10\%$	A = N/A	and Sn	4 = 13" Reel	A = Std.
0201	Z = 10V		Number of	$M = \pm 20\%$				
0402	Y = 16V		Zeros					
0603	3 = 25V							
0805	D = 35V							A .
1206	5 = 50V							
1210	1 = 100V							The same
1812								
**EIA 010	005							RoHS COMPLIANT

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

TYPICAL ELECTRICAL CHARACTERISTICS





121720





Parame	ter/Test	X5R Specification Limits	Measuring C	onditions
Operating Tem		-55°C to +85°C	Temperature Cy	cle Chamber
Capac Dissipati	itance on Factor	Within specified tolerance ≤ 2.5% for ≥ 50V DC rating ≤ 12.5% for 25V, 35V DC rating ≤ 12.5% Max. for 16V DC rating and lower Contact Factory for DF by PN	Freq.: 1.0 kH Voltage: 1.0V For Cap > 10 μF, 0.5	rms ± .2V
Insulation	Resistance	10,000MΩ or 500MΩ - μF, whichever is less	Charge device with rate secs @ room te	
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250% seconds, w/charge and disto 50 mA	scharge current limited
	Appearance	No defects	Deflection	: 2mm
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 30) seconds 1mm/sec
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)		
	Insulation Resistance	≥ Initial Value x 0.3	90 m	m
Solder	ability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic sold ± 0.5 sec	
	Appearance	No defects, <25% leaching of either end terminal		
	Capacitance Variation	≤ ±7.5%		
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic 60seconds. Store at room	n temperature for 24 ±
	Insulation Resistance	Meets Initial Values (As Above)	2hours before measuring	g electrical properties.
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and hours at room t	
	Appearance	No visual defects	Charge device with 1.5X	rated voltage in test
	Capacitance Variation	≤ ±12.5%	chamber set at 85°C ± (+48, -	2°C for 1000 hours
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	Note: Contact factory for part numbers that are to	
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	voltag	
	Dielectric Strength	Meets Initial Values (As Above)	Remove from test chambe temperature for	
	Appearance	No visual defects		
	Capacitance Variation	≤ ±12.5%	Store in a test chamber se 5% relative humidity for 10	
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	rated voltage	e applied.
,	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber a temperature and 24 ± 2 hours befo	l humidity for
	Dielectric Strength	Meets Initial Values (As Above)	2122110010 0010	

Capacitance Range



PREFERRED SIZES ARE SHADED

Case Size		010	01*			0201 Reflow Only					04	02						0603							0805			
Soldering		Reflov	v Only		Re	flow 0	nly			-	Reflow	/Wav	e				Refl	ow/W	feve					Ref	ow/W	feve		
Packaging		Paper/Er				II Pape						aper						II Pap								ossed		
(L) Length	mm (in.)	0.40 : (0.016 ±	± 0.02		0.6	60 ± 0. 24 ± 0.	09				1.00 :	± 0.20 ± 0.00					1.6	60 ± 0 63 ± 0	.20					2.0	01 ± 0 79 ± 0	.20		
W) Width	mm (in.)	0.20 ±				30 ± 0. 11 ± 0.						± 0.20 ± 0.00						80 ± 0 31 ± 0							25 ± 0 49 ± 0			
(t) Terminal	mm (in.)	0.10 : (0.004 ±				15 ± 0. 06 ± 0.						± 0.15 ± 0.00						35 ± 0 14 ± 0							50 ± 0 20 ± 0			
Voltage:	`	6.3	10	4	6.3	10	16	25	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50
Cap (pF) 100	101		В					Α																				
150	151		В					Α																				
220	221		В					Α						С														
330	331		В					Α						С														
470	471		В					Α						С														
680	681		В					Α						С														
1000	102		В				Α	Α						С														
1500	152	В	В				Α	Α						С														
2200	222	В	В			Α	Α	Α						С														
3300	332	В	В			Α	Α	Α						С														
4700	472	В	В			Α	Α	Α					С								G							
6800	682	В	В			Α	Α	Α					С								G							
Cap (µF) 0.01	103	В	В			Α	Α	Α					С						G	G	G							
0.015	150	В											С						G	G	G							
0.022	223	В			Α	Α	Α	Α				С	С						G	G	G							N
0.033	333	В										С							G	G	G							N
0.047	473	В			Α	Α	Α	Α				С	С						G	G	G							N
0.068	689	В										С							G		G				ļ			N
0.1	104	В			Α	Α	Α	Α			С	С	С	С					G	G	G					N	N	N
0.15	154	_																	G						_	N	N	
0.22	224	В		Α	Α	Α				С	С	С	С	С				G	G							N	N	N
0.33	334													-				G	G	_					-	N	_	
0.47	474 684	В		Α	Α				С	С	С	С	С	E				G	J							N	Р	Р
0.68				Α	Α		_		_	_	_	_	0	_			_	G		_	_	<u> </u>	-		N.I.	N	P	Р
1.0	105 155			Α	Α	С	С		С	С	С	С	С	_	G	G	G	G	J	G	G	_	-	-	N	N	Р	Р
2.2	225			С	С	С			С		С	С	С	_	_		1			V	V		-	NI	NI	P	P	Р
3.3	335			U	U	U	-		U	С	U	U	U		G	G	J	J	J	K	K		N	N N	N	P	P	Р
4.7	475			С	С	-	-	-	Е	Е	Е	Е	-	-	J	J	J	G	K		-	N	P	J	N	N	P	Р
10	106			U	U		_	_	E	E	E	Е	-		K	J	K	K	K		-	P	P	P	P	P	Р	P
22	226				-				E	G			_		K	K	K	I.	I N			P	P	P	P	P		$\vdash\vdash\vdash$
47	476					1	-			G	-				K	K			-			P	P	P				$\vdash\vdash$
100	107				 		 		-	-	 		\vdash	-	IX	IX		-	 	-					 	<u> </u>		$\vdash \vdash \vdash$
Voltage:	107	6.3	10	4	6.3	10	16	25	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50
Case Size		0.5		0201				0.0		02		00		0.0		0603			- 00		0.0		0805		, 00	_ 55		
Cast bize												_						3000							3000			

Letter	Α	В	С	E	G	J	K	М	N	Р	Q	Х	Y	Z
Max. Thicknes	0.33 s (0.013)	0.22 (0.009)	0.56 (0.022)	0.71 (0.028)	0.90 (0.035)	0.94 (0.037)	1.02 (0.040)	1.27 (0.050)	1.40 (0.055)	1.52 (0.060)	1.78 (0.070)	2.29 (0.090)	2.54 (0.100)	2.79 (0.110)
	, ,	, ,	PA	PER	,	,	, ,			EMBC	SSED		, ,	

PAPER and EMBOSSED available for 01005 NOTE: Contact factory for non-specified capacitance values *EIA 01005





PREFERRED SIZES ARE SHADED

Case Size					1206							1210							1812			
Soldering				Refl	ow/W						Re	flow C						Re	flow 0			
Packaging				Paper	/Emb	ossec	<u></u>					/Emb							Embos			
(L) Length	mm				20 ± 0.							20 ± 0.							50 ± 0.			
	(in.)				26 ± 0. 50 ± 0.							26 ± 0. 50 ± 0.							77 ± 0. 20 ± 0.			
W) Width	mm (in.)				50 ± 0. 53 ± 0.							98 ± 0.							20 ± 0. 26 ± 0.			
(t) T	mm				50 ± 0.							50 ± 0.							61 ± 0.			
(t) Terminal	(in.)				20 ± 0.							20 ± 0							24 ± 0.			
Voltage:		4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50
Cap (pF) 100	101																					
150	151																					
220	221																					
330	331																					
470	471																					
680	681																					
1000	102																					
1500	152																					
2200	222																					
3300	332																					
4700	472																					
6800	682																					
Cap (µF) 0.01	103																					
0.015	150																					
0.022	223																					
0.033	333																					
0.047	473																					
0.068	689																					
0.1	104																					
0.15	154																					
0.22	224																					
0.33	334					_								\ \								
0.47 0.68	474 684					Q	Q							Х	Х							
1.0	105					0	_	0					Х	Х	Х							
1.5	155					Q	Q	Q					٨	^	٨							
2.2	225			Q	Q	0	0	Q					Х	Z	Z				\vdash			
3.3	335		Q	Q	Ų	Ų	Ų	Ų					٨						-	-		-
4.7	475	Χ	X	X	Х	Х	Х	Х			Z	Z	Z	Z	Z							
10	106	X	X	X	X	X	X	X		Х	X	Z	Z	Z	Z					Z		
22	226	X	X	X	X	X	^	^	Z	Z	Z	Z	Z			Z	Z	Z	Z			
47	476	X	X	X	X	^			Z	Z	Z	Z	Z									1
100	107	X	X	_ ^					Z	Z												
Voltage:	107	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50
Case Size					1206				•			1210				•			1812			

Letter	Α	В	С	E	G	J	K	М	N	P	Q	X	Υ	Z
Max.	0.33	0.22	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.009)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PA	PER						EMBO:	SSED			

PAPER and EMBOSSED available for 01005

NOTE: Contact factory for non-specified capacitance values *EIA 01005

Y5V Dielectric

General Specifications





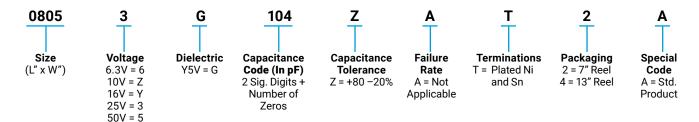
GENERAL DESCRIPTION

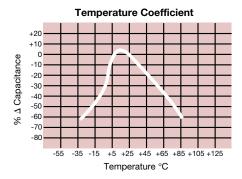
Y5V formulations are for general-purpose use in a limited temperature range. They have a wide temperature characteristic of +22% −82% capacitance change over the operating temperature range of −30°C to +85°C.

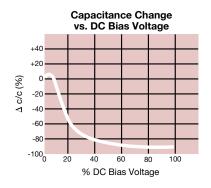
These characteristics make Y5V ideal for decoupling applications within limited temperature range.

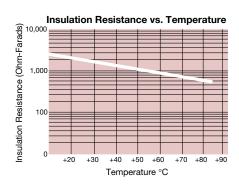


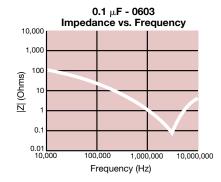
PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

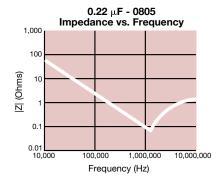


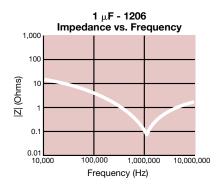












Y5V Dielectric





Parame	ter/Test	Y5V Specification Limits	Measuring (Conditions
Operating Tem	perature Range	-30°C to +85°C	Temperature C	ycle Chamber
Capac	itance	Within specified tolerance		
Dissipation	on Factor	≤ 5.0% for ≥ 50V DC rating ≤ 7.0% for 25V DC rating ≤ 9.0% for 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Freq.: 1.0 k Voltage: 1.0' For Cap > 10 μF, 0.	Vrms ± .2V
Insulation	Resistance	10,000MΩ or 500MΩ - μ F, whichever is less	Charge device with rated @ room tem	
Dielectric	Strength	No breakdown or visual defects	Charge device with 250 1-5 seconds, w/charge limited to 50	and discharge current
	Appearance	No defects	Deflectio	n: 2mm
Resistance to	Capacitance Variation	≤ ±30%	Test Time: 3	30 seconds 7 1mm/sec
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	l	
	Insulation Resistance	≥ Initial Value x 0.1	90 n	mm
Solder	ability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5	
	Appearance	No defects, <25% leaching of either end terminal		
	Capacitance Variation	≤ ±20%		
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room	temperature for 24 ± 2
	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects	Step 1: -30°C ± 2°	30 ± 3 minutes
	Capacitance Variation	≤ ±20%	Step 2: Room Temp	≤ 3 minutes
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ±2 hours at ro	
	Appearance	No visual defects	-	
	Capacitance Variation	≤ ±30%	Charge device with twic	
Load Life	Dissipation Factor	≤ Initial Value x 1.5 (See Above)	for 1000 hou	
	Insulation Resistance	≥ Initial Value x 0.1 (See Above)	Remove from test chamb temperature for 24 ± 2 ho	
	Dielectric Strength	Meets Initial Values (As Above)		
	Appearance	No visual defects		
	Capacitance Variation	≤ ±30%	Store in a test chamber s 5% relative humidi	
Load Humidity	Dissipation Factor	≤ Initial Value x 1.5 (See above)	(+48, -0) with rated	l voltage applied.
Trainfulty	Insulation Resistance	≥ Initial Value x 0.1 (See Above)	Remove from chamber temperature an 24 ± 2 hours bef	d humidity for
	Dielectric Strength	Meets Initial Values (As Above)	Z4 I Z Hours ben	ore measuring.

Y5V Dielectric





PREFERRED SIZES ARE SHADED

SIZE		020)1			0402				06	03			80	305			12	06			12	10	
Solderi	ng	Reflow	Only		Ref	low/W	ave		F	Reflow	//Wav	 e		Reflow	v/Wav	e		Reflow	Mfeve	9	F	Reflow	/Wav	e
Packagi	ing	All Pa	aper		A	II Pape	er			All F	aper		Pa	per/E	mbos	sed	Pa	per/Er	nboss	ed	Pa	per/Er	nboss	sed
(1) 1	mm	0.60 ±	0.09		1.0	00 ± 0.	10			1.60 :	± 0.15			2.01	± 0.20			3.20 ±	0.20			3.20 :	± 0.20	
(L) Length	(in.)	(0.024 ±	0.004)		(0.04	40 ± 0.	004)	(0	0.063 :	± 0.00	6)	(0	0.079	± 0.00	8)	(0.126 ±	0.00	8)	(0).126 :	± 0.00	8)
14/) 14/; alab	mm	0.30 ±	0.09		0.5	50 ± 0.	10			.81 ±	0.15			1.25	± 0.20			1.60 ±	0.20			2.50 :	± 0.20	
W) Width	(in.)	(0.011 ±	0.004)		(0.02	20 ± 0.	004)	(0	0.032 :	± 0.00	6)	(0	0.049	± 0.00	8)	(0.063 ±	0.00	8)	(0	0.098 :	± 0.00	8)
(t) Terminal	mm	0.15 ±	0.05		0.2	25 ± 0.	15			0.35	± 0.15			0.50	± 0.25			0.50 ±	0.25			.50 ±	0.25	
(t) Terminal	(in.)	(0.006 ±	0.002)		(0.0°)	10 ± 0.	006)	(0	0.014 :	± 0.00	6)	(0	0.020	± 0.01	0)	(0.020 ±	£ 0.010	0)	(0	0.020 :	± 0.01	0)
	WVDC	6.3	10	6	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50
Сар	820																				~	<	W	
(pF)	1000		Α																-	للرك	<		7	4
	2200		Α																	(5		لل	ŢT
	4700		Α																	_	$\overline{}$	_		
Сар	0.010	Α	Α																		-	7		
(μF)	0.022	Α																			_ '	1		
	0.047	Α				С																		
	0.10				С	С					G	G				K								
	0.22									G														
	0.33									G														
	0.47					С				G	G													
	1.0			С	С				G	G	J			N	N	N		М	М	М				N
	2.2				С				J					N	N				K	Q				
	4.7												N	N	N			Р	Q			N	N	
	10.0												N	Р			Q	Q	Х		Х	Q	Q	Z
	22.0																Q				Х	Z		
	47.0																							
	WVDC	6.3	10	6	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50	10	16	25	50
SIZE		020)1	0402				06	03			80	305			12	06			12	10			
Letter	Α	С	E		G	J		K		М	N		Р		Q	Х		Υ		Z				
Max.	0.33	0.56	0.71		.90	0.94	4	1.02		.27	1.4	0	1.52		.78	2.2		2.54		.79				
Thickness	(0.013)	(0.022)	(0.028)	+-	035)	(0.03		(0.040)	+	050)	(0.05	-	(0.060	-	070)	(0.09	-	(0.100)	(0.	110)				

PAPER

EMBOSSED

060120

MLCC Gold Termination — AU Series



General Specifications



KYOCERA AVX will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of Gold. This termination is indicated by the use of a "7" or "G" in the 12th position of the KYOCERA AVX Catalog Part Number. This fulfills KYOCERA AVX's commitment to providing a full range of products to our customers. Please contact the factory if you require additional information on our MLCC Gold Termination.

PART NUMBER

AU03	Y	G	104	<u>K</u>	<u>A</u>	7	<u>2</u>	<u>A</u>
Size AU02 - 0402 AU03 - 0603 AU05 - 0805 AU06 - 1206 AU10 - 1210 AU12 - 1812 AU13 - 1825 AU14 - 2225 AU16 - 0306 AU17 - 0508	Voltage 6.3V = 6 10V = Z 16V = Y 25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	Dielectric COG (NPO) = A X7R = C X5R = D	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance B = \pm .10 pF (<10pF) C = \pm .25 pF (<10pF) D = \pm .50 pF (<10pF) F = \pm 1% (\geq 10 pF) G = \pm 2% (\geq 10 pF) J = \pm 5% K = \pm 10% M = \pm 20%	Failure Rate A = Not Applicable	Terminations G*=1.9 μ" to 7.87 μ" 7 = 100 μ" minimum	Packaging 2 = 7" Reel 4 = 13" Reel U = 4mm TR (01005) Contact Factory For Multiples*	Special Code A = Std. Product

^{*} Contact factory for availability.

AU18 - 0612





PREFERRED SIZES ARE SHADED

SIZE			AU02			AU	103				AU05					AL	J06		
Solderi	na		flow/Epc			Reflow	/Epoxy/				flow/Epo					Reflow	/Epoxy/		
Packagi			Vire Bond All Pape			Wire I					Vire Bone er/Embo					Wire Paper/E	Bond* mbosse	d	
(L) Length	mm	1	.00 ± 0.1	10		1.60 :				2	2.01 ± 0.2	20				3.20	± 0.20		
	(in.) mm		040 ± 0.0			0.063 :					079 ± 0.0 .25 ± 0.2		-				± 0.008) ± 0.20		
W) Width	(in.)	(0.0	020 ± 0.0	004)		(0.032 :	± 0.006)			(0.	049 ± 0.0	008)				(0.063)	± 0.008)		
(t) Terminal	mm (in.)).25 ± 0.1 010 ± 0.0			0.35 :					0.50 ± 0.2 020 ± 0.0						± 0.25 ± 0.010)		
	WVDC	16	25	50	16	25	50	100	16	25	50	100	200	16	25	50	100	200	500
Cap	0.5	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
(pF)	1.0 1.2	C C	C	C	G G	G G	G G	G	J J	J	J	J	J	J	J	J	J	J	J
	1.5	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	1.8 2.2	C C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J
	2.7	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	3.3	С	С	С	G	G	G	G	J	J -	J -	J -	J	J	J	J	J	J	J
	3.9 4.7	C C	C	C	G G	G G	G	G	J J	J J	J	J J	J	J	J	J J	J	J	J
	5.6	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	6.8 8.2	C C	C	C	G G	G G	G	G	J	J	J	J	J	J	J	J	J	J	J
	10	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	12 15	С	C	C	G G	G G	G	G G	J	J	J	J	J	J	J	J	J	J	J
	18	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	22	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	27 33	C	C	C	G	G G	G	G	J	J	J	J	J	J	J	J	J	J	J
	39	С	С	С	G	G	G	G	J	J	J	J	J	Ĵ	J	J	J	J	J
	47 56	C	C	C	G G	G G	G	G	J	J	J	J	J	J	J	J	J	J	J
	68	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	82	C	C	C	G	G G	G	G	J	J	J	J	J	J	J	J	J	J	J
	100 120	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J J	J
	150	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	180 220	C	CC	C	G G	G G	G G	G	J	J	J	J	J	J	J	J	J	J	J
	270	С	С	С	G	G	G	G	J	J	J	J	М	J	J	J	J	J	М
	330 390	C	C	C	G G	G G	G G	G	J	J	J	J	M M	J	J	J	J	J	M M
	470	Ċ	c	c	G	G	G		Ĵ	Ĵ	J	J	М	J	J	J	J	J	М
	560 680				G G	G G	G		J	J	J	J	M M	J	J	J	J	J	M P
	820				G	G	G		J	J	J	J	M	J	J	J	J	M	
	1000				G	G	G		J	J	J	J	М	J	J	J	J	Q	
	1200 1500								J	J	J			J	J	J	J M	Q Q	
	1800								J	J	J			J	J	М	М		
	2200 2700								J	J J	N N			J	J	M M	P P		
	3300								J	J				J	J	М	Р		
	3900 4700								J	J				J	J	M M	P P		
	5600													J	J	M			
	6800 8200													M M	M M				
	0.010			†										M	M				
	0.012					1	-W_												
	0.015 0.018	- 0					1	_	 										
	0.022			_			1)	ŢΤ											
	0.027		(_)]	_	_	_	-								-		
	0.039				$\dot{\gamma}$														
	0.047 0.068				t			_											
	0.082		ı	ı	1	ı	ı	1											
	0.1	16	25	EO	16	25	EO	100	16	25	EO	100	200	10	25	EO	100	200	EOO
	WVDC SIZE	16	25 AU02	50	16	25 AU	50 103	100	16	25	50 AU05	100	200	16	25	50 AL	100 J06	200	500
	UILL		7.302								,,,,,,,					Α.			

^{*} Contact Factory

Letter	Α	С	Е	G	J	K	М	N	Р	Q	X	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMB	DSSED			



Capacitance Range (NP0 Dielectric)

PREFERRED SIZES ARE SHADED

SIZE				AU10					AU12				AU13			AU14	
Solderii	ng			flow/Epo					flow/Epo				Reflow/Epoxy	/		Reflow/Epoxy	/
Packagi				Vire Bond er/Embo					Vire Bond				Wire Bond*	<u> </u>		Wire Bond*	
	mm			.20 ± 0.2					.50 ± 0.3				4.50 ± 0.30			5.72 ± 0.25	-
(L) Length	(in.)		(0.1	126 ± 0.0	(80			(0.	177 ± 0.0	112)			(0.177 ± 0.012	2)	((0.225 ± 0.010))
W) Width	mm			.50 ± 0.2					.20 ± 0.2				6.40 ± 0.40			6.35 ± 0.25	
,	(in.)			0.0 ± 0.0					126 ± 0.0				(0.252 ± 0.016	<u>s)</u>	((0.250 ± 0.010))
(t) Terminal	mm (in.)			.50 ± 0.2 020 ± 0.0					0.61 ± 0.3 024 ± 0.0				0.61 ± 0.36 (0.024 ± 0.014	1)		0.64 ± 0.39 (0.025 ± 0.015	5)
	WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	50	100	200
Cap (pF)	0.5 1.0																
u ,	1.2																
	1.5 1.8														_		[:
	2.2														كاس		W
	2.7 3.3) 1 T
	3.9																
	4.7 5.6															المحا	
	6.8														ı	ΓtΙ	ī
	8.2 10				-	J										-	
	12					J											
	15 18					J											
	22					J											
	27 33					J											
	39					J											
	47 56					J											
	68					J											
	82 100					J											
	120					Ĵ											
	150 180					J											
	220					J											
	270 330					J											
	390					М											
	470 560	J	J	J	J	M											
	680	J	J	J	J	М											
	820 1000	J	J	J	J	M	K	K	K	K	М	M	M	M	M	M	P
	1200	J	J	J	М	М	K	K	K	К	М	М	М	М	М	М	Р
	1500 1800	J	J	J	M	М	K	K	K	K	M M	M M	M M	M M	M M	M M	P P
	2200	J	J	J	Q		K	K	К	K	Р	М	М	М	М	М	Р
	2700 3300	J	J	J	Q		K	K	K	P P	Q Q	M M	M M	M M	M M	M M	P P
	3900	J	J	М			K	K	K	Р	Q	М	М	М	М	М	Р
	4700 5600	J J	J	М	-	-	K	K	K	P P	Q X	M M	M M	M M	M M	M M	P P
	6800	J	J				K	K	М	x	.,	M	М	M	М	М	Р
	8200 0.010	J	J		-	-	K	M	M			M M	M M		M M	M M	P P
	0.012	Ĵ	Ĵ				K	М				M	М		М	М	Р
	0.015 0.018					-	M	M				M P	M M		M M	M M	Y
	0.022						М	М				Р			М	Y	Υ
	0.027			-	-	-	M	M				P P			P P	Y	Y
	0.039						М	М				Р			Р		
	0.047 0.068					-	M	M M				Р			P P		
	0.082						M	M							Q		
	0.1 WVDC	25	50	100	200	500	25	50	100	200	500	50	100	200	Q 50	100	200
		20		100	200	000	1 20	- 50	100		000		100	200	50	100	200

* Contact Factory

111101111000	(0.0.0)	(0.022)	PAPER	(0.000)	(0.007)	(0.0.0)	(0.000)	(0.000)	(OSSED	(0.050)	(0.100)	(0.1.0)
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Letter	Α	С	E	G	J	K	М	N	Р	Q	Х	Υ	Z





Capacitance Range (X7R Dielectric)

PREFERRED SIZES ARE SHADED

			AU	102					AU03	5						AU0	5						Αl	106			
Soldering				/Ероху	1/				ow/Ep		'					ow/E		/					eflow				
			Wire I						ire Bo							ire Bo							Wire				
Packaging			All P						II Pap					P		r/Em		ed					per/E				
(L) Length	mm			± 0.10	4\				60 ± 0							01 ±							3.20				
() - 3-	(in.)			± 0.004	1)				63 ± 0)					79 ±		3)					.126				
W) Width	mm		0.50		• \				81 ± 0							25 ±		• •					1.60				
	(in.)		0.25	0.004	1)				32 ± 0 35 ± 0)					49 ± 50 ±		3)					0.50				
(t) Terminal	mm				- \													٠,									Į.
WVDC	(in.)	10	16	25	50	63	10	16	14 ± 0 25	50	100	200	63		16	20 ±		100	200	62	10	16	.020	50.0	100	200	EOO
WVDC	100	IU	ID	25	50	0.3	10	סו	25	50	100	200	ರಿವ	10	16	25	50	100	200	63	10	10	25	50	100	200	500
Сар	150																										
(pF)	220				С				G																		
	330				C				G	G	G	G		J	J	J	J	J	J								K
	470				C					G	G	G		J	J	J	J	J	J								K
	680				C					G	G	G		J	J	J	J	J	Ĵ								K
	1000				C					G	G	G		J	J	J	J	J	J								K
	1500				C					G	G			J	J	Ĵ	Ĵ	Ĵ	Ĵ		J	J	J	J	J	J	М
	2200				Č					Ğ	G			Ĵ	J	Ĵ	Ĵ	Ĵ	Ĵ		Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	М
	3300			С	C					G	G			J	J	J	J	J	J		J	J	J	J	J	J	М
	4700			C	С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	М
	6800		С	С						G	G			J	J	J	J	J	J		J	J	J	J	J	J	Р
	0.010		С					G		G	G			J	J	J	J	J	J		J	J	J	J	J	J	Р
Cap (µF)	0.015		С						G	G				J	J	J	J	J	J		J	J	J	J	J	М	
(με)	0.022	С	С						G	G				J	J	J	J	J	N		J	J	J	J	J	М	
	0.033	C							G	G				J	J	J	J	N			J	J	J	J	J	М	
l .	0.047							G	G	G				J	J	J	J	N			J	J	J	J	J	М	
	0.068							G	G	G				J	J	J	J	N			J	J	J	J	J	Р	
	0.10						G	G	G	G				J	J	J	J				J	J	J	J	М	Р	1
	0.15					G	G							J	J	J	N	N			J	J	J	J	Q		
	0.22					G	G							J	J	N	N	N			J	J	J	J	Q		\vdash
	0.33													N	N	N	N	N			J	J	М	Р	Q		
	0.47													N	N	N	N	N			M	M	M	P	Q		
	0.68													N	N	N	\vdash	-	-		M	M	Q	Q	Q		
	1.0													N	N	N					M	М		Q	Q		
	1.5 2.2															P*						Q Q	Q				
	3.3															Ρ"					Q	Ų	Q		-		
	3.3 4.7													P*							Q	Q					
	10													Ρ							0*	Ų					
	22															-				0*	Ų						
	47																			Q							
	100																										
1	NVDC	10	16	25	50	63	10	16	25	50	100	200	63	10	16	25	50	100	200	63	10	16	25	50	100	200	500
	SIZE	10	10	AU02					AU03		100			.0		AU0		100			10			106	100	_00	

^{*} Contact Factory

	Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
	Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
1	Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
				PAPER						FMRC	SSFD			



Capacitance Range (X7R Dielectric)

PREFERRED SIZES ARE SHADED

SIZE					AU10						J12			J13		J14
Solderin	a				flow/Epo					Reflow	/Epoxy/		Reflow	/Epoxy/		/Epoxy/
					Wire Bond						Bond*			Bond*		Bond*
Packagir	ng mm				er/Embos 3.20 ± 0.2						bossed ± 0.30			bossed ± 0.30		bossed ± 0.25
(L) Length	(in.)				126 ± 0.2						± 0.30 ± 0.012)			± 0.30 ± 0.012)		± 0.25 ± 0.010)
	mm				$\frac{120 \pm 0.0}{2.50 \pm 0.2}$						± 0.012)			± 0.40		± 0.010)
W) Width	(in.)				098 ± 0.0						± 0.008)			± 0.016)		± 0.010)
(I) T : 1	mm				0.50 ± 0.2					0.61	± 0.36			± 0.36		± 0.39
(t) Terminal	(in.)			(0.	020 ± 0.0	10)				(0.024)	± 0.014)		(0.024 :	± 0.014)		± 0.015)
WVDC		10	16	25	50	100	200	500	50	100	200	500	50	100	50	100
Сар	100															
(pF)	150															
(F-)	220												ļ			
	330														-W-	
	470										-				` `_<	
	680														1) 1	ÎT
	1000)	_ (J ~	* ·
	1500	J	J	J	J	J	J	M					$\overline{}$			24.54
	2200	J	J	J	J	J	J	M		1			Ĭ.			
	3300	J	J	J	J	J	J	M					t	1		
	4700 6800	J	J	J	J	J	J	M M				I	1	Ĭ	I	
	0.010	J	J	J	J	J	J	M	K	K	K	K	M	М	М	Р
Сар	0.010	J	J	J	J	J	J	P	K	K	K	P	M	M	M	P
(μF)	0.013	J	J	J	J	J	J	Q	K	K	K	P	M	M	M	P
	0.022	J	J	J	J	J	J	Q	K	K	K	X	M	M	M	P
	0.033	J	J	J	J	J	J	ų ų	K	K	K	Ž	M	M	M	р' Р
	0.068	Ĵ	J	Ĵ	Ĵ	Ĵ	M		K	K	K	Z	M	M	M	P .
	0.10	J	J	J	J	J	М		K	K	K	Z	М	М	М	P
	0.15	J	J	J	J	М	Z		K	К	Р		М	М	М	Р
	0.22	J	J	J	J	Р	Z		K	K	Р		М	М	М	Р
	0.33	J	J	J	J	Q			K	М	Х		М	М	М	P
	0.47	М	М	M	M	Q			K	P			M	M	M	Р
	0.68	M N	M N	Р	X	X Z			M M	Q X			M M	P	M M	P P
	1.5	N N	N N	Z	Z	Z			Z	Z			M		M	X
	2.2	X	X	Z	Z	Z			Z	Z			IVI		M	^
	3.3	X	X	Z	Z	_			Z						.,,	
	4.7	X	X	Z	Z				Z							
	10	Z	Z	Z												
	22															
	47															
	100	10	1.0	0.5	F 0	100	0.0.0	500	F0.	100	200	F00	F0.	100	F 0	1.0.0
	WVDC SIZE	10	16	25	5 0 AU10	100	200	500	50	100	200 J 12	500	50	100 J13	50	100 J 14
	SIZE				AUIU					AL	114		AU	,13	AL	714

^{*} Contact Factory

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBO	DSSED			



Capacitance Range (X5R Dielectric)

PREFERRED SIZES ARE SHADED

SIZE				Αl	J02					-	AU0	3					ΑL	105					Αl	J06						AU10	0				4	U12	
Solderi	ina			flow						Reflo	ow/E	рох	у					/Epc						/Epo						ow/E		y					оху/
				Vire							e Bo							Bono						Bono						е Во				_		e Bor	
Packagi				All F	<u> </u>						l Par							mbo						mbo		1		Pa		/Emb		ed		F		nbos	
(L) Length	mm (in.)		(0	1.00 .040	± 0.0	04)				(0.06	60 ± 0	.006)			(0.	079 :	± 0.20 ± 0.00	08)			(0.	126	± 0.20	08)				(0.12	20 ± 0 26 ± 0	.008)		(0.17	0 ± 0. 7 ± 0.	012)
(W) Width	mm (in.)			0.50 .020							31 ± 0 32 ± 0)					± 0.20 ± 0.00						± 0.20 ± 0.00						0 ± 0 98 ± 0)		(0 ± 0. 6 ± 0.	
(t) Terminal	mm			0.25							35 ± 0							± 0.25						± 0.2						50 ± 0						1 ± 0.	
WVDC	(in.)	4		.010			50	-		`	4 ± 0				6.3	10		± 0.01			6.3			± 0.0°		50	-	6.3	`	20 ± 0 16			T = 0	_		4 ± 0. 25	014) 50
Сар	100	4	6.3	10	16	25	50	4	6.3	10	16	25	35	50	6.3	10	16	25	35	50	6.3	10	16	25	35	50	4	6.3	10	16	25	35	50	6.3	10	25	50
(pF)	150																											ŀ									
(PF)	220																																				
	330						С																														
	470						С																														
	680					1	С		1																												
	1000						С																														
	1500						C																														
	2200 3300						C																														
	4700					С								G																							
	6800					C								G																							
Сар	0.010					С								G																							
(µF)	0.015					С						G	G	G																							
. ,	0.022				С	С						G	G	G						N																	
	0.033				С							G	G	G						N																	
	0.047				С	С						G	G	G						N																	
	0.068				С							G		G						N																	
	0.10		С		С	С						G		G				N		N																	
	0.15											G						N	N																		
	0.22		C*								G	G						N	N																		
	0.33	04									G	G						N						_	_	Q											
	0.47 0.68	C*									G							N N						Q	Q								X				
	1.0					-			G	G	G	J*			N		N	N		P*				Q	Q						Х	Х	X				
	1.5														N		1							٧	٧						^						
	2.2	C*	l					G*	G*	J*	J*	l			N	N	N	N					Q	Q							Z	Х					
	3.3							J*	J*	J*	J*				N	N					Q	Q															
	4.7							J*	J*	J*						N	N*	N*			Q	Q	Q	Q						Q	Z						
	10							K*							P*	P*	P*				Q	Q	Q	Q*					Х	Z	Z					Z	
	22														P*						Q*	Q*	Q*					Z	Z	Z	Z						
	47																				Q*							Z*									
	100																										Z*	Z*									
	WVDC	4	6.3			25	50	4	6.3				35	50	6.3	10		25	35	50	6.3	10		25	35	50	4	6.3		16	25	35	50	6.3		25	50
	SIZE			Αl	J02						AU0	3					ΑL	105					Αl	J06						AU10	0					U12	

^{*} Contact Factory

Letter	Α	С	E	G	J	K	М	Ν	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

= *Optional Specifications - Contact Factory

NOTE: Contact factory for non-specified capacitance values

AU16/AU17/AU18



	IZE		(AU1 030	5)			(0	U17	3)			((AU1 061:	2)	
Pacl	kaging			nboss					boss					nboss		
Length	mm (in.)			31 ± 0 32 ± 0)		1.2 0.05(7 ± 0. 0 ± 0.					0 ± 0).25).010)	
Width	mm (in.)			0 ± 0)	(2.0	0 ± 0. 0 ± 0.					20 ± 0 26 ± 0).25).010)	
Cap Code	WVDC	4	6.3	10	16	25	6.3	10	16	25	50	6.3	10	16	25	50
102	Cap 0.001		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	V
222	(μF) .0022		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
332	0.0033		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
472	0.0047		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
682	0.0068		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
103	0.01		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
153	0.015		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	W
223	0.022		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	W
333	0.033		Α	Α	Α		S	S	S	٧	٧	S	S	S	S	W
473	0.047		Α	Α	Α		S	S	S	٧	Α	S	S	S	S	W
683	0.068		Α	Α	Α		S	S	S	Α	Α	S	S	S	٧	W
104	0.1		Α	Α	///		S	S	٧	Α	Α	S	S	S	٧	W
154	0.15		Α	Α			S	S	٧			S	S	S	W	W
224	0.22		Α	Α			S	S	Α			S	S	٧	W	
334	0.33						٧	٧	Α			S	S	٧		
474	0.47						٧	٧	M			S	S	٧		
684	0.68						Α	Α	///			٧	٧	W		
105	1	A					Α	Α				٧	٧	Α		
155	1.5						/N/					W	W			
225	2.2											Α	Α			
335	3.3											///				
475	4.7														Ì	
685	6.8															
106	10															

Solid = X7R





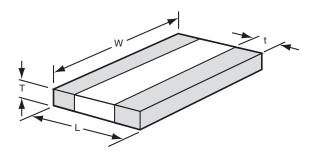
mm (in.) AU16 (0306)Code Thickness

0.56 (0.022)

	mm (in.)
	AU16 (0508)
Code	Thickness
S	0.56 (0.022)
V	0.76 (0.030)
Α	1.02 (0.040)

	mm (in.)
	AU16 (0612)
Code	Thickness
S	0.56 (0.022)
V	0.76 (0.030)
W	1.02 (0.040)
Α	1.27 (0.050)

PHYSICAL DIMENSIONS AND **PAD LAYOUT**



PHYSICAL DIMENSIONS

MM (IN.)

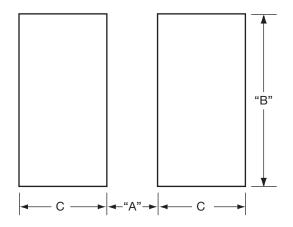
	L	W	t
AU16	0.81 ± 0.15	1.60 ± 0.15	0.13 min.
(0306)	(0.032 ± 0.006)	(0.063 ± 0.006)	(0.005 min.)
AU17	1.27 ± 0.25	2.00 ± 0.25	0.13 min.
(0508)	(0.050 ± 0.010)	(0.080 ± 0.010)	(0.005 min.)
AU18	1.60 ± 0.25	3.20 ± 0.25	0.13 min.
(0612)	(0.063 ± 0.010)	(0.126 ± 0.010)	(0.005 min.)

T - See Range Chart for Thickness and Codes

PAD LAYOUT DIMENSIONS

MM (IN.)

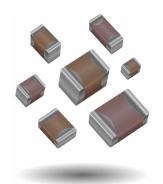
	Α	В	С
AU16 (0306)	0.31 (0.012)	1.52 (0.060)	0.51 (0.020)
AU17 (0508)	0.51 (0.020)	2.03 (0.080)	0.51 (0.020)
AU18 (0612)	0.76 (0.030)	3.05 (0.120)	0.635 (0.025)



MLCC Tin/Lead Termination "B" (LD Series)







KYOCERA AVX will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the KYOCERA AVX Catalog Part Number. This fulfills KYOCERA AVX's commitment to providing a full range of products to our customers. KYOCERA AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

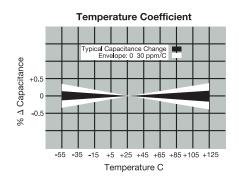
Not RoHS Compliant

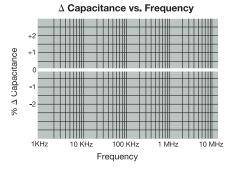
LD05	5	Α	101	J	<u>A</u>	В	2	Α
Size LD02 - 0402 LD03 - 0603 LD04 - 0504*	Voltage 6.3V = 6 10V = Z 16V = Y	Dielectric COG (NPO) = A X7R = C X5R = D	Capacitance Code (In pF) 2 Sig. Digits + Number of	Capacitance Tolerance B = ±.10 pF (<10pF) C = ±.25 pF (<10pF)	Failure Rate A = Not Applicable	Terminations B = 5% min lead X = FLEXITERM® with 5% min	Packaging 2 = 7" Reel 4 = 13" Reel	Special Code A = Std. Product
LD05 - 0805 LD06 - 1206 LD10 - 1210 LD12 - 1812 LD13 - 1825 LD14 - 2225 LD20 - 2220	25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	X8R = F	Zeros	D = ±.50 pF (<10pF) F = ±1% (≥ 10 pF) G = ±2% (≥ 10 pF) J = ±5% K = ±10% M = ±20%	4 = Automotive	lead** **X7R only	Contact Factory For Multiples*	

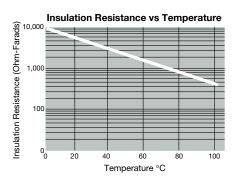
*LD04 has the same CV ranges as LD03.

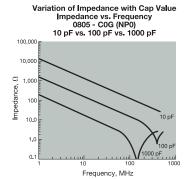
See FLEXITERM® section for CV options

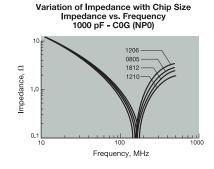
NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

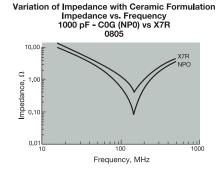


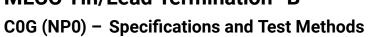














Parame	ter/Test	NP0 Specification Limits	Measuring Conditions			
	perature Range	-55°C to +125°C	Temperature Cy	cle Chamber		
Сарас	itance	Within specified tolerance	Freq.: 1.0 MHz ± 10%			
(3	<30 pF: Q≥ 400+20 x Cap Value ≥30 pF: Q≥ 1000	1.0 kHz ± 10% for Voltage: 1.0\	/rms ± .2V		
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with 60 ± 5 secs @ roon			
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250' 1-5 seconds, w/charge a limited to 50 Note: Charge device with for 500V c	and discharge current mA (max) 150% of rated voltage		
	Appearance	No defects	Deflection			
Resistance to Flexure	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Test Time: 3	0 seconds 1 _{mm/sec}		
Stresses	Q	Meets Initial Values (As Above)				
	Insulation Resistance	≥ Initial Value x 0.3	90 m			
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5			
	Appearance	No defects, <25% leaching of either end terminal				
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater		-1d		
Resistance to Solder Heat	Q	Meets Initial Values (As Above)	Dip device in eutectic se seconds. Store at room t			
Solder Heat	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	electrical properties.		
	Dielectric Strength	Meets Initial Values (As Above)				
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes		
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp	≤ 3 minutes		
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes		
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes		
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and measure after 24 hours at room temperature			
	Appearance	No visual defects				
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twice chamber set at	e rated voltage in test		
Load Life	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	for 1000 hour	rs (+48, -0).		
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	temperature f before me	or 24 hours		
	Dielectric Strength	Meets Initial Values (As Above)				
	Appearance	No visual defects				
	Capacitance Variation	≤ ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber se	et at 85°C ± 2°C/ 85% ±		
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	5% relative humidity for 1000 hours (+48, -0) with rated voltage applied.			
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature for 24 ± 2 ho			
	Dielectric Strength	Meets Initial Values (As Above)				





PREFERRED SIZES ARE SHADED

			-			1	-												
SIZE			LD02			LD	03				LD05					LD0			
Solderi			eflow/Wa				//Wave				flow/Wav					Reflow/\			
Packag			All Paper				aper		Paper/Embossed 2.01 ± 0.20					Paper/Embossed					
(L) Length	mm (in.)		.00 ± 0.1 040 ± 0.0				± 0.15 ± 0.006)		2.01 ± 0.20 (0.079 ± 0.008)					3.20 ± 0.20 (0.126 ± 0.008)					
	mm		0.50 ± 0.0				± 0.006) ± 0.15		1.25 ± 0.20					(0.126 ± 0.008) 1.60 ± 0.20					
W) Width	(in.)		020 ± 0.0				± 0.006)		(0.049 ± 0.008)					((0.063 ± (
(t) Terminal	mm		.25 ± 0.1			0.35 :	± 0.15		0.50 ± 0.25							0.50 ± 0			
(t) Terriman	(in.)		010 ± 0.0		5) (0.014 ± 0.006) 50 16 25 50 100				(0.020 ± 0.010)					10		(0.020 ± 0		000	- FMO
Сар	WVDC 0.5	16 C	25 C	C	G	G	G	G G	16 J	25 J	50 J	100 J	200 J	16 J	25 J	50 J	100 J	200 J	500 J
(pF)	1.0	Č	Č	Č	Ğ	Ğ	Ğ	Ğ	Ĵ	Ĵ	Ĵ	Ĵ	J	Ĵ	Ĵ	J	J	Ĵ	Ĵ
, ,	1.2	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	1.5	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	1.8 2.2	C C	C	C	G G	G G	G G	G G	J	J	J	J J	J	J	J	J	J	J	J
	2.7	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	3.3	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	Ĵ	J	J
	3.9	С	С	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	4.7	C	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	5.6 6.8	C C	C	C	G G	G G	G G	G G	J	J	J	J	J	J	J	J	J	J	J
	8.2	С	С	č	Ğ	Ğ	Ğ	Ğ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	Ĵ	J	Ĵ	Ĵ	Ĵ
	10	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	12 15	C C	C	C	G	G G	G G	G G	J	J	J	J	J	J	J J	J	J	J	J
	18	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	22	С	С	c	Ğ	G	G	G	J	Ĵ	J	Ĵ	Ĵ	Ĵ	Ĵ	J	Ĵ	Ĵ	Ĵ
	27	C	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	33 39	С	C	С	G	G G	G	G G	J	J	J	J	J	J	J	J	J	J	J
	47	C C	C	C	G G	G	G G	G	J	J	J	J J	J	J	J	J	J	J	J
	56	C	C	C	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	68	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	82	C	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	100 120	C	C	C	G G	G G	G G	G G	J	J	J	J J	J	J	J	J	J	J	J
	150	C	C	Č	Ğ	Ğ	Ğ	Ğ	Ĵ	Ĵ	J	Ĵ	J	J	Ĵ	J	J	Ĵ	Ĵ
	180	С	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J
	220	C	С	С	G	G	G	G	J	J	J	J	J	J	J	J	J	J	M
	270 330	C C	C	C	G	G	G	G G	J	J	J	J	M M	J	J	J	J	J	M
	390	C	C	Č	Ğ	G	Ğ	Ğ	Ĵ	Ĵ	J	Ĵ	M	Ĵ	Ĵ	J	J	Ĵ	M
	470	С	С	С	G	G	G		J	J	J	J	М	J	J	J	J	J	М
	560				G	G	G		J	J	J	J	М	J	J	J	J	J	М
	680 820				G	G G	G G		J	J	J	J		J	J	J	J	J	Р
	1000				G G	G	G		J	J	J	J		J	J	J	J	M Q	
	1200					Ğ			Ĵ	Ĵ	J			J	Ĵ	J	Ĵ	Q	
	1500								J	J	J			J	J	J	М	Q	$oxed{oxed}$
	1800 2200								J	J	J			J	J	M M	M P		
	2700								J	J	N			J	J	M	P		
	3300								J	J				J	J	М	Р		
	3900								J	J				J	J	M	P		
	4700 5600					-			J	J				J	J	M	Р		$\vdash \vdash \vdash$
	6800													M	M	IVI			
	8200											<u></u>		M	M			<u></u>	
Cap	0.010													М	М				
(pF)	0.012 0.015				I		I												
	0.018		† .	-1-	~	W-	_									1			$\vdash \vdash$
	0.022		1	~	_ `	رر	ÎT												
	0.027		↓ ()	الر	<u>*'</u> _									1			\Box
	0.033		`	\	<u>_</u>														
	0.039 0.047				4														
	0.047		t		t I		. –												H
	0.082																		
	0.1	10	0.5	F2	1.	C=		100	11	C=		100		10	C=		100	000	
	WVDC SIZE	16	25 LD02	50	16	25	50 03	100	16	25	50 LD05	100	200	16	25	50 LD0	100	200	500
	SIZE		LDU2			LD	US				LDUD					LDU	U		

Letter	Α	С	E	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
PAPER						EMBOSSED							





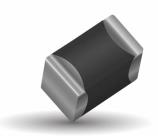
PREFERRED SIZES ARE SHADED

SIZ	E			LD10					LD12				LD1	<u> </u>			LD14	
Solder				Reflow Or					Reflow Or	ulv.		Reflow Only				Reflow Only		
Packag				er/Embo					Il Emboss			All Embossed			All Embossed			
(L) Length	mm			3.20 + 0.2					4.50 ± 0.3			4.50 ± 0.30			5.72 ± 0.25			
(L) Length	(in.)			126 ± 0.0 2.50 ± 0.2					177 ± 0.0 3.20 ± 0.2			(0.177 ± 0.012) 6.40 ± 0.40			(0.225 ± 0.010)			
W) Width	mm (in.)		(0.	098 ± 0.0	008)			(0.	126 ± 0.0	008)			(0.252 ±	0.016)		(6.35 ± 0.25 0.250 ± 0.010)
(t) Terminal	mm (in.)			0.50 ± 0.2 020 ± 0.0					0.61 ± 0.3 024 ± 0.0				0.61 ± (0.024 ±				0.64 ± 0.39 0.025 ± 0.015)
	WVDC	25	50	100	200	500	25	50	100	200	500	50	100		200	50	100	200
Cap	0.5																	
(pF)	1.0 1.2																	
	1.5																	
	1.8																/	<i>⁄</i>
	2.2															ياسى		W
	3.3															_ < _) <u>f</u> T
	3.9																~)	
	4.7 5.6				1							-				_		
	6.8																t	
	8.2 10			-		J					-	-		-+				
	12					J												
	15 18					J												\vdash
	22					J												
	27					J												
	33 39					J												
	47					Ĵ												
	56					J												
	68 82					J J												
	100					J												
	120 150					J												
	180					J												
	220					J												
	270 330					J												
	390					М												
	470 560	J	J		J	M												
	680	J	J	J	J	M												
	820	J	J	J	J	М												
	1000 1200	J	J	J	J M	M M	K K	K K	K K	K K	M M	M M	M M		M M	M M	M M	P P
	1500	J	J	J	M	M	K	K	K	K	M	M	M		M	M	M	P
	1800	J	J	J	M		K	K	K	K	М	M	М		М	М	М	P
	2200 2700	J	J J	J	QQ		K	K	K K	K P	P Q	M M	M M		M M	M M	M M	P P
	3300	J	J	J			Р	Р	Р	Р	Q	М	М		М	М	М	Р
	3900 4700	J	J	M M			P P	P P	P P	P P	Q Y	M M	M M		M M	M M	M M	P P
	5600	J	J	.41			Р	Р	Р	Р	Y	M	M		М	М	М	Р
	6800 8200	J	J				P P	P P	Q Q	Q Q	Y	M M	M M		М	M M	M M	P P
Сар	0.010	J	J				Р	Р	Q	Q	Υ	М	М			М	М	Р
(pF)	0.012 0.015	J	J				P P	P P	Q	X	Y	M	M M			M M	M	P Y
	0.015						P	P	Q X	X	Y	M P	M			M	M M	Y
	0.022						Р	P	Х	Х		P				М	Υ	Y
	0.027			-			Q Q	X	X	Z Z	_	P P				P P	Y	Y
	0.039						Х	X	Z	Z		Р				Р		
	0.047 0.068			_			Z	X Z	Z Z	Z		Р				P P		
	0.088						Z	Z	Z							Q		
	0.1	25	EO	100	200	Enn	Z	Z	Z	200	EOO		10		200	Q	100	200
SIZ	WVDC	25	50	100 LD10	200	500	25	50	100 LD12	200	500	50	100 LD1		200	50	100 LD14	200
Ų,L	-																-	
Letter	Α	С		E	G	J		K	М		N	Р	Q	Х	Y	Z		
Max.	0.33	0.56		0.71	0.90	0.9		1.02	1.27		.40	1.52	1.78	2.29	2.54			
Thickness	(0.013)	(0.022		0.028)	(0.035)	(0.0	37)	(0.040)	(0.050	0) (0.	055)	(0.060)	(0.070)	(0.090)	(0.100) (0.110)		
			F	PAPER								EMBC	SSED					









KYOCERA AVX will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the KYOCERA AVX Catalog Part Number. This fulfills KYOCERA AVX's commitment to providing a full range of products to our customers. KYOCERA AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

Not RoHS Compliant

PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

LD05	<u>5</u>	F T	101		<u>A</u>	<u>B</u>	2	<u>A</u>
Size LD02 - 0402 LD03 - 0603 LD04 - 0504* LD05 - 0805 LD06 - 1206 LD10 - 1210 LD12 - 1812 LD13 - 1825 LD14 - 2225 LD20 - 2220	Voltage 6.3V = 6 10V = Z 16V = Y 25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	Dielectric X8R = F	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance B = ±.10 pF (<10pF) C = ±.25 pF (<10pF) D = ±.50 pF (<10pF) F = ±1% (≥ 10 pF) G = ±2% (≥ 10 pF) J = ±5% K = ±10% M = ±20%	Failure Rate A = Not Applicable	Terminations B = 5% min lead X = FLEXITERM® with 5% min lead** **X7R only	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples*	Special Code A = Std. Product

LD04 has the same CV ranges as LD03.

See FLEXITERM® section for CV options

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.





Parame	ter/Test	X8R Specification Limits	Measuring	Conditions			
Operating Tem	perature Range	-55°C to +150°C	Temperature C	ycle Chamber			
Capac	itance	Within specified tolerance	Frog : 1 0 k	√U¬ ± 100/			
Dissipati	on Factor	≤ 2.5% for ≥ 50V DC rating ≤ 3.5% for 25V DC and 16V DC rating	Freq.: 1.0 k Voltage: 1.0				
Insulation	Resistance	100,000ΜΩ or 1000ΜΩ - μF, whichever is less	Charge device with rated voltage for 120 ± 5 secs @ room temp/humidity				
Dielectric	Strength	No breakdown or visual defects	Charge device with 250% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.				
	Appearance	No defects	Deflectio	n: 2mm			
Resistance to	Capacitance Variation	≤ ±12%	Deflection: 2mm Test Time: 30 seconds				
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)					
	Insulation Resistance	≥ Initial Value x 0.3	90 r	mm			
Solder	ability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutection for 5.0 ± 0.				
	Appearance	No defects, <25% leaching of either end terminal					
	Capacitance Variation	≤ ±7.5%					
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room	temperature for 24 ± 2			
	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.			
	Dielectric Strength	Meets Initial Values (As Above)					
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes			
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes			
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes			
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes			
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro	and measure after oom temperature			
	Appearance	No visual defects					
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 r				
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hou				
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test chamb temperature for 24 ± 2 h				
	Dielectric Strength	Meets Initial Values (As Above)					
	Appearance	No visual defects					
	Capacitance Variation	≤ ±12.5%	Store in a test chamber s 5% relative humidi				
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated	d voltage applied.			
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature an 24 ± 2 hours bef	d humidity for			
	Dielectric Strength	Meets Initial Values (As Above)	Z-7 ± 2 Hours ber	ore measuring.			



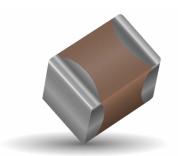
X8R - Capacitance Range

	SIZE	LD	03	LD	05	LD06		
	WVDC	25V	50V	25V	50V	25V	50V	
271	Cap 270	G	G					
331	(pF) 330	G	G	J	J			
471	470	G	G	J	J			
681	680	G	G	J	J			
102	1000	G	G	J	J	J	J	
152	1500	G	G	J	J	J	J	
182	1800	G	G	J	J	J	J	
222	2200	G	G	J	J	J	J	
272	2700	G	G	J	J	J	J	
332	3300	G	G	J	J	J	J	
392	3900	G	G	J	J	J	J	
472	4700	G	G	J	J	J	J	
562	5600	G	G	J	J	J	J	
682	6800	G	G	J	J	J	J	
822	Cap 8200	G	G	J	J	J	J	
103	(μF) 0.01	G	G	J	J	J	J	
123	0.012	G	G	J	J	J	J	
153	0.015	G	G	J	J	J	J	
183	0.018	G	G	J	J	J	J	
223	0.022	G	G	J	J	J	J	
273	0.027	G	G	J	J	J	J	
333	0.033	G	G	J	J	J	J	
393	0.039	G	G	J	J	J	J	
473	0.047	G	G	J	J	J	J	
563	0.056	G		N	N	M	М	
683	0.068	G		N	N	М	М	
823	0.082			N	N	М	М	
104	0.1			N	N	M	М	
124	0.12			N	N	M	М	
154	0.15			N	N	M	М	
184	0.18			N		М	М	
224	0.22			N		М	М	
274	0.27					M	М	
334	0.33					М	М	
394	0.39					M		
474	0.47					M		
684	0.68							
824	0.82							
105	1							
	WVDC	25V	50V	25V	50V	25V	50V	
	SIZE	LD	03	LD	05	LD	06	

Letter	Α	С	E	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
	PAPER								EMBC	SSED			

X7R - General Specifications





KYOCERA AVX will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the KYOCERA AVX Catalog Part Number. This fulfills KYOCERA AVX's commitment to providing a full range of products to our customers. KYOCERA AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

Not RoHS Compliant

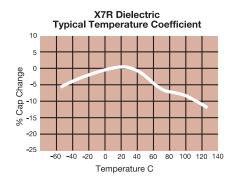
PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

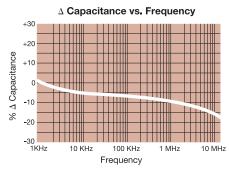
LD05	5	<u>c</u>	101	J	<u>A</u>	<u>B</u>	2	<u>A</u>
Size LD03 - 0603 LD04 - 0504* LD05 - 0805 LD06 - 1206 LD10 - 1210 LD12 - 1812 LD13 - 1825 LD14 - 2225 LD20 - 2220	Voltage 6.3V = 6 10V = Z 16V = Y 25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	Dielectric X7R = C	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance B = ±.10 pF (<10pF) C = ±.25 pF (<10pF) D = ±.50 pF (<10pF) F = ±1% (≥ 10 pF) G = ±2% (≥ 10 pF) J = ±5% K = ±10% M = ±20%	Failure Rate A = Not Applicable	Terminations B = 5% min lead X = FLEXITERM® with 5% min lead** **X7R only	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples*	Special Code A = Std. Product

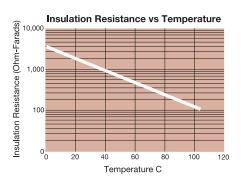
^{*}LD04 has the same CV ranges as LD03.

See FLEXITERM® section for CV options

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.



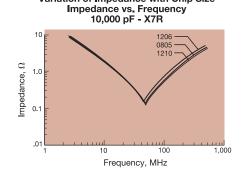




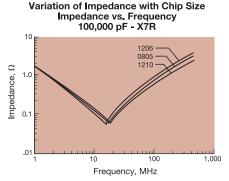
0805 10.00 1 000 pF Impedance, Ω 0.01 100 1000 Frequency, MHz

Variation of Impedance with Cap Value

Impedance vs. Frequency 1,000 pF vs. 10,000 pF - X7R



Variation of Impedance with Chip Size







Parame	ter/Test	X7R Specification Limits	Measuring (Conditions		
Operating Tem	perature Range	-55°C to +125°C	Temperature C	ycle Chamber		
Capac	itance	Within specified tolerance				
Dissipati	on Factor	≤ 10% for ≥ 50V DC rating ≤ 12.5% for 25V DC rating ≤ 12.5% for 25V and 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Freq.: 1.0 k Voltage: 1.0'			
Insulation	Resistance	100,000ΜΩ or 1000ΜΩ - μF, whichever is less	Charge device with 120 ± 5 secs @ roo			
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250 1-5 seconds, w/charge limited to 50 Note: Charge device with for 500V	and discharge current mA (max) n 150% of rated voltage		
	Appearance	No defects	Deflectio	n: 2mm		
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3			
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	V			
	Insulation Resistance	≥ Initial Value x 0.3	90 n	nm —		
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5			
	Appearance	No defects, <25% leaching of either end terminal				
	Capacitance Variation	≤ ±7.5%				
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room	temperature for 24 ± 2		
	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.		
	Dielectric Strength	Meets Initial Values (As Above)				
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes		
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes		
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes		
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes		
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro			
	Appearance	No visual defects				
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 r test chamber set			
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hou			
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test chamber and stabilize at r temperature for 24 ± 2 hours before measur			
	Dielectric Strength	Meets Initial Values (As Above)				
	Appearance	No visual defects				
	Capacitance Variation	≤ ±12.5%	Store in a test chamber set at 85°C ± 2°C/ 85 5% relative humidity for 1000 hours			
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated	l voltage applied.		
numany	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature an	d humidity for		
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 hours bef	ore measuring.		

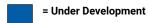




PREFERRED SIZES ARE SHADED

								ш							ш											
SIZE			LD02					LD03							LD05							LD				
Solderi			low/W					low/W							low/W							Reflow				
Packag			II Pap					II Pap							r/Emb						Pa	per/Er		ed		
(L) Length	mm (in.)		00 ± 0 40 ± 0					60 ± 0 63 ± 0							01 ± 0. 79 ± 0.						(3.20 ± ± 0.126		0)		
	mm		10 ± 0 50 ± 0					81 ± 0							25 ± 0.							1.60 ±		0)		
W) Width	(in.)		20 ± 0					32 ± 0							49 ± 0.						(0.063		B)		
(t) Terminal	mm	0.2	25 ± 0	.15			0.3	35 ± 0	.15						50 ± 0.							0.50 ±				
()	(in.)	_	10 ± 0					14 ± 0							20 ± 0.						$\overline{}$	0.020 ±				
WVD		16	25	50	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	500
Сар	100																									
(pF)	150																									
	220			С																						
	330			С					G	G	G		J	J	J	J	J	J								K
	470			С					G	G	G		J	J	J	J	J	J								K
	680			С					G	G	G		J	J	J	J	J	J								K
	1000			С					G	G	G		J	J	J	J	J	J								K
	1500			С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	M
	2200		_	С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	M
	3300		С	C					G	G			J	J	J	J	J	J		J	J	J	J	J	J	M
	4700 6800	^	С	С					G	G			J	J	J	J	J	J		J	J	J	J	J	J	M P
Con	0.010	C	C	-					G	G			J	J	J	J	J	J		J	J	J	J	J	J	P
Cap (µF)	0.010	C	C	1				G	G	G			J	J	J	J J	J	J		J	J	J	J	J J	M	Р
(με)	0.013	C						G	G				J	J	J	J	J	J		J	J	J	J	J	M	
	0.022	С						G	G				J	J	J	J	N	IN		J	J	J	J	J	M	
	0.033	C					G	G	G				J	J	J	J	N			J	J	J	J	J	M	
	0.068						G	G	G				J.J	J	J	Ĵ	N			J	Ĵ	Ĵ	Ĵ	Ĵ	P	
	0.10		C*			G	G	G	G				J	J	J	J	N			J	J	J	J	P	P	
	0.15			1	G	G							Ĵ	Ĵ	Ĵ	N	N			J	Ĵ	Ĵ	Ĵ	Q		
	0.22				G	G							Ĵ	Ĵ	N	N	N			J	Ĵ	Ĵ	Ĵ	Q		
	0.33				_	-							N	N	N	N	N			J	J	М	P	Q		
	0.47							J*					N	N	N	N	N			М	М	М	Р	Q		
	0.68												N	N	N					М	М	Q	Q	Q		
	1.0					J*	J*						N	N	N*					М	М	Q	Q	Q		
	1.5																			Р	Q	Q				
	2.2				J*									L	P*					Q	Q	Q				
	3.3																									
	4.7												P*	P*						Q*	Q*	Q*				
	10											P*	Р							Q*	Q*	Q				
	22																		Q*							
	47																									
	100																									
	WVDC	16	25	50	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	6.3	10	16	25	50	100	200	500
	SIZE		LD02					LD03							LD05							LD	06			

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013) (0.022) (0.028) (0.035) (0.03					(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			







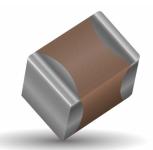
PREFERRED SIZES ARE SHADED

SIZE					LD10					LD	12		LC	013		LD	20		LD	14
Solderin	ng			R	eflow On	ly				Reflov				w Only		Reflov				w Only
Packagi	ng				er/Embo					All Emb				bossed		All Eml				bossed
(L) Length	mm				.20 + 0.2					4.50 ±				± 0.30			± 0.50			± 0.25
(L) Length	(in.)				26 ± 0.0					(0.177 ±				± 0.012)		(0.224 :				± 0.010)
W) Width	mm				.50 ± 0.2					3.20 ±				± 0.40			± 0.40			± 0.25
	(in.)				98 ± 0.0					(0.126 ±				± 0.016)		(0.197 :			(0.250	
(t) Terminal	mm				.50 ± 0.2					0.61 ±				± 0.36			± 0.39			± 0.39
WVDC	(in.)	10	16	25	20 ± 0.0 50	10)	200	500	50	(0.024 ±	200	500	50	± 0.014)	25	50	± 0.015) 100	200	(0.025 :	100
	100	10	16	25	50	100	200	500	50	100	200	500	50	100	25	50	100	200	50	100
Cap (pF)	150																			
(pr)	220																		<u> </u>	
	330															<u> </u>	-[\sim	W	
	470)) [
	680																$\overline{}$	1_)	~
	1000															Γ				
	1500	J	J	J	J	J	J	М										4 ₹		
	2200	J	J	J	J	J	J	М												
	3300	J	J	J	J	J	J	М												
	4700	J	J	J	J	J	J	М												
	6800	J	J	J	J	J	J	М												_
Cap	0.010	J	J	J	J	J	J	М	K	K	K	K	M	М		X	X	X	M	P
(μF)	0.015	J	J	J	J	J	J	Р	K	K	K	Р	M	M		X	X	X	M	P
	0.022	J J	J	J	J	J	J	Q O	K	K	K	P X	M	M M		X	X	X	M M	P
	0.033		J	-	-	-	J	Ų	K	K		Z	M	M		X	X	X		P
	0.047	J J	J	J	J J	J	J M		K K	K	K K	Z	M	M		X	X	X	M M	P
	0.10		J	J	J	J	M		K	K	K	Z	M	M		X	X	X	M	P
	0.15	J	J	J	J	M	Z		K	K	P		M	M		x	l x	x	M	P
	0.22	J	Ĵ	Ĵ	Ĵ	P	Z		ĸ	K	P.		M	M		x	x	X	M	Р
	0.33	J	J	J	J	Q			K	М	Х		М	М		X	X	X	М	P
	0.47	М	М	М	М	Q			К	Р			М	М		Х	Х	Х	М	Р
	0.68	М	М	Р	Х	Х			М	Q			М	Р		Х	X		М	Р
	1.0	N	N	Р	Х	Z			М	Х			М	Р		Х	Х		М	Р
	1.5	N	N	Z	Z	Z			Z	Z			М			Х	X		М	X
	2.2	X	Х	Z	Z	Z			Z	Z						Х	Х		М	
	3.3	Х	Х	Z	Z				Z	_						X	Z			
	4.7	X	X	Z	Z				Z	Z						X	Z			
	10	<u>Z</u>	Z	Z	Z								-		7	Z	Z		-	\vdash
	22 47	Z Z	Z												Z					
	100	2																		
	WVDC	10	16	25	50	100	200	500	50	100	200	500	50	100	25	50	100	200	50	100
SIZE	11100	10	10		LD10	100	200	300	30	LD		300		013	20	LD		200		014
CIZE																				• •

Lette	r	Α	С	E	G	J	K	М	N	Р	Q	Χ	Υ	Z
Max		0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickne	ess	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
·				PAPER						EMBC	SSED			

X5R - General Specifications





KYOCERA AVX will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the KYOCERA AVX Catalog Part Number. This fulfills KYOCERA AVX's commitment to providing a full range of products to our customers. KYOCERA AVX has provided in the following pages a full range of values that we are currently offering in this special "B" termination. Please contact the factory if you require additional information on our MLCC Tin/Lead Termination "B" products.

Not RoHS Compliant

PART NUMBER (SEE PAGE 4 FOR COMPLETE PART NUMBER EXPLANATION)

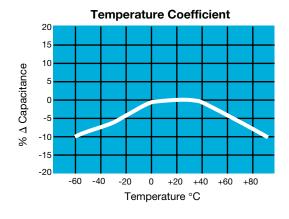
LD05	<u>5</u>	D	101	Ţ	<u>A</u>	<u>B</u>	<u>2</u>	<u>A</u>
Size LD02 - 0402 LD03 - 0603 LD04 - 0504* LD05 - 0805 LD06 - 1206 LD10 - 1210 LD12 - 1812 LD13 - 1825 LD14 - 2225 LD20 - 2220	Voltage 6.3V = 6 10V = Z 16V = Y 25V = 3 35V = D 50V = 5 100V = 1 200V = 2 500V = 7	Dielectric X5R = D	Capacitance Code (In pF) 2 Sig. Digits + Number of Zeros	Capacitance Tolerance B = ±.10 pF (<10pF) C = ±.25 pF (<10pF) D = ±.50 pF (<10pF) F = ±1% (≥ 10 pF) G = ±2% (≥ 10 pF) J = ±5% K = ±10% M = ±20%	Failure Rate A = Not Applicable	Terminations B = 5% min lead X = FLEXITERM® with 5% min lead** **X7R only	Packaging 2 = 7" Reel 4 = 13" Reel Contact Factory For Multiples*	Special Code A = Std. Product

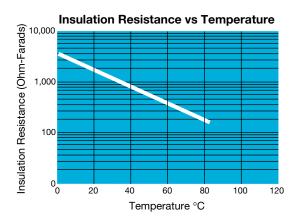
^{*}LD04 has the same CV ranges as LD03.

NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers. Contact factory for non-specified capacitance values.

See FLEXITERM® section for CV options

TYPICAL ELECTRICAL CHARACTERISTICS









Parame	ter/Test	X5R Specification Limits	Measuring (Conditions		
Operating Tem	perature Range	-55°C to +85°C	Temperature C	ycle Chamber		
Capac	itance	Within specified tolerance				
Dissipati	on Factor	≤ 2.5% for ≥ 50V DC rating ≤ 3.0% for 25V, 35V DC rating ≤ 12.5% Max. for 16V DC rating and lower Contact Factory for DF by PN	Freq.: 1.0 k Voltage: 1.0 For Cap > 10 µF, 0	Vrms ± .2V		
Insulation	Resistance	10,000MΩ or 500MΩ - μF, whichever is less	Charge device with 120 ± 5 secs @ roo			
Dielectric	Strength	No breakdown or visual defects	Charge device with 250 1-5 seconds, w/charge limited to 50	and discharge current		
	Appearance	No defects	Deflectio	n: 2mm		
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3			
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	The state of the s			
	Insulation Resistance	≥ Initial Value x 0.3	90 r			
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.9			
	Appearance	No defects, <25% leaching of either end terminal				
	Capacitance Variation	≤ ±7.5%				
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic s seconds. Store at room	temperature for 24 ± 2		
	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.		
	Dielectric Strength	Meets Initial Values (As Above)				
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes		
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes		
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +85°C ± 2°	30 ± 3 minutes		
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes		
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro			
	Appearance	No visual defects	0 1	v . I b		
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 chamber set at 85°C: (+48, -0). Note: Contac	± 2°C for 1000 hours		
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	specification part numl	pers that are tested at		
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test chamb			
	Dielectric Strength	Meets Initial Values (As Above)	temperature for 24 ± 2 hours before measu			
	Appearance	No visual defects				
	Capacitance Variation	≤ ±12.5%	Store in a test chamber s 5% relative humidi			
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	5% relative humidity for 1000 hours (+48, -0) with rated voltage applied.			
,	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature an 24 ± 2 hours bef	d humidity for		
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 Hours ber	o.c.medodinig.		





PREFERRED SIZES ARE SHADED

											_						п	11																			
SIZE				L	D02	2				L	D0	3					LD	05					LD	06						.D10)				LD	12	
Solderi	ng		R	Reflo	w/V	Vave				Refle	۱/wc	Wav	е			Re	flow	/Wav	e.			Re	eflow	/Wa	ve				Refl	ow/V	/ave						
Packag	ing			All	Pap	oer				All	Pa	per			Р	аре	r/Er	nbo	sse	d	Р	аре	r/Er	nbo	sse	d		Pa		'Emb		ed					
(L) Length	mm			1.00								0.15						0.20					.20 ±							0 ± 0							
, ,	(in.) mm			.040 0.50		0.004)		+	(0.06		0.00 0.15						0.00					126 ±					(6 ± 0 0 ± 0)		⊢	_		_
W) Width	(in.)					0.004)			(0.03								0.00					.00 <u>1</u> 063 ±					(8 ± 0)					
(t) Terminal	mm			0.25								0.15						0.2					.50 ±							0 ± 0							\neg
WVDO	(in.)	1				0.006) 5 25	50	1 1	163	0.01	4±(0.00	6) T 25	T 50	63	(0.0 110)20 ±	0.0	10) 135	50	63	(0.0	020 ±	25	10) 35	50	1	ا <u>(</u> ا	0.02	0 ± 0	.010 I 25	25	50	6.3	10	25	50
Cap	100	4	0.3	10	10	23	30	, 4	0.3	10	10	23	33	30	0.3	10	10	23	33	30	0.3	10	10	23	33	30	4	0.3	10	10	23	33	30	0.3	10	23	30
(pF)	150					ł		Ì																													
(F-)	220						С																														
	330				l	1	С		1			1																							H		
	470						С																							-1-	7	~	\leq	▼ -N	٧-	_	
	680		L		L	\perp	С		L	L	L		L				L		L	L				L	L			_	<	جّ	\leq	_		$\bigcap_{i=1}^{\infty}$)_	ŤŦ	
	1000						С																						(. `)		ىلر	ノニ		
	1500				1		С																							_	<u>_</u>	4	_				
	2200						С																								4	t					
	3300						С																								- 1						
	4700					С								G																				'			
	6800		L	-	-	С	Н	+	+	-	-	╀	_	G	_				L									_						<u> </u>	Н		\vdash
Cap	0.010					С								G																							
(μF)	0.015 0.022				С	C						G	G	G						N																	
	0.022				C	_	Н	+	1			G	G	G						N														\vdash	Н		H
	0.033				C			ł				G	G	G						N																	
	0.068				C		1					G	"	G						N																	
	0.10			С	c		т	1	1			G		G				N		N														†	Н		
	0.15				П		1	İ	İ			G			i			N	N																		
	0.22		C*					İ			G	G						N	N							Q											
	0.33										G	G						N																			
	0.47	C*	C*			1					G							N						Q	Q								Х				
	0.68										G							N																	Ш		
		C*	C*	C*					G	G	G	J*					N	N		P*				Q	Q						Χ	Х	Х				
	1.5				1																										_						
	2.2	C*	<u> </u>	⊢	-	+	⊢	G*	_	J*	J*	\vdash	\vdash	\vdash		N	N	N	\vdash	\vdash			Q	Q	<u> </u>			<u> </u>			Z	Χ		 	\sqcup	_	\vdash
	3.3							J*	J*	J*	J*				N	N	N IV	N IV			X	X	V	V						0	7	1					
	4.7							J*	J*	J*	1				N P	N P	N* P	N*			X	X	X	X					V	Q	Z					Z	
	10 22			\vdash	1	+	\vdash	K*		+	-	+	\vdash	-	P*	Р	Р				X	X	X	X		H		Z	Z	Z Z	Z	\vdash		\vdash	\vdash		H
	47														Ρ"						X	^	Α.	^				Z*		Z							
	100																				^						Z*	Z									
	WVDC	4	6.3	10	16	5 25	50) 4	6.3	10	16	25	35	50	6.3	10	16	25	35	50	6.3	10	16	25	35	50			10	16	25	35	50	6.3	10	25	50
	SIZE		_	_	D02		_			_	DO	_					LD						LD	_	_	_				D10		_				12	

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

^{*}Optional Specifications - Contact factory

NOTE: Contact factory for non-specified capacitance values

Automotive MLCC

General Specifications



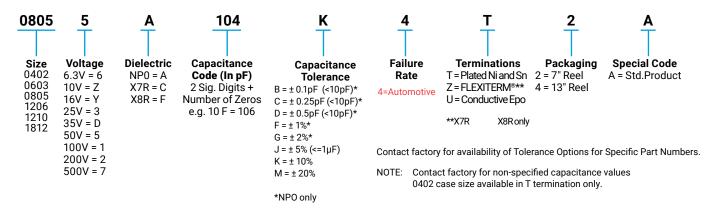


GENERAL DESCRIPTION

KYOCERA AVX has supported the Automotive Industry requirements for Multilayer Ceramic Capacitors consistently for more than 25 years. Products have been developed and tested specifically for automotive applications and all manufacturing facilities are QS9000 and VDA 6.4 approved.

KYOCERA AVX is using AECQ200 as the qualification vehicle for this transition. A detailed qualification package is available on request and contains results on a range of part numbers.

HOW TO ORDER



COMMERCIAL VS AUTOMOTIVE MLCC PROCESS COMPARISON

	Commercial	Automotive
Administrative	Standard Part Numbers. No restriction on who purchases these parts.	Specific Automotive Part Number. sed to control supply of product to Automotive customers.
Lot Qualification (Destructive Physical Analysis - DPA)	As per EIA RS469	Increased sample plan stricter criteria.
Visual/Cosmetic Quality	Standard process and inspection	100% inspection
Application Robustness	Standard sampling for accelerated wave solder on X7R dielectrics	Increased sampling for accelerated wave solder on X7R and NP0 followed by lot by lot reliability testing.

All Tests have Accept/Reject Criteria 0/1

Automotive MLCC

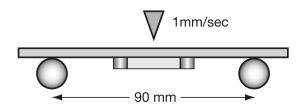
NP0/X7R Dielectric



FLEXITERM FEATURES

a) Bend Test

The capacitor is soldered to the PC Board as shown:



Typical bend test results are shown below:

Style	Conventional	Soft Term
0603	>2mm	>5
0805	>2mm	>5
1206	>2mm	>5

a) Temperature Cycle testing FLEXITERM® has the ability to withstand at least 1000 cycles between -55°C and +125°C

Automotive MLCC-NP0



Capacitance Range

SIZ	ZE	04	02		06	03				0805						206		
Solde		Reflow	//Wave		Reflow	//Wave			Re	eflow/Wa	ive				Reflov	//Wave		
WV		25V	50V	25V	50V	100V	200V	25V	50V	100V	200V	250V	25V	50V	100V	200V	250V	500V
0R5	0.5	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
1R0	1.0	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
1R2	1.2	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
1R5	1.5	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
1R8	1.8	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
2R2	2.2	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
2R7	2.7	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
3R3	3.3	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
3R9	3.9	0	С	G	G G	G	G	J	J	J	N	N	J	J	J	J	J	J
4R7 5R6	4.7 5.6	C	C C	G G		G G	G G	J	J	J	N N	N N	J	J	J	J	J	J
6R8	6.8	C	C	G	G G	G	G	J	J	J	N	N	J	J	J	J	J	J
8R2	8.2	С	C	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
100	10.0	С	C	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
120	12	С	C	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
150	15	C	C	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
180	18	С	C	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
220	22	C	C	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
270	27	C	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
330	33	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
390	39	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
470	47	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J	J	J
510	51	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J		
560	56	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J		
680	68	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J		
820	82	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J		
101	100	С	С	G	G	G	G	J	J	J	N	N	J	J	J	J		
121	120			G	G	G		J	J	J	N	N	J	J	J	J		
151	150			G	G	G		J	J	J	N	N	J	J	J	J		
181	180			G	G	G		J	J	J	N	N	J	J	J	J		
221	220			G	G	G		J	J	J	N	N	J	J	J	J		
271	270			G	G	G		J	J	J	N	N	J	J	J	J		
331	330			G	G	G		J	J	J	N	N	J	J	J	J		
391	390			G G	G G			J	J	J			J	J	J	J		
471 561	470 560			G	G			J	J	J			J	J	J	J		
681	680			G	G			J	J	J			J	J	J	J		
821	820			G	G			J	J	J			J	J	J	J		
102	1000							J	J	J			J	J	J	J		
122	1200							3	3	3			3	3	J			
152	1500																	
182	1800														<u> </u>			
222	2200																	
272	2700																	
	3300																	
392	3900																	
	4700																	
	10nF																	
WV	DC	25V	50V	25V	50V	100V	200V	25V	50V	100V	200V	250V	25V	50V	100V	200V	250V	500V
Siz		04	02		06	03				0805					12	206		,
		-													12			

Letter	А	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBO	SSED			

Automotive MLCC - X7R



Capacitance Range

s	ize		0402					0603						08	05						1206		-				12	10			18	312			2	220		
	dering	R	eflow/W	ave			Re	eflow/W	ave					Reflow						Re	flow/W	ave					Reflo				Reflo					ow Only		
(L) Length	mm (in.)	(0	1 ± 0.1 .04 ± 0.0	004)			(0.	1.6 ± 0.1 063 ± 0.	15 006)					2.01 (0.079 :	± 0.2 ± 0.008)					(0.1	3.2 ± 0. 26 ± 0.	2 008)					3.2 (0.126	± 0.2 ± 0.008)			4.5 (0.177	± 0.3 ± 0.012)			5.7 (0.22	' ± 0.5 4 ± 0.02)		
(W) Width	mm (in.)	(0	0.5 ± 0.	004)			(0.	0.81 ± 0. 032 ± 0.	006)					1.25 (0.049 :	± 0.008)					(0.0	1.6 ± 0. 163 ± 0.	(800					(0.098				_	± 0.008)			(0.197	± 0.4 ' ± 0.016)	
(t) Terminal	mm (in.)		0.25 ± 0. .01 ± 0.0					0.35 ± 0. 014 ± 0.						0.5 ± (0.02 :							0.5 ± 0.2 .02 ± 0.						0.5 ± (0.02 :				0.61 (0.024	± 0.36 ± 0.014)			(0.025	± 0.39 ± 0.015		
	VDC	16V	25V	50V	10V	16V	25V	50V	100V	200V	250V	16V	25V	50V	100V	200V	250V	16V	25V	50V	100V	200V	250V	500V	16V	25V	50V	100V	200V	250V	50V	100V	25V	50V	100V	200V	250V	500V
101 221	100 220	С	С	С	G	G	G	G	G	G			_			_				-		<u> </u>	-	-	-	-			M	Q			 					\vdash
271	270	С	С	С	G	G	G	G	G	G	_									-		+	+-	\vdash	+	1			M	Q	_		 					Н
331	330	С	С	С	G	G	G	G	G	G													 						М	Q								П
391	390	С	С	С	G	G	G	G	G	G																			М	Q								П
471	470	С	С	С	G	G	G	G	G	G																			М	Q								
561	560	С	С	С	G	G	G	G	G	G																			М	Q								口
681	680	С	С	С	G	G	G	G	G	G																			М	Q								ш
821 102	820	С	С	С	G	G	G	G	G	G												—			- V	1/	V	- V	М	Q	- 1/	1/	1					$\vdash \vdash$
102	1000 1220	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	M	Q	K	K	\vdash	\vdash				Н
152	1500	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	M	Q	K	K		\vdash				\vdash
182	1800	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	К	K	К	К	М	Q	К	K						\sqcap
222	2200	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	К	К	К	К	М	Q	К	К						П
272	2700	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	К	М	Q	K	K						
332	3300	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	М	Q	K	K						\square
392	3900	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	М	Q	K	K						\vdash
472	4700	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	М	Q	K	K	\vdash	\vdash				$\vdash\vdash$
562 682	5600 6800	С	С	C	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	M	Q	K	K	\vdash	\vdash				\vdash
822	8200	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	M	Q	К	K						Н
103	Cap 0.01	С	С	С	G	G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	К	К	К	К	М	Q	К	К						П
123	(uF) 0.012	С			G	G	G	G	G			J	J	J	N	N	N	J	J	J	J	J	J		K	K	K	К	М	Q	K	K						
153	0.015	С			G	G	G	G	G			J	J	J	N	N	N	J	J	J	J	J	J		K	K	K	K	М	Q	K	K						
183	0.018	С			G	G	G	G	G	_		J	J	J	N	N	N	J	J	J	J	J	J	_	K	K	K	K	М	Q	K	K						\vdash
223	0.022	С	-		G	G	G	G	G	-		J	J	J	N	N	N	J	J	J	J	J	J	-	K	K	K	K	М	Q	K	K	-					\vdash
273 333	0.027	С			G	G	G	G	J	_		J	J	J	N N	N N	N N	J	J	J	J	J	J		K	K	K	K	M	Q	K K	K	-	\vdash				\vdash
393	0.039				G	G	G	G	J			J	J	J	N	N	N	J	J	J	J	М	М		K	K	K	K	м	Q	K	K						М
473	0.047				G	G	G	G	J			J	J	J	N	N	N	J	J	J	М	М	М		К	К	К	К	М	Q	К	K						П
563	0.056				G	G	G	G	J			J	J	J	N			J	J	J	М	М	М		K	K	K	М	М	Q	K	K						
683	0.068				G	G	G	G	J			J	J	J	N			J	J	J	М	М	М		K	K	K	М	М	Q	K	K						\square
823	0.082		-		G	G	G	G	J	_	_	J	J	J	N	_	<u> </u>	J	J	J	M	M	M	_	K	K	K	M	Q	Q	K	K	-	<u> </u>				
104 124	0.12	\vdash	\vdash	-	G	G	G J	G	J		-	J	J	J	N N	\vdash	-	J	J	J M	M	P	P Q		K	K	K	M P	Q	Q	K	K	\vdash	\vdash		\vdash		Х
154	0.12	\vdash	\vdash		G	J	J		\vdash	+	1	M	N	N	N		\vdash	J	J	M	M	Q	Q		K	K	K	P	Q	Q	K	K		\vdash				Н
224	0.13				G	J	J		<u> </u>			М	N	N	N			J	M	M	Q	Q	Q		M	M	M	P	Q	Q	М	M						М
334	0.33							1	İ	l		N	N	N	N			J	М	Р	Q			1	Р	Р	Р	Q	Z	Z	Х	Х						\Box
474	0.47											N	N	N	N			М	М	Р	Q				Р	Р	Р	Q			Х	Х						
684	0.68											N	N	N	N			М	Q	Q	Q				Р	Р	Q	Х			Х	Х						
105	1	_						1	<u> </u>			N	N	N	N			М	Q	Q	Q	<u> </u>	<u> </u>	<u> </u>	P	Q	Q	Z			X	Х		Z	Z	X	X	ш
155	1.5	_	\vdash	<u> </u>	-	-	-	1	-	-	-	N	N	<u> </u>	-	-	-	Q	Q	Q	Q	-	\vdash	\vdash	P	Q	Z	Z		-	X	X	-	Z	Z	Z	Z	ш
225 335	2.2 3.3	\vdash	\vdash	\vdash	\vdash	\vdash	\vdash	+	\vdash	\vdash	\vdash	N	N	\vdash	\vdash	\vdash	\vdash	Q	Q	Q	Q	\vdash	\vdash	\vdash	Z	Z	Z	Z		\vdash	Z	Z	-	Z	Z			$\vdash\vdash$
475	4.7		\vdash		<u> </u>		\vdash	+		 	\vdash						\vdash	Q	Q	Q	\vdash	\vdash	\vdash	\vdash	X	Z	Z	Z			Z		\vdash	Z	Z			М
106	10						i –	1		1												t			Z	Z	Z				Z		Z	Z	Z			П
226	22																																Z					
	VDC	16V	25V	50V	10V	16V	25V	50V	100V	200V	250V	16V	25V	50V		200V	250V	16V	25V	50V	100V	200V	250V	500V	16V	25V	50V	100V	200V	250V	50V	100V	25V	50V	100V		250V	500V
s	ize		0402					0603						08	05						1206						12	10			18	12			2	220		

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.04)	(0.05)	(0.055)	(0.060)	(0.07)	(0.09)	(0.1)	(0.11)
			PAPER						FMR	OSSED			7

Automotive MLCC - X8R



Capacitance Range

	SIZE			0603			0805		12	06
	Soldering	J		Reflow/Wave			Reflow/Wave		Reflow	/Wave
WVDC	W	VDC	25V	50V	100V	25V	50V	100V	25V	50V
472	pF	4700	G	G	G	J	J	J	J	J
562		5600	G	G	G	J	J	J	J	J
682		6800	G	G	G	J	J	J	J	J
822		8200	G	G	G	J	J	J	J	J
103	uF	0.01	G	G	G	J	J	J	J	J
123		0.012	G	G		J	J	N	J	J
153		0.015	G	G		J	J	N	J	J
183		0.018	G	G		J	J	N	J	J
223		0.022	G	G		J	J	N	J	J
273		0.027	G	G		J	J		J	J
333		0.033	G	G		J	J		J	J
393		0.039	G	G		J	J		J	J
473		0.047	G	G		J	J		J	J
563		0.056	G			N	N		М	М
683		0.068	G			N	N		М	М
823		0.082				N	N		М	М
104		0.1				N	N		M	М
124		0.12				N	N		М	М
154		0.15				N	N		М	М
184		0.18				N			М	М
224		0.22				N			М	М
274		0.27							М	М
334		0.33							М	М
394		0.39							М	М
474		0.47							М	Q
684		0.68							Q	Q
824		0.82							Q	Q
105		1							Q	Q
WVDC		/DC	25V	50V	100V	25V	50V	100V	25V	50V
	SIZE			0603			0805		12	06

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

APS for COTS+ High Reliability Applications



General Specifications Surface Mount NP0, X7R and X8R/L MLCCs



KYOCERA AVX's APS COTS+ series of multilayer ceramic capacitors offers the customer a high reliability solution with an ultralow failure rate, <1ppb, in a variety of case sizes and voltages. The APS range encompasses a wide range of dielectric types to meet the customer's requirements from low temperature/voltage capacitance change dielectric, NPO, to high preforming capacitance voltage X7R to high temperature reliability dielectrics, X8R/L.

APS capacitors have a wider capacitance range than MIL spec parts that satisfies the need for higher CV demands and board space saving requirements. Each production lot is extensively tested and removes the requirement for customer specific drawings. The testing regime uses many of the MIL-STD test methods as per MIL-PRF-55681 and has a field failure rate of less than 1 ppb. The APS testing series uses KYOCERA AVX's unique in-house maverick testing detection system that eliminates infant mortality failures.

Applications suitable for APS include Industrial, Telecommunications, Aviation, and Military. The APS is available with a range of different termination finishes, Flexiterm®, Nickel / Tin and Tin with Pb1. Flexiterm® technology delivers improved thermo-mechanical stress resistance.

APS RELIABILITY TEST SUMMARY

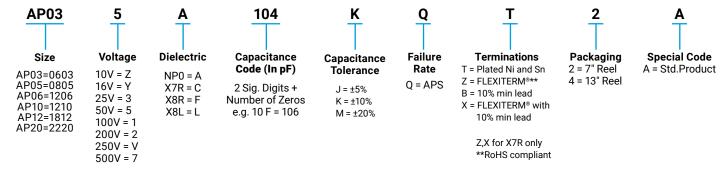
- 100% Visual Inspection
- DPA
- IR, DF, Cap, DWV
- Maverick Lot Review
- Thermal Shocl
- 85/85 Testina
- Additional Life Testing
- C of C with every Order
- Quarterly Data Package

FEATURES

- The APS range has been extensively reliability tested as standard resulting in an ultralow failure rate, ≤1ppb
- The APS range is available with Flexiterm® that deliver's high thermo-mechanical stress resistance.
- High CV range enabling board space saving requirements.

Dielectric	Temperature/Percentage Cap Change
NP0	-30ppm +30ppm from -55°C + 125°C
X7R	-15% +15% from -55°C to + 125°C
X8R	-15% +15% from -55°C to + 150°C
X8L	-15% +40% from -55°C to + 150°C

HOW TO ORDER



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Number.

APS COTS+ NP0 Series



Capacitance Range

Size	AP	03 = 060	03	AP	05 = 08	05		AF	P06 = 12	06			AP10 :	= 1210	
WVDC	25V	50V	100V	25V	50V	100V	25V	50V	100V	200V	500V	25V	50V	100V	200V
100 10pF	G	G	G	J	J	J	J	J	J	J	J				
120 12	G	G	G	J	J	J	J	J	J	J	J				
150 15	G	G	G	J	J	J	J	J	J	J	J				
180 18	G	G	G	J	J	J	J	J	J	J					
220 22	G	G	G	J	J	J	J	J	J	J					
270 27	G	G	G	J	J	J	J	J	J	J					
330 33	G	G	G	J	J	J	J	J	J	J					
390 39	G	G	G	J	J	J	J	J	J	J					
470 47	G	G	G	J	J	J	J	J	J	J					
510 51	G	G	G	J	J	J	J	J	J	J					
560 56	G	G	G	J	J	J	J	J	J	J					
680 68	G	G	G	J	J	J	J	J	J	J					
820 82	G	G	G	J	J	J	J	J	J	J					
101 100	G	G	G	J	J	J	J	J	J	J					
121 120	G	G	G	J	J	J	J	J	J	J					
151 150	G	G	G	J	J	J	J	J	J	J					
181 180	G	G	G	J	J	J	J	J	J	J					
221 220	G	G	G	J	J	J	J	J	J	J					
271 270	G	G	G	J	J	J	J	J	J	J					
331 330	G	G	G	J	J	J	J	J	J	J					
391 390	G	G		J	J	J	J	J	J	J					
471 470	G	G		J	J	J	J	J	J	J					
561 560				J	J	J	J	J	J	J					
681 680				J	J	J	J	J	J	J					
821 820				J	J	J	J	J	J	J					
102 1000				J	J	J	J	J	J	J		J	J	J	J
122 1200												J	J	М	М
152 1500												J	J	М	М
182 1800												J	J	М	М
222 2200												J	J	М	М
272 2700															
332 3300															
392 3900															
472 4700															
103 10nF															
WVDC	25V	50V	100V	25V	50V	100V	25V	50V	100V	200V	500V	25V	50V	100V	200V
Size	AP	03 = 060	03	AP	05 = 08	05		AF	P06 = 12	06			AP10 :	= 1210	



Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBO	SSED			

TS 16949, ISO 9001Certified

APS COTS+ X7R Series



Capacitance Range

	Size		AP	03 = 06	503			AP	05 = 0	805				AP06 =	1206				AP10 :	= 1210)	AP12	= 1812	AP2	20 = 22	220
	WVDC	16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	16V	25V	50V	100V	200V	500V	16V	25V	50V	100V	50V	100V	25V	50V	100V
102	Cap 1000	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	K	К	К	К	К	K			
182	(pF) 1800	G	G	G	G		J	J	J	J	J	J	J	J	J	J	J	K	К	K	К	K	K			
222	2200	G	G	G	G		J	J	J	J	J	J	J	J	J	J	J	K	К	K	К	K	K			
332	3300	G	G	G	G		J	J	J	J	J	J	J	J	J	J	J	K	К	K	K	K	K			
472	4700	G	G	G	G		J	J	J	J	J	J	J	J	J	J	J	K	К	K	К	K	K			
103	0.01	G	G	G	G		J	J	J	J	J	J	J	J	J	J	J	K	К	K	K	K	K			
123	0.012	G	G	G			J	J	J	М		J	J	J	J	J		K	K	K	K	K	K			
153	0.015	G	G	G			J	J	J	М		J	J	J	J	J		K	K	K	K	K	K			
183	0.018	G	G	G			J	J	J	М		J	J	J	J	J		K	К	K	K	K	K			
223	0.022	G	G	G			J	J	J	М		J	J	J	J	J		K	К	K	K	K	K			
273	0.027	G	G	G			J	J	J	М		J	J	J	J	J		K	K	K	K	K	K			
333	0.033	G	G	G			J	J	J	М		J	J	J	J	J		K	K	K	K	K	K			
473	0.047	G	G	G			J	J	J	М		J	J	J	М	J		K	К	K	K	K	K			
563	0.056	G	G	G			J	J	J	М		J	J	J	М	J		K	K	K	М	K	K			
683	0.068	G	G	G			J	J	J	М		J	J	J	М	J		K	К	K	М	K	K			
823	0.082	G	G	G			J	J	J	М		J	J	J	М	J		K	К	K	М	K	K			
104	0.1	G	G	G			J	J	М	М		J	J	J	М	J		K	K	K	М	K	K			
124	0.12						J	J	М	N		J	J	М	М			K	K	K	Р	K	K			
154	0.15						М	N	М	N		J	J	М	М			K	K	K	Р	K	K			
224	0.22						М	N	М	N		J	М	М	Q			М	М	M	Р	М	М			
334	0.33						N	N	М	N		J	М	Р	Q			Р	Р	Р	Q	Х	Χ			
474	0.47						N	N	М	N		М	М	Р	Q			Р	Р	Р	Q	Х	Χ			
684	0.68						N	N	N			М	Q	Q	Q			Р	Р	Q	Х	Х	Х			
105	Cap 1.0						N	N	N*			М	Q	Q	Q*			Р	Q	Q	Z*	Х	Х			
155	(μF) 1.5											Q	Q	Q				Р	Q	Z	Z	Х	Х			
225	2.2											Q	Q	Q				Z	Z	Z	Z*	Z	Z			
335	3.3											Q						Х	Z	Z	Z	Z				
475	4.7											Q						Х	Z	Z		Z*				
106	10																	Z	Z*						Z	Z*
226	22																							Z		
	WVDC	16V	25V	50V		200V	16V	25V	50V		200V	16V	25V	50V	100V	200V	500V	16V	25V	50V		50V	100V	25V		100V
	Size		AP	03 = 06	503			AP	05 = 0	805				AP06 =	1206				AP10 :	= 1210)	AP12	= 1812	AP2	20 = 22	220

^{*}Not currently available with lead plating finish, contact plant for further information.

Letter	Α	С	E	G	J	K	М	N	Р	Q	X	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						FMBO	SSED			

TS 16949, ISO 9001Certified

APS COTS+ X8R/L Series



Capacitance Range

X8R

	SIZE	AP03 =	: 0603	AP05	= 0805	AP06 =	1206
,	WVDC	25V	50V	25V	50V	25V	50V
331	Cap 330	G	G	J	J		
471	(pF) 470	G	G	J	J		
681	680	G	G	J	J		
102	1000	G	G	J	J	J	J
152	1500	G	G	J	J	J	J
222	2200	G	G	J	J	J	J
332	3300	G	G	J	J	J	J
472	4700	G	G	J	J	J	J
682	6800	G	G	J	J	J	J
103	Cap 0.01	G	G	J	J	J	J
153	(μF) 0.015	G	G	J	J	J	J
223	0.022	G	G	J	J	J	J
333	0.033	G	G	J	J	J	J
473	0.047	G	G	J	J	J	J
683	0.068	G		N	N	M	М
104	0.1			N	N	M	М
154	0.15			N	N	M	М
224	0.22	·		N		М	М
334	0.33	·				М	М
474	0.47					М	
684	0.68	<u> </u>					<u> </u>
105	1						
	WVDC	25V	50V	25V	50V	25V	50V
	SIZE	06	03	08	305	120	6

X8L

	SIZE		AP03 = 0603	3		AP05 = 080	5		AP06 :	= 1206			
	WVDC	25V	50V	100V	25V	50V	100V	16V	25V	50V	100V		
331	Cap 330	-	G	G	-	J	J	-	-				
471	(pF) 470		G	G		J	J						
681	680		G	G		J	J						
102	1000		G	G		J	J						
152	1500		G	G		J	J			J	J		
222	2200		G	G		J	J			J	J		
332	3300		G	G		J	J			J	J		
472	4700		G	G		J	J			J	J		
682	6800		G	G		J	J			J	J		
103	Cap 0.01		G	G		J	J			J	J		
153	(μF) 0.015	G	G		J	J	J			J	J		
223	0.022	G	G		J	J	J			J	J		
333	0.033	G	G		J	J	N			J	J		
473	0.047	G	G		J	J	N			J	J		
683	0.068	G	G		J	J				J	J		
104	0.1	G	G		J	J				J	М		
154	0.15				J	N		J	J	J	Q		
224	0.22				N	Ζ		J	J	J	Q		
334	0.33				N			J	М	Р	Q		
474	0.47				N			М	М	Р			
684	0.68							М					
105	1				25V			М					
	WVDC	25V	25V 50V 100V			50V	100V	16V	V 25V 50V 100V				
	SIZE		0603			0805		1206					



Letter	Α	С	Е	G	J	K	М	N	Р	Q	Х	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBO	SSED			

TS 16949, ISO 9001Certified

General Specifications





GENERAL DESCRIPTION

With increased requirements from the automotive industry for additional component robustness, KYOCERA AVX recognized the need to produce a MLCC with enhanced mechanical strength. It was noted that many components may be subject to severe flexing and vibration when used in various under the hood automotive and other harsh environment applications.

To satisfy the requirement for enhanced mechanical strength, KYOCERA AVX had to find a way of ensuring electrical integrity is maintained whilst external forces are being applied to the component. It was found that the structure of the termination needed to be flexible and after much research and development, KYOCERA AVX launched FLEXITERM®. FLEXITERM® is designed to enhance the mechanical flexure and temperature cycling performance of a standard ceramic capacitor with an X7R dielectric. The industry standard for flexure is 2mm minimum. Using FLEXITERM®, KYOCERA AVX provides up to 5mm of flexure without internal cracks. Beyond 5mm, the capacitor will generally fail "open".

As well as for automotive applications FLEXITERM® will provide Design Engineers with a satisfactory solution when designing PCB's which may be subject to high levels of board flexure.

PRODUCT ADVANTAGES

- High mechanical performance able to withstand, 5mm bend test guaranteed
- Increased temperature cycling performance, 3000 cycles and beyond
- Flexible termination system
- Reduction in circuit board flex failures
- Base metal electrode system
- Automotive or commercial grade products available
- AECQ200 Qualified
- Approved to VW 80808 Specification

APPLICATIONS

High Flexure Stress Circuit Boards

· e.g. Depanelization: Components near edges of board.

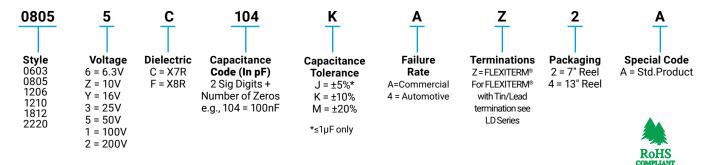
Variable Temperature Applications

- · Soft termination offers improved reliability performance in applications where there is temperature variation.
- · e.g. All kind of engine sensors: Direct connection to battery rail.

Automotive Applications

- Improved reliability.
- Excellent mechanical performance and thermo mechanical performance.

HOW TO ORDER



NOTE: Contact factory for availability of Tolerance Options for Specific Part Numbers.

Specifications and Test Methods

KYOCERa

PERFORMANCE TESTING

AEC-0200 Qualification:

Created by the Automotive Electronics

Specification defining stress test qualification for passive components

Testing:

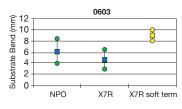
Key tests used to compare soft termination to AEC-Q200 qualification:

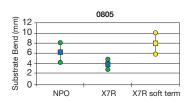
- **Bend Test**
- Temperature Cycle Test

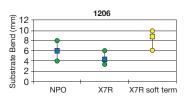


BOARD BEND TEST RESULTS

AEC-Q200 Vrs FLEXITERM® Bend Test







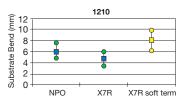


TABLE SUMMARY

Typical bend test results are shown below:

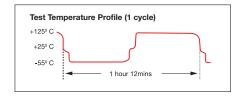
Style	Conventional Termination	FLEXITERM®
0603	>2mm	>5mm
0805	>2mm	>5mm
1206	>2mm	>5mm

TEMPERATURE CYCLE TEST PROCEDURE

Test Procedure as per AEC-0200:

The test is conducted to determine the resistance of the component when it is exposed to extremes of alternating high and low temperatures.

- Sample lot size quantity 77 pieces
- TC chamber cycle from -55°C to +125°C for 1000 cycles
- Interim electrical measurements at 250, 500, 1000 cycles
- Measure parameter capacitance dissipation factor, insulation resistance



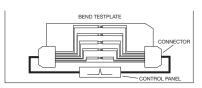
BOARD BEND TEST PROCEDURE

According to AEC-Q200

Test Procedure as per AEC-Q200: Sample size: 20 components

Span: 90mm Minimum deflection spec: 2 mm

- Components soldered onto FR4 PCB (Figure 1)
- Board connected electrically to the test equipment



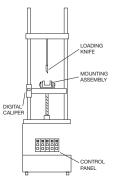


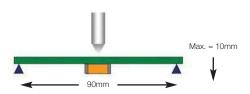
Fig 1 - PCB layout with electrical connections

Fig 2 - Board Bend test equipment

ENHANCED SOFT TERMINATION BEND TEST PROCEDURE

Bend Test

The capacitor is soldered to the printed circuit board as shown and is bent up to 10mm at 1mm per second:



- · The board is placed on 2 supports 90mm apart (capacitor side down)
- The row of capacitors is aligned with the load stressing knife



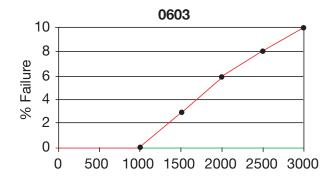
- · The load is applied and the deflection where the part starts to crack is recorded (Note: Equipment detects the start of the crack using a highly sensitive current detection circuit)
- The maximum deflection capability is 10mm

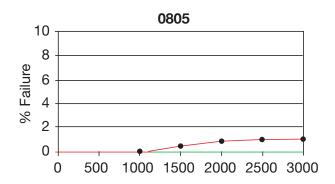


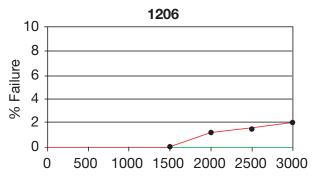
Specifications and Test Methods

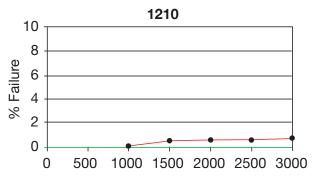


BEYOND 1000 CYCLES: TEMPERATURE CYCLE TEST RESULTS









Green = Soft Term MLCC (Flexiterm) Red = Standard MLCC

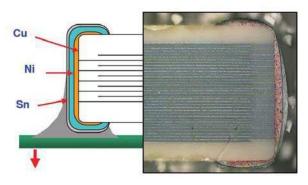
Soft Term - No Defects up to 3000 cycles

AEC-Q200 specification states 1000 cycles compared to 3000 temperature cycles.

FLEXITERM® TEST SUMMARY

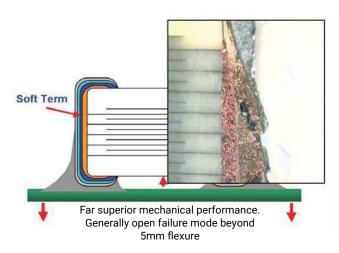
- · Qualified to AEC-Q200 test/specification with the exception of using 3000 temperature cycles (up to +150°C bend test guaranteed greater than 5mm).
- · FLEXITERM® provides improved performance compared to standard termination systems.
- Board bend test improvement by a factor of 2 to 4 times.
- Temperature Cycling:
 - 0% Failure up to 3000 cycles
 - No ESR change up to 3000 cycle

WITHOUT SOFT TERMINATION



Major fear is of latent board flex failures.

WITH SOFT TERMINATION





Capacitance Range X8R Dielectric

	SIZE	06	03	08	305	1206			
Sc	oldering	Reflow	//Wave	Reflov	v/Wave	Reflow	/Wave		
	WVDC	25V	50V	25V	50V	25V	50V		
	Cap 270	G	G						
	(pF) 330	G	G	J	J				
471	470	G	G	J	J				
681	680	G	G	J	J				
102	1000	G	G	J	J	J	J		
152	1500	G	G	J	J	J	J		
182	1800	G	G	J	J	J	J		
222	2200 2700	G	G	J	J	J	J		
332	3300	G G	G G	J	J	J	J		
332	3900	G	G	J	J	J	J		
472	4700	G	G	J	J	J	J		
562	5600	G	G	J	J	J	J		
682	6800	G	G	J	J	J	J		
822	8200	G	G	J	J	Ĵ	J		
	Cap 0.01	G	G	Ĵ	J	J	J		
123	(µF) 0.012	G	G	Ĵ	J	J	J		
153	0.015	G	G	J	J	J	J		
183	0.018	G	G	J	J	J	J		
223	0.022	G	G	J	J	J	J		
273	0.027	G	G	J	J	J	J		
333	0.033	G	G	J	J	J	J		
393	0.039	G	G	J	J	J	J		
473	0.047	G	G	J	J	J	J		
563	0.056	G		N	N	М	М		
683	0.068	G		N	N	М	М		
823	0.082			N	N	M	M		
104	0.1			N	N	M	M		
124 154	0.12 0.15			N N	N N	M M	M M		
184	0.15			N N	I N	M M	M		
224	0.18			N N		M	M		
274	0.22			IN		M	M		
334	0.33				1	M	M		
394	0.39					M	141		
474	0.47					M			
684	0.68								
824	0.82		İ	İ					
105	1								
	WVDC	25V	50V	25V	50V	25V 50V			
	SIZE	06	03	08	305	12	06		

Letter	Α	С	Е	G	J	K	М	N	Р	Q	Χ	Υ	Z
Max. Thickness	0.33 (0.013)	0.56 (0.022)	0.71 (0.028)	0.90 (0.035)	0.94 (0.037)	1.02 (0.040)	1.27 (0.050)	1.40 (0.055)	1.52 (0.060)	1.78 (0.070)	2.29 (0.090)	2.54 (0.100)	2.79 (0.110)
			PAPER						EMBO	SSED			

TS 16949, ISO 9001Certified



Capacitance Range X7R Dielectric

	Size			0402					06	03					(805						120	6			1210			1812		2220			
	Solderi			low/ V				R		/Wave						w/Wa	ve				Re	eflow/					Reflov		V		w Only	Re	eflow (
	WVDC					10V	16V				200V	250V	16V	25V				250V	16V	25V				/250V	1500V						100 V			
221	Cap	220	С	C	С											С																	-	
271	(pF)	270	C	C	C																								i –					
331	<u> </u>	330	C	C	C																								i –					
391		390	С	С	С					İ															İ						Ì			İ
471		470	С	С	С																				1						Î			
561		560	С	С	С																													
681		680	С	С	С				Ĭ					İ	Ì																			
821		820	С	С	С																								İ					İ
102		1000	С	С	С		G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	N	N			
182		1800	С	С	С		G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	N	N			
222		2200	С	С	С		G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	N	N			
332		3300	С	С	С		G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	N	N			
472		4700	С	С	С		G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	N	N			
103	Cap	0.01	С				G	G	G	G	G	G	J	J	J	J	J	J	J	J	J	J	J	J	J	K	K	K	K	N	N			
123	(µF)	0.012	С				G	G	G				J	J	J	N	N	N	J	J	J	J	J	J		K	K	K	K	N	N			
153		0.015	С				G	G	G				J	J	J	N	N	N	J	J	J	J	J	J		K	K	K	K	N	N			
183		0.018	С				G	G	G				J	J	J	N	N	N	J	J	J	J	J	J		K	K	K	K	N	N			
223		0.022	С				G	G	G				J	J	J	N	N	N	J	J	J	J	J	J		K	K	K	K	N	N			
273		0.027	С				G	G	G				J	J	J	N	N	N	J	J	J	J	J	J		K	K	K	K	N	N			
333		0.033	С	_			G	G	G				J	J	J	N	N	N	J	J	J	J	J	J		K	K	K	K	N	N			
473		0.047					G	G	G				J	J	J	N	N	N	J	J	J	М	J	J	_	K	K	K	K	N	N			
563		0.056					G	G	G				J	J	J	N			J	J	J	М	J	J	_	K	K	K	M	N	N			
683		0.068		-			G	G	G	_			J	J	Į J	N			J	J	J	M	J	J	_	K	K	K	M	N	N			<u> </u>
823		0.082	_				G	G	G				J	J	J	N			J	J	J	M	J	J	_	K	K	K	M	N	N			-
104		0.1	С	-			G	G	G	-			J	J	J	N		_	J	J	J	M	J	J	-	K	K	K	M	N	N			
124 154		0.12		-					-				J M	J N	N	N		_	J	J	M	M	-	-	-	K	K	K	P	N	N N			-
224		0.15				_							_		_	N			J	J	M	0			1	K	K	K	_	N				
334		0.22		+	-	G	J	J	J	-	-		M N	N	N N	N N		_	J	M	M P	0	-	1	1	M P	M P	M P	P 0	N X	N X	\vdash	-	-
474		0.33		\vdash	-	J	J	J		-	_		N	N	N	N		\vdash	M	M	P	Q	-	 	_	P	P	P	Q	X	X			\vdash
684		0.47		 		J	J	J			-		N	N	N	N			M	0	0	0	_	<u> </u>	+	P	P	Q	X	X	X			
105		1		+-		\vdash	\vdash	\vdash	\vdash		-		N	N	N	N			M	Q	Q	0	_	1	 	P	0	Q	Z	X	X			<u> </u>
155		1.5		1	-	H	-	1	1	-			N	N	IN	IN			Q	Q	Q	Ų		1	-	P	0	Z	Z	X	X		-	
225		2.2		\vdash	-	\vdash	\vdash	-	 	-			N	N		1	 		Q	Q	Q		+	1	<u> </u>	X	Z	Z	Z	Z	Z		 	<u> </u>
335		3.3		\vdash	\vdash	\vdash	\vdash	\vdash	\vdash							\vdash			0	ō	٧_		+	\vdash	\vdash	X	Z	Z	Z	Z				\vdash
475		4.7		<u> </u>					 						1				Q	Q		1	t -		<u> </u>	X	Z	Z	Z	Z				Z
106		10		t		\vdash			\vdash					t	+	<u> </u>	<u> </u>		_	<u> </u>		t	<u> </u>			Z	Z	Z					Z	Z
226		22															<u> </u>							t	i –	_	_	1				Z		
	WVDC		16V	25V	50V	10V	16V	25V	50V	100 V	200V	250V	16V	25V	50V	100 V	200V	250V	16V	25V	50V	100 V	200V	250v	500V	16V	25V	50V	100 V	50V	100 V	25V	50V	100 V
	Size			0402		1			06					,		805						120		,,	,		12				312		2220	

Letter	Α	С	E	G	J	K	М	N	Р	Q	Χ	Υ	Z
Max.	0.33	0.56	0.71	0.90	0.94	1.02	1.27	1.40	1.52	1.78	2.29	2.54	2.79
Thickness	(0.013)	(0.022)	(0.028)	(0.035)	(0.037)	(0.040)	(0.050)	(0.055)	(0.060)	(0.070)	(0.090)	(0.100)	(0.110)
			PAPER						EMBC	SSED			

FLEXISAFE MLC Chips

General Specifications and Capacitance Range For Ultra Safety Critical Applications





KYOCERA AVX have developed a range of components specifically for safety critical applications.

Utilizing the award-winning FLEXITERM™ layer in conjunction with the cascade design previously used for high voltage MLCCs, a range of ceramic capacitors is now available for customers who require components designed with an industry leading set of safety features.

The FLEXITERM™ layer protects the component from any damage to the ceramic resulting from mechanical stress during PCB assembly or use with end customers. Board flexure type mechanical damage accounts for the majority of MLCC failures. The addition of the cascade structure protects the component from low insulation resistance failure resulting from other common causes for failure; thermal stress damage, repetitive strike ESD damage and placement damage. With the inclusion of the cascade design structure to complement the FLEXITERM™ layer, the FLEXISAFE range of capacitors has unbeatable safety features. Flexisafe capacitors are qualified in accordance with AEC-Q200 standard. AEC-Q200 detailed qualification data is available on request

HOW TO ORDER

FS05 104 K Q Z 2 Special Size Voltage **Dielectric** Capacitance Capacitance **Failure Terminations Packaging** Code FS03 = 0603Code (In pF) **Tolerance** Z = FLEXITERM™ 2 = 7" Reel 16V = Y Rate FS05 = 0805 *X = FLEXITERM™ 4 = 13" Reel A = Std.Product $J = \pm 5\%$ 25V = 32 Sig. Digits + A = Commercial FS06 = 1206 K = ±10% with 5% min lead 50V = 5Number of 4 = Automotive FS10 = 1210 $M = \pm 20\%$ *Not RoHS Compliant Zeros 0 = APS100V = 1 e.g. $10\mu F = 106$

CAPACITANCE RANGE FLEXISAFE X7R

SI	SIZE FS03 = 0603					FS05 :	= 0805		FS	S06 = 120	6	FS10 = 1210			
W\	/DC	16	25	50	100	16	25	50	100	16	25	50	16	25	50
102	1000	G	G	G	G	J	J	J	J	J	J	J			
182	1800	G	G	G	G	J	J	J	ک	J	J	J			
222	2200	G	G	G	G	J	J	J	٦	J	J	J			
332	3300	G	G	G	G	J	J	J	J	J	J	J			
472	4700	G	G	G	G	J	J	J	J	J	J	J			
682	6800	G	G	G	G	J	J	J	J	J	J	J			
103	0.01	G	G	G	G	J	J	J	٦	J	J	J			
123	0.012	G	G	G		J	J	J	ک	J	J	J			
153	0.015	G	G	G		J	J	J	ک	J	J	J			
183	0.018	G	G	G		J	J	J	٦	J	J	J			
223	0.022	G	G	G		N	N	N	N	J	J	7			
273	0.027					N	N	N	N	7	7	7			
333	0.033					N	N	N	N	7	7	7			
473	0.047					N	N	N	N	М	М	М			
563	0.056					N	N	N	Ν	М	М	М			
683	0.068					N	N	N	N	М	М	М			
823	0.082					N	N	N	N	М	М	М			
104	0.1					N	N	N	N	М	М	М			
124	0.12	, and the second				, in the second				М	М	М	·		
154	0.15									М	М	М	Q	Q	Q
224	0.22												Q	Q	Q
334	0.33												Q	Q	Q
474	0.47												Q	Q	Q

Letter	G	J	М	N	Q
Max. Thickness	0.90 (0.035)	0.94 (0.037)	1.27 (0.050)	1.40 (0.055)	1.78 (0.070)
	PAF	PFR		FMBOSSFD	





Capacitor Array

Capacitor Array (IPC)



BENEFITS OF USING CAPACITOR ARRAYS

KYOCERA AVX capacitor arrays offer designers the opportunity to lower placement costs, increase assembly line output through lower component count per board and to reduce real estate requirements.

Reduced Costs

Placement costs are greatly reduced by effectively placing one device instead of four or two. This results in increased throughput and translates into savings on machine time. Inventory levels are lowered and further savings are made on solder materials, etc.

Space Saving

Space savings can be quite dramatic when compared to the use of discrete chip capacitors. As an example, the 0508 4-element array offers a space reduction of >40% vs. 4 x 0402 discrete capacitors and of >70% vs. 4 x 0603 discrete capacitors. (This calculation is dependent on the spacing of the discrete components.)

Increased Throughput

Assuming that there are 220 passive components placed in a mobile

A reduction in the passive count to 200 (by replacing discrete components with arrays) results in an increase in throughput of approximately 9%.

A reduction of 40 placements increases throughput by 18%.

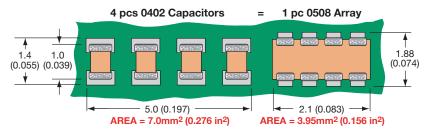
For high volume users of cap arrays using the very latest placement equipment capable of placing 10 components per second, the increase in throughput can be very significant and can have the overall effect of reducing the number of placement machines required to mount components:

If 120 million 2-element arrays or 40 million 4-element arrays were placed in a year, the requirement for placement equipment would be reduced by one machine.

During a 20Hr operational day a machine places 720K components. Over a working year of 167 days the machine can place approximately 120 million. If 2-element arrays are mounted instead of discrete components, then the number of placements is reduced by a factor of two and in the scenario where 120 million 2-element arrays are placed there is a saving of one pick and place machine.

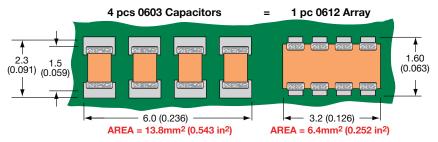
Smaller volume users can also benefit from replacing discrete components with arrays. The total number of placements is reduced thus creating spare capacity on placement machines. This in turn generates the opportunity to increase overall production output without further investment in new equipment.

W2A (0508) Capacitor Arrays



The 0508 4-element capacitor array gives a PCB space saving of over 40% vs four 0402 discretes and over 70% vs four 0603 discrete capacitors.

W3A (0612) Capacitor Arrays



The 0612 4-element capacitor array gives a PCB space saving of over 50% vs four 0603 discretes and over 70% vs four 0805 discrete capacitors.



Capacitor Array (IPC)





0508 - 2 Element



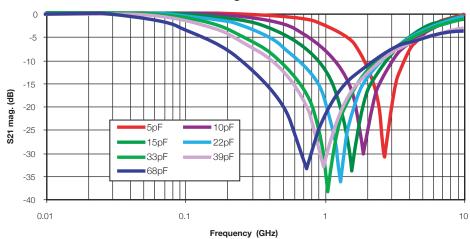
GENERAL DESCRIPTION

KYOCERA AVX is the market leader in the development and manufacture of capacitor arrays. The array family of products also includes the 0612 4-element device as well as 0508 2-element and 4-element series, all of which have received widespread acceptance in the marketplace.

KYOCERA AVX capacitor arrays are available in X5R, X7R and NP0 (C0G) ceramic dielectrics to cover a broad range of capacitance values. Voltage ratings from 6.3 Volts up to 100 Volts are offered. KYOCERA AVX also now offers a range of automotive capacitor arrays qualified to AEC-Q200 (see separate table).

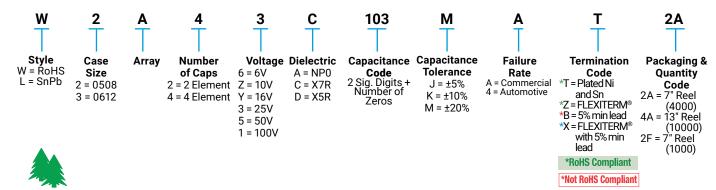
Key markets for capacitor arrays are Mobile and Cordless Phones, Digital Set Top Boxes, Computer Motherboards and Peripherals as well as Automotive applications, RF Modems, Networking Products, etc.

AVX Capacitor Array - W2A41A***K S21 Magnitude



HOW TO ORDER

RoHS COMPLIANT



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.



032417





S	IZE		W	2 = 050	08	W	3 = 061	2	
# Fle	ments	+		4			4		
	dering	\dashv	Po		N/O	Po	flow/Wa	VA	
	kaqinq	+					per/Embossed		
	mr	n		.30 ± 0.1			.60 ± 0.15		
Length	(in			051 ± 0.0			0.00 ± 0.00		
Width	mr			2.10 ± 0.1			.20 ± 0.20		
Max.	(in		(0.	083 ± 0.0 0.94	06)	(0.	126 ± 0.00 1.35)8)	
Thickness	mr (in			(0.037)			(0.053)		
	/VDC	\top	16	25	50	16	25	50	
1R0	Сар	1.0							
1R2	(pF)	1.2							
1R5		1.5							
1R8		1.8							
2R2	:	2.2							
2R7	:	2.7							
3R3		3.3							
3R9		3.9							
4R7		4.7							
5R6		5.6							
6R8		5.8							
8R2		3.2							
100		10							
120		12							
150		15							
180		18							
220 270		22 27							
330		33							
390		39							
470		47							
560		56							
680		68							
820		82							
101	1	00							
121	1	20							
151	1	50							
181	1	80							
221		20							
271		70							
331		30							
391		90							
471		70							
561		60							
681 821		80 20							
102		00							
102		00							
152	150								
182		00							
222		00							
272		00							
332		00							
392		00							
472		00							
562	56	00							
682	68	00							
822	82	00						L	

= Supported Values





	SIZE				N2 =	050	8			٧	V2 =	050	8				V3 =	061	2	
#	Elemen	ts				2						4					4	4		
	Soldering				Reflov		e					//Wav					Reflow			
	Packaqinq					aper				Paper/Embossed						per/E				
Lengt	:h	mm (in.)		((0.051	± 0.15			1.30 ± 0.15 (0.051 ± 0.006)				1.60 ± 0.150 (0.063 ± 0.006)							
NAC 111		mm				± 0.00			2.10 ± 0.15							£ 0.20	0)			
Width	1	(in.)		((0.083	± 0.00					.083 :	± 0.00				(0).126 :	£ 0.00	8)	
Max.		mm				94						94						35		
Thick	ness WVDC	(in.)		10		037) 25	50	100	6	10)37) 25	50	100		10	(0.0		50	100
101	Cap	100	6	10	16	25	50	100	6	10	16	25	50	100	6	10	16	25	50	100
121	(PF)	120																		1
151	` '	150																		
181		180																		
221		220																		
271 331		270 330																		
391		390																		
471		470																		
561		560																		
681		680																		
821		820																		
102 122		1000 1200																		
152		1500																		
182		1800																		
222		2200																		
272		2700																		
332 392		3300 3900																		
472		4700																		
562		5600																		
682		6800																		
822		8200																		
103		0.010																		
123 153		0.012 0.015																		
183		0.018																		
223		0.022																		
273		0.027																		
333		0.033																		
393 473		0.039 0.047																		
563		0.056																		
683		0.068																		
823		0.082																		
104		0.10																		
124 154		0.12 0.15																		
184		0.15									 		\vdash							H
224		0.22																		
274		0.27																		
334		0.33																		
474 564		0.47 0.56																		
684		0.56		\vdash					H		 		 							H
824		0.82																		
105		1.0	L			L	L_	<u> </u>	L	L		L	L_	L	L	L	L_	L	L_	
125		1.2																		7
155		1.5																		
185 225		1.8 2.2	-				-	-	-	-	-		-				-		-	H
335		3.3																		
475		4.7	L			L				L			L	L		L		L		<u> </u>
106		10																		
226		22																		
476		47																		
107		100																		ш

Automotive Capacitor Array (IPC)





As the market leader in the development and manufacture of capacitor arrays KYOCERA AVX is pleased to offer a range of AEC-Q200 qualified arrays to compliment our product offering to the Automotive industry. Both the KYOCERA AVX 0612 and 0508 4-element capacitor array styles are qualified to the AEC-Q200 automotive specifications.

AEC-Q200 is the Automotive Industry qualification standard and a detailed qualification package is available on request. All KYOCERA AVX automotive capacitor array production facilities are certified to ISO/TS 16949:2002.

X7R

W3 = 0612

W2 = 0508

HOW TO ORDER

<u>w</u>	3	<u>A</u>	4	<u>Y</u>	<u>c</u>	<u>104</u>	K	4	<u>T</u>	2A
Style W = RoHS L = SnPb	Case Size 2 = 0508 3 = 0612	Array	Number of Caps	Voltage Z = 10V Y = 16V 3 = 25V 5 = 50V 1 = 100V	Dielectric A = NP0 C = X7R F = X8R	Capacitance Code (In pF) Significant Digits + Number of Zeros e.g. 10µF=106	Capacitance Tolerance *J = $\pm 5\%$ *K = $\pm 10\%$ *M = $\pm 20\%$	Failure Rate 4 = Automotive	Terminations *T = Plated Ni and Sn *Z = FLEXITERM® B = 5% min lead X = FLEXITERM® with 5% min lead *RoHS Compliant	Packaging & Quantity Code 2A = 7" Reel (4000) 4A = 13" Reel (10000) 2F = 7" Reel (1000)

^{*}Contact factory for availability by part number for K = ±10% and J = ±5% tolerance.

KII	20	10	20
NI	PU,		JG

SIZE		W3	3 = 06	12
No. of Elen	nents	Re	flow/Wa	ive
WVDC	;	16	25	50
1R0 Ca	p 1.0			
1R2 (pF				
1R5	1.5			
1R8	1.8			
2R2	2.2			
2R7	2.7			
3R3	3.3			
3R9	3.9			
4R7 5R6	4.7 5.6			
6R8	6.8			
8R2	8.2			
100	10			
120	12			
150	15			
180	18			
220	22			
270	27			
330	33			
390	39			
470	47			
560	56			
680	68			
820	82			
101	100			
121	120			
151	150			
181	180			
221	220			
271	270 330			
331 391	330			
471	470			
561	560			
681	680			
821	820		l	
102	1000			
122	1200		l	
152	1500		l	
182	1800		İ	
222	2200		ĺ	
272	2700			
332	3300			
392	3900			
472	4700			
562	5600			
682	6800			
822	8200			

= NPO/COG

INO.	OI Elettie	1115			_				+				4		
	WVDC		16	25	50	100	16	25	50	100	10	16	25	50	100
101	Cap	100													
121	(pF)	120													
151		150													
181		180													
221		220													
271		270													
331		330													
391		390													
171		470													
561		560													
581		680													
321		820													
102		1000													
122		1200													
152		1500													
182		1800													

W2 = 0508

101 121 151 181 221 331 391 471 561 102 122 152 272 332 392 472 562 681 2200 3900 4700 5600 6800 103 123 153 153 223 Cap 0 010 (μF) 0.012 273 333 393 473 563 0.027 0.039 683 0.068 823 104 124 0.082 0.10 0.12

*Not RoHS Compliant





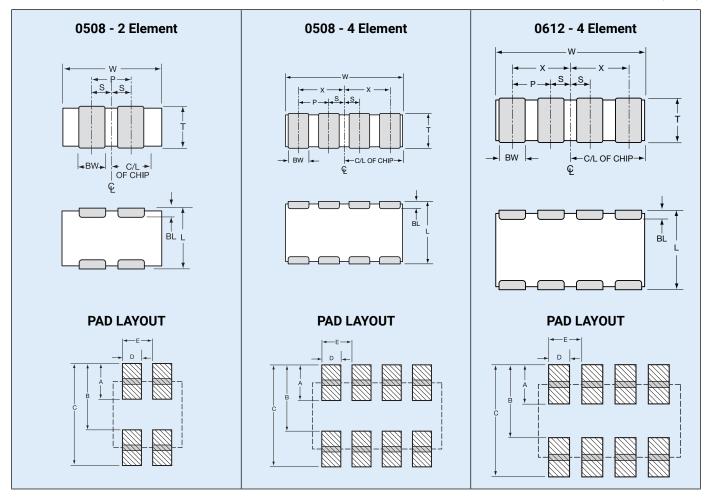
For RoHS compliant products.





PART & PAD LAYOUT DIMENSIONS

millimeters (inches)



PART DIMENSIONS

0508 - 2 Element

L	W	Т	BW	BL	Р	S
1.30 ± 0.15	2.10 ± 0.15	0.94 MAX	0.43 ± 0.10	0.33 ± 0.08	1.00 REF	0.50 ± 0.10
(0.051 ± 0.006)	(0.083 ± 0.006)	(0.037 MAX)	(0.017 ± 0.004)	(0.013 ± 0.003)	(0.039 REF)	(0.020 ± 0.004)

0508 - 4 Element

L	W	T	BW	BL	Р	X	S
1.30 ± 0.15	2.10 ± 0.15	0.94 MAX	0.25 ± 0.06	0.20 ± 0.08	0.50 REF	0.75 ± 0.10	0.25 ± 0.10
(0.051 ± 0.006)	(0.083 ± 0.006)	(0.037 MAX)	(0.010 ± 0.003)	(0.008 ± 0.003)	(0.020 REF)	(0.030 ± 0.004)	(0.010 ± 0.004)

0612 - 4 Element

L	W	Т	BW	BL	Р	Χ	S
1.60 ± 0.20	3.20 ± 0.20	1.35 MAX	0.41 ± 0.10		0.76 REF	1.14 ± 0.10	0.38 ± 0.10
(0.063 ± 0.008)	(0.126 ± 0.008)	(0.053 MAX)	(0.016 ± 0.004)	(0.007 + 0.010) -0.003	(0.030 REF)	(0.045 ± 0.004)	(0.015 ± 0.004)

PAD LAYOUT DIMENSIONS

0508 - 2 Element

Α	В	С	D	E
0.68	1.32	2.00	0.46	1.00
(0.027)	(0.052)	(0.079)	(0.018)	(0.039)

0508 - 4 Element

Α	В	С	D	E
0.56	1.32	1.88	0.30	0.50
(0.022)	(0.052)	(0.074)	(0.012)	(0.020)

0612 - 4 Element

Α	В	С	D	E
0.89	1.65	2.54	0.46	0.76
(0.035)	(0.065)	(0.100)	(0.018)	(0.030)

Low Inductance Capacitors

Introduction



The signal integrity characteristics of a Power Delivery Network (PDN) are becoming critical aspects of board level and semiconductor package designs due to higher operating frequencies, larger power demands, and the ever shrinking lower and upper voltage limits around low operating voltages. These power system challenges are coming from mainstream designs with operating frequencies of 300MHz or greater, modest ICs with power demand of 15 watts or more, and operating voltages below 3 volts.

The classic PDN topology is comprised of a series of capacitor stages. Figure 1 is an example of this architecture with multiple capacitor stages.

An ideal capacitor can transfer all its stored energy to a load instantly. A real capacitor has parasitics that prevent instantaneous transfer of a capacitor's stored energy. The true nature of a capacitor can be modeled as an RLC equivalent circuit. For most simulation purposes, it is possible to model the characteristics of a real capacitor with one capacitor, one resistor, and one inductor. The RLC values in this model are commonly referred to as equivalent series capacitance (ESC), equivalent series resistance (ESR), and equivalent series inductance (ESL).

The ESL of a capacitor determines the speed of energy transfer to a load. The lower the ESL of a capacitor, the faster that energy can be transferred to a load. Historically, there has been a tradeoff between energy storage (capacitance) and inductance (speed of energy delivery). Low ESL devices typically have low capacitance. Likewise, higher capacitance devices typically have higher ESLs. This tradeoff between ESL (speed of energy delivery) and capacitance (energy storage) drives the PDN design topology that places the fastest low ESL capacitors as close to the load as possible. Low Inductance MLCCs are found on semiconductor packages and on boards as close as possible to the load.

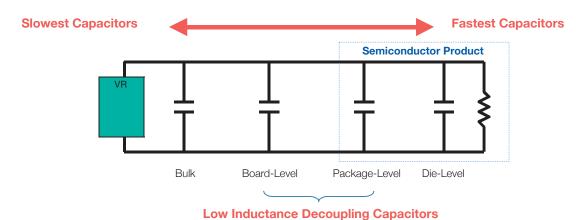


Figure 1 Classic Power Delivery Network (PDN) Architecture

LOW INDUCTANCE CHIP CAPACITORS

The key physical characteristic determining equivalent series inductance (ESL) of a capacitor is the size of the current loop it creates. The smaller the current loop, the lower the ESL. A standard surface mount MLCC is rectangular in shape with electrical terminations on its shorter sides. A Low Inductance Chip Capacitor (LICC) sometimes referred to as Reverse Geometry Capacitor (RGC) has its terminations on the longer side of its rectangular shape.

When the distance between terminations is reduced, the size of the current loop is reduced. Since the size of the current loop is the primary driver of inductance, an 0306 with a smaller current loop has significantly lower ESL then an 0603. The reduction in ESL varies by EIA size, however, ESL is typically reduced 60% or more with an LICC versus a standard MLCC.

INTERDIGITATED CAPACITORS

The size of a current loop has the greatest impact on the ESL characteristics of a surface mount capacitor. There is a secondary method for decreasing the ESL of a capacitor. This secondary method uses adjacent opposing current loops to reduce ESL. The InterDigitated Capacitor (IDC) utilizes both primary and secondary methods of reducing inductance. The IDC architecture shrinks the distance between terminations to minimize the current loop size, then further reduces inductance by creating adjacent opposing current loops.

An IDC is one single capacitor with an internal structure that has been optimized for low ESL. Similar to standard MLCC versus LICCs, the reduction in ESL varies by EIA case size. Typically, for the same EIA size, an IDC delivers an ESL that is at least 80% lower than an MLCC.

Low Inductance Capacitors

Introduction



LAND GRID ARRAY (LGA) CAPACITORS

Land Grid Array (LGA) capacitors are based on the first Low ESL MLCC technology created to specifically address the design needs of current day Power Delivery Networks (PDNs). This is the 3rd low inductance capacitor technology developed by KYOCERA AVX. LGA technology provides engineers with new options. The LGA internal structure and manufacturing technology eliminates the historic need for a device to be physically small to create small current loops to minimize inductance.

The first family of LGA products are 2 terminal devices. A 2 terminal 0306 LGA delivers ESL performance that is equal to or better than an 0306 8 terminal IDC. The 2 terminal 0805 LGA delivers ESL performance that approaches the 0508 8 terminal IDC. New designs that would have used 8 terminal IDCs are moving to 2 terminal LGAs because the layout is easier for a 2 terminal device and manufacturing yield is better for a 2 terminal LGA versus an 8 terminal IDC.

LGA technology is also used in a 4 terminal family of products that KYOCERA AVX is sampling and will formerly introduce in 2008. Beyond 2008, there are new multi-terminal LGA product families that will provide even more attractive options for PDN designers.

LOW INDUCTANCE CHIP ARRAYS (LICA®)

The LICA® product family is the result of a joint development effort between KYOCERA AVX and IBM to develop a high performance MLCC family of decoupling capacitors. LICA was introduced in the 1980s and remains the leading choice of designers in high performance semiconductor packages and high reliability board level decoupling applications.

LICA® products are used in 99.999% uptime semiconductor package applications on both ceramic and organic substrates. The C4 solder ball termination option is the perfect compliment to flip-chip packaging technology. Mainframe class CPUs, ultimate performance multi-chip modules, and communications systems that must have the reliability of 5 9's use LICA®.

LICA® products with either Sn/Pb or Pb-free solder balls are used for decoupling in high reliability military and aerospace applications. These LICA® devices are used for decoupling of large pin count FPGAs, ASICs, CPUs, and other high power ICs with low operating voltages.

When high reliability decoupling applications require the very lowest ESL capacitors, LICA® products are the best option.

470 nF 0306 Impedance Comparison

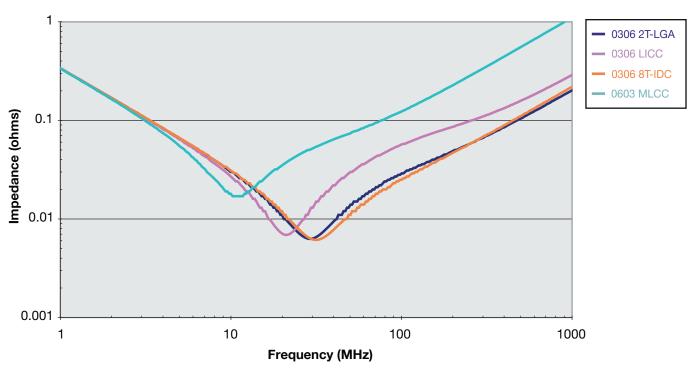


Figure 2 MLCC, LICC, IDC, and LGA technologies deliver different levels of equivalent series inductance (ESL).

Low Inductance Ceramic Capacitors



LICC (Low Inductance Chip Capacitors) 0306/0508/0612 RoHS Compliant

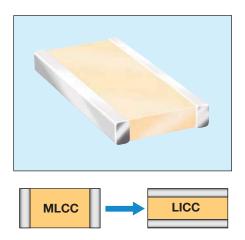
GENERAL DESCRIPTION

The key physical characteristic determining equivalent series inductance (ESL) of a capacitor is the size of the current loop it creates. The smaller the current loop, the lower the ESL.

A standard surface mount MLCC is rectangular in shape with electrical terminations on its shorter sides. A Low Inductance Chip Capacitor (LICC) sometimes referred to as Reverse Geometry Capacitor (RGC) has its terminations on the longer sides of its rectangular shape. The image on the right shows the termination differences between an MLCC and an LICC.

When the distance between terminations is reduced, the size of the current loop is reduced. Since the size of the current loop is the primary driver of inductance, an 0306 with a smaller current loop has significantly lower ESL then an 0603. The reduction in ESL varies by EIA size, however, ESL is typically reduced 60% or more with an LICC versus a standard MLCC.

KYOCERA AVX LICC products are available with a lead-free finish of plated Nickel/Tin.

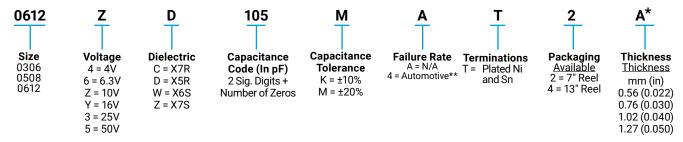


PERFORMANCE CHARACTERISTICS

Capacitance Tolerances	K = ±10%; M = ±20%
Operation Temperature Range	X7R = -55°C to +125°C X5R = -55°C to +85°C X7S = -55°C to +125°C
Temperature Coefficient	X7R, X5R = ±15%; X7S = ±22%
Voltage Ratings	4, 6.3, 10, 16, 25 VDC
Dissipation Factor	4V, 6.3V = 6.5% max; 10V = 5.0% max; 16V = 3.5% max; 25V = 3.0% max
Insulation Resistance (@+25°C, RVDC)	100,000MΩ min, or 1,000MΩ per μF min.,whichever is less



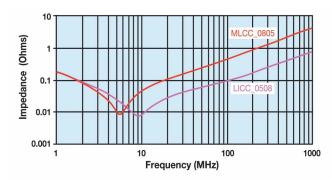
HOW TO ORDER

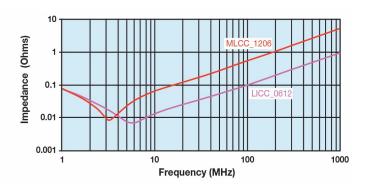


^{*}See the thickness tables on the next page.

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

TYPICAL IMPEDANCE CHARACTERISTICS







^{**}Select voltages for Automotive version, contact factory

Low Inductance Ceramic Capacitors



LICC (Low Inductance Chip Capacitors) 0306/0508/0612 RoHS Compliant

			0306	5			(0508	3			0612				
Pac	kaging		Embossed			Embossed				Embossed						
Length	mm		0.81 + 0.15				1.27 + 0.25				1.60 + 0.25 (0.063 ± 0.010)					
	(in.)			32 ± 0. 50 + 0.					50 ± 0.					3 ± 0 20 + 0		
Width	mm (in.)			50 + 0. 53 ± 0.					30 ± 0.					20 + 0 26 ± 0		
Cap Code	WVDC	4	6.3	10	16	25	6.3	10	16	25	50	6.3	10	16	25	50
102	Cap 0.001		Α	Α	Α	Α	٧	V	V	٧	V	S	S	S	S	٧
222	(μF) .0022		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
332	0.0033		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
472	0.0047		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
682	0.0068		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
103	0.01		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧
153	0.015		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	W
223	0.022		Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	W
333	0.033		Α	Α	Α		S	S	S	٧	٧	S	S	S	S	W
473	0.047		Α	Α	Α		S	S	S	٧	Α	S	S	S	S	W
683	0.068		Α	Α	Α		S	S	S	Α	Α	S	S	S	٧	W
104	0.1		Α	Α	1		S	S	٧	Α	Α	S	S	S	٧	W
154	0.15		Α	Α			S	S	٧			S	S	S	W	W
224	0.22		Α	Α			S	S	Α			S	S	٧	W	
334	0.33						٧	٧	Α			S	S	٧		
474	0.47						٧	٧	/N/			S	S	٧		
684	0.68						Α	Α				V	٧	W		
105	1	A					Α	Α				V	٧	Α		
155	1.5						//					W	W			
225	2.2											Α	Α			
335	3.3											//				
475	4.7															
685	6.8															
106	10															

Solid = X7R





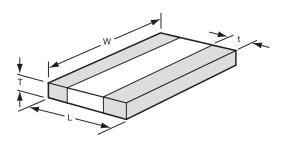


	mm (in.)
	0306
Code	Thickness
Α	0.56 (0.022)

	mm (in.)
	0508
Code	Thickness
S	0.56 (0.022)
V	0.76 (0.030)
Α	1.02 (0.040)

	mm (in.)					
0612						
Code	Thickness					
S	0.56 (0.022)					
V	0.76 (0.030)					
W	1.02 (0.040)					
Α	1.27 (0.050)					

PHYSICAL DIMENSIONS AND PAD LAYOUT



PHYSICAL DIMENSIONS

MM (IN.)

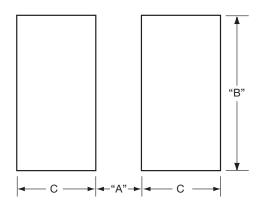
Size	L	W	t
0306	0.81 ± 0.15	1.60 ± 0.15	0.13 min.
0306	(0.032 ± 0.006)	(0.063 ± 0.006)	(0.005 min.)
0508	1.27 ± 0.25	2.00 ± 0.25	0.13 min.
0306	(0.050 ± 0.010)	(0.080 ± 0.010)	(0.005 min.)
0612	1.60 ± 0.25	3.20 ± 0.25	0.13 min.
0012	(0.063 ± 0.010)	(0.126 ± 0.010)	(0.005 min.)

T - See Range Chart for Thickness and Codes

PAD LAYOUT DIMENSIONS

MM (IN.)

Size	Α	В	С
0306	0.31 (0.012)	1.52 (0.060)	0.51 (0.020)
0508	0.51 (0.020)	2.03 (0.080)	0.76 (0.030)
0612	0.76 (0.030)	3.05 (0.120)	0.635 (0.025)



Low Inductance Capacitors with SnPb Terminations





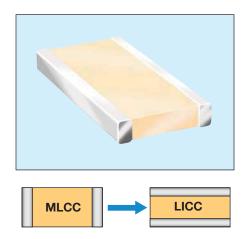
GENERAL DESCRIPTION

The key physical characteristic determining equivalent series inductance (ESL) of a capacitor is the size of the current loop it creates. The smaller the current loop, the lower the ESL.

A standard surface mount MLCC is rectangular in shape with electrical terminations on its shorter sides. A Low Inductance Chip Capacitor (LICC) sometimes referred to as Reverse Geometry Capacitor (RGC) has its terminations on the longer sides of its rectangular shape. The image on the right shows the termination differences between an MLCC and an LICC.

When the distance between terminations is reduced, the size of the current loop is reduced. Since the size of the current loop is the primary driver of inductance, an 0306 with a smaller current loop has significantly lower ESL then an 0603. The reduction in ESL varies by EIA size, however, ESL is typically reduced 60% or more with an LICC versus a standard MLCC.

AVX LICC products are available with a lead termination for high reliability military and aerospace applications that must avoid tin whisker reliability



PERFORMANCE CHARACTERISTICS

Capacitance Tolerances	K = ±10%; M = ±20%
Operation Temperature Range	X7R = -55°C to +125°C X5R = -55°C to +85°C X7S = -55°C to +125°C
Temperature Coefficient	X7R, X5R = ±15%; X7S = ±22%
Voltage Ratings	4, 6.3, 10, 16, 25 VDC
Dissipation Factor	4V, 6.3V = 6.5% max; 10V = 5.0% max; 16V = 3.5% max; 25V = 3.0% max
Insulation Resistance (@+25°C, RVDC)	100,000MΩ min, or 1,000MΩ per μF min.,whichever is less

*Not RoHS Compliant

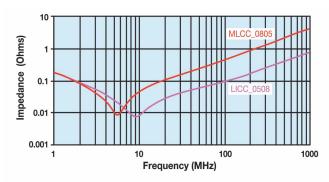
HOW TO ORDER

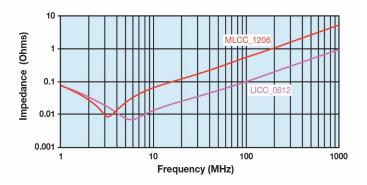


*See the thickness tables on the next page.

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

TYPICAL IMPEDANCE CHARACTERISTICS







Low Inductance Capacitors with SnPb Terminations



LD16/LD17/LD18 Tin-Lead Termination "B"

	SIZE	LD16 (0306) Embossed				LD17 (0508)					LD18 (0612)					
	ckaging mm		0.81 ±				Embossed 1.27 ± 0.25					Embossed 1.60 ± 0.25				
Length	(in.)	(0.032 ±		5)			50 ± 0					53 ± 0.			
Width	mm (in.)	(1.60±		5)			00 ± 0. 30 ± 0.					20 ± 0. 26 ± 0.			
Cap Code	WVDC	6.3	10	16	25	6.3	10	16	25	50	6.3	10	16	25	50	
102	Cap 0.001	Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧	
222	(μF) .0022	Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧	
332	0.0033	Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧	
472	0.0047	Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧	
682	0.0068	Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧	
103	0.01	Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	٧	
153	0.015	Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	W	
223	0.022	Α	Α	Α	Α	S	S	S	S	٧	S	S	S	S	W	
333	0.033	Α	Α	Α		S	S	S	٧	٧	S	S	S	S	W	
473	0.047	Α	Α	Α		S	S	S	٧	Α	S	S	S	S	W	
683	0.068	Α	Α	Α		S	S	S	Α	Α	S	S	S	٧	W	
104	0.1	Α	Α	/N/		S	S	٧	Α	Α	S	S	S	٧	W	
154	0.15	Α	Α			S	S	٧			S	S	S	W	W	
224	0.22	Α	Α			S	S	Α			S	S	٧	W		
334	0.33					٧	٧	Α			S	S	٧			
474	0.47					٧	٧	///			S	S	٧			
684	0.68					Α	Α				V	٧	W			
105	1					Α	Α				V	٧	Α			
155	1.5										W	W				
225	2.2										Α	Α				
335	3.3										//					
475	4.7															
685	6.8															
106	10															

Solid = X7R



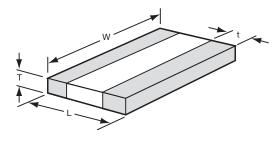


mm (in.)						
LD16						
((0306)					
ode	Thickness					
Α	0.56 (0.022)					

mm (in.)					
	LD17				
((0508)				
Code	Thickness				
S	0.56 (0.022)				
V	0.76 (0.030)				
Α	1.02 (0.040)				

	mm (in.)					
	LD18					
((0612)					
Code	Thickness					
S	0.56 (0.022)					
V	0.76 (0.030)					
W	1.02 (0.040)					
Α	1.27 (0.050)					

PHYSICAL DIMENSIONS AND **PAD LAYOUT**



PHYSICAL DIMENSIONS

MM (IN.)

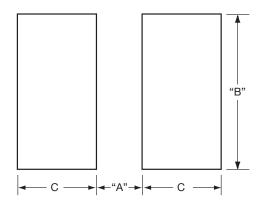
Size	L	W	t
LD16	0.81 ± 0.15	1.60 ± 0.15	0.13 min.
(0306)	(0.032 ± 0.006)	(0.063 ± 0.006)	(0.005 min.)
LD17	1.27 ± 0.25	2.00 ± 0.25	0.13 min.
(0508)	(0.050 ± 0.010)	(0.080 ± 0.010)	(0.005 min.)
LD18	1.60 ± 0.25	3.20 ± 0.25	0.13 min.
(0612)	(0.063 ± 0.010)	(0.126 ± 0.010)	(0.005 min.)

T - See Range Chart for Thickness and Codes

PAD LAYOUT DIMENSIONS

MM (IN.)

			· · · · · · · · · · · · · · · · · · ·				
Size	Α	В	С				
LD16 (0306)	0.31 (0.012)	1.52 (0.060)	0.51 (0.020)				
LD17 (0508)	0.51 (0.020)	2.03 (0.080)	0.76 (0.030)				
LD18 (0612)	0.76 (0.030)	3.05 (0.120)	0.635 (0.025)				



IDC Low Inductance Capacitors (RoHS)

IDC (InterDigitated Capacitors) 0306/0612/0508



GENERAL DESCRIPTION

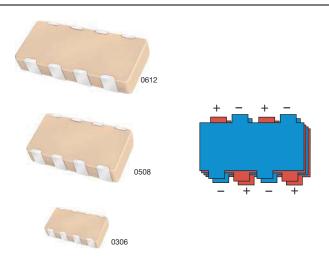
Inter-Digitated Capacitors (IDCs) are used for both semiconductor package and board level decoupling. The equivalent series inductance (ESL) of a single capacitor or an array of capacitors in parallel determines the response time of a Power Delivery Network (PDN). The lower the ESL of a PDN, the faster the response time. A designer can use many standard MLCCs in parallel to reduce ESL or a low ESL Inter-Digitated Capacitor (IDC) device. These IDC devices are available in versions with a maximum height of 0.95mm or 0.55mm.

IDCs are typically used on packages of semiconductor products with power levels of 15 watts or greater. Inter-Digitated Capacitors are used on CPU, GPU, ASIC, and ASSP devices produced on 0.13µ, 90nm, 65nm, and 45nm processes. IDC devices are used on both ceramic and organic package substrates. These low ESL surface mount capacitors can be placed on the bottom side or the top side of a package substrate. The low profile 0.55mm maximum height IDCs can easily be used on the bottom side of BGA packages or on the die side of packages under a heat spreader.

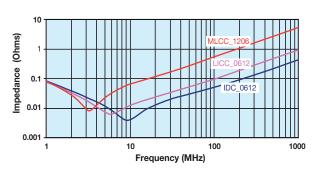
IDCs are used for board level decoupling of systems with speeds of 300MHz or greater. Low ESL IDCs free up valuable board space by reducing the number of capacitors required versus standard MLCCs. There are additional benefits to reducing the number of capacitors beyond saving board space including higher reliability from a reduction in the number of components and lower placement costs based on the need for fewer capacitors.

The Inter-Digitated Capacitor (IDC) technology was developed by KYOCERA AVX. This is the second family of Low Inductance MLCC products created by KYOCERA AVX. IDCs are a cost effective alternative to KYOCERA AVX's first generation low ESL family for high-reliability applications known as LICA (Low Inductance Chip Array).

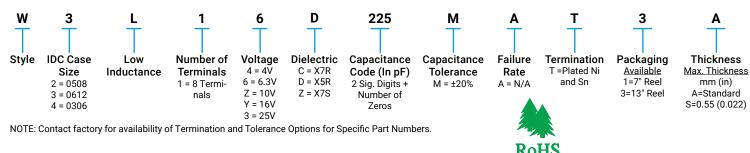
KYOCERA AVX IDC products are available with a lead-free finish of plated Nickel/ Tin.



TYPICAL IMPEDANCE



HOW TO ORDER



PERFORMANCE CHARACTERISTICS

Capacitance Tolerance	±20% Preferred
Operation Temperature Range	X7R = -55°C to +125°C X5R = -55°C to +85°C X7S = -55°C to +125°C
Temperature Coefficient	±15% (0VDC), ±22% (X7S)
Voltage Ratings	4, 6.3, 10, 16, 25 VDC
Dissipation Factor	≤ 6.3V = 6.5% max; 10V = 5.0% max; ≥ 16V = 3.5% max
Insulation Resistance (@+25°C, RVDC)	100,000MΩ min, or 1,000MΩ per μ F min.,whichever is less

Dissipation Factor	No problems observed after 2.5 x RVDC for 5 seconds at 50mA max current
CTE (ppm/C)	12.0
Thermal Conductivity	4-5W/M K
Terminations Available	Plated Nickel and Solder

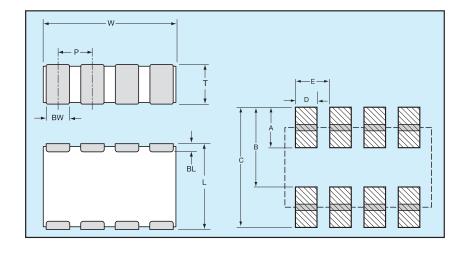
IDC Low Inductance Capacitors (RoHS)



IDC (InterDigitated Capacitors) 0306/0612/0508

SIZE	W4 =	0306	W2 = Thin 0508						W2	2 = 05	80		W	3= Tł	nin 06	12		W3	3 = 06	512		W3	= TH	ICK 0	612
Max. mm	0.	55			0.55.			0.95					0.55			0.95				1.22					
Thickness (in.)	(0.0	122)		(0.022	2)		(0.037)						(0.0	022)		(0.037)				(0.048)				
WVDC	4	6.3	4	6.3	10	16	25	4	6.3	10	16	25	4	6.3	10	16	4	6.3	10	16	25	4	6.3	10	16
Cap (µF) 0.010																									
0.022																									
0.033																									
0.047																									
0.068																									
0.10																									
0.22																									
0.33																									
0.47																									
0.68																									
1.0																									
1.5																									
2.2																									
3.3																									

PHYSICAL DIMENSIONS AND PAD LAYOUT



Consult factory for additional requirements



PHYSICAL CHIP DIMENSIONS

MILLIMETERS (INCHES)

SIZE	W	L	BW	BL	P
0206	1.60 ± 0.20	0.82 ± 0.10	0.25 ± 0.10	0.20 ± 0.10	0.40 ± 0.05
0306	(0.063 ± 0.008)	(0.032 ± 0.006)	(0.010 ± 0.004)	(0.008± 0.004)	(0.015 ± 0.002)
0508	2.03 ± 0.20	1.27 ± 0.20	0.30 ± 0.10	0.25 ± 0.15	0.50 ± 0.05
0306	(0.080 ± 0.008)	(0.050 ± 0.008)	(0.012 ± 0.004)	(0.010± 0.006)	(0.020 ± 0.002)
0612	3.20 ± 0.20	1.60 ± 0.20	0.50 ± 0.10	0.25 ± 0.15	0.80 ± 0.10
0012	(0.126 ± 0.008)	(0.063 ± 0.008)	(0.020 ± 0.004)	(0.010 ± 0.006)	(0.031 ± 0.004)

PAD LAYOUT DI-MENSIONS

SIZE	Α	В	С	D	E
0306	0.38	0.89	1.27	0.20	0.40
	(0.015)	(0.035)	(0.050)	(0.008)	(0.015)
0508	0.64	1.27	1.91	0.28	0.50
	(0.025)	(0.050)	(0.075)	(0.011)	(0.020)
0612	0.89	1.65	2.54	0.45	0.80
	(0.035)	(0.065)	(0.010)	(0.018)	(0.031)

IDC Low Inductance Capacitors (SnPb)

IDC (InterDigitated Capacitors) 0306/0612/0508



GENERAL DESCRIPTION

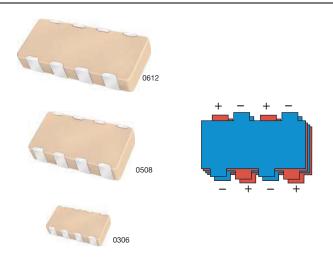
Inter-Digitated Capacitors (IDCs) are used for both semiconductor package and board level decoupling. The equivalent series inductance (ESL) of a single capacitor or an array of capacitors in parallel determines the response time of a Power Delivery Network (PDN). The lower the ESL of a PDN, the faster the response time. A designer can use many standard MLCCs in parallel to reduce ESL or a low ESL Inter-Digitated Capacitor (IDC) device. These IDC devices are available in versions with a maximum height of 0.95mm or 0.55mm.

IDCs are typically used on packages of semiconductor products with power levels of 15 watts or greater. Inter-Digitated Capacitors are used on CPU, GPU, ASIC, and ASSP devices produced on 0.13µ, 90nm, 65nm, and 45nm processes. IDC devices are used on both ceramic and organic package substrates. These low ESL surface mount capacitors can be placed on the bottom side or the top side of a package substrate. The low profile 0.55mm maximum height IDCs can easily be used on the bottom side of BGA packages or on the die side of packages under a heat spreader.

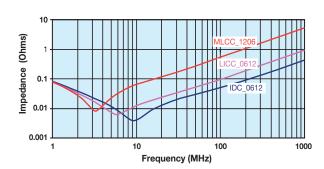
IDCs are used for board level decoupling of systems with speeds of 300MHz or greater. Low ESL IDCs free up valuable board space by reducing the number of capacitors required versus standard MLCCs. There are additional benefits to reducing the number of capacitors beyond saving board space including higher reliability from a reduction in the number of components and lower placement costs based on the need for fewer capacitors.

The Inter-Digitated Capacitor (IDC) technology was developed by KYOCERA AVX. This is the second family of Low Inductance MLCC products created by KYOCERA AVX. IDCs are a cost effective alternative to KYOCERA AVX's first generation low ESL family for high-reliability applications known as LICA (Low Inductance Chip Array).

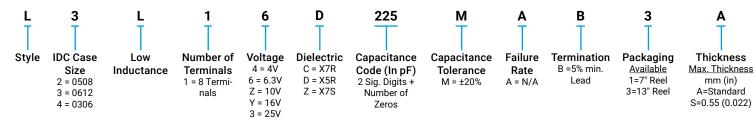
KYOCERA AVX IDC products are available with a lead termination for high reliability military and aerospace applications that must avoid tin whisker reliability issues.



TYPICAL IMPEDANCE



HOW TO ORDER



NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

Not RoHS Compliant

PERFORMANCE CHARACTERISTICS

Capacitance Tolerance	±20% Preferred
Operation Temperature Range	X7R = -55°C to +125°C X5R = -55°C to +85°C X7S = -55°C to +125°C
Temperature Coefficient	±15% (0VDC), ±22% (X7S)
Voltage Ratings	4, 6.3, 10, 16, 25 VDC
Dissipation Factor	≤ 6.3V = 6.5% max; 10V = 5.0% max; ≥ 16V = 3.5% max
Insulation Resistance (@+25°C, RVDC)	100,000MΩ min, or 1,000MΩ per μF min.,whichever is less

Dissipation Factor	5 seconds at 50mA max current
CTE (ppm/C)	12.0
Thermal Conductivity	4-5W/M K
Terminations Available	Plated Nickel and Solder

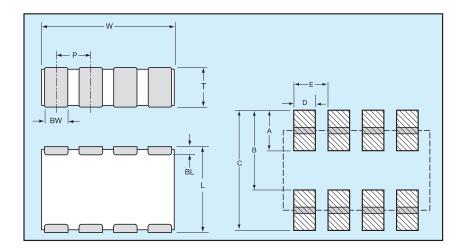
IDC Low Inductance Capacitors (SnPb)



IDC (InterDigitated Capacitors) with Sn/Pb Termination 0306/0612/0508

SIZE	W4 =	0306		W2 =	Thin	0508	3		W2	2 = 05	808		W	3= Tł	nin 06	12		W3	3 = 06	512		W3	= TH	ICK 0	612
Max. mm					0.55.					0.95					.55			0.95					1.:		
Thickness (in.)					(0.022					(0.037)		1			022)				(0.037			(0.048)			
WVDC	4	6.3	4	6.3	10	16	25	4	6.3	10	16	25	4	6.3	10	16	4	6.3	10	16	25	4	6.3	10	16
Cap (μF) 0.010																									
0.022																									
0.033																									
0.047																									
0.068																									
0.10																									
0.22																									
0.33																									
0.47																									
0.68																									
1.0																									
1.5																									
2.2																									
3.3																									

PHYSICAL DIMENSIONS AND PAD LAYOUT



Consult factory for additional requirements



PHYSICAL CHIP DIMENSIONS

MILLIMETERS (INCHES)

SIZE	W	L	BW	BL	Р
0206	1.60 ± 0.20	0.82 ± 0.10	0.25 ± 0.10	0.20 ± 0.10	0.40 ± 0.05
0306	(0.063 ± 0.008)	(0.032 ± 0.006)	(0.010 ± 0.004)	(0.008± 0.004)	(0.015 ± 0.002)
OFOO	2.03 ± 0.20	1.27 ± 0.20	0.30 ± 0.10	0.25 ± 0.15	0.50 ± 0.05
0508	(0.080 ± 0.008)	(0.050 ± 0.008)	(0.012 ± 0.004)	(0.010± 0.006)	(0.020 ± 0.002)
0612	3.20 ± 0.20	1.60 ± 0.20	0.50 ± 0.10	0.25 ± 0.15	0.80 ± 0.10
0012	(0.126 ± 0.008)	(0.063 ± 0.008)	(0.020 ± 0.004)	(0.010 ± 0.006)	(0.031 ± 0.004)

PAD LAYOUT DI-MENSIONS

SIZE	Α	В	С	D	Е
0306	0.38	0.89	1.27	0.20	0.40
	(0.015)	(0.035)	(0.050)	(0.008)	(0.015)
0508	0.64	1.27	1.91	0.28	0.50
	(0.025)	(0.050)	(0.075)	(0.011)	(0.020)
0612	0.89	1.65	2.54	0.45	0.80
	(0.035)	(0.065)	(0.010)	(0.018)	(0.031)

LGA Low Inductance Capacitors

0204/0306 Land Grid Array





Land Grid Array (LGA) capacitors are the latest family of low inductance MLCCs from KYOCERA AVX. These new LGA products are the third low inductance family developed by KYOCERA AVX. The innovative LGA technology sets a new standard for low inductance MLCC performance.

Our initial 2 terminal versions of LGA technology deliver the performance of an 8 terminal IDC low inductance MLCC with a number of advantages including:

- Simplified layout of 2 large solder pads compared to 8 small pads for IDCs
- Opportunity to reduce PCB or substrate contribution to system ESL by using multiple parallel vias in solder pads
- Advanced FCT manufacturing process used to create uniformly flat terminations on the capacitor that resist "tombstoning"
- Better solder joint reliability

APPLICATIONS

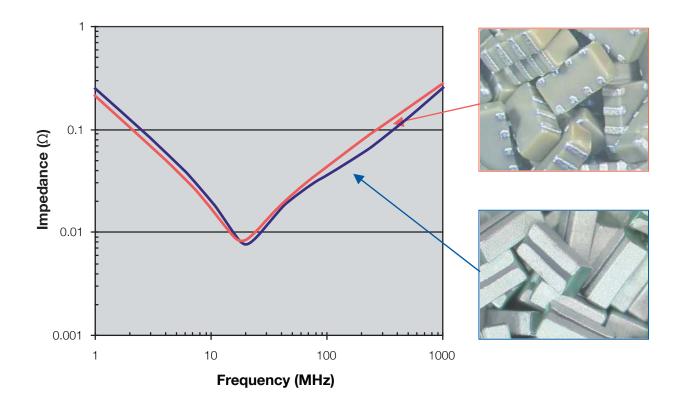
Semiconductor Packages

- · Microprocessors/CPUs
- Graphics Processors/GPUs
- Chipsets
- **FPGAs**
- **ASICs**

Board Level Device Decoupling

- · Frequencies of 300 MHz or more
- · ICs drawing 15W or more
- · Low voltages
- · High speed buses

0306 2 TERMINAL LGA COMPARISON WITH 0306 8 TERMINAL IDC



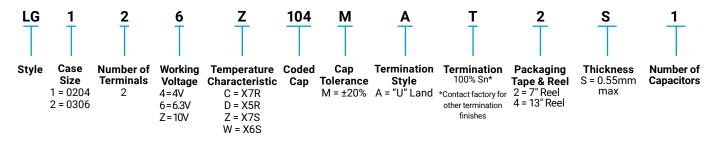
LGA Low Inductance Capacitors

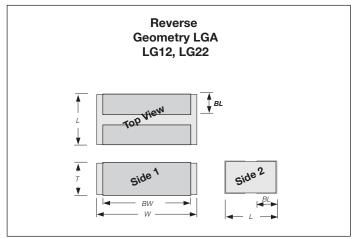




SIZE	SIZE LG12 (LG2	2 (03	306)			
Length mm (in.)			0.50 (0	0.020)				0.76 (0.030)							
Width mm (in.)			1.00 (0	0.039)						1.6	0.0)	63)			
Temp. Char.	X5R	(D)	X78	S (Z)	X6S	(W)	Х	7R (C	:)	X5R	(D)	X7S	(Z)	X6S	(W)
Working Voltage	6.3	4	6.3	4	6.3	4	10	6.3	4	6.3	4	6.3	4	6.3	4
	(6)	(4)	(6)	(4)	(6)	(4)	(Z)	(6)	(4)	(6)	(4)	(6)	(4)	(6)	(4)
Cap (µF) 0.010 (103)															
0.022 (223)															
0.047 (473)															
0.100 (104)															
0.220 (224)															
0.330 (334)															
0.470 (474)															
1.000 (105)															
2.200 (225)															
		= X7	R		= X5	R		= X7	S		= X6	S			

HOW TO ORDER





PART DIMENSIONS

MM (INCHES)

Series	L	w	Т	BW	BL
LG12 (0204)	0.5 ± 0.05	1.00 ± 0.10	0.50 ± 0.05	0.8 ± 0.10	0.13 ± 0.08
	(0.020±0.002)	(0.039 ± 0.004)	(0.020 ± 0.002)	(0.031 ± 0.004)	(0.005 ± 0.003)
LG22 (0306)	0.76 ± 0.10	1.60 ± 0.10	0.50 ± 0.05	1.50 ±0.10	0.28 ± 0.08
	(0.030 ± 0.004)	(0.063 ± 0.004)	(0.020 ± 0.002)	(0.059 ± 0.004)	(0.011 ± 0.003)



RECOMMENDED SOLDER PAD DIMENSIONS

PAD DIMENSIONS	MM (INCHES)



Series	PL	PW1	G
LG12 (0204)	0.50 (0.020)	1.00 (0.039)	0.20 (0.008)
LG22 (0306)	0.65 (0.026)	1.50 (0.059)	0.20 (0.008)

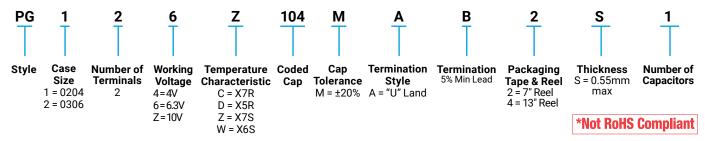
LGA Low Inductance Capacitors

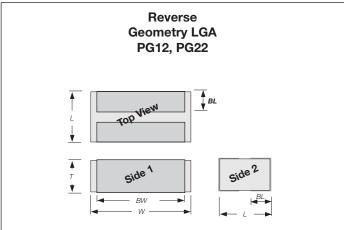


0204/0306 Land Grid Array - Tin/Lead Termination "B"

SIZE		PG12 (0204)								PG2	2 (03	306)			
Length mm (in.)			0.50 (0.020))					0.7	6 (0.0	30)			
Width mm (in.)			1.00 (0.039))					1.6	1.60 (0.063)				
Temp. Char.	X5F	(D)	X78	(Z)	X6S	(W)	Х	7R (C)	X5R	(D)	X7S	(Z)	X6S	(W)
Working Voltage	6.3	4	6.3	4	6.3	4	10	6.3	4	6.3	4	6.3	4	6.3	4
	(6)	(4)	(6)	(4)	(6)	(4)	(Z)	(6)	(4)	(6)	(4)	(6)	(4)	(6)	(4)
Cap (µF) 0.010 (103)															
0.022 (223)															
0.047 (473)															
0.100 (104)															
0.220 (224)															
0.330 (334)															
0.470 (474)															
1.000 (105)															
2.200 (225)															
		= X7	R		= X5	R		= X7	S		= X6	S			

HOW TO ORDER





PART DIMENSIONS

MM (INCHES)

Series	L	W	Т	BW	BL
PG12 (0204)	0.5 ± 0.05	1.00 ± 0.10	0.50 ± 0.05	0.8 ± 0.10	0.13 ± 0.08
	(0.020±0.002)	(0.039 ± 0.004)	(0.020 ± 0.002)	(0.031 ± 0.004)	(0.005 ± 0.003)
PG22 (0306)	0.76 ± 0.10	1.60 ± 0.10	0.50 ± 0.05	1.50 ±0.10	0.28 ± 0.08
	(0.030 ± 0.004)	(0.063 ± 0.004)	(0.020 ± 0.002)	(0.059 ± 0.004)	(0.011 ± 0.003)

RECOMMENDED SOLDER PAD DIMENSIONS

MM (INCHES)



Series	PL	PW1	G
PG12 (0204)	0.50 (0.020)	1.00 (0.039)	0.20 (0.008)
PG22 (0306)	0.65 (0.026)	1.50 (0.059)	0.20 (0.008)

AT Series - 200°C & 250°C Rated





Present military specifications, as well as a majority of commercial applications, require a maximum operating temperature of 125°C. However, the emerging market for high temperature electronics demands capacitors operating reliably at temperatures beyond 125°C. KYOCERA AVX's high temperature chip capacitor product line, has been extended with the BME COG chip. All AT chips have verified capabilities of long term operation up to 250°C for applications in both military and commercial businesses. These capacitors demonstrate high volumetric efficiency, high insulation resistance and low ESR/ESL for the most demanding applications, such as "down-hole" oil exploration and aerospace programs.

HOW TO ORDER

AT10	3	Т	104	K	Α	Т	2	Α
	T	T	\top	T	T	Τ	Т	Т
Style	Voltage	Temperature	Capacitance Code	Capacitance	Test Level	Termination	Packaging	Special
AT03 = 0603	Code	Coefficient	(2 significant digits	Tolerance	A = Standard	1 = Pd/Ag	2 = 7" Reel	Code
AT05 = 0805	16V = Y	PME	+ no. of zeros)	$J = \pm 5\%$		T = 100% Sn Plated	4 = 13" Reel	A = Standard
AT06 = 1206	25V = 3	C0G 250°C = A	101 = 100pF	$K = \pm 10\%$		(RoHS Compliant)	9 = Bulk	
AT10 = 1210	50V = 5	COG 200°C = 2	102 = 1nF	$M = \pm 20\%$		7 = Ni/Au Plated		
AT12 = 1812		VHT 250°C = T	103 = 10nF			(For 250°C BME		
AT14 = 2225		VHT 200°C = 4	104 = 100nF			COG Only)		
		BME	105 = 1μF			• •		
		C0G 250°C = 5	·					
		COG 200°C = 3						

ELECTRICAL SPECIFICATIONS

Temperature Coefficient

PME COG 0±30ppm/°C, -55C to 250°C BME COG 0±30ppm/°C, -55C to 200°C

See TCC Plot for +250°C

VHT: T ±15%, -55°C to +150°C See TCC Plot for +250°C

Capacitance Test (MIL-STD-202, Method 305) 25°C, 1.0 ± 0.2 Vrms (open circuit voltage) @ 1kHz

Dissipation factor 25°C

COG: 0.15% Max at 1.0 ± 0.2 Vrms (open circuit voltage) @ 1kHz VHT: 2.5% Max at 1.0 ± 0.2 Vrms (open circuit voltage) @ 1kHz

Insulation Resistance 25°C (MIL-STD-202, Method 302)

100GΩ or 1000MΩ- μ F (whichever is less)

Insulation Resistance 125°C (MIL-STD-202, Method 302) $10G\Omega$ or $100M\Omega$ - μ F (whichever is less)

Insulation Resistance 200°C (MIL-STD-202, Method 302) 1GΩ or 10MΩ- μ F (whichever is less)

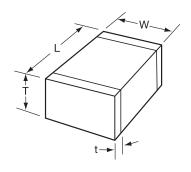
Insulation Resistance 250°C (MIL-STD-202, Method 302) 100M Ω or 1M Ω -uF (whichever is less)

Direct Withstanding Voltage 25°C (Flash Test)

250% rated voltage for 5 seconds with 50mA max charging current

DIMENSIONS:

MILLIMETERS (INCHES)



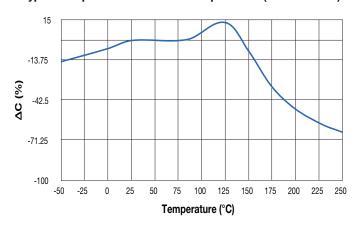
Size		AT03 = 0603	AT05= 0805	AT06=1206	AT10=1210	AT12=1812	AT14=2225
(L) Length		1.60 ± 0.15	2.01 ± 0.20	3.20 ± 0.20	3.20 ± 0.20	4.50 ± 0.30	5.72 ± 0.25
(L) Lengui		(0.063 ± 0.006)	(0.079 ± 0.008)	(0.126 ± 0.008)	(0.126 ± 0.008)	(0.177 ± 0.012)	(0.225 ± 0.010)
(W) Width		0.81 ± 0.15	1.25 ± 0.20	1.60 ± 0.20	2.50 ± 0.20	3.20 ± 0.20	6.35 ± 0.25
(vv) vviatri		(0.032 ± 0.006)	(0.049 ± 0.008)	(0.063 ± 0.008)	(0.098 ± 0.008)	(0.126 ± 0.008)	(0.250 ± 0.010)
(T) Thickness N	104	1.02	1.30	1.52	1.70	2.54	2.54
(T) Thickness Max.		(0.040)	(0.051)	(0.060)	(0.067)	(0.100)	(0.100)
(t) m	in.	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)
terminal m	ax.	0.75 (0.030)	0.75 (0.030)	0.75 (0.030)	0.75 (0.030)	1.02 (0.040)	1.02 (0.040)

AT Series - 200°C & 250°C Rated

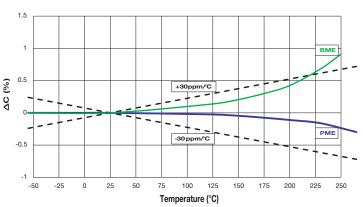


PERFORMANCE CHARACTERISTICS

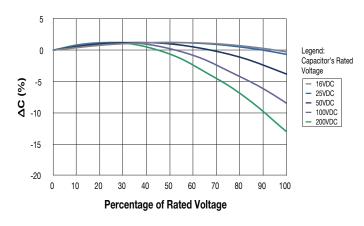
Typical Temperature Coefficient of Capacitance (VHT Dielectric)



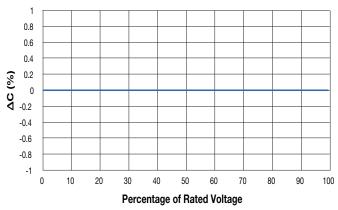
Typical Temperature Coefficient of Capacitance (COG Dielectric)



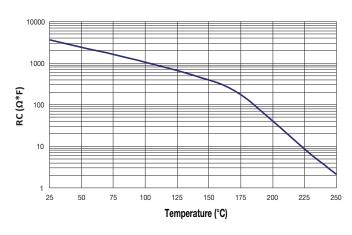
Typical Voltage Coefficient of Capacitance (VHT Dielectric)



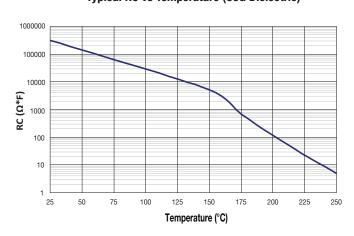
Typical Voltage Coefficient of Capacitance (COG Dielectric)



Typical RC vs Temperature (VHT Dielectric)



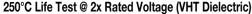
Typical RC vs Temperature (COG Dielectric)

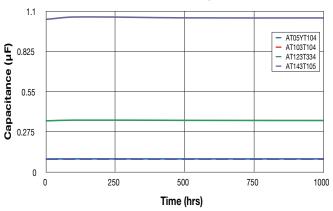


AT Series - 200°C & 250°C Rated



RELIABILITY

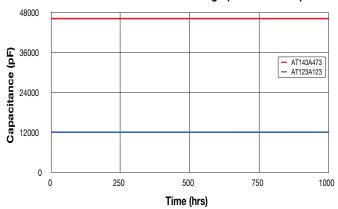




VHT - Failure Rate	VHT - Failure Rate @ 90% Confidence Level (%/1000 hours)										
Temperature (°C)	50% Rated Voltage	100% Rated Voltage									
200	0.002	0.017									
250	0.026	0.210									

^{*}Typical 1210, 1812, 2225 Failure Rate Analysis based on 250°C testing and voltage ratings specified on the following page.

250°C Life Test @ 2x Rated Voltage (C0G Dielectric)

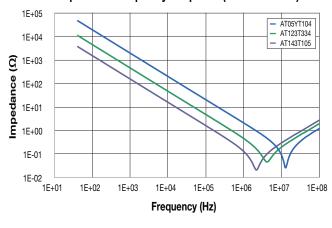


COG - Failure Rate	COG - Failure Rate @ 90% Confidence Level (%/1000 hours)											
Temperature (°C) 50% Rated Voltage 100% Rated Voltage												
200	0.006	0.047										
250	0.074	0.590										

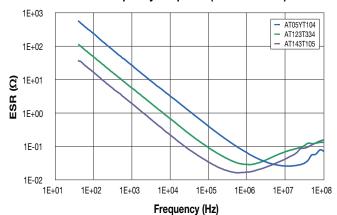
^{*}Typical 1812 and 2225 Failure Rate Analysis based on 250°C testing and voltage ratings specified on the following page.

FREQUENCY RESPONSE

Impedance Frequency Response (VHT Dielectric)

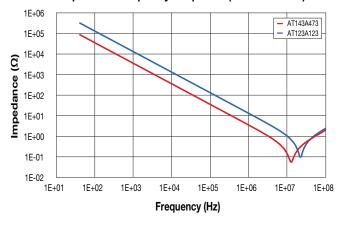


ESR Frequency Response (VHT Dielectric)

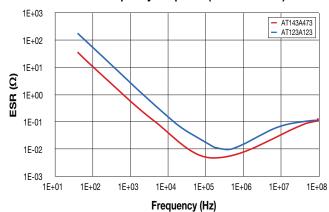


₡Kyocera

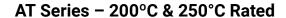
Impedance Frequency Response (COG Dielectric)



ESR Frequency Response (COG Dielectric)



The Important Information/Disclaimer is incorporated in the catalog where these specifications came from or available online at www.kyocera-avx.com/disclaimer/ by reference and should be reviewed in full before placing any order.





CAPACITANCE RANGE PREFERRED SIZES ARE SHADED

			emp. Coeffi AT03 =	ATO		ΔΤι	06 =	AT1	0 =	AT12 =	AT14 =
(Case S	ize	0603	-	05		206	ı	10	1812	2225
-	Solderi	na	Reflow/Wave				v/Wave	Reflov		Reflow Only	Reflow Only
		mm	1.60±0.15	2.01			±0.20	3.20		4.50±0.30	5.72±0.25
L)	Length	(in.)	(0.063±0.006)	(0.079:	±0.008)	(0.126	±0.008)	(0.126±0.008)		(0.177±0.012)	(0.225±0.010
W)	Width	mm (im.)	0.81 ± 0.15		±0.20		±0.20	2.50		3.20±0.20	6.35±0.25
,		(in.)	(0.032±0.006)	(0.049 :		(0.063±0.008) ((0.098±		(0.126±0.008) 2.54	(0.250±0.010
r) 1	Thickness	mm (in.)	1.02 (0.040)	(0.0			52 060)	(0.0		(0.100)	(0.100)
		min	0.25(0.010)	0.25(0.010)	0.25(0		0.25(0.010)	0.25(0.010)
1) 1	Terminal	max	0.75(0.030)	0.75(0.030)	0.75(1.02 (0.040)	1.02 (0.040)
Rat	ted Tem		200	_	00		00	20		200	200
	np. Coef		4	4			4			4	4
	/oltage		25	25	50	25	50	25	50	50	50
	1000	102									
	1200	122									
	1500	152									
	1800	182									
	2200	222					-				
	2700	272					\vdash				
ap		_									
F)	3300	332						<u> </u>			
	3900	392									
	4700	472									
	5600	562									
	6800	682									
	8200	822									
	0.010	103									
	0.012	123									
	0.015	153									
	0.018	183									
	0.018	223									
	<u> </u>	<u> </u>									
	0.027	273									
	0.033	333									
	0.039	393									
	0.047	473									
	0.056	563									
	0.068	683									
	0.082	823									
ap	0.100	104									
ıF)	0.120	124									
	0.150	154									
	0.180	184					\vdash				
	0.180	224									
		_					\vdash				
	0.270	274					<u> </u>				
	0.330	334					<u> </u>		ļ		
	0.390	394									
	0.470	474					<u> </u>				
	0.560	564									
	0.680	684									
	0.820	824									
	1.000	105									
١	/oltage		25	25	50	25	50	25	50	50	50
	ted Tem	<u>` </u>	200		00		00		00	200	200
			AT03 =)5 =		06 =	AT1		AT12 =	AT14 =
(Case S	ize	0603		05 05		206	ı	10	1812	2225

			AT03 =	AIC)5 =	AII)6 =	AII	10 =	AT12 =	AT14 =
	Case	Size	0603	08	05	12	06	12	10	1812	2225
_	Solde	rina	Reflow/Wave		/Wave		//Wave		v Only	Reflow Only	Reflow Only
		mm	1.60±0.15	2.01:			±0.20	3.20:		4.50±0.30	5.72±0.25
L) L	ength.	(in.)	(0.063±0.006)	(0.079:	£0.008)	(0.126:	±0.008)	(0.126:	±0.008)	(0.177±0.012)	(0.225±0.010
W)	Width	mm	0.81 ± 0.15		±0.20		±0.20	2.50:		3.20±0.20	6.35±0.25
**)	Widti	(in.)	(0.032±0.006)	(0.049:			±0.008)	(0.098±		(0.126±0.008)	(0.250±0.010
n) T	hickness	mm	1.02	1.			52	1.		2.54	2.54
, .		(in.)	(0.040)	(0.0			060)	(0.0		(0.100)	(0.100)
t) T	erminal	min	0.25(0.010)	0.25(0.010)	0.25(-	0.25 (0.010)	0.25(0.010)
_		max	0.75(0.030)	0.75(0.030)	0.75(1.02 (0.040)	1.02 (0.040)
	ated Ter		250	2	50	2	50	2	50	250	250
	emp. Co		T 16	1.0	0.5	1.0	0.5	1.0	0.5	T	T
_	Voltag		16	16	25	16	25	16	25	25	25
ļ	1000	102									
Į	1200	122									
-	1500	152									
Ī	1800	182									
ŀ	2200	222									
ар	2700	272									
oF)	3300	332									
"	3900	392									
-	4700	472									
ŀ											
ļ	5600	562									
Į	6800	682									
-	8200	822									
П	0.010	103									
ı	0.012	123									
ł	0.015	153									
ŀ	0.018	183									
ŀ											
ŀ	0.022	223									
Į	0.027	273									
Į	0.033	333									
-[0.039	393									
ı	0.047	473									
Ì	0.056	563									
ŀ	0.068	683									
ŀ	0.0082										
ар		823									
ıF)	0.100	104									
Į	0.120	124									
l	0.150	154									
ſ	0.180	184									
Ì	0.220	224									
ŀ	0.270	274									
ŀ	0.330	334	 				-				
ŀ			1								
ļ	0.390	394									
ļ	0.470	474	ļ								
1	0.560	564									
ſ	0.680	684									
İ	0.820	824									
ŀ	1.000	105									
ᆚ	Voltag		16	16	25	16	25	16	25	25	25
			250								
_											
R	ated Ter	np. (~C)	AT03 =		50)5 =		50)6 =		50 1 0 =	250 AT12 =	250 AT14 =

Voltage rating per table. Capacitance values specified at 25°C, derate capacitance value based on TCC and VCC Plots on page 107. NOTE: Contact factory for non-specified capacitance values.

AT Series - 200°C & 250°C Rated



CAPACITANCE RANGE PREFERRED SIZES ARE SHADED

			G Ter	np. Coefficie		0°C Rated		
(Case Si	ze	AT0	3=0603	AT05	=0805	AT06:	=1206
	Solderii	ng	Reflo	w/Wave	Reflov	v/Wave	Reflow	/Wave
(L)	Length	mm		0±0.15		±0.20	3.20:	
(14/)	14/: 444	(in.)		3±0.006)		±0.008)	(0.126:	
(VV)	Width	mm (in.)		1±0.15 2±0.006)		±0.20 ±0.008)	(0.063:	
T) T	Thickness	mm		1.02		.30		52
		(in.)	(0	1.040)	(0.1	051)	(0.0)	60)
t) T	Terminal	min		5(0.010)		(0.010)	0.25(
_		max		5(0.030)		0.030)	0.75(
Kai	ted Temp	.(°C)		200		00	20	00
	Temp. Coefficei	nt		3		3	3	3
	/oltage (\neg	25	50	25	50	25	50
Сар		390						
oF)	47	470						
	56	560						
	68	680						
	82	820						
	100	101						
	120	121						
	150	151						
	180	181						
	220	221						
	270	271						
	330	331						
	390	391						
	470 560	471						
	680	561 681						
	820	821						
	1000	102						
	1200	122						
	1500	152						
	1800	182						
	2200	222						
	2700	272						
	3300	332						
	3900	392						
	4700	472						
	5600	562		1				
	6800	682		+				
٠	8200	822		+				
Jap μF)	0.010	1		+				
. /	0.012	123 153		+	-			
	0.018	183		1				
	0.018	223		1				
	0.022	273		1				
	0.027	333		1				
	0.039	393						
	0.047	473		İ				
	0.056	563						
	0.068	683						
	0.082	823						
		. –7						

			G (Ni/Au) Te	mp. coemcient. 5	250°C Rated
Cas	se Siz	e	AT03=0603	AT05=0805	AT06 = 1206
Sol	lderin	g	Reflow/Wave	Reflow/Wave	Reflow/Wave
L) Len	ngth <u>mr</u>	m	1.60±0.15	2.01 ± 0.20	3.20±0.20
,	(in		(0.063±0.006)	(0.079±0.008)	(0.126±0.008)
W) Wi	idth mr	$\overline{}$	0.81 ± 0.15	1.25±0.20	1.60±0.20
,	(in	-	(0.032±0.006)	(0.049±0.008)	(0.063±0.008)
T)	mr	$\overline{}$	1.02	1.30	1.52
Thickne		_	(0.040)	(0.051)	(0.060)
t)	mi	'n	0.25(0.010)	0.25(0.010)	0.25(0.010)
ermir			0.75 (0.030)	0.75(0.030)	0.75 (0.030)
Rated	Temp.	_	250	250	250
	<u>Гетр.</u>	١,٠,١			
	efficein	,	5	5	5
	tage (\	-	25	25	25
			23	23	23
.r. 🗀	$\overline{}$	90			
"/	47 4	70			
Ŀ	56 5	60			
Le	58 6	80			
E	32 8	20			
		01			
\vdash	$\overline{}$	$\overline{}$			
_	_	21			
\vdash	$\overline{}$	51			
1	80 1	81			
2	20 2	21			
2	70 2	71			
3	30 3	31			
_	_	91			
\vdash	$\overline{}$	\rightarrow			
_		71			
5	-	61			
6	80 6	81			
8	20 8	21			
10	000 1	02			
12	200 1	22			
_		52			
_	$\overline{}$	82			
-		\rightarrow			
		22			
27	700 2	72			
33	300 3	32			
39	900 3	92			
47	700 4	72			
_	-	62			
		82			
	\neg	\rightarrow			
-	-	22		 	
ap 0.0	$\overline{}$	03			
_	-	23			
0.0	015 1	53			
0.0	018 1	83			
0.0	022 2	23	·		
	027 2				
-	033 3	\rightarrow			
	$\overline{}$	\neg			
	039 3	\neg			
	\neg	73			
0.0	056 5	63			
0.0	068 6	83			
0.0	082 8	23			
_	100 1	$\overline{}$			
	tage (\		25	25	25
	Temp.		250	250	250
raicu	. c.rip.	\neg	AT03=0603	AT05=0805	AT06=1206
	se Siz				

Voltage rating per table. Capacitance values specified at 25°C, derate capacitance value based on TCC and VCC Plots on page 107. NOTE: Contact factory for non-specified capacitance values.

AT06=1206

50



25

50

AT05=0805

25

0.100 104

Voltage (V) Rated Temp. (°C)

Case Size

25

AT03=0603

AT Series - 200°C & 250°C Rated



CAPACITANCE RANGE PREFERRED SIZES ARE SHADED

PN	1E	E COG Temp. Coefficient: 2 200°C Rated e Size AT05 = 0805 AT06 = 1206 AT10 = 1210 AT12 = 1812 AT14 =						P	ME	COC	Temp. C	Coefficient: A	250°C Rate	ed	
C	ase S	ize	AT05 = 0805	AT06 = 1206	AT10 = 1210	AT12 = 1812	AT14 = 2225		Case S	Size	AT05 = 0805	AT06 = 1206	AT10 = 1210	AT12 = 1812	AT14 = 2225
S	olderi	na	Reflow/Wave	Reflow/Wave	Reflow Only	Reflow Only	Reflow Only		Solder	ina	Reflow/Wave	Reflow/Wave	Reflow Only	Reflow Only	Reflow Only
		mm	2.01 ± 0.20	3.20 ± 0.20	3.20 ± 0.20	4.50 ± 0.30	2.75 ± 0.25			mm	2.01 ± 0.20	3.20 ± 0.20	3.20 ± 0.20	4.50 ± 0.30	2.75 ± 0.25
(L) Ler	ngth	(in.)	(0.079 ± 0.008)	(0.126 ± 0.008)	(0.126 ± 0.008)	(0.177 ± 0.012)	(0.225 ± 0.010)	(L) L	Length	(in.)	(0.079 ± 0.008)	(0.126 ± 0.008)	(0.126 ± 0.008)	(0.177 ± 0.012)	(0.225 ± 0.010)
OAO ME	.Jak	mm	1.25 ± 0.20	1.60 ± 0.20	2.50 ± 0.20	3.20 ± 0.20	6.35 ± 0.25	(140)	147: -141-	mm	1.25 ± 0.20	1.60 ± 0.20	2.50 ± 0.20	3.20 ± 0.20	6.35 ± 0.25
(W) Wi	atn	(in.)	(0.049 ± 0.008)	(0.063 ± 0.008)	(0.098 ± 0.008)	(0.126 ± 0.008)	(0.250 ± 0.010)	(vv)	Width	(in.)	(0.049 ± 0.008)	(0.063 ± 0.008)	(0.098 ± 0.008)	(0.126 ± 0.008)	(0.250 ± 0.010)
(T) Thi	ckness	mm	1.30	1.52	1.70	2.54	2.54	(T) 1	Thickness	mm	1.30	1.52	1.70	2.54	2.54
(1) 1111	CKIIESS	(in.)	(0.051)	(0.060)	(0.067)	(0.100)	(0.100)	(1)	THICKHESS	(in.)	(0.051)	(0.060)	(0.067)	(0.100)	(0.100)
(t) Terr	minal	min	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	(t) T	erminal	min	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)	0.25 (0.010)
.,		max	0.75 (0.030)	0.75 (0.030)	0.75 (0.030)	1.02 (0.040)	1.02 (0.040)			max	0.75 (0.030)	0.75 (0.030)	0.75 (0.030)	1.02 (0.040)	1.02 (0.040)
_	d Temp	<u> </u>	200	200	200	200	200		ated Tem		250	250	250	250	250
_	p. Coef		2	2	2	2	2	Te	mp. Coe		Α	Α	Α	Α	Α
V	oltage		50	50	50	50	50		Voltage		25	25	25	25	25
	100	101							100	101					
-	120	121							120	121					
-	150	151							150	151					
	180 220	181 221							180 220	181 221			-		-
-	270	271							270	271					
	330	331							330	331					
	390	391							390	391			-		-
	470	471							470	471					
F	560	561							560	561					
F	680	681							680	681					
Can -	820	821						Cap	820	821					
Cap (pF)	1000	102						(pF)	1000	102					
1° ' E	1200	122						4 /	1200	122					
	1500	152							1500	152					
	1800	182							1800	182					
	2200	222							2200	222					
	2700	272							2700	272					
	3300	332						İ	3300	332					
	3900	392							3900	392					
	4700	472							4700	472					
1 H	5600	562							5600	562					
	6800	682							6800	682					
\rightarrow	8200	822							8200	822					
	0.010								0.010						
	0.012	123							0.012						
	0.015								0.015				-		
	0.018								0.018				-	 	
	0.022	223 273							0.022	223			-	-	
	0.027	333						Сар	0.027				-	 	
1(IIF) L	0.033	393						(μF)	0.033	393				-	
1 H	0.039	473							0.039	473			 	 	
. ⊢	0.047								0.047	_			 		
1 F	0.068	683							0.030				+	†	1
	0.082								0.082	_					
	0.100								0.100				<u> </u>	1	1
	oltage		50	50	50	50	50		Voltage	_	25	25	25	25	25
		p. (°C)	200	200	200	200	200		ted Tem	` /	250	250	250	250	250
_	ase S			AT06 = 1206					Case S			AT06 = 1206			
	ast 3	176	MI03 - 0003	A100 - 1200	A110 - 1210	A112 - 1012	A1 14 - 2223		Case 3	120	A103 - 0003	A100 - 1200	A110 - 1210	A112 - 1012	M114 - 2223

Voltage rating per table. Capacitance values specified at 25°C, derate capacitance value based on TCC and VCC Plots on page 107. NOTE: Contact factory for non-specified capacitance values.

For 600V to 5000V Applications





High value, low leakage and small size are difficult parameters to obtain in capacitors for high voltage systems. KYOCERA AVX special high voltage MLC chip capacitors meet these performance characteristics and are designed for applications such as snubbers in high frequency power converters, resonators in SMPS, and high voltage coupling/dc blocking. These high voltage chip designs exhibit low ESRs at high frequencies.

Larger physical sizes than normally encountered chips are used to make high voltage MLC chip products. Special precautions must be taken in applying these chips in surface mount assemblies. The temperature gradient during heating or cooling cycles should not exceed 4°C per second. The preheat temperature must be within 50°C of the peak temperature reached by the ceramic bodies through the soldering process. Chip sizes 1210 and larger should be reflow soldered only. Capacitors may require protective surface coating to prevent external arcing.

For 1825, 2225 and 3640 sizes, KYOCERA AVX offers leaded version in either thru-hole or SMT configurations (for details see section on high voltage leaded MLC chips)

NEW 630V RANGE

HOW TO ORDER

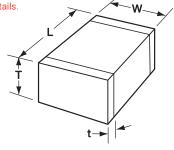
1808	Α	Α	271	M	Α	Т	2	Α
	Τ	Τ	T	T	T	T	Ţ	T
Style	Voltage	Temperature	Capacitance	Capacitance	Test Level	Termination*	Packaging	Special
0805	C = 600V/630V	Coefficient	Code	Tolerance	A = Standard	T = Plated Ni and Sn	2 = 7" Reel**	Code
1206	A = 1000V	A = NPO (COG)	(2 significant digits	COG: $J = \pm 5\%$		(RoHS Compliant)	4 = 13" Reel	A = Standard
1210	S = 1500V	C = X7R ` ´	+ no. of zeros)	$K = \pm 10\%$				
1808	G = 2000V		Examples:	$M = \pm 20\%$				
1812	W = 2500V		10 pF = 100	X7R: $K = \pm 10\%$				
1825	H = 3000V		100 pF = 101	$M = \pm 20\%$				
2220	J = 4000V		1,000 pF = 102	Z = +80%,				
2225	K = 5000V		22,000 pF = 223	-20%				
3640			220,000 pF = 224					
***			1 μF = 105					

Notes:

- 1. Capacitors with X7R dielectrics are not intended for applications across AC supply mains or AC line filtering with polarity reversal. Contact plant for recommendations. Contact factory for availability of Termination and Tolerance options for Specific Part Numbers.
- *Terminations with 5% minimum lead (Pb) is available, see pages 100 and 101 for LD style. Leaded terminations are available, see pages 102-106.

**The 3640 Style is not available on 7" Reels.

^{***} KYOCERA AVX offers nonstandard chip sizes. Contact factory for details





DIMENSIONS: millimeters (inches)

SIZE	0805	1206	1210*	1808*	1812*	1825*	2220*	2225*	3640*
(L) Length	2.10 ± 0.20	3.30 ± 0.30	3.30 ± 0.40	4.60 ± 0.50	4.60 ± 0.50	4.60 ± 0.50	5.70 ± 0.50	5.72 ± 0.25	9.14 ± 0.25
	(0.083 ± 0.008)	(0.130 ± 0.012)	(0.130 ± 0.016)	(0.181 ± 0.020)	(0.181 ± 0.020)	(0.181 ± 0.020)	(0.224 ± 0.020)	(0.225 ± 0.010)	(0.360 ± 0.010)
(W) Width	1.25 ± 0.20	1.60 ± 0.20	2.50 ± 0.30	2.00 ± 0.20	3.20 ± 0.30	6.30 ± 0.40	5.00 ± 0.40	6.35 ± 0.25	10.2 ± 0.25
	(0.049 ±0.008)	(0.063 ± 0.008)	(0.098 ± 0.012)	(0.079 ± 0.008)	(0.126 ± 0.012)	(0.248 ± 0.016)	(0.197 ± 0.016)	(0.250 ± 0.010)	(0.400 ± 0.010)
(T) Thickness	1.35	1.80	2.80	2.20	2.80	3.40	3.40	2.54	2.54
Max.	(0.053)	(0.071)	(0.110)	(0.087)	(0.110)	(0.134)	(0.134)	(0.100)	(0.100)
(t) terminal min. max.	0.50 ± 0.20	0.60 ± 0.20	0.75 ± 0.35	0.75 ± 0.35	0.75 ± 0.35	0.75 ± 0.35	0.85 ± 0.35	0.85 ± 0.35	0.76 (0.030)
	(0.020 ± 0.008)	(0.024 ± 0.008)	(0.030 ± 0.014)	(0.030 ± 0.014)	(0.030 ± 0.014)	(0.030 ± 0.014)	(0.033 ± 0.014)	(0.033 ± 0.014)	1.52 (0.060)

^{*}Reflow Soldering Only

For 600V to 5000V Applications



NPO (COG) DIELECTRIC - PERFORMANCE CHARACTERISTICS

Capacitance Range	10 pF to 0.100 μF (25°C, 1.0 ±0.2 Vrms at 1kHz, for ≤ 1000 pF use 1 MHz)
Capacitance Tolerances	±5%, ±10%, ±20%
Dissipation Factor	0.1% max. (+25°C, 1.0 ±0.2 Vrms, 1kHz, for ≤ 1000 pF use 1 MHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	0 ±30 ppm/°C (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K MΩ min. or 1000 MΩ - μF min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K MΩ min. or 100 MΩ - μF min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

NPO (COG) CAPACITANCE RANGE - PREFERRED SIZES ARE SHADED

Case S	ize		0805	;			1206			1210								18	308							18	12				
Solderi			low/V			Refl	low/W	ave					w Onl	у						w Onl	у							v Only			
(L) Length	mm		10 ± 0			3.3	30 + 0.	30					+ 0.40						4.60	+ 0.50							4.60 +	+ 0.50			\neg
110 140 1-1	(in.)	(0.08	35 ± 0	.008)		(0.13	30 + 0.	012)			((0.130	+ 0.01	6)				((+ 0.02						(0		0.012	2)		\blacksquare
W) Width	mm (:)		25 ± 0		/0		+0.30/		۱4۱		//	2.50	+ 0.30	o))				11	2.00	+ 0.20	O)					(0	3.20 +		٠,		
	(in.) mm	(0.02	49 ± 0 1.35		(0	.003 +	-0.012 1.80	/-0.00	14)		(+ 0.01 .80	<u>Z)</u>				((+ 0.00 20	8)					(0	2.8	+ 0.008	3)		\rightarrow
(T) Thickness	(in.)	((0.053			((0.071))					110)							087)							(0.1				
(t) Terminal	mm		50 + 0				50 + 0.						+ 0.35	;						+ 0.35							0.75+			_	\neg
()	(in.)	(0.02	20 + 0	.008)			4 + 0.0					(.030	0.014)		İ				0.014							(.030 (0.014)			
Voltage	(V)	600	630	1000	600	630	1000	1500	2000	600	630	1000	1500	2000	3000	600	630	1000	1500	2000	2500	3000	4000	600	630	1000	1500	2000	2500	3000	4000
Cap (pF)	.5 0R5 1.0 1R0		Α	С																											\square
			Α	С		-					_				_								-							\longrightarrow	\vdash
	1.2 1R2		Α	C	\ \	. V	. V	. V	. V					_		_		_					-							\rightarrow	\vdash
	1.5 1R5 1.8 1R8	A	A	C	X	X	X	X	X		-	-		-	-	_	_	-				-								\rightarrow	-
	2.2 2R2	A	A	C	X	X	X	X	X						-		С	С				С	С							\rightarrow	
	2.7 2R7	A	A	C	X	X	X	X	X		-			<u> </u>	-		C	C	С	C	С	C	C							\rightarrow	\vdash
	3.3 3R3	Ā	A	C	X	X	X	X	X								C	Č	C	Č	Č	Č	C							\rightarrow	-
	3.9 3R9	A	A	Č	X	X	X	X	X					<u> </u>			Č	Č	C	č	Č	Č	Č							-	-
	4.7 4R7	A	A	Č	X	X	X	X	X								Č	Č	Č	Č	Č	Č	C							\neg	
	5.6 5R6	Α	Α	C	Х	Х	Х	Х	Х								C	C	C	C	Ċ	C	C							\neg	
	6.8 6R8	Α	Α	C	Х	Х	Х	X	X				İ				C	C	C	Č	C	C	C			İ		İ		$\neg \uparrow$	
	8.2 8R2	Α	Α	С	Χ	Χ	Х	Χ	Х						L		С	С	С	С	С	С	С								
	10 100	Α	Α	С	С	С	С	С	С	С	М	М	D	М	F	С	С	С	С	С	С	С	С	С	С	С	С	С	С	С	Е
	12 120	Α	Α	С	С	С	С	С	С	С	М	М	D	М	F	С	С	С	С	С	С	С	С	С	С	С	С	С	С	С	Е
	15 150	Α	Α	С	С	С	С	С	C	С	М	М	D	М	F	С	С	С	С	С	С	С	С	С	С	С	С	С	С	С	E
	18 180	A	Α	С	С	С	С	С	C	С	М	М	D	М	F	С	С	C	С	C	C	С	С	С	C	C	С	C	С	С	E
	22 220	A	Α	C	C	C	C	C	C	C	M	M	D	M	F	C	C	C	C	C	C	C	E	C	C	C	C	Ç	С	С	늗
	27 270	A	Α	C	C	C	C	C	C	C	М	M	D	М	+	C	C	C	С	C	C	C	F	C	C	C	C	F	C	С	늗
	33 330	A	Α	C	C	C	C	C	C	C	M	M	D	М	F	С	С	C	С	C	C	С	F	C	C	C	С	F	С	С	늗
	39 390 47 470	A	A	C	C	C	C	C	C	C	M	M	D D	M	F	C	C	C	C	C	C	C	C	C	C	C	C	F	C	C	듣
	56 560	A	A	C	C	C	C	C	C	C	M	M	C	C	+-	C	C	C	C	C	C	C	C	C	C	C	C	F	C	C	늗
	68 680	A	A	C	C	C	C	C	C	C	M	M	C	C	F	C	C	C	C	C	C	C		C	C	C	C	F	C	C	F
	82 820	X	X	X	č	č	Č	č	č	Č	M	M	č	Č	F	Č	C	Č	C	Č	Č	C		C	C	Č	C	F	C	C	F
	100 101	X	X	X	C	C	C	C	Č	Č	M	C	Č	Č	Ė	Č	Č	Č	Č	Č	F	F		Č	Č	Č	Č	Ė	C	Č	F
	120 121	C	С	С	Č	Č	Č	Ĕ	Ĕ	Č	M	Č	Č	C	F	C	C	C	C	C	F	F		C	C	C	C	F	С	C	G
	150 151	C	C	C	C	C	C	Ē	E	C	М	C	Ē	Ē	F	C	C	C	F	F	F	F		C	C	C	C	F	C	C	Ğ
	180 181	С	С	С	С	C	E	Е	Е	C	М	E	Е	Е	F	С	С	С	F	F	F	F		С	С	С	С	F	F	F	
	220 221	С	С	С	С	С	Е	Е	Е	С	М	Е	Е	Е	F	С	С	С	F	F	F	F		С	С	С	С	F	F	F	
	270 271	С	С	С	С	С	Е	Е	Е	С	М	Е	Е	E	G	С	F	С	F	F	F	F		С	С	С	С	F	F	F	
	330 331	С	С	С	С	C	E	E	E	С	М	E	E	E		С	F	F	F	F	F	F		С	С	С	F	F	F	F	
	390 391	<u>C</u>	C	С	С	C	E	E	E	С	M	E	E	E		C	F	F	F	F	F	F		С	C	C	F	<u>F</u>	F	F	_
	470 471	<u>C</u>	C		C	C	Ę	Е	E	C	M	Ę	늗	ΙĒ		C	F	Į Ę	F	늗	F	<u> </u>		C	C	ᆣ	F	ᆣ	<u> </u>	F	_
	560 561	C	C		С	C	E			С	M	E	Ę	I E		С	F	F	F	F		F		С	C	<u> </u>	F	F	F	F	_
	680 681 750 751	C	C		C E	C E	E			C	M	E	G	E		C	F	F	F	F				C	C	듣	F	F	G	G	
	820 821	C	C		E	E	E			C	M	E	G	F		C	F	F	F	F				C	C	F	F	F	G	G	-
	1000 102		C		Ē	Ē	Ē			C	C	Ė	F	F		C	F	F	Ē	F				C	C	F	F	F	G	G	
	1200 102		C		Ē	Ē	Ē			Č	C	Ē		F		C	F	F	Ē	F				C	Č	F	Ė	Ė			
	1500 152		C		Ē	Ē				C	C	F		G		Ē	F	F		F		i –		C	C	F	F	F		\neg	
	1800 182		С		Е	Е				С	C	G		G		Е	F	F		F				С	С	F	G	F			
	2200 222		С		Е	Е				Е	С	G				Е	F	F						С	С	Е	G	G			
	2700 272			$oxed{\Box}$	Е	Е				Е	С	G				Е	F	F						С	С	Е	G	G			\vdash
	3300 332		_	<u> </u>	E	E		<u> </u>		E	C	G		<u> </u>		E	F	F	<u> </u>		_	<u> </u>	<u> </u>	C	C	F		G			<u> </u>
	3900 392		_	├	E	E		<u> </u>	-	E	C	G	_	-	-	E	F		_	-	-	├	-	C	C	F	_	_			—
	4700 472		_	-	Е	Е	-	<u> </u>	-	E	C E	_	-	-	-	E	F	_	-	-	-	-	-	C	C	G		-		\rightarrow	
	5600 562 6800 682		_	\vdash	\vdash	\vdash	\vdash	\vdash	-		E	_	-	-	-	F	F		-	-	-	\vdash	\vdash	C	C	G		-	\vdash	\rightarrow	-
	8200 822			 	<u> </u>	1	1	<u> </u>	-	<u> </u>	F		-	<u> </u>	1		F			-		 	1	E	C			-	\vdash	\rightarrow	-
	0.010 103		_	\vdash	\vdash	\vdash	\vdash	\vdash	 		F		 	 	 	 	F		\vdash	 	 	\vdash	\vdash	F	F			 	\vdash	\dashv	-
	0.012 123			t	<u> </u>						G											t		F	F					\dashv	
	0.015 153																							G	G					\dashv	
	0.018 183																							Ğ	G					\neg	
	0.022 223														L						L				F						
	0.027 273																								G						
	0.033 333																								G						
	0.047 473		\Box	$oxed{\Box}$				_	_		_	_	_				\Box		\Box	_	_	_		\Box		_		_		Ш.	_
	0.056 563													_	_			_													<u> </u>
	0.068 683		_	-	<u> </u>	-	-	<u> </u>	-	<u> </u>	<u> </u>	-	-	-	-	-	<u> </u>	-	_	-	-	-	-	_	_	-	_	-	\vdash		<u> </u>
	0.100 104	600	620	1000	600	620	1000	1500	2002	600	620	1000	1500	2000	2000	600	620	1000	1500	2000	2500	2000	4000	600	620	1000	1500	2002	2500	2000	4000
Voltage Case S		000	0805		000	030	1206	1500	2000	000	030		11500 210	2000	3000	000	030	1000		12000 308	2500	3000	14000	000	030	1000	15 <u>00</u> 18		Z3UU	3000	4000
Uase S	126		5000				1200					14							10	,,,,,							10	14			

Letter	Α	С	Е	F	G	Х	7
Max.	0.813	1.448	1.8034	2.2098	2.794	0.940	3.30
Thickness	(0.032)	(0.057)	(0.071)	(0.087)	(0.110)	(0.037)	(0.130)







NPO (COG) CAPACITANCE RANGE - PREFERRED SIZES ARE SHADED

Case Siz	-				18									2220									2225									3640				
Solderin	_				Reflo		у			_				flow C									flow C									flow C				
(L) Length	mm (in.)			(4.60 : 0.181 :		0)							.70 0.5 224 0.0									70 ± 0. 25 ± 0.									14 ± 0. 60 ± 0.				
W) Width	mm				6.30		,						5	.00 0.4	10							6	.30 0.4	10							10	0.2 ± 0.	25			
TT) WIGHT	(in.)			(0.248		5)						(0.1	197 0.0	016)							(0.2	50 ± 0.	010)							(0.4	00 ± 0.	010)			
(T) Thickness	mm (in.)				(0.1	40 (34)								3.40 (0.134)								3.40 (0.100))								2.54 (0.100)			
(t) Terminal	mm				0.75									.85 0.3									85 ± 0.									76 (0.0				
Voltage (V	max	600	620		0.030			Lanna	4000	600	620	1000		33 ± 0.		2000	14000	F000	600	620	1000		33 ± 0.		2000	4000	[F000	600	1 620	11000		52 (0.0		3000	4000	5000
Cap (pF) 1.5		000	030	1000	1500	2000	2500	3000	4000	600	030	1000	1500	2000	2500	3000	4000	5000	600	030	1000	1500	2000	2500	3000	4000	5000	600	030	1000	1500	2000	2500	3000	4000	5000
1.8	1R8																																			
2.2						_									-		_		_				_						-	_		_		$\vdash \vdash$		\vdash
3.3																																		\vdash		-
3.9	-																																			
4.7																																		\vdash		\vdash
5.6	-																																			-
8.2																																				
10		E	E	G	E	F	E	F	F	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F						<u> </u>	igwdown	-]
12		E	E	G G	E	F	E	F	F	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F							\vdash		\dashv
18	180	Е	Е	G	Е	F	Е	F	F	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	F	F									
22		E	Е	G	E	F	E	F	F	E	E	E	Е	E	E	E	E	E	E	E	E	E	E	E	E	F	F							\square		\vdash
33		E	E	G G	E	F	E	F	F	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F			\vdash	\vdash			\vdash		\dashv
39	390	Е	Е	G	Е	F	Е	F	F	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	F	F									
47		Е	Е	G	E	F	Е	F	F	E	Е	Е	Е	Е	E	E	E	Е	E	E	Е	Е	E	E	E	F	G									G
56		E	E	G G	E	F	E	F	F	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F	G							\vdash		G G
82		E	E	G	E	F	E	F	F	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F	G									G
100		Е	Е	G	Е	F	Е	F	F	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	G	G				G	G	G	G	G	G
120 150		E	E	G G	E	F	E	F	F	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E E	E	G G	G				G G	G	G G	G G	G G	G G
180		E	E	G	E	F	E	F	F	E	E	E	E	E	E	E	F	F	E	E	E	E	E	E	E	G	G				G	G	G	G	G	G
220		Е	Е	G	Е	F	Е	F	F	Е	Е	Е	Е	Е	Е	Е	F	F	Е	Е	Е	Е	Е	Е	Е	G	G				G	G	G	G	G	G
330		E	E	G G	E	F	E	F	F	E	E	E	E	E	E	E			E	E	E	E	E	E	E	G G	G				G G	G	G G	G	G G	G G
390		E	E	G	E	F	E	F		E	E	E	E	E	E	E			E	E	E	E	E	E	E	G					G	G	G	G	G	G
470		Е	Е	G	E	F	Е	F		E	Е	Е	Е	Е	Е	Е			E	Е	E	Е	Е	Е	Е	G					G	G	G	G	G	G
560		E	E	G G	E	F	E F	F G		E	E	E	E	E	E F	E F			E	E	E	E	E	E	E	G					G G	G G	G	G	G G	G G
750		Е	E	G	E	F	F	G		E	E	E	E	Е	F	F			Е	E	E	Е	E	Е	E						G	G	G	G	G	G
820		E	E	G	E	F	F	G		E	E	E	Е	E	F	F			E	E	E	E	E	F	E						G	G	G	G	G	G
1000		E	E	G G	E	F	F G	G		E	E	E	E	E	F G	F G			E	E	E	E	E	E F	E F			G	G	G	G	G	G	G	G G	
1500		Е	Е	G	F	G	G	G		E	Е	E	F	F	G	G			E	E	Е	Е	E	F	F			G	G	G	G	G	G	G		
1800		Е	Е	G	F	G	G	G		E	Е	E	F	F	G	G			E	E	Е	Е	E	G	G			G	G	G	G	G	G	G		\blacksquare
2200 2700		E	E	G G	G G	G G		G		E	E	E	G G	G					E	E	E	E F	E F					G	G	G	G	G	G	G		$\overline{}$
3300		E	Е	G	G	G				E	Е	Е	G	G					E	E	Е	F	F					G	G	G	G	G	G			
3900		E	Е	G	G	G				E	E	Е	G	G					E	E	E	G	G					G	G	G	G	G	G	\Box		\vdash
4700 5600		E F	E F	G G	G	G				E F	E F	E F	G G	G					F	F	F	G G	G					G	G	G	G	G		\vdash		$\overline{}$
6800		F	F	G		G				F	F	F	,						F	F	F	G	G					G	G	G	G	G				
8200		F	F	G		G				G 7	G	G							G	G	G							G	G	G	G			\Box		\Box
Cap (μF) 0.010 0.012		F F	F	G G						7	7	7							G G	G G	G							G	G	G	G			$\vdash \vdash$		\vdash
0.015		F	F					L											G	G								G	G	G						
0.018		F	F																G	G								G	G	G						
	223	F	F									-		-		-		-	G	G				\vdash		\vdash	-	G	G	G				$\vdash \vdash$	\dashv	\vdash
	333	_	F				L	Ĺ											G	G								G	G		L					
0.039		G	G																															П		口
	473 563	G G	G G									_							G G	G G				\vdash				G	G		\vdash			$\vdash \vdash$		\Box
0.068	683	G	G																G	G																
	104	441	46.	10	4 8 7 7		0.5	06:	40-	46.	40.	10	4811		0.5		40	E0.	467	461	10	4 8 7 7		05:			B.C.	4		467		04.	0.5	200	10	
Voltage (600	630	1000		2000 25	2500	3000	4000	600	630	1000		2000 2220		3000	4000	5000	600	630	1000		2000 2225		3000	4000	5000	600	630	1000				3000	4000	5000
Case Siz	.e				18	25								2220									2225									3640				

Letter	A	С	Е	F	G	Х	7
Max.	0.813	1.448	1.8034	2.2098	2.794	0.940	3.30
Thickness	(0.032)	(0.057)	(0.071)	(0.087)	(0.110)	(0.037)	(0.130)
Inickness	(0.032)	(0.057)	(0.071)	(0.087)	(0.110)	(0.037)	(0.1



For 600V to 5000V Applications



X7R Dielectric

Performance Characteristics

Capacitance Range	10 pF to 0.82 μF (25°C, 1.0 ±0.2 Vrms at 1kHz)
Capacitance Tolerances	±10%; ±20%; +80%, -20%
Dissipation Factor	2.5% max. (+25°C, 1.0 ±0.2 Vrms, 1kHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	±15% (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K MΩ min. or 1000 MΩ - μF min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K MΩ min. or 100 MΩ - μF min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

X7R CAPACITANCE RANGE - PREFERRED SIZES ARE SHADED

Case Size			0805				1206					1210						18	808			1812								
Soldering			ow/W				low/W					low 0						Reflov								Reflov				
(L) Length mr			.10 0.2 35 ± 0.0				30 ± 0. 30 ± 0.					.30 0.4 30 0.0					,		± 0.50	۸						4.60 ±				
· · · · (III.			25 ± 0.0				+0.30/					.50 0.0					(± 0.020 0.20)						0.177 ± 3.20 ±)		
(in.	.)		49 ± 0.0		(0.063	+0.012		l)			98 0.0					(0.079 :	± 0.008)						$(0.126 \pm$	0.008)		
(T) Thickness mr (in.	.)		1.35 (0.053)	20			1.80 (0.071					2.80 (0.110)						(0.0	20 087)							(0.1	00)			
(t) Terminal ma			50 ± 0.: 20 ± 0.:				60 ± 0. 24 ± 0.					.75 0.3 30 ± 0.0					(± 0.35 ± 0.014	١.						0.75 ± ± 0.030)		١		
Voltage (V)		600	630		600				2000	600			1500	2000	600	630			2000		3000	4000	600	630		1500			3000	4000
	101	Χ	Χ	С	С	С	Е	Е	Е	Е	Ε	Е	Е	Е																
120 1	121	Х	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е																
150 1	151	Х	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е																
	181	Х	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е																
	221	Х	Х	С	С	С	E	E	E	E	E	E	Е	E																
	271	Х	Х	С	C	С	E	E	E	E	E	E	E	E									Е	Е	Е	Е	Е			
	331	X	X	С	С	С	E	E	E	E	E	E	E	E	Е	Е	Е	Е	Е	Е	F		E	E	E	E	E			
	391	X	X	С	С	С	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F		E	E	E	E	E			
	471	X	X	С	С	С	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F		E	E	E	E	E	Е	Е	
	561	X	X	С	С	С	E	E	E	E	E	E	E	E	E	E	E	E	E	F	-		E	E	E	E	E	E	E	
	_	_		_	-	_	_	_	_		E		_		E	E	_		E	-	-		E	_	-	E	_	F	F	
	681	X	X	С	С	С	E	E	E	E E		E	E	E			E	E		F	F			E	E	_	E	F	F	
	751	X	X	С	С	С	E	E	E		E	E	E	E	E	E	E		E		F	\vdash	E			E	E	F	_	_
	821	X	X	С	С	С	E	Е	E	Е	E	Е	E	E	E	E	E	E	Е	F	F		E	E	E	E	E	F	F F	
	102	X	Х	Х	С	С	E	E	E	E	E	E	E	E	E	E E	E	E	E	F	F		E F	E	F	E F	E	_	F	
	122	Х	X	Х	С	С		E	E	E	E	E	E	E	E	_	E		E	F	-					_	F	F		
	152	X	X	Х	С	С	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F		F	F	F	F	F	G	G	
	182	X	X	С	С	С	E	E	E	E	E	E	E	E	Е	E	E	E	E	F	F		F	F	F	F	F	G	G	
	222	X	Х	Х	С	С	E	E	Е	E	E	E	F	E	E	E	E	F	F	F			F	F	F	F	F	G	G	
	272	С	С		С	С	E	Е		E	E	E	F	E	E	E	E		F		-					F	F	G	G	
	332	С	С	_	С	С	E			E	E	E	F	Е	E	E	E	F	F	_	-		F	F	F	F	F	G	G	
	392	С	С		С	С	E			E	E	E	F		E	E	E	F			-		F	F	F	F	F	G	G	
	472	С	С	_	С	С	E			E	E	E			E	E	E				-		F		F	_		G	G	_
	562	С	C		C	С	E			E E	E E	E	F		E E	E	E	F					F	F	F	G	G	G		
	682	С	_	_	С	С	_					E				E	E	-					F	-	F	G	G	_		
	822	C C	С		C	С	E			E	E E	E			E	E	E						F	F	F	G	G G			
	103	С	C	_	E	C E	E			E	E	E			F	F	F						F	F	F	G G	G			
	153 183	С	С		E	E				E	E	E			F	F	F				-		F	F	G	G			_	
	223	С	С		E	F				E	E	F			F	F	F						F	F	G					
	273	C	U		_					E		г			F	F	г				-		F	F	G				_	
	333			-	E E	E	-	-	-	E	E		-		F	F	-	-	-	-	-	\vdash	F	F	G		-	-	-	\vdash
	393							-		E	E				F	F		-	-	-	\vdash		F	F	G					-
	473			_	-	-		-		E	E		_		F	F		-	-	-	1		F	F	G		_	-	-	-
	563				-	<u> </u>	_	<u> </u>		F	F		_		F	F		-	<u> </u>	<u> </u>	-	\vdash	F	F	G		_			\vdash
	\rightarrow			-		-	-	-	-	F	F		-		F	F	-	-	-	-		\vdash	F	F	-		-	-	-	-
	683 823			_	-	_	_	_		F	F							-	_	_	\vdash		F	F		-			_	_
	104						-		-	F	F		-			-	-	-				\vdash	F	F	-		-	-	-	-
	154				-	<u> </u>	_	<u> </u>	_							_	_	_	\vdash	\vdash	_	\vdash	G	G	_	_				\vdash
	224																	-			-	\vdash	G	G					-	
	274				-	-		-								-		-	-	-	-	\vdash	G	G		-			-	-
	334																				 	$\vdash\vdash$	-		\vdash					\vdash
	\rightarrow			-		\vdash		\vdash			-		-			-	<u> </u>	-	\vdash	\vdash	\vdash	\vdash	-	<u> </u>	\vdash	-	-	-	-	\vdash
	394 474								-							-		-				\vdash	-		-				-	-
	564				-	-		-								-		-	-	-	-	\vdash	-		\vdash	-			-	\vdash
	684																				-	$\vdash\vdash\vdash$	-		<u> </u>					<u> </u>
	824					\vdash		\vdash										-	\vdash	\vdash	-	$\vdash\vdash$			\vdash					\vdash
	105																	-				\vdash							-	
Voltage (V)	100	600	630	1000	600	630	1000	1500	2000	600	630	1000	1500	2000	600	630	1000	1500	2000	2500	3000	4000	600	630	1000	1500	2000	2500	3000	4000
Case Size	\dashv		0805	1000	000	030	1206		2000	000	000	1210	1000	2000	000	030	1000	18		2300	10000	4000	000	1 000	1.000	18		2000	0000	1-000
Case Size			2003				1200					1210						18	00							18	14			

	Letter	Α	С	Е	F	G	Χ	7
	Max.	0.813	1.448	1.8034	2.2098	2.794	0.940	3.30
_1	Thickness	(0.032)	(0.057)	(0.071)	(0.087)	(0.110)	(0.037)	(0.130)



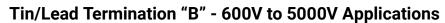




X7R CAPACITANCE RANGE **PREFERRED SIZES ARE SHADED**

Case Size				18	25								2220									222	5				3640								
Soldering				Reflov									low 0									flow (eflow (
(L) Length mm			((4.60 : 0.181 :									0 ± 0. 4 ± 0.									70 ± 0 25 ± 0									14 ± 0 60 ± 0				
W) Width mm				6.30 :	± 0.40							5.0	0 ± 0.	40							6.3	30 ± 0	.40							10	0.2 ± 0	.25			
(T) mm			((0.248 : 3.		6)							7 ± 0. 3.40	016)							(0.2	50 ± 0 3.40								(0.4	00 ± 0 2.54			_	
Thickness (in.)				(0.1									0.134									(0.100								0	(0.100				
(t) Terminal mm max			((: 0.75 : 0.030	± 0.35 ± 0.014	4)							5 ± 0. 3 ± 0.									85 ± 0 33 ± 0									76 (0.0 52 (0.0				
Voltage (V)	600	630					3000	4000	600	630	1000				3000	4000	5000	600	630	1000				3000	4000	5000	600	630	1000				3000	4000	5000
Cap (pF) 100 101																																		لـــــا	\sqcup
120 121		-				-																								ļ				\square	\square
150 151																						1												\vdash	
180 181		-		-	-	-	-	-			-																			-				Ш	\vdash
220 221 270 271																																		\vdash	\vdash
330 331		1				-										-														-			\vdash	\vdash	$\vdash\vdash$
390 391																																	\vdash	\vdash	\vdash
470 471																																		\vdash	\vdash
560 561		1														\vdash							\vdash		Н								Н	\vdash	\vdash
680 681	\vdash	+						\vdash	\vdash							\vdash						\vdash			\vdash							\vdash	\vdash	\vdash	
750 751																																		\vdash	
820 821																																		\vdash	
1000 102	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G
1200 122	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G
1500 152	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G
1800 182	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G
2200 222	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G
2700 272	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G
3300 332	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G
3900 392	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	
4700 472	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	
5600 562	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	
6800 682	F	F	F	G	G	G	G		F	F	F	F	F	G	G	-		F	F	F	F	F	G	G			G	G	G	G	G	G	G	G	
8200 822	F	F	F	G	G	G	G	-	F	F	F	G	G	G	G	-		F	F	F	F	F	G	G			G G	G	G	G	G	G	G	\vdash	\vdash
Cap (μF) 0.010 103 0.015 153	F	F	F	G G	G G	G	G		F	F	F	G G	G G	G G	G			F	F	F	G	G	G	G			G	G G	G	G	G G	G	G G	ightharpoonup	\vdash
0.018 183	F	F	F	G	G	G			F	F	F	G	G	G		-		F	F	F	G	G	G	G			G	G	G	G	G	G	G	\vdash	\vdash
0.022 223	F	F	F	G	G		 	<u> </u>	F	F	F	G	G	_		-		F	F	F	G	G	G				G	G	G	G	G	G	0	\vdash	\vdash
0.027 273	F	F	F	G					F	F	F	G	G	 				F	F	F	G	G	-				G	G	G	G	G			\vdash	\vdash
0.033 333	F	F	F	G					F	F	F	G	-			-		F	F	F	G	G					G	G	G	G	_		Н	-	\vdash
0.039 393	F	F	F	G					F	F	F	G						F	F	F	G	Ť					G	G	G	G				\vdash	
0.047 473	F	F	F	Р					F	F	F	G						F	F	F	G						G	G	G	G				\vdash	
0.056 563	F	F	F	G					F	F	F	G						F	F	F	G						G	G	G	G				\neg	
0.068 683	F	F	G						F	F	G							F	F	F	G						G	G	G	G				П	
0.082 823	F	F	G						F	F	G							F	F	G							G	G						\Box	
0.100 104	F	F	G						F	F	G							F	F	G							G	G						\Box	
0.150 154	F	F							F	F	G							F	F	G							G	G							
0.220 224	F	F							F	F	G							F	F								G	G						ш	igsquare
0.270 274	F	F				_			F	F		L						F	F	_	<u> </u>	\vdash			Ш		G	G		_				لــــــــــــــــــــــــــــــــــــــ	igsquare
0.330 334	F	F				<u> </u>			F	F								F	F			<u> </u>					G	G		<u> </u>				لـــــا	
0.390 394	_	F	_	<u> </u>	<u> </u>	<u> </u>	<u> </u>		F	F	-							F	F	_	_	<u> </u>	_		\square		G	G	_	<u> </u>	_		\square	igwdap	\sqcup
0.470 474	F	F	_	_	_	_	_	\vdash	F	F		<u> </u>			\vdash	\square		F	F	-	_	\vdash	-		Н		G	G	_	_	_	\vdash	\vdash	للم	\vdash
0.560 564	G	G		_	_	-	_	\vdash	G G	G G		-				\vdash		F G	F G	-	<u> </u>		-		\vdash		G	G		-	_	\vdash	\vdash	-	\vdash
0.680 684 0.820 824	-	+		-	-	\vdash	-	-	G	G		-		_				G	G	-		\vdash	-		\vdash			-		\vdash		-		\vdash	\vdash
1.000 105	\vdash	+				-		\vdash								\vdash		G	G			\vdash			\vdash							\vdash	\vdash	\vdash	
Voltage (V)	600	630	1000	1500	2000	2500	3000	4000	600	630	1000	1500	2000	2500	3000	4000	5000	600	630	1000	1500	2000	2500	3000	4000	5000	600	630	1000	1500	2000	2500	3000	4000	5000
Case Size	550	1 000	,,,,,,,	18		1_000	, 5000		000	000			2220		5000	.000	3003	555	1 000	,,,,,,,,		2225		3000	.000	3003		_ ~~		1.000	3640		3000		3000
JUGG GIEC																															2370				

	Letter	Α	С	E	F	G	Χ	7
	Max. Thickness	0.813 (0.032)	1.448 (0.057)	1.8034 (0.071)	2.2098 (0.087)	2.794 (0.110)	0.940 (0.037)	3.30 (0.130)
L	THIORITCOO	(0.002)	(0.007)	(0.071)	(0.007)	(0.110)	(0.007)	(0.100)







NEW 630V RANGE

KYOCERA AVX will support those customers for commercial and military Multilayer Ceramic Capacitors with a termination consisting of 5% minimum lead. This termination is indicated by the use of a "B" in the 12th position of the KYOCERA AVX Catalog Part Number. This fulfills KYOCERA AVX's commitment to providing a full range of products to our customers. KYOCERA AVX has provided in the following pages, a full range of values that we are offering in this "B" termination.

Larger physical sizes than normally encountered chips are used to make high voltage MLC chip product. Special precautions must be taken in applying these chips in surface mount assemblies. The temperature gradient during heating or cooling cycles should not exceed 4°C per second.

The preheat temperature must be within 50°C of the peak temperature reached by the ceramic bodies through the soldering process. Chip sizes 1210 and larger should be reflow soldered only. Capacitors may require protective surface coating to prevent external arcing.

For 1825, 2225 and 3640 sizes, KYOCERA AVX offers leaded version in either thru-hole or SMT configurations (for details see section on high voltage leaded MLC chips).

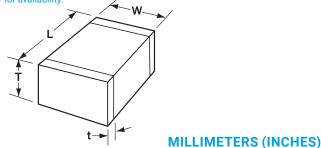
HOW TO ORDER

LD08	Α	Α	271	K	Α	В	2	Α
$\overline{}$	Ţ	Ţ	$\overline{}$	T	T	Ţ	Ţ	T
LD06 - 1206 LD10 - 1210 LD08 - 1808 LD12 - 1812 LD13 - 1825	Voltage 600V/630V = C 1000V = A 1500V = S 2000V = G 2500V = W 3000V = H	Temperature Coefficient COG = A X7R = C	Capacitance Code (2 significant digits + no. of zeros) Examples: 10 pF = 100 100 pF = 101	Capacitance Tolerance COG: J = ±5% K = ±10% M = ±20% X7R: K = ±10% M = ±20%	Test Level A = Standard 4 = Automotive*	Termination* B = 5% Min Pb X = FLEXITERM® 5% min. Pb*	Packaging 2 = 7" Reel** 4 = 13" Reel	Special Code A = Standard
LD20 - 2220 LD14 - 2225 LD40 - 3640 ***	4000V = J 5000V = K		1,000 pF = 102 22,000 pF = 223 220,000 pF = 224 1 µF =105	Z = +80%, -2	20%			

Notes: Capacitors with X7R dielectrics are not intended for applications across AC supply mains or AC line filtering with polarity reversal. Contact plant for recommendations. Contact factory for availability of Termination and Tolerance options for Specific Part Numbers.

- * FLEXITERM is not available in the LD40 Style
- ** The LD40 Style is not available on 7" Reels.
- *** KYOCERA AVX offers nonstandard chip sizes. Contact factory for details.
- * Not all values are supported in Automotive grade. Please contact factory for availability





DIMENSIONS

SIZE		LD05 (0805)	LD06 (1206)	LD10* (1210)	LD08* (1808)	LD12* (1812)	LD13* (1825)	LD20* (2220)	LD14* (2225)	LD40* (3640)
(L) Length		2.10 ± 0.20	3.30 ± 0.30	3.30 ± 0.40	4.60 ± 0.50	4.60 ± 0.50	4.60 ± 0.50	5.70 ± 0.50	5.70 ± 0.50	9.14 ± 0.25
(=) =0gu.	'	(0.083 ± 0.008)	(0.130 ± 0.012)	(0.130 ± 0.016)	(0.181 ± 0.020)	(0.181 ± 0.020)	(0.181 ± 0.020)	(0.224 ± 0.020)	(0.224 ± 0.020)	(0.360 ± 0.010)
(W) Width		1.25 ± 0.20	1.60 ± 0.20	2.50 ± 0.30	2.00 ± 0.20	3.20 ± 0.30	6.30 ± 0.40	5.00 ± 0.40	6.30 ± 0.40	10.2 ± 0.25
(vv) vviatn		(0.049 ± 0.008)	(0.063 ± 0.008)	(0.098 ± 0.012)	(0.079 ± 0.008)	(0.126 ± 0.012)	(0.248 ± 0.016)	(0.197 ± 0.016)	(0.248 ± 0.016)	(0.400 ± 0.010)
(T) Thickr	ness	1.35	1.80	2.80	2.20	2.80	3.40	3.40	3.40	2.54
Max.		(0.053)	(0.071)	(0.110)	(0.087)	(0.110)	(0.134)	(0.134)	(0.134)	(0.100)
(t)	min.	0.50 ± 0.20	0.60 ± 0.20	0.75 ± 0.35	0.75 ± 0.35	0.75 ± 0.35	0.75 ± 0.35	0.85 ± 0.35	0.85 ± 0.35	0.76 (0.030)
terminal	max.	(0.020 ± 0.008)	(0.024 ± 0.008)	(0.030 ± 0.014)	(0.030 ± 0.014)	(0.030 ± 0.014)	(0.030 ± 0.014)	(0.033 ± 0.014)	(0.033 ± 0.014)	1.52 (0.060)

^{*}Reflow Soldering Only

Performance of ceramic capacitors can be simulated by using the online SpiMLCC software program - http://spicat.avx.com/mlcc Custom values, ratings and configurations are also available





Tin/Lead Termination "B" - 600V to 5000V Applications

NP0 (C0G) Dielectric

Performance Characteristics

Capacitance Range	10 pF to 0.047 μF
Capacitance Range	(25°C, 1.0 ±0.2 Vrms at 1kHz, for ≤ 1000 pF use 1 MHz)
Capacitance Tolerances	±5%, ±10%, ±20%
Dissipation Factor	0.1% max. (+25°C, 1.0 ±0.2 Vrms, 1kHz, for ≤ 1000 pF use 1 MHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	0 ±30 ppm/°C (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K MΩ min. or 1000 MΩ - μF min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K MΩ min. or 100 MΩ - μF min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

HIGH VOLTAGE COG CAPACITANCE VALUES

VOLTA	GE	LD05 (0805)	LD06 (1206)	LD10 (1210)	LD08 (1808)	LD12 (1812)	LD13 (1825)	LD20 (2220)	LD14 (2225)	LD40 (3640)
600/630	min.	10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF	1000 pF
000/030	max.	330 pF	1200 pF	2700 pF	3300 pF	5600 pF	0.012 μF	0.012 pF	0.018 μF	0.047 µF
1000	min.	10 pF	10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF
1000	max.	180 pF	560 pF	1500 pF	2200 pF	3300 pF	8200 pF	0.010 pF	0.010 μF	0.022 μF
1500	min.	_	10 pF	10 pF	10 pF	10 pF	100 pF	100 pF	100 pF	100 pF
1300	max.	-	270 pF	680 pF	820 pF	1800 pF	4700 pF	4700 pF	5600 pF	0.010 μF
2000	min.	_	10 pF	10 pF	10 pF	10 pF	100 pF	100 pF	100 pF	100 pF
2000	max.	-	120 pF	270 pF	330 pF	1000 pF	1800 pF	2200 pF	2700 pF	6800 pF
2500	min.	-	-	-	10 pF	10 pF	10 pF	100 pF	100 pF	100 pF
2300	max.	-	-	_	180 pF	470 pF	1200 pF	1500 pF	1800 pF	3900 pF
3000	min.	_	-	_	10 pF	10 pF	10 pF	10 pF	10 pF	100 pF
3000	max.	-	-	-	120 pF	330 pF	820 pF	1000 pF	1200 pF	2700 pF
4000	min.	_	_	-	10 pF	10 pF	10 pF	10 pF	10 pF	100 pF
4000	max.	-	-	-	47 pF	150 pF	330 pF	470 pF	560 pF	1200 pF
5000	min.	_	_	_	_	_	_	10 pF	10 pF	10 pF
3000	max.	_	-	_	_	_	_	220 pF	270 pF	820 pF

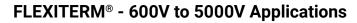
X7R Dielectric

Performance Characteristics

Capacitance Range	10 pF to 0.56 μF (25°C, 1.0 ±0.2 Vrms at 1kHz)
Capacitance Tolerances	±10%; ±20%; +80%, -20%
Dissipation Factor	2.5% max. (+25°C, 1.0 ±0.2 Vrms, 1kHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	±15% (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K M Ω min. or 1000 M Ω - μF min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K MΩ min. or 100 MΩ - μF min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

HIGH VOLTAGE X7R MAXIMUM CAPACITANCE VALUES

VOLTA	AGE	0805	1206	1210	1808	1812	1825	2220	2225	3640
600/630	min.	100 pF	1000 pF	1000 pF	1000 pF	1000 pF	0.010 μF	0.010 µF	0.010 μF	0.010 μF
000/030	max.	6800 pF	0.022 μF	0.056 μF	0.068 μF	0.120 μF	0.390 μF	0.270 µF	0.330 μF	0.560 μF
1000	min.	100 pF	100 pF	1000 pF	1000 pF	1000 pF	1000 pF	1000 pF	1000 pF	0.010 µF
1000	max.	1500 pF	6800 pF	0.015 μF	0.018 μF	0.039 μF	0.100 μF	0.120 µF	0.150 μF	0.220 µF
1500	min.	_	100 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF	1000 pF
1500	max.	_	2700 pF	5600 pF	6800 pF	0.015 µF	0.056 µF	0.056 µF	0.068 µF	0.100 µF
2000	min.	-	10 pF	100 pF	100 pF	100 pF	100 pF	1000 pF	1000 pF	1000 pF
2000	max.	_	1500 pF	3300 pF	3300 pF	8200 pF	0.022 µF	0.027 µF	0.033 µF	0.027 µF
2500	min.	_	-	-	10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF
2500	max.	_	_	_	2200 pF	5600 pF	0.015 μF	0.018 µF	0.022 μF	0.022 µF
3000	min.	_	-	-	10 pF	10 pF	100 pF	100 pF	100 pF	1000 pF
3000	max.	_	_	_	1800 pF	3900 pF	0.010 μF	0.012 µF	0.015 μF	0.018 µF
4000	min.	_	-	-	-	-	-	-	-	100 pF
4000	max.	_	_	_	_	_	_	_	_	6800 pF
5000	min.	_	_	-	_	_	_	-	_	100 pF
3000	max.	_	_	_	_	_	_	_	_	3300 pF







High value, low leakage and small size are difficult parameters to obtain in capacitors for high voltage systems. KYOCERA AVX special high voltage MLC chips capacitors meet these performance characteristics and are designed for applications such as snubbers in high frequency power converters, resonators in SMPS, and high voltage coupling/DC blocking. These high voltage chip designs exhibit low ESRs at high frequencies.

To make high voltage chips, larger physical sizes than are normally encountered are necessary. These larger sizes require that special precautions be taken in applying these chips in surface mount assemblies. In response to this, and to follow from the success of the FLEXITERM® range of low voltage parts, KYOCERA AVX is delighted to offer a FLEXITERM® high voltage range of capacitors, FLEXITERM®.

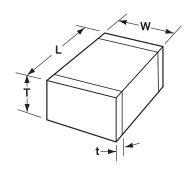
The FLEXITERM® layer is designed to enhance the mechanical flexure and temperature cycling performance of a standard ceramic capacitor, giving customers a solution where board flexure or temperature cycle damage are concerns.

HOW TO ORDER

1808	A T	<u>c</u> T	<u>272</u>	<u>K</u>	<u>A</u>	Z 	2	<u>A</u>
Style 0805 1206 1210 1808 1812 1825 2220 2225 ****	Voltage 600V/630V = C 1000V = A 1500V = S 2000V = G 2500V = W 3000V = H 4000V = J 5000V = K	Temperature Coefficient COG = A X7R = C	Capacitance Code (2 significant digits + no. of zeros) Examples: 10 pF = 100 100 pF = 101 1,000 pF = 102 22,000 pF = 223 220,000 pF = 224 1 μF =105	Capacitance Tolerance COG: J = ±5% K = ±10% M = ±20% X7R: K = ±10% M = ±20% Z = +80%, -20%	Test Level	Termination* Z=FLEXITERM® 100% Tin (RoHS Compliant)	Packaging 2 = 7" Reel 4 = 13" Reel	Special Code A = Standard

Notes: Capacitors with X7R dielectrics are not intended for applications across AC supply mains or AC line filtering with polarity reversal. Contact plant for recommendations. Contact factory for availability of Termination and Tolerance options for Specific Part Numbers.

^{***} KYOCERA AVX offers nonstandard chip sizes. Contact factory for details.





DIMENSIONS millimeters (inches)

SIZE	0805	1206	1210*	1808*	1812*	1825*	2220*	2225*
(L) Length	2.10 ± 0.20 (0.083 ± 0.008)	3.30 ± 0.30 (0.130 ± 0.012)	3.30 ± 0.40 (0.130 ± 0.016)	4.60 ± 0.50 (0.181 ± 0.020)	4.60 ± 0.50 (0.181 ± 0.020)	4.60 ± 0.50 (0.181 ± 0.020)	5.70 ± 0.50 (0.224 ± 0.020)	5.70 ± 0.50 (0.224 ± 0.020)
(W) Width	1.25 ± 0.20 (0.049 ±0.008)	$1.60^{+0.30}_{-0.10}$ $(0.063^{+0.012}_{-0.004})$	2.50 ± 0.30 (0.098 ± 0.012)	2.00 ± 0.20 (0.079 ± 0.008)	3.20 ± 0.30 (0.126 ± 0.012)	6.30 ± 0.40 (0.248 ± 0.016)	5.00 ± 0.40 (0.197 ± 0.016)	6.30 ± 0.40 (0.248 ± 0.016)
(T) Thickness Ma	1.35 (0.053)	1.80 (0.071)	2.80 (0.110)	2.20 (0.087)	2.80 (0.110)	3.40 (0.134)	3.40 (0.134)	3.40 (0.134)
(t) terminal mi	/	0.60 ± 0.20 (0.024 ± 0.008)	0.75 ± 0.35 (0.030 ± 0.014)	0.75 ± 0.35 (0.030 ± 0.014)	0.75 ± 0.35 (0.030 ± 0.014)	0.75 ± 0.35 (0.030 ± 0.014)	0.85 ± 0.35 (0.033 ± 0.014)	0.85 ± 0.35 (0.033 ± 0.014)

^{*}Reflow Soldering Only



Performance of SMPS capacitors can be simulated by downloading SpiCalci software program - http://www.avx.com/SpiApps/default.asp#spicalci Custom values, ratings and configurations are also available.

FLEXITERM® - 600V to 5000V Applications

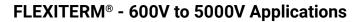


NP0 (COG) Dielectric Performance Characteristics

Capacitance Range	10 pF to 0.100 μF (+25°C, 1.0 ±0.2 Vrms, 1kHz)
Capacitance Tolerances	±5%, ±10%, ±20%
Dissipation Factor	0.1% max. (+25°C, 1.0 ±0.2 Vrms, 1kHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	0 ±30 ppm/°C (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K MΩ min. or 1000 MΩ - μF min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K MΩ min. or 100 MΩ - μF min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

NPO (COG) CAPACITANCE RANGE PREFERRED SIZES ARE SHADED

Case Size		0805				1206					1210			ı			18	808			1812 Reflow Only								
Soldering	Re	flow/W	lave		Ref	low/W					flow O	nly					Reflo												
(L) Length mm (in.)		2.10 ± 0. 083 ± 0.				.30 ± 0. 30 ± 0.					30 ± 0.4 30 ± 0.0							± 0.50 ± 0.020))						4.60 ± 0.181 ±)		
W) Width mm	1	.25 ± 0.	20		1.60	± 0.30	/-0.10	4)		2.	50 ± 0.0 98 ± 0.0	30					2.00:	± 0.20 ± 0.008							3.20 ±	₹ 0.30			
(T) Thickness (in.)	(0.	049 ± 0. 1.35		<u> </u>	(0.063 :	1.80		4)			2.80						2.	20)						0.126 ± 2.8	80)		
(III.)	-	(0.053) 0.50 ± 0.) 20			(0.071 .60 ± 0.					(0.110) 75 ± 0.:			-				087) ± 0.35							(0.1 0.75 ±				
(t) Ferminal max	(0.	020 ± 0.	008)		(0.0	24 ± 0.	(800.			(0.0	30 ± 0.0	014)					0.030 :	± 0.014							$0.030 \pm$	0.014			
Voltage (V) Cap (pF) 1.5 1R		630	1000	600	630	1000	1500	2000	600	630	1000	1500	2000	600	630	1000	1500	2000	2500	3000	4000	600	630	1000	1500	2000	2500	3000	4000
1.8 1R		A		X	X	X	X	X																					
2.2 2R		Α		Х	Х	Х	Х	Х																					
2.7 2R 3.3 3R		A		X	X	X	X	X						├		C	C	C	C	C									
3.9 3R	9 A	Α		Х	Х	Х	Х	Х								C	С	C	С	С									
4.7 4R 5.6 5R		A		X	X	X	X	X						<u> </u>		C	C	C	C	C				-					
6.8 6R		A		X	X	X	X	X						 		C	C	C	C	C									
8.2 8R	2 A	Α		Х	Х	Х	Χ	Х								С	С	С	С	С									
10 10 12 12		A	A	X	X	X	X	X	C	C	D D	D D	D D	C	C	C	C	C	C	C	C	C	C	C	C	C	C	C	F
15 15	0 A	Α	Α	Х	Х	Х	Х	Х	С	С	D	D	D	С	С	С	С	С	С	С	С	С	С	С	С	С	С	С	E
18 18 22 22		A	A	X	X	X	X	X	O O	C	D D	D D	D D	С	С	C	C	C	C	C	C	C	C	C	C	C	C	С	E
27 27		A	A	X	X	X	X	X	C	C	D	D	D	C	C	C	C	C	C	C	C	C	C	C	C	C	C	C	E
33 33		Α	Α	X	X	X	D	D	С	С	D	D	D	С	С	С	С	С	С	С	С	С	С	С	С	С	С	С	E
39 39 47 47		A	A	X	X	X M	D D	D D	C	C	D D	D D	D D	C	C	C	C	C	C	C	C	C	C	C	C	C	C	C C	E
56 56		Α	Α	X	X	М	С	С	С	С	D	С	С	С	С	С	С	С	С	С	Ŭ	С	С	С	С	С	С	С	F
68 68		A X	A X	X	X	M C	C	C	C	C	D D	C	C	C	C	C	C	C	C	C		C	C	C	C	C	C	C C	F
82 82 100 10		X	X	X	X	C	C	C	C	C	С	C	С	C	C	C	C	C	F	F		C	C	C	C	C	C	С	F
120 12		С	С	Х	Х	С	Е	Е	С	С	С	С	С	С	С	С	С	С	F	F		С	С	С	С	С	С	С	G
150 15 180 18		C	C	X	X	C E	E	E	C	C	C E	E	E	C	C	C	F	F	F	F		C	C	C	C	C	C F	C F	G
220 22		C		X	X	E	E	E	С	С	E	E	E	C	C	C	F	F	F	F		C	C	C	С	C	F	F	
270 27 330 33		С		С	С	E	E	E	С	С	E	E	E	С	С	C F	F	F	F	F		С	С	С	C	C F	F	F	
330 33 390 39		C		C	C	E	E	E	C	C	E	E	E	C	C	F	F	F	F	F		C	C	C	F	F	F	F	
470 47	1 C	С		C	С	Е	Е	Е	С	С	Е	Е	Е	С	С	F	F	F	F	F		С	С	F	F	F	F	F	
560 56 680 68		C		C	C	E F			C	C	E F	E F	E F	C	C	F	F	F				C	C	F	F	F	F G	F G	
750 75		C		E	E	E			С	С	E	G	G	C	C	F	F	F				C	C	F	F	F	G	G	
820 82		С		E E	E	E			С	C	E	G	G	C C	C	F	E	E F				C C	C	F	F	F	G	G	
1000 10: 1200 12:		1		E	E	E			C	C	E			E	E	F	E	E	_			C	C	F	E	E	G	G	
1500 15				Е	Е				С	С	G			Е	Е	F						С	С	F	F	F			
1800 18 2200 22				E	E				C E	C E	G			E	E	F						C	C	F E	F G	F G			
2700 27	2			Е	Е				Е	Е				E	Е							С	С	Е	G	G			
3300 33 3900 39				Е	Е				E F	E F				E F	E F							C	C	F					
4700 47									E	E				E	E							С	C	G					
5600 56	2								Е	Е				Е	Е							С	C						
6800 68 8200 82		+	-	 	\vdash	-	-	-	-	-	-			F	F		-	-	-	-	-	C F	C E	-			-	-	\vdash
Cap (µF) 0.010 10		1			1																	E	E						
0.012 12	3																					F	F						
0.015 15	_																					G	G						
0.018 18	-	1																				G	G						
0.022 22	-	1			1									<u> </u>							-								
0.033 33	_	+		<u> </u>	\vdash		-							 	-			-	-	-	-	-		-					_
0.047 473	_	+-		 	\vdash		-	-	<u> </u>	-				\vdash		-			-	-	-	-	-	-					-
0.068 68	_	+		 	 		1		-	-				\vdash					1	1				1					
0.100 10	_	1			<u> </u>																								
Voltage (V)	600		1000	600	630			2000	600	630		1500	2000	600	630	1000			2500	3000	4000	600	630	1000			2500	3000	4000
Case Size		0805				1206					1210						18	808							18	12			

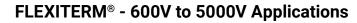




NPO (COG) CAPACITANCE RANGE PREFERRED SIZES ARE SHADED

Case Size				1	825				2220 Reflow Only											2225									
Soldering				Refle	ow Only	y						R	eflow (Only							Re	eflow (Only						
(L) Length mm (in.)					± 0.50								.70 ± 0									.72 ± 0							
mm					± 0.02				-				.00 ± 0									.35 ± 0							
W) Width (in.)				(0.248	± 0.01								197 ± 0	0.016)								50 ± 0	.010)						
(T) Thickness mm (in.)					3.40 .134)								3.40 (0.134									3.40 (0.134							
(t) Terminal mm max					± 0.35				0.85 ± 0.35 (0.033 ± 0.014)												0.	.85 ± 0							
Voltage (V)	600	630	1000			2500	3000	4000	600	630	1000				3000	4000	5000	600	630	1000	1500	2000	2500	3000	4000	5000			
Cap (pF) 1.5 1R5																													
1.8 1R8 2.2 2R2									_																				
2.7 2R7									 									- 											
3.3 3R3																													
3.9 3R9 4.7 4R7									-														-						
5.6 5R6																													
6.8 6R8																													
8.2 8R2 10 100	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	F	F			
12 120	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	Ė	E	E	E	E	E	E	F	F			
15 150	Е	Е	Е	Е	Е	E	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	F	F			
18 180 22 220	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F			
27 270	Ē	E	Ē	Ē	Ē	Ē	E	E	Ē	Ē	Ē	E	Ē	Ē	E	E	E	Ē	E	Ē	E	Ē	Ē	E	F	F			
33 330	Е	Е	E	E	E	E	Е	E	Ε	E	E	E	E	E	E	E	E	Е	Е	E	Е	E	E	E	F	F			
39 390 47 470	E	E	E	E	E	E	E	E F	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F G			
56 560	E	E	E	E	E	E	E	F	E	E	E	E	E	E	E	E	E	Е	E	E	E	E	E	E	F	G			
68 680	Е	E	E	E	E	E	E	F	E	E	E	E	E	E	E	E	E	Е	E	E	E	E	E	E	F	G			
82 820 100 101	E	E	E	E	E	E	E	F	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	E	F G	G G			
120 121	E	Е	E	Е	E	E	Е	F	E	E	E	E	Е	E	Е	E	Е	E E E E E E							G	G			
150 151 180 181	E	E	E	E	E	E	E	F	E	E	E	E	E	E	E	E F	E F	E	E	E	E	E	E	E	G	G			
180 181 220 221	E	E	E	E	E	E	E	F	E	E	E	E	E	E	E	F	F	E	E	E	E	E	E	E	G G	G G			
270 271	Е	Е	Е	Е	Е	Е	Е	F	Е	Е	Е	Е	Е	Е	Е			Е	Е	Е	Е	Е	Е	Е	G	G			
330 331 390 391	E	E	E	E	E	E	E	F	E	E	E	E	E	E	E			E	E	E	E	E	E	E	G G				
470 471	E	E	Ē	Ē	Ē	Ē	E		Ē	Ē	Ē	E	Ē	Ē	E			Ē	E	Ē	E	Ē	Ē	E	G				
560 561	Е	Е	E	E	E	E	E		E	E	E	E	E	E	Е			Е	Е	Е	Е	E	Е	E	G				
680 681 750 751	E	E	E	E	E	F	F		E	E	E	E	E	F	F			E	E	E	E	E	E	E					
820 821	Ē	E	Ē	Е	Ē	F	F		E	Ē	Ē	Ē	Е	F	F			Е	E	Е	Е	Е	F	Е					
1000 102	E	E	E	E	E	F	F		E	E	E	E	E	F	F			E	E	E	E	E	E	E					
1200 122 1500 152	E	E	E	E F	E F	G G	G G		E	E	E	E F	E F	G G	G			E	E	E	E	E	F	F					
1800 182	Ε	Е	Е	F	F	G	G		Е	Е	Е	F	F	G	G			Е	Е	Е	Е	Е	G	G					
2200 222 2700 272	E	E	E	G G	G G				E	E	E	G G	G G					E	E	E	E F	E F							
3300 332	E	E	Ē	G	G				Ē	Ē	Ē	G	G					Ē	E	Ē	F	F							
3900 392	Е	Е	Е	G	G				Е	Е	Е	G	G					E E E G G											
4700 472 5600 562	E F	E F	E F	G	G G				E F	E F	E F	G	G					F	F	F	G	G							
6800 682	F	F	F						F	F	F							F	F	F	G	G							
8200 822	G	G	G						G	G	G							G	G	G									
Cap (μF) 0.010 103 0.012 123									\vdash									G G	G	G G									
0.012 123																		G	G	G									
0.018 183																		G	G	G									
0.022 223 0.033 333				-					<u> </u>									G G	G	G G									
0.033 333									\vdash									G	G	G									
0.056 563																		G	G	G									
0.068 683 0.100 104																		G	G	G			-						
Voltage (V)	600	630	1000			2500	3000	4000	600	630	1000	1500	2000	2500	3000	4000	5000			1000	1500			3000	4000	5000			
Case Size				1	825								2220)								2225)						

Letter	Α	С	E	F	G	Х
Max.	0.813	1.448	1.803	2.210	2.794	0.940
Thickness	(0.032)	(0.057)	(0.071)	(0.087)	(0.110)	(0.037)





X7R Dielectric

Performance Characteristics

Capacitance Range	10 pF to 0.82 μF (25°C, 1.0 ±0.2 Vrms at 1kHz)
Capacitance Tolerances	±10%; ±20%; +80%, -20%
Dissipation Factor	2.5% max. (+25°C, 1.0 ±0.2 Vrms, 1kHz)
Operating Temperature Range	-55°C to +125°C
Temperature Characteristic	±15% (0 VDC)
Voltage Ratings	600, 630, 1000, 1500, 2000, 2500, 3000, 4000 & 5000 VDC (+125°C)
Insulation Resistance (+25°C, at 500 VDC)	100K MΩ min. or 1000 MΩ - μF min., whichever is less
Insulation Resistance (+125°C, at 500 VDC)	10K MΩ min. or 100 MΩ - μF min., whichever is less
Dielectric Strength	Minimum 120% rated voltage for 5 seconds at 50 mA max. current

X7R CAPACITANCE RANGE PREFERRED SIZES ARE SHADED

Case Size	e I		0805				1206			1210 1808 Reflow Only Reflow Only Reflow Only Reflow Only Reflow O										1812 Reflow Only											
Soldering			low/W				low/W	lave			Ret	flow 0	nly					Reflo	w Only	,						Reflov	v Only				
(L) Longth	nm ìn.)	2	2.10 0.2 83 ± 0.0	0		3.	30 ± 0. 30 ± 0.	30			3	.30 0.4 130 0.0	0					4.60	± 0.50 ± 0.020							4.60 ± 0.181 ±	0.50)			
W) Width	nm in.)	1	.25 0.2 49 ± 0.0	.0	(+0.30/	-0.10	1)		2	.50 0.3 098 0.0	0					2.00	0.20 ± 0.008							3.20 ± 0.126 ±	0.30				
(T) Thickness 1	nm in.)		1.35 (0.053)		, T		1.80 (0.071		,			2.80 (0.110)					,	2.	20 20 087)	,						2.8	30	,			
(t) Terminal	nm nax	0.	50 ± 0.2 20 ± 0.0	20		0.	60 ± 0. 24 ± 0.	20			0	.75 0.3 30 ± 0.0	5				(0.75	± 0.35 ± 0.014	1)						0.75 ±	0.35)			
Voltage (V)	· iux		630		600		1000		2000	600		1000		2000	600	630			2000		3000	4000	600	630		1500			3000	4000	
Cap (pF) 100	101	Х	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е																	
120	121	Χ	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е																	
150	151	Χ	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е																	
180	181	Χ	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е																	
220	221	Х	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е																	
270	271	Х	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е									Е	Е	Е	Е	Е			_	
330	331	Х	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	F		Е	Е	Е	Е	Е			_	
390	391	Х	Х	С	С	С	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	E	Е	Е	Е	F		Е	E	Е	Е	Е				
470	471	Х	Х	С	С	С	E	E	E	E	E	E	E	E	Е	E	E	E	E	E	F		E	E	E	E	E	E	E		
560	561	X	X	C	С	C	E	E E	E	E E	E E	E	E	E E	E E	E	E E	E	E E	F	F		E E	E	E E	E	E	E F	E F		
680	681	X	_	_	С		_		_	_	_	E	_	-	_		_	_	_	_	_		_	_	_	_	_	_	_	_	
750 820	751 821	X	X	C	C	C	E	E	E	E	E	E	E	E	E E	E	E	E F	E	F	F		E E	E	E	E	E	F	F		
1000	102	X	X	С	С	С	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F		E	E	E	E	E	F	F		
1200	102	X	X	С	С	С	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F		F	F	F	F	F	F	F	_	
1500	152	X	X	С	С	С	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F		F	F	F	F	F	G	G		
1800	182	X	X		С	С	E	E	E	E	E	E	E	E	E	E	E	E	E	F	F		F	F	F	F	F	G	G		
2200	222	X	X		С	С	E	E	E	E	E	E	F	E	E	E	E	F	F	F	•		F	F	F	F	F	G	G		
2700	272	X	Х		С	С	E	E	_	E	E	E	F	E	E	E	E	F	F				F	F	F	F	F	G	G		
3300	332	X	X		С	С	E	_		E	E	E	F	E	E	E	E	F	F				F	F	F	F	F	G	G		
3900	392	Х	Х		С	С	E			E	E	E	G		E	E	E	F					F	F	F	F	F	G	G		
4700	472	Х	Х		С	С	Е			Е	Е	Е	G		Е	Е	Е	F					F	F	F	F	F	G	G		
5600	562	Х	Х		С	С	Е			Е	Е	Е	G		Е	Е	Е	F					F	F	F	G	G				
6800	682	Х	Х		С	С	Е			Е	Е	Е			Е	Е	Е	F					F	F	F	G	G				
8200	822	Χ	Х		С	С	Е			Е	Е	Е			Е	Е	Е						F	F	Е	G	G				
Cap (µF) 0.010	103	С	С		С	С	Е			Е	Е	Е			Е	Е	Е						F	F	F	G	G				
0.015	153	С	С		Е	Е	Е			Е	Е	Е			F	F	F						F	F	F	G					
0.018	183	С	С		Е	Е				Е	Е	Е			F	F	F						F	F	G						
0.022	223	С	С		Е	Е				Е	Е	Е			F	F	F						F	F	G						
0.027	273				Е	Е				Е	Е				F	F							F	F	G						
0.033	333				Е	Е				Е	Е				F	F							F	F	G						
0.039	393		ļ							E	Е				F	F			-		-		F	F	G					ļ	
0.047	473				<u> </u>					E	E				F	F		-		-			F	F	G						
0.056	563		-		<u> </u>	<u> </u>				F	F			\vdash	F	F		-	-	-	<u> </u>		F	F				_		<u> </u>	
0.068	683 823		-		 		-		-	F	F F			\vdash	F	F		-	1	-	1		F	F		-		-		-	
0.100	104		-			-		-		F	F		_	\vdash				 		-	-		F	F			_			-	
0.100	154		1		-	-					F			\vdash	_					+			G	G						-	
0.130	224		 		-	\vdash		-						\vdash						 			G	G							
0.270	274					\vdash				\vdash				\vdash	<u> </u>									-							
0.330	334				l -					\vdash				\vdash						\vdash											
0.390	394				 					\vdash				\vdash	<u> </u>																
0.470	474													\vdash						t											
0.560	564													\vdash																	
0.680	684				1																										
0.820	824																														
1.000	105		L															L	L	L	L				L					L	
Voltage (V)			630		600	630			2000	600				2000	600	630	1000			2500	3000	4000	600	630	1000			2500	3000	4000	
Case Size	9		0805				1206					1210						18	808							18	12				





X7R CAPACITANCE RANGE PREFERRED SIZES ARE SHADED

Case Size				18	25				2220 Reflow Only										2225 Reflow Only								3640									
Soldering				Reflo																							Reflow Only 9.14 ± 0.25									
(L) Length mm			(0.50 0.020)							70 0.5 24 0.0									72 ± 0 25 ± 0									360 ± 0					
W) Width mm				6.30	0.40							5.	00 0.4	10								35 ± 0								5	.72 ± 0	.25				
(in.)			(().248 : 3.	± 0.01	6)						(0.1	97 0.0 3.40	116)							(0.2	50 ± 0 2.54								(0.2	225 ± 0 2.54	.010)				
Thickness (in.)				(0.1									0.134)								2.54 (0.100)									(0.100)				
(t) Terminal mm					0.35								85 0.3									35 ± 0									76 (0.0					
·· max	600	1			± 0.01		Loono	14000	600	600	1000		3 ± 0.		Ioooo	14000	Leono	600		Iaooo			0.014)	loooo	14000	L 5000	600	1 600	11000		.52 (0.0		Loono	14000	15000	
Voltage (V) Cap (pF) 100 101	600	630	1000	1500	2000	2500	3000	4000	600	630	1000	1500	2000	2500	3000	4000	5000	600	630	1000	1500	2000	2500	3000	4000	5000	600	630	1000	1500	2000	2500	3000	4000	5000	
120 121									\neg																								—	 	\vdash	
150 151		\vdash																															\vdash		\vdash	
180 181																																			\Box	
220 221																																				
270 271																																				
330 331																																		<u> </u>		
390 391	_	_	_	_	_	<u> </u>	<u> </u>	\sqcup	_								Щ					<u> </u>	_		_		<u> </u>	_	_	1	_		ـــــ	Ь—	oxdot	
470 471	_	1				-	-	\vdash	_								Щ					<u> </u>	_				<u> </u>	-	-	1	-		Ь—	<u> </u>	+	
560 561 680 681	-	-	\vdash	_	_	-	-	\vdash	-					-		-	\vdash		-			\vdash	\vdash	-	-		<u> </u>	\vdash	-	+	\vdash		\vdash	\vdash	+-	
680 681 750 751	\vdash	\vdash	\vdash	\vdash	\vdash	\vdash	\vdash	\vdash	\dashv				\vdash	\vdash			\vdash		\vdash			\vdash	\vdash		\vdash		\vdash	\vdash	\vdash	+	\vdash		\vdash	\vdash	+-	
750 751 820 821		1	<u> </u>	<u> </u>	<u> </u>	1	1	++	-								\vdash		<u> </u>						<u> </u>		┢	<u> </u>	1	+	<u> </u>		\vdash	\vdash	+	
1000 102	F	F	F	F	F	F	F		F	F	F	F	F	F	G		\vdash	F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G	
1200 122	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G	
1500 152	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G	
1800 182	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G	
2200 222	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G	
2700 272	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G	
3300 332	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G	G	
3900 392	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G		
4700 472	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G		
5600 562	F	F	F	F	F	F	F		F	F	F	F	F	F	G			F	F	F	F	F	F	F			G	G	G	G	G	G	G	G		
6800 682	F	F	F	G	G	G	G		F	F	F	F	F	G	G			F	F	F	F	F	G	G			G	G	G	G	G	G	G	G	<u> </u>	
8200 822	F	F	F	G	G	G	G		F	F	F	G	G	G	G			F	F	F	F	F	G	G			G	G	G	G	G	G	G	<u> </u>	\sqcup	
Cap (µF) 0.010 103	F	F	F	G	G	G	G		F	F	F	G	G	G	G			F	F	F	F	F	G	G			G	G	G	G	G	G	G	<u> </u>	\vdash	
0.015 153	F	F	F	G	G	G			F	F	F	G	G	G				F	F	F	G	G	G	G			G	G	G	G	G	G	G	<u> </u>	\vdash	
0.018 183	1	F	F	G	G	_	-		_		F	G	G	G			\vdash	_		F	G	G	G				G	G	G	G	G	G	G	—	\vdash	
0.022 223	F	F	F	G	G	-	_		F	F	F	G	G			-		F	F	F	G	G	G				G	G	G	G	G	G	₩	<u> </u>	+-	
0.027 273	F	F	F	G	—	-	-	\vdash	F	F	F	G	G	-			\vdash	F	F	F	G	G	_		<u> </u>	\vdash	G	G	G	G	G		₩	\vdash	+-	
0.033 333	F	F	F	G	_	-	-		F	F	F	G				-	\vdash	F	F	F	G	G		-	-		G G	G	G	G			\vdash	\vdash	+-	
0.039 393 0.047 473	F	F	F	G P		-	-	\vdash	F	F	F	G G		-				F	F	F	G		-				G	G	G G	G			\vdash	\vdash	+-	
0.047 473 0.056 563	-	F	-	G		-	-		-	F	F	G		 			\vdash	F	F	F	G		<u> </u>		<u> </u>	\vdash	G	G	G	G			\vdash	\vdash	+-	
0.068 683	F	F	G	-		1	1		F	F	G	9					\vdash	F	F	F	G		\vdash		\vdash	\vdash	G	G	G	G			\vdash	\vdash	\vdash	
0.082 823	E	F	G			-	-		F	F	G			 				F	F	G	- 0						G	G					\vdash	\vdash	\vdash	
0.100 104	E	F	G			 	 		F	F	G			 				F	F	G							G	G		1			\vdash	\vdash	\vdash	
0.150 154	F	F	-			 	 		F	F	G						H	F	F	G							G	G		1			\vdash	\vdash	\vdash	
0.220 224	F	F				t	t		F	F	G		\vdash					F	F			\vdash					G	G		+			\vdash	\vdash	+	
0.270 274	F	F							F	F								F	F								G	G							\vdash	
0.330 334	F	F				İ	İ		F	F								F	F								G	G								
0.390 394	F	F							F	F								F	F								G	G								
0.470 474	F	F							F	F								F	F								G	G								
0.560 564	G	G						\sqcup	G	G							Ш	F	F							$oxed{oxed}$	G	G					ullet	$ldsymbol{ldsymbol{ldsymbol{eta}}}$	\sqcup	
0.680 684	_	<u> </u>							G	G							Щ	G	G								L			1			↓	<u> </u>	oxdot	
0.820 824	_	1	_	_	_	-	-	\Box	G	G			_	_	_		\sqcup	G	G			_	-		_	\vdash	⊢	-	_	1	-		—	₩	\sqcup	
1.000 105 Voltage (V)	600	630	1000	1500	2000	2500	3000	4000	G 600	G 630	1000	1500	2000	2500	3000	4000	5000	G 600	G 630	1000	1500	2000	2500	3000	4000	5000	600	630	1000	1500	2000	2500	3000	4000	5000	
Case Size	000	1 030	1000		25	12300	10000	14000	JUU	030	1000		2220		10000	1 4 000	3000	000	030	1000		2225		13000	14000	3000	000	030	1000	1300	3640		13000	4000	1 3000	
													0																					_		

l	Letter	Α	С	Е	F	G	Р	Х
	Max.	0.813	1.448	1.8034	2.2098	2.794	3.048	0.940
	Thickness	(0.032)	(0.057)	(0.071)	(0.087)	(0.110)	(0.120)	(0.037)



High Voltage MLC Chip Capacitors



For 600V to 3000V Automotive Applications - AEC-Q200





Modern automotive electronics could require components capable to work with high voltage (e.g. xenon lamp circuits or power converters in hybrid cards). KYOCERA AVX offers high voltage ceramic capacitors qualified according to AEC-Q200 standard.

High value, low leakage and small size are diffocult parameters to obtain in cpacitors for high voltage systems. KYOCERA AVX special hgih voltage MLC chip capacitors meet these performance characteristics and are designed for applications such as snubbers in high frequency power converters, resonators in SMPS, and high voltage coupling/dc blocking. These high voltage chip designs exhibit low ESRs at high frequencies.

Due to high voltage nature, larger physical dimensions are necessary. These larger sizes require special precautions to be taken in applying of MLC chips. The temperature gradient during heating or cooling cycles should not exceed 4°C per second. The preheat temperature must be within 50°C of the peak temperature reached by the ceramic bodies through the soldering process. Chip sizes 1210 and larger should be reflow soldered only. Capacitors may require protective surface coating to prevent external arcing.

To improve mechanical and thermal resistance, KYOCERA AVX recommend to use flexible terminations system - FLEXITERM®.

HOW TO ORDER

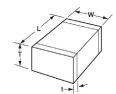
1210	С	С	223	K	4	Т	2	Α
\top	T	Τ		T	\top	T	T	T
Size	Voltage	Dielectric	Capacitance	Capacitance	Failure Rate	Terminations	Packaging	Special Code
1206	C = 630V	X7R = C	Code	Tolerance	4 = Automotive	T = Plated Ni and Sn	2 = 7" Reel	A = Std. Product
1210	A = 1000V		2 Sig. Digits +	K = ±10%		Z = FLEXITERM®	4 = 13" Reel	
1808	S = 1500V		Number of Zeros	M = ±20%				
1812	G = 2000V		e.g. 103 = 10nF					
2220	W = 2500V		(223 = 22nF)					
	H = 3000V		, ,					

^{*}KYOCERA AVX offers nonstandard case size. Contact factory for details.

Notes: Capacitors with X7R dielectrics are not indeded for applications across AC supply mains or AC line filtering with polarity reversal. Please contact KYOCERA AVX for recommendations

CHIP DIMENSIONS DESCRIPTION

(SEE CAPACITANCE RANGE CHART ON PAGE 128)



L = Length W = Width T = Thickness t = Terminal

X7R DIELECTRIC PERFORMANCE CHARACTERISTICS

Parameter/Test	Specification Limits	Measuring Conditions		
Operating Temperature Range	-55°C to +125°C	Temperature Cycle Chamber		
Capacitance	within specified tolerance	Freq.: 1kHz ±10%		
Dissipation Factor	2.5% max.	Voltage: 1.0Vrm s ±0.2Vrms		
Capacitance Tolerance	±5% (J), ±10% (K), ±20% (M)	T = +25°C, V = 0Vdc		
Temperature Characteristics	X7R = ±15%	Vdc = 0V, T = (-55°C to +125°C)		
Insulation Resistance	100GΩ min. or 1000MΩ • μF min. (whichever is less) 10GΩ min. or 100MΩ • μF min. (whichever is less)	T = +25°C, V = 500Vdc T = +125°C, V = 500Vdc (t ≥ 120 sec, I ≤ 50mA)		
Dielectric Strength	No breakdown or visual defect	120% of rated voltage t ≤ 5 sec, l ≤ 50mA		

High Voltage MLC Chips FLEXITERM®



For 600V to 3000V Automotive Applications - AEC-Q200

X7R CAPACITANCE RANGE PREFERRED SIZES ARE SHADED

Case Siz	ze l			1206	,			12	10				18	808					18	12					2220		
Solderin			Ref	low/W				Reflow		e				w Only						v Only					flow 0	nly	
(L) Length	mm			.2 ± 0					± 0.2			4.57 ± 0.25						± 0.3					5.7 ± 0.				
(L) Length	(in.)			26 ± 0			(0	0.126 :		8)			<u> </u>	± 0.01))			(0		± 0.012	2)				224 ± 0		
W) Width	mm			.6 ± 0			,,		± 0.2	٥)			2.03 :					,,		± 0.2	2)				5 ± 0.4		
,	(in.)			53 ± 0.5 5 ± 0.5			((0.098 :		8)		(0.08 ± 0.01) 0.61 ± 0.36			(0.126 ± 0.008) 0.61 ± 0.36				(0.197 ± 0.016) 0.64 ± 0.39								
(t) Terminal	mm max			5 ± 0 02 ± 0.				0.5 ± 0.25 (0.02 ± 0.01)		ł			± 0.36 ± 0.01	4)			((± 0.36 ± 0.014	4)				04 ± 0. 25 ± 0.			
Voltage (630			2000	2500					630					3000	630					3000	630				3000
Cap (pF) 101	100	C	E	E	E	E	030	1000	1300	2000	030	1000	1300	2000	2300	3000	030	1000	1300	2000	2300	3000	030	1000	1300	2000	3000
121	120	C	E	E	E	E																			<u> </u>		
151	150	C	E	E	E	E																					
181	180	С	Е	Е	Е	Е																					
221	220	С	Е	Е	Е	Е					Е	Е	Е	Е	Е	Е											
271	270	С	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е											
331	330	С	Е	Е	E	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	F	Е										
391	390	С	Е	Е	E	Е	Е	Е	Е	Е	Е	Е	Е	Е	Е	F	Е										
471	470	С	Е	Е	E	Е	Е	Е	Е	Е	Е	Е	Е	Е	F	F	Е	Е	Е	Е	Е	Е					
561	560	С	E	Е	E	E	Е	Е	Е	E	E	E	E	E	F	F	Е	E	E	E	Е	E	<u> </u>			$\sqcup \sqcup$	
681	680	С	E	E	E	E	E	E	E	E	E	E	F	F	F	F	E	E	E	E	F	F	<u> </u>		-	$\vdash \vdash$	<u> </u>
821	820	C	Е	Е	E	Е	Е	Е	Е	E	E	E	F	F	F	F	Е	E	Е	E	F	F		Г			-
102 122	1000 1220	C	E	E	E	Е	E	E	E	E	Е	Е	F	F	F	F	E F	E F	E F	E F	F G	F	F	F	F	F	G
152	1500	С	E	E	E		E	E	E	E	-						F	F	F	F	G		F	F	F	F	G
182	1800	С	E	E	<u> </u>		E	E	E	E	-						F	F	F	F	G		F	F	F	F	G
222	2200	С	E	E			E	E	E	E							F	F	F	F	G		F	F	F	F	G
272	2700	C	E	E			E	E	E	E							F	F	F	F	U		F	F	F	F	
332		C	E				E	E	E	E							F	F	F	F			F	F	F	F	
392	3900	С	Е				Е	Е	Е								F	F	F	F			F	F	F	F	
472	4700	С	Е				Е	Е	Е								F	F	G	G			F	F	F	F	
562	5600	С	Е				Е	Е	Е								F	F	G	G			F	F	F	F	
682	6800	Е	Е				Е	Е									F	F	G	G			F	F	F	F	
822	8200	Е					Е	E									F	F	G	G			F	F	G	G	
103	0.01	Е					E	E									F	F	G				G	G	G	G	
123					-		E	E									F	F	G				G	G	G	G	
153							E	E			_						F	F	G				G	G	G	G	
183 223							E	Е			-						F	F					G G	G	G	G	
273							0				-						F	Г					G	G	G	G	
333							Q				 						F						G	G			
393					<u> </u>												F						G	G			
473																	Х						G	G			
563	0.056																						G	Υ			
683	0.068																						G	Υ			
823	0.082																						G	Υ			
104	0.1						<u> </u>				<u> </u>												G	Υ		\sqcup	
124	0.12									_	<u> </u>												G		<u> </u>		
154	0.15				-	-				-				_									G		-	$\vdash \vdash$	
224	0.22				_	-	 			-	 			_				_	_				<u> </u>		-	$\vdash \vdash$	_
334 474					+	-	 			-	-			-			-	-	-	-	-		<u> </u>	-	-	$\vdash \vdash$	-
684					 		\vdash				\vdash												\vdash		-	\vdash	
105					\vdash		\vdash				\vdash												\vdash			\vdash	
155					<u> </u>																					\vdash	
225					<u> </u>																						
335						1	Ì				Ì												i –		1		
475																											
106																											
226																											
WVDC		630	1000		2000	2500	630			2000	630	1000			2500	3000	630	1000			2500	3000	630	1000			3000
Size				1206				12	10				18	ng.					18	12					2220		

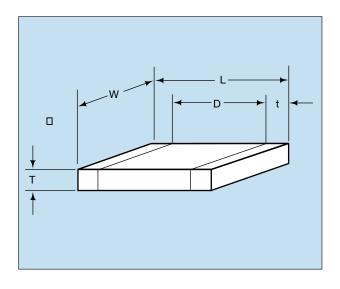
NOTE: Contact factory for non-specified capacitance values

Letter	Α	С	E	F	G	Q	Х	Υ
Max	0.813	1.448	1.8034	2.2098	2.794	1.78	2.29	2.54
Thickness	(0.032)	(0.057)	(0.071)	(0.087)	(0.110)	(0.07)	(0.09)	(0.1)



Part Number Example CDR01 thru CDR06





MILITARY DESIGNATION PER MIL-PRF-55681

Part Number Example CDR01 BP 101 В S M MIL Style Voltage-temperature Limits Capacitance Rated Voltage

Capacitance Tolerance

Termination Finish

Failure Rate

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

MIL Style: CDR01, CDR02, CDR03, CDR04, CDR05,

CDR06

Voltage Temperature Limits:

BP = 0 ± 30 ppm/°C without voltage; 0 ± 30 ppm/°C with rated voltage from -55°C to +125°C

BX = $\pm 15\%$ without voltage; $\pm 15 - 25\%$ with rated voltage from -55°C to +125°C

Capacitance: Two digit figures followed by multiplier (number of zeros to be added) e.g., 101 = 100 pF

Rated Voltage: A = 50V, B = 100V

Capacitance Tolerance: J ± 5%, K ± 10%, M ± 20%

Termination Finish:

M = Palladium silver

N = Silver-nickel-gold

S = Solder coated final with a minimum of 4 percent lead

T = Silver

Base metallization-barrier metal-solder coated (tin/lead alloy, with a minimum of 4 percent lead)

W = Base metallization-barrier metal-tinned (tin or tin/lead alloy)

Y = Base metallization-barrier metal-tin (100 percent)

Z = Base metallization-barrier metal-tinned (tin/lead alloy, with a minimum of 4 percent lead)

*See MIL-PRF-55681 Specification for more details

M = 1.0%, P = .1%, R = .01%, Failure Rate Level:

S = .001%

Packaging: Bulk is standard packaging. Tape and reel per RS481 is available upon request.

*Not RoHS Compliant

CROSS REFERENCE: MIL-PRF-55681/CDR01 THRU CDR06*

Per	Ctula	1 (1)	14/: Jal. (14/)	Thickr	ness (T)		D	Termination Band (t)		
MIL-PRF-55681	Style	Length (L)	Width (W)	Min.	Max.	Min.	Max.	Min.	Max.	
CDR01	0805	.080 ± .015	.050 ± .015	.022	.055	.030	_	.010	_	
CDR02	1805	.180 ± .015	.050 ± .015	.022	.055	_	_	.010	.030	
CDR03	1808	.180 ± .015	.080 ± .018	.022	.080	_	_	.010	.030	
CDR04	1812	.180 ± .015	.125 ± .015	.022	.080	_	_	.010	.030	
CDR05	1825	.180 + .020 015	+.020 .250 ₀₁₅	.020	.080	_	_	.010	.030	
CDR06	2225	.225 ± .020	.250 ± .020	.020	.080	_	_	.010	.030	

*For CDR11, 12, 13, and 14 see KYOCERA AVX Microwave Chip Capacitor Catalog

Military Part Number Identification CDR01 thru CDR06



CDR01 thru CDR06 to MIL-PRF-55681

Y Y Y Y Y Y Y Y Y Y Y Y Y Y Y Y Y Y Y	BP BP BP B	100 100 100 100 100 100 100 100 100 100
XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX	BP BP BP BP BP BP BP BP BP BP BP BP BP,BX BP,BX BP,BX BY,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX	BP BP BP BP BP BP BP BP BP BP BP BP BP,BX BP,BX BP,BX BY,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX	BP BP BP BP BP BP BP BP BP BP BP BP,BX BP,BX BP,BX BY,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX	BP BP BP BP BP BP BP BP BPBX BPBX BPBX	100 100 100 100 100 100 100 100 100 100
X X X X X X X X X X X X X X X X X X X	BP BP BP BP BP BP BP BP,BX BP,BX BP,BX BP,BX BP,BX BX,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
X X X X X X X X X X X X X X X X X X X	BP BP BP BP BP BP BP BP,BX BP,BX BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
XXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXXX	BP BP BP BP BP BP BP,BX BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
7, 7, 7, 7, 7, 7, 7, 8, 8, 8, 8, 8, 8, 8, 8, 8, 8, 8, 8, 8,	BP BP BP BP BP BP,BX BP,BX BP,BX BX,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
Y, Y, X, X, X, X, X, X, X, X, X, X, X, X, X,	BP BP BP BP BP BP,BX BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
, J,K,J,K,K,K,K,K,K,K,K,K,K,K,K,K,K,K,K,	BP BP BP BP,BX BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
J,K J,K K,M K,M K,M K,M K,M K,M K,M K,M K,M K	BP BP BP BP,BX BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
J J,K J,K K,M K,M K,M K,M K,M K,M K,M K,M K,M K	BP BP,BX BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
J,K J,K K,M K,M K,M K,M K,M K,M K,M K,M K,M K	BP BP,BX BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
J,K J,K K,M K K,M K K,M K K,M K K,M K	BP,BX BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
J,K J,K K,M K K,M K K,M K K,M K K,M K	BP,BX BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
J,K K,M K K,M K K,M K K,M K K,M K	BP,BX BX BX BX BX BX BX BX BX BX BX BX BX B	100 100 100 100 100 100 100 100 100 100
K,M K K,M K K,M K K,M K K,M K	BX BX BX BX BX BX BX BX BX BX BX BX BX	100 100 100 100 100 100 100 100 100
K K,M K K,M K K,M K K,M K	BX BX BX BX BX BX BX BX BX BX BX BX BX	100 100 100 100 100 100 100 100
K,M K K,M K K,M K K,M K	BX BX BX BX BX BX BX BX BX BX BX	100 100 100 100 100 100 100 100
K K,M K K,M K K,M K K,M K	BX BX BX BX BX BX BX BX BX	100 100 100 100 100 100 100
K,M K K,M K K,M K K,M	BX BX BX BX BX BX BX BX	100 100 100 100 100 100
K K,M K K,M K K,M	BX BX BX BX BX BX	100 100 100 100 100
K,M K K,M K K,M K	BX BX BX BX BX	100 100 100 100
K K,M K K,M K	BX BX BX BX	100 100 100
K,M K K,M K	BX BX BX	100 100
K K,M K	BX BX	100
K,M K	BX	
K		100
	BX	
1/14		100
K,M	BX	100
K	BX	100
K,M	BX	100
K	BX	50
K,M	BX	50
		,
J,K	BP	100
Ĵ	BP	100
K	BX	100
K,M	BX	100
K	BX	100
	BX	100
•		100
		100
		50
		50
		50
		50
	K K,M K K,M K K,M K K,M K	K BX K,M BX K BX K,M BX K,M BX K,M BX K,M BX K BX K,M BX K BX

Military Type Designation/	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage- temperature limits	WVDC
Style 1808/CDF	203		temperature iimits	
CDR03BP331B	330	J.K	BP	100
CDR03BP391B	390	J	BP	100
CDR03BP471B	470	J,K	BP	100
CDR03BP561B	560	J	BP	100
CDR03BP681B	680	J,K	BP	100
CDR03BP821B	820	J	BP BP	100
CDR03BP102B	1000	J,K	BP	100
CDR03BX123B	12,000	K	BX	100
CDR03BX153B	15.000	K,M	BX	100
CDR03BX183B	18.000	K	BX	100
CDR03BX223B	22,000	K,M	BX	100
CDR03BX273B	27.000	K	BX	100
CDR03BX333B	33.000	K,M	BX	100
CDR03BX393A	39.000	K	BX	50
CDR03BX473A	47.000	K,M	BX	50
CDR03BX563A	56.000	K	BX	50
CDR03BX683A	68.000	K,M	BX	50
Style 1812/CDF		,		
CDR04BP122B	1200	J	BP	100
CDR04BP152B	1500	J,K	BP	100
CDR04BP182B	1800	J	BP	100
CDR04BP222B	2200	J,K	BP	100
CDR04BP272B	2700	J	BP BP	100
CDR04BP332B	3300	J,K	BP	100
CDR04BX393B	39.000	K	BX	100
CDR04BX473B	47.000	K,M	BX	100
CDR04BX563B	56.000	K	BX	100
CDR04BX823A	82.000	K	BX	50
CDR04BX104A	100,000	K,M	BX	50
CDR04BX124A	120,000	K	BX	50
CDR04BX154A	150.000	K,M	BX	50
CDR04BX184A	180.000	K	BX	50
Style 1825/CDF	R05			
CDR05BP392B	3900	J,K	BP	100
CDR05BP472B	4700	J,K	BP	100
CDR05BP562B	5600	J,K	BP	100
CDR05BX683B	68,000	K,M	BX	100
CDR05BX823B	82,000	K	BX	100
CDR05BX104B	100,000	K,M	BX	100
CDR05BX124B	120,000	K	BX	100
CDR05BX154B	150.000	K,M	BX	100
CDR05BX224A	220.000	K,M	BX	50
CDR05BX274A	270,000	K	BX	50
CDR05BX334A	330,000	K,M	BX	50
Style 2225/CDF				
CDR06BP682B	6800	J,K	BP	100
CDR06BP822B	8200	J,K	BP	100
CDR06BP103B	10,000	J,K	BP	100
CDR06BX394A	390.000	K	BX	50
CDR06BX474A	470.000	K,M	BX	50

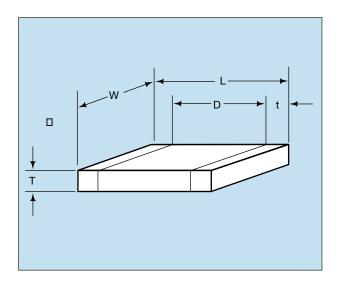
Add appropriate failure rate

Add appropriate termination finish

Capacitance Tolerance

Part Number Example CDR31 thru CDR35





MILITARY DESIGNATION PER MIL-PRF-55681

Part Number Example (example) CDR31 BP 101 В Κ S M MIL Style Voltage-Temperature Limits Capacitance Rated Voltage Capacitance Tolerance **Termination Finish** Failure Rate

NOTE: Contact factory for availability of Termination and Tolerance Options for Specific Part Numbers.

MIL Style: CDR31, CDR32, CDR33, CDR34, CDR35

Voltage-Temperature Limits:

BP = 0 ± 30 ppm/°C without voltage; 0 ± 30 ppm/°C with rated voltage from -55°C to +125°C

BX = $\pm 15\%$ without voltage; $\pm 15 - 25\%$ with rated voltage from -55°C to +125°C

Capacitance: Two digit figures followed by multiplier (number of zeros to be added) e.g., 101 = 100 pF

Rated Voltage: A = 50V. B = 100V

Capacitance Tolerance: B \pm .10 pF, C \pm .25 pF, D \pm .5

pF, F ± 1%, J ± 5%, K ± 10%,

M ± 20%

Termination Finish:

M = Palladium silver

N = Silver-nickel-gold

Solder coated final with a minimum of 4 percent lead S =

U = Base metallization-barrier metal-solder coated (tin/lead alloy, with a minimum of 4 percent lead)

W = Base metallization-barrier metal-tinned (tin or tin/lead alloy)

Y = Base metallization-barrier metal-tin (100 percent)

Z = Base metallization-barrier metal-tinned (tin/lead alloy, with a minimum of 4 percent lead)

*See MIL-PRF-55681 Specification for more details

Failure Rate Level: M = 1.0%, P = .1%, R = .01%,

S = .001%

Packaging: Bulk is standard packaging. Tape and reel per RS481 is available upon request.

*Not RoHS Compliant

CROSS REFERENCE: MIL-PRF-55681/CDR31 THRU CDR35

Per MIL-PRF-55681	Style	Length (L)	Width (W)	Thickness (T)	D	Termination Band (t)		
rei wiiL-rki -55001		(mm)	(mm)	Max. (mm)	Max. (mm)	Min. (mm)	Max. (mm)	
CDR31	0805	2.00	1.25	1.3	.50	.70	.30	
CDR32	1206	3.20	1.60	1.3	_	.70	.30	
CDR33	1210	3.20	2.50	1.5	_	.70	.30	
CDR34	1812	4.50	3.20	1.5	_	.70	.30	
CDR35	1825	4.50	6.40	1.5	_	.70	.30	





CDR31 to MIL-PRF-55681/7

Designation 1 /	in pF	Capacitance tolerance	and voltage- temperature limits	WVDC
Style 0805/C	DR31 (BP)			
CDR31BP1R0B	1.0	B,C	BP	100
CDR31BP1R1B	1.1	B,C	BP	100
CDR31BP1R2B	1.2	B,C	BP	100
CDR31BP1R3B	1.3	B,C	BP	100
CDR31BP1R5B	1.5	B,C	BP	100
CDR31BP1R6B	1.6	B,C	BP	100
CDR31BP1R8B	1.8	B,C	BP	100
CDR31BP2R0B	2.0 2.2	B,C	BP BP	100 100
CDR31BP2R2B CDR31BP2R4B	2.2	B,C B,C	BP BP	100
CDR31BP2R4B	2.4	B,C,D	BP	100
CDR31BP3R0B	3.0	B,C,D B,C,D	BP BP	100
CDR31BP3R3B	3.3	B,C,D	BP	100
CDR31BP3R6B	3.6	B,C,D	BP	100
CDR31BP3R9B	3.9	B,C,D	BP	100
CDR31BP4R3B	4.3	B,C,D	BP	100
CDR31BP4R7B	4.7	B,C,D	BP	100
CDR31BP5R1B	5.1	B,C,D	BP	100
CDR31BP5R6B	5.6	B,C,D	BP	100
CDR31BP6R2B	6.2	B,C,D	BP	100
CDR31BP6R8B	6.8	B,C,D	BP	100
CDR31BP7R5B	7.5	B,C,D	BP	100
CDR31BP8R2B	8.2	B,C,D	BP	100
CDR31BP9R1B	9.1	B,C,D	BP	100
CDR31BP100B	10	FJ,K	BP	100
CDR31BP110B	11	FJ,K	BP	100
CDR31BP120B	12	FJ,K	BP	100
CDR31BP130B CDR31BP150B	13 15	FJ,K FJ,K	BP BP	100 100
CDR31BP150B	16	FJ,K FJ,K	BP BP	100
CDR31BP180B	18	FJ.K	BP	100
CDR31BP100B	20	F,J,K	BP BP	100
CDR31BP220B	22	FJ,K	BP	100
CDR31BP240B	24	F,J,K	BP	100
CDR31BP270B	27	FJ,K	BP	100
CDR31BP300B	30	FJ,K	BP	100
CDR31BP330B	33	F,J,K	BP	100
CDR31BP360B	36	FJ,K	BP	100
CDR31BP390B	39	F,J,K	BP	100
CDR31BP430B	43	FJ,K	BP	100
CDR31BP470B	47	FJ,K	BP	100
CDR31BP510B	51	F,J,K	BP	100
CDR31BP560B	56	FJ,K	BP	100
CDR31BP620B	62	F,J,K	BP	100
CDR31BP680B	68	FJ,K	BP	100
CDR31BP750B	75	FJ,K	BP	100
CDR31BP820B CDR31BP910B	82 91	F,J,K FJ,K	BP BP	100 100

L	Add appropriate failure rate
_	Add appropriate termination finish
	Capacitance Tolerance

Military Type Designation 1/	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage-	WVDC
Designation 1/	in pr	tolerance	temperature limits	
Style 0805/0	DR31 (BP)	cont'd		
CDR31BP101B	100	F,J,K	BP	100
CDR31BP111B	110	F,J,K	BP	100
CDR31BP121B	120	F,J,K	BP	100
CDR31BP131B	130	F,J,K	BP	100
CDR31BP151B	150	F,J,K	BP	100
CDR31BP161B	160	F,J,K	BP	100
CDR31BP181B	180	F,J,K	BP	100
CDR31BP201B	200	F,J,K	BP	100
CDR31BP221B	220	F,J,K	BP	100
CDR31BP241B	240	F,J,K	BP	100
CDR31BP271B	270	F,J,K	BP	100
CDR31BP301B	300	F,J,K	BP	100
CDR31BP331B	330	F,J,K	BP	100
CDR31BP361B	360	F,J,K	BP	100
CDR31BP391B	390	F,J,K	BP	100
CDR31BP431B	430	F,J,K	BP	100
CDR31BP471B	470	F,J,K	BP	100
CDR31BP511A	510	F,J,K	BP	50
CDR31BP561A	560	F,J,K	BP	50
CDR31BP621A	620	F,J,K	BP	50
CDR31BP681A	680	F,J,K	BP	50
Style 0805/0	DR31 (BX)			
CDR31BX471B	470	K.M	BX	100
CDR31BX561B	560	K,M	BX	100
CDR31BX681B	680	K,M	BX	100
CDR31BX821B	820	K,M	BX	100
CDR31BX102B	1,000	K,M	BX	100
CDR31BX122B	1,200	K,M	BX	100
CDR31BX152B	1,500	K,M	BX	100
CDR31BX182B	1,800	K,M	BX	100
CDR31BX222B	2,200	K,M	BX	100
CDR31BX272B	2,700	K,M	BX	100
CDR31BX332B	3,300	K,M	BX	100
CDR31BX392B	3,900	K,M	BX	100
CDR31BX472B	4,700	K,M	BX	100
CDR31BX562A	5,600	K,M	BX	50
CDR31BX682A	6,800	K,M	BX	50
CDR31BX822A	8,200	K,M	BX	50
CDR31BX103A	10,000	K,M	BX	50
CDR31BX123A	12,000	K,M	BX	50
CDR31BX153A	15.000	K,M	BX	50
CDR31BX183A	18.000	K,M	BX	50

Add appropriate failure rate Add appropriate termination finish Capacitance Tolerance

^{1/} The complete part number will include additional symbols to indicate capacitance tolerance, termination and failure rate level.





CDR32 to MIL-PRF-55681/8

Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance Tolerance	Rated temperature and Voltage- Temperature Limits	WVDC
Style 1206/0	DR32 (BP)			
CDR32BP1R0B— CDR32BP1R1B— CDR32BP1R3B— CDR32BP1R5B— CDR32BP1R6B— CDR32BP1R8B— CDR32BP2R0B— CDR32BP2R2B— CDR32BP2R4B— CDR32BP2R4B— CDR32BP2R7B— CDR32BP3R0B— CDR32BP3R0B— CDR32BP3R0B— CDR32BP3R0B— CDR32BP3R3B— CDR32BP3R3B— CDR32BP3R6B— CDR32BP3R6B— CDR32BP3R6B—	1.0 1.1 1.2 1.3 1.5 1.6 1.8 2.0 2.2 2.4 2.7 3.0 3.3 3.6 3.9 4.3	B,C B,C B,C B,C B,C B,C B,C B,C B,C,D B,C,D B,C,D B,C,D B,C,D	BP BP BP BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100 100 100
CDR32BP4R3B CDR32BP5R1B CDR32BP5R6B CDR32BP6R2B CDR32BP7R5B CDR32BP7R5B CDR32BP9R1B CDR32BP10B CDR32BP110B CDR32BP120B CDR32BP130B CDR32BP130B CDR32BP130B CDR32BP130B CDR32BP130B	4.3 4.7 5.1 5.6 6.2 6.8 7.5 8.2 9.1 10 11 12	B,C,D B,C,D B,C,D B,C,D B,C,D B,C,D B,C,D B,C,D FJ,K FJ,K FJ,K	BP BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100 100 100
CDR32BP150B— CDR32BP160B— CDR32BP180B— CDR32BP200B— CDR32BP220B— CDR32BP240B— CDR32BP240B— CDR32BP270B— CDR32BP300B—	15 16 18 20 22 24 27 30	FJ,K FJ,K FJ,K FJ,K FJ,K FJ,K FJ,K	BP BP BP BP BP BP BP	100 100 100 100 100 100 100
CDR32BP330B CDR32BP360B CDR32BP430B CDR32BP470B CDR32BP510B CDR32BP560B CDR32BP620B CDR32BP680B CDR32BP750B CDR32BP820B CDR32BP910B	33 36 39 43 47 51 56 62 68 75 82 91	EJ'K EJ'K EJ'K EJ'K EJ'K EJ'K EJ'K	BP BP BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100 100 100

91	FJ,K	BP	1
 Add appropriat 	e failure rate		
- Add appropriat		nish	
- Capacitance To		111011	
- Capacitance it	delance		

	-	Т		
Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance Tolerance	Rated Temperature and Voltage- Temperature Limits	WVDC
Style 1206/0	DR32 (BP)	cont'd		
CDR32BP101B	100	FJ,K	BP	100
CDR32BP111B	110	FJ,K	BP	100
CDR32BP121B	120	FJ,K	BP	100
CDR32BP131B	130	FJ,K	BP	100
CDR32BP151B	150	FJ,K	BP	100
CDR32BP161B	160	FJ,K	BP	100
CDR32BP181B	180	F,J,K	BP	100
CDR32BP201B	200	FJ,K	BP	100
CDR32BP221B	220	F,J,K	BP	100
CDR32BP241B	240	FJ,K	BP	100
CDR32BP271B	270	FJ,K	BP	100
CDR32BP301B	300	F,J,K	BP	100
CDR32BP331B	330	FJ,K	BP	100
CDR32BP361B	360	F,J,K	BP	100
CDR32BP391B	390	FJ,K	BP	100
CDR32BP431B	430	FJ,K	BP	100
CDR32BP471B	470	F,J,K	BP	100
CDR32BP511B	510	FJ,K	BP	100
CDR32BP561B	560	F,J,K	BP	100
CDR32BP621B	620	FJ,K	BP	100
CDR32BP681B	680	FJ,K	BP	100
CDR32BP751B	750	F,J,K	BP	100
CDR32BP821B	820	FJ,K	BP	100
CDR32BP911B	910	F,J,K	BP	100
CDR32BP102B	1,000	FJ,K	BP	100
CDR32BP112A	1,100	FJ,K	BP	50
CDR32BP122A	1,200	F,J,K	BP	50
CDR32BP132A	1,300	FJ,K	BP	50
CDR32BP152A	1,500	F,J,K	BP	50
CDR32BP162A	1,600	FJ,K	BP	50
CDR32BP182A	1,800	FJ,K	BP	50
CDR32BP202A	2,000	F,J,K	BP	50
CDR32BP222A	2,200	FJ,K	BP	50
Style 1206/0	DR32 (BX)			
CDR32BX472B	4,700	K,M	BX	100
CDR32BX562B	5,600	K,M	BX	100
CDR32BX682B	6,800	K,M	BX	100
CDR32BX822B	8,200	K,M	BX	100
CDR32BX103B	10,000	K,M	BX	100
CDR32BX123B	12,000	K,M	BX	100
CDR32BX123B	15.000	K,M	BX	100
CDR32BX183A	18.000	K,M	BX	50
CDR32BX223A	22,000	K,M	BX	50
CDR32BX273A	27,000	K,M	BX	50
CDR32BX373A	33.000	K,M	BX	50
CDR32BX393A	39.000	K,M	BX BX	50 50
CDR3ZBA393A	37.000	1 17,171		JU

Add appropriate failure rate Add appropriate termination finish

Capacitance Tolerance

^{1/} The complete part number will include additional symbols to indicate capacitance tolerance, termination and failure rate level.





CDR33/34/35 to MIL-PRF-55681/9/10/11

Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage- temperature limits	WVDC
Style 1210/0	DR33 (BP)			
CDR33BP102B— CDR33BP112B— CDR33BP122B— CDR33BP132B— CDR33BP152B— CDR33BP162B— CDR33BP162B— CDR33BP202B— CDR33BP202B— CDR33BP222B— CDR33BP222A— CDR33BP222A— CDR33BP222A—	1,000 1,100 1,200 1,300 1,500 1,600 1,800 2,000 2,200 2,400 2,700	FJ,K FJ,K FJ,K FJ,K FJ,K FJ,K FJ,K FJ,K	BP BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100 50
CDR33BP302A CDR33BP332A	3,000 3,300	F,J,K FJ,K	BP BP	50 50
Style 1210/0	DR33 (BX)			
CDR33BX153B— CDR33BX183B— CDR33BX223B— CDR33BX273B— CDR33BX393A— CDR33BX473A— CDR33BX563A— CDR33BX683A— CDR33BX823A— CDR33BX823A— CDR33BX104A—	15.000 18.000 22,000 27.000 39.000 47.000 56.000 68.000 82,000 100,000	K,M K,M K,M K,M K,M K,M K,M K,M	BX BX BX BX BX BX BX BX BX BX	100 100 100 100 50 50 50 50 50
Style 1812/0	DR34 (BP)			
CDR34BP222B— CDR34BP242B— CDR34BP302B— CDR34BP332B— CDR34BP392B— CDR34BP392B— CDR34BP472B— CDR34BP472B— CDR34BP512A— CDR34BP512A— CDR34BP622A— CDR34BP622A— CDR34BP682A— CDR34BP752A— CDR34BP822A— CDR34BP822A— CDR34BP812A— CDR34BP912A— CDR34BP912A— CDR34BP912A— CDR34BP9103A—	2,200 2,400 2,700 3,000 3,300 3,600 3,900 4,300 4,700 5,100 5,600 6,200 6,800 7,500 8,200 9,100 10,000	EJYK EJYK EJYK EJYK EJYK EJYK EJYK EJYK	BP BP BP BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100 50 50 50 50 50 50

 Add appropriate failure rate
Add appropriate termination finish
Canacitance Tolerance

Military Type Designation <u>1</u> /	Capacitance in pF	Capacitance tolerance	Rated temperature and voltage- temperature limits	WVDC
Style 1812/0	DR34 (BX)			
CDR34BX273B CDR34BX333B CDR34BX393B CDR34BX473B CDR34BX563B CDR34BX104A CDR34BX124A CDR34BX154A CDR34BX184A	27.000 33.000 39.000 47.000 56.000 100,000 120,000 150.000 180.000	K,M K,M K,M K,M K,M K,M K,M	BX BX BX BX BX BX BX BX BX	100 100 100 100 100 50 50 50 50
Style 1825/0	DR35 (BP)			
CDR35BP472B— CDR35BP562B— CDR35BP62B— CDR35BP62B— CDR35BP62B— CDR35BP752B— CDR35BP12B— CDR35BP103B— CDR35BP13A— CDR35BP13A— CDR35BP13A— CDR35BP13A— CDR35BP163A— CDR35BP163A— CDR35BP163A— CDR35BP163A— CDR35BP163A— CDR35BP16	4,700 5,100 5,600 6,200 6,800 7,500 8,200 9,100 10,000 11,000 12,000 13.000 15.000 16.000 18,000 20,000 22,000	£1,K £1,K £1,K £1,K £1,K £1,K £1,K £1,K	BP BP BP BP BP BP BP BP BP BP BP BP	100 100 100 100 100 100 100 100 50 50 50 50 50 50
Style 1825/0	DR35 (BX)			
CDR35BX563B— CDR35BX683B— CDR35BX823B— CDR35BX104B— CDR35BX124B— CDR35BX154B— CDR35BX154B— CDR35BX224A— CDR35BX274A— CDR35BX334A— CDR35BX394A— CDR35BX394A— CDR35BX374A—	56.000 68.000 82,000 100,000 120,000 150.000 180.000 270.000 330.000 390.000 470.000	K,M K,M K,M K,M K,M K,M K,M K,M K,M K,M	BX BX BX BX BX BX BX BX BX BX	100 100 100 100 100 100 50 50 50 50 50

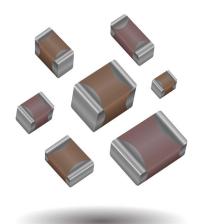
Add appropriate failure rate Add appropriate termination finish Capacitance Tolerance

^{1/} The complete part number will include additional symbols to indicate capacitance tolerance, termination and failure rate level.

MLCC Medical Applications – MM Series







The MM series is a multi-layer ceramic capacitor designed for use in medical applications other than implantable/life support. These components have the design & change control expected for medical devices and also offer enhanced LAT including reliability testing and 100% inspection.

APPLICATIONS

Implantable, Non-Life Supporting Medical Devices

· e.g. implanted temporary cardiac monitor, insulin pumps

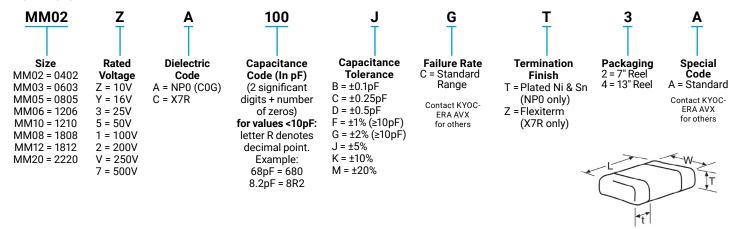
External, Life Supporting Medical Devices

· e.g. heart pump external controller

External Devices

· e.g. patient monitoring, diagnostic equipment

HOW TO ORDER



COMMERCIAL VS MM SERIES PROCESS COMPARISON

	Commercial	MM Series
Administrative	Standard part numbers; no restriction on who purchases these parts	Specific series part number, used to control supply of product
Lot Qualification Destructive Physical Analysis (DPA)	As per EIA RS469	Increased sample plan – stricter criteria
Visual/Cosmetic Quality	Standard process and inspection	100% inspection
Application Robustness	Standard sampling for accelerated wave solder on X7R dielectrics	Increased sampling for accelerated wave solder on X7R and NP0 followed by lot by lot reliability testing
Design/Change Control	Required to inform customer of changes in: form fit function	KYOCERA AVX will qualify and notify customers before making any change to the following materials or processes: Dielectric formulation, type, or supplier Metal formulation, type, or supplier Termination material formulation, type, or supplier Manufacturing equipment type Quality testing regime including sample size and accept/reject criteria

062121



NP0 (C0G) - Specifications & Test Methods

Parame	ter/Test	NP0 Specification Limits	Measuring Conditions					
	perature Range	-55°C to +125°C	Temperature Cycle Chamber					
•	eitance Q	Within specified tolerance <30 pF: Q≥ 400+20 x Cap Value ≥30 pF: Q≥ 1000	Freq.: 1.0 MHz ± 10% for cap ≤ 1000 pF 1.0 kHz ± 10% for cap > 1000 pF Voltage: 1.0Vrms ± .2V					
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with rated voltage for 60 ± 5 secs @ room temp/humidity					
Dielectric	: Strength	No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.					
	Appearance	No defects	Deflection: 2mm					
Resistance to	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Test Time: 30 seconds					
Flexure Stresses	Q	Meets Initial Values (As Above)						
	Insulation Resistance	≥ Initial Value x 0.3	90 mm					
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic solder at 230 ± 5°C for 5.0 ± 0.5 seconds					
	Appearance	No defects, <25% leaching of either end terminal						
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater						
Resistance to Solder Heat	Q	Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± 2					
ooluci ilcut	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring electrical properties.					
	Dielectric Strength	Meets Initial Values (As Above)						
	Appearance	No visual defects	Step 1: -55°C ± 2° 30 ± 3 minutes					
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp ≤ 3 minutes					
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2° 30 ± 3 minutes					
Giloux	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp ≤ 3 minutes					
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and measure after 24 hours at room temperature					
	Appearance	No visual defects						
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twice rated voltage in test					
Load Life	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	chamber set at 125°C ± 2°C for 1000 hours (+48, -0). Remove from test chamber and stabilize at					
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	room temperature for 24 hours before measuring.					
	Dielectric Strength	Meets Initial Values (As Above)	belove modelling.					
	Appearance	No visual defects						
	Capacitance Variation	≤ ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber set at 85°C ± 2°C/ 85%					
Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	± 5% relative humidity for 1000 hours (+48, -0) with rated voltage applied.					
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber and stabilize at room temperature for 24 ± 2 hours before measuring.					
	Dielectric Strength	Meets Initial Values (As Above)						



NP0/C0G Capacitance Range

PREFERRED SIZES ARE SHADED

SIZE			06	03				0805	1206				
	WVDC	16	25	50	100	16	25	50	100	16	25	50	100
Cap 0.5													
(pF) 1.0	1R0												
1.2	1R2												
1.5	1R5												
1.8	1R8												
2.2	2R2												
2.7	2R7												
3.3	3R3												
3.9	3R9												
4.7	4R7												
5.6	5R6												
6.8	6R8												
8.2	8R2												
10	100												
12	120												
15	150												
18	180												
22	220												
27	270												
33	330												
39	390												
47	470												
56	560												
68	680												
82	820												
100	101												
120	121												
150	151												
180	181												
220	221												
270	271												
330	331												
390	391												
470	471												
560	561												
680	681												
820	821												
1000	102												
1200	122				-					-			
1500 WVD0		16	25	50	100	16	25	50	100	16	25	50	100
		10			100	10		 					
SIZE			06	03				0805				1206	

113016



X7R Specifications and Test Methods

Parame	ter/Test	X7R Specification Limits	Measuring (
	perature Range	-55°C to +125°C	Temperature C	ycle Chamber				
Capac	itance	Within specified tolerance						
Dissipati	on Factor	≤ 10% for ≥ 50V DC rating ≤ 12.5% for 25V DC rating ≤ 12.5% for 25V and 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Freq.: 1.0 kHz ± 10% Voltage: 1.0Vrms ± .2V					
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with rated voltage for 120 ± 5 secs @ room temp/humidity					
Dielectric	: Strength	No breakdown or visual defects	Charge device with 250% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.					
	Appearance	No defects	Deflection	n: 2mm				
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3					
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	V					
	Insulation Resistance	≥ Initial Value x 0.3	90 n					
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5					
	Appearance	No defects, <25% leaching of either end terminal						
	Capacitance Variation	≤ ±7.5%						
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± hours before measuring electrical properties					
oolder riedt	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.				
	Dielectric Strength	Meets Initial Values (As Above)						
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes				
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes				
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes				
Cincon	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes				
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles 24 ± 2 hours at ro	and measure after om temperature				
	Appearance	No visual defects						
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 r test chamber set	at 125°C ± 2°C				
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hou					
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test char room temperature for	24 ± 2 hours before				
	Dielectric Strength	Meets Initial Values (As Above)	measu					
	Appearance	No visual defects						
	Capacitance Variation	≤ ±12.5%	Store in a test chamber s ± 5% relative humid	ity for 1000 hours				
Load Humidity	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated	•				
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber and stabilize at room temperature and humidity for 24 ± 2 hours before measuring.					
	Dielectric Strength	Meets Initial Values (As Above)						



X7R Capacitance Range

PREFERRED SIZES ARE SHADED

	SIZE	E		040)2			0	603	}				(080	5						12	06							12	10				1	808	8	1812				:	2220	
		WVDC	16	25	50	10	16	25	50	10	0 200	10	16	25	50	100	200	250	10	16	25	50	100	200	250	500	10	16	25	50	100	200	250	500	50	100	200	50	100	200	250	25	50	100
Сар	220	221																																								\neg		
(pF)	270	271								T																																П		
(F-)	330	331						T		T													П								T											П		\Box
	390	391						i –	i –	T													П		İ				1		i –								İ			\neg		\Box
	470	471						T															П		M				İ	İ	İ								İ			\neg		\Box
	560	561						1		1													П																			\neg		\Box
	680	681						1	1	T													П																			\neg		\Box
	820	821		Т				T	T	T													П		M						İ											\neg		
	1000	102						1															П		П																	\neg		\Box
	1200	122						1		T		1											П						T		t											\neg		\Box
	1500	152		Т				1	1	1																													İ			\neg		
	1800	182																																			П					\dashv		$\overline{}$
	2200	222																																			П		t			\dashv		$\overline{}$
	2700	272																																			\Box		\vdash	\vdash		\dashv		
	3300	332																																		Н	Н		\vdash	\vdash		\dashv		г
	3900	392		Н	1		1	+	+	+													Н		Н				1		1	_	Н									\vdash		М
	4700	472						+	1	+													Н							1	1											\vdash		\vdash
	5600	562					+	+	+	+													Н						 		1					H						\vdash		т
	6800	682						+	+	+													Н								+											\dashv		\vdash
	8200	822					+	+	+	+													Н						1		1					\vdash	\vdash					\vdash		\vdash
сар	0.010	103		H	+	\vdash	+	+	+	+												\vdash	Н		H				\vdash	\vdash	+											\vdash		М
uF	0.010	123					+	+	+	-					\vdash								Н		Н				 		+		Н				\vdash	_				\vdash		М
ur	0.012	153		Н	+			+	+		+												Н		Н				1		+						\vdash					\dashv		М
	0.018	183		H	+		+	+	+		+												Н		Н				\vdash		+						\vdash					\vdash		М
	0.018	223		Н	+		+	+	+		+												Н		Н				-		+	_	Н				\vdash					\dashv		М
	0.022	273		Н	+		+	+	+	-	+					\vdash							Н		Н				1		+	_	Н									\vdash		М
	0.027	333		Н	+		+	+	+		+												Н		Н				 	\vdash	+						\vdash					\vdash		Н
	0.039	393		Н	+		+	╁	+		+												Н						-	 	╁	_					\vdash					\vdash		М
	0.039	473	-	\vdash	+		\vdash	+	+		+					\vdash						\vdash	Н		Н				 		+	_	Н				\vdash					\vdash		\vdash
	0.047	563		\vdash	+		+	+	+	-	+												Н		Н				 	 	+	_	Н				\vdash	_	 			\vdash		\vdash
		683					+	+	+														Н		Н				 		1						\vdash					\vdash		\vdash
	0.068	823		\vdash	+		+	+	+		+												Н		Н				\vdash		+						\vdash					\vdash		\vdash
			1	\vdash	+		+	+	+	+	+												Н		Н				\vdash		+					\vdash	\vdash					\vdash		\vdash
	0.10 0.12	104 124		\vdash	+						+														Н												\vdash							
	0.12	154		+	+			+	+	+													Н		\vdash								\vdash				+							
				\vdash	+			+	+	+	+					\vdash							Н		Н							\vdash	\vdash			\vdash	\vdash							
	0.22	224 334		\vdash	+		1	+	+	+	+						\vdash						Н		\vdash							_	\vdash				\vdash							
			_	\vdash	+	\vdash	+	+	+	+	+				\vdash								Н		Н												H			\vdash	\vdash			
	0.47	474		+	+	\vdash	\vdash	+	+	+	+				\vdash	\vdash	\vdash						Н		\vdash							_	$\vdash\vdash$		\vdash	\vdash	\vdash			\vdash	\vdash			-
	0.56	564		+	+	\vdash	+	+	+	+	+			\vdash	\vdash	\vdash	\vdash						Н		\vdash								\vdash		-	\vdash	\vdash			\vdash	\vdash			
	0.68	684		\vdash	+	\vdash	\vdash	+	+	+	+			\vdash	\vdash		\vdash					_	Н		\vdash								\vdash			\vdash	\vdash		\vdash	\vdash				
	0.82	824		\vdash	+	\vdash	\vdash	+	+	+	+			\vdash	\vdash		\vdash					-	Н		\vdash								\vdash		-		\vdash		-		H			\blacksquare
	1.0	105		\vdash	+	\vdash	\vdash	+	+	+	+		-		\vdash	\vdash					\vdash	_	Н		Н						-	\vdash	\vdash			\vdash	\vdash		\vdash	\vdash	\vdash			
	1.2	125		\vdash	+	\vdash	\vdash	+	+	+	-	1							-			_	Н		\vdash				-	-	1		\vdash		-		\vdash		\vdash		\vdash			
	1.5	155		0-	FC	10	100	0-	F.0	100	0.000	10	1.0	05		400	200	050	40	2.0	05	50	100	000	050	FOC	10	1.0	05	FC	100	000	050	FOC		400	000		100	000	050	05	50	100
	WVD					10	16				0 200	10	16				200	250	10	16	25		_	200	250	500	10	16	25			200	250	500				50						
	SIZE	E	(040)2			0	603	}				(080	5						12	06							12	10				1	808	8		18	12		:	222	0
			_			_						_							_																									

110116

Packaging of Chip Components



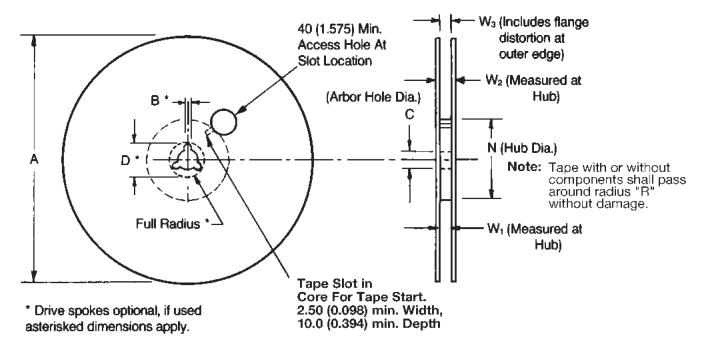


TAPE & REEL QUANTITIES

All tape and reel specifications are in compliance with RS481.

	4mm	8mm	12mm	
Paper or Embossed Carrier		0612, 0508, 0805, 1206, 1210		
Embossed Only	0101		1808	1812, 1825 2220, 2225
Paper Only		0101, 0201, 0306, 0402, 0603		
Qty. per Reel/7" Reel	4,000	1,000, 2,000, 3,000 or 4,000, 10,000, 15,000, 20,000 Contact factory for exact quantity	3,000	500, 1,000 Contact factory for exact quantity
Qty. per Reel/13" Reel		5,000, 10,000, 50,000 Contact factory for exact quantity	10,000	4,000

REEL DIMENSIONS



Tape Size ⁽¹⁾	A Max.	B* Min.	С	D* Min.	N Min.	W ₁	W ₂ Max.	W ₃
4mm	1.80 (7.087)	1.5 (0.059)	13.0±0.5 (0.522±0.020)	20.2 (0.795)	60.0 (2.362)	4.35±0.3 (0.171±0.011)	7.95 (0.312)	
8mm	330	1.5	13.0 ^{+0.50}	20.2	50.0	8.40 ^{+1.5} (0.331 ^{+0.059})	14.4 (0.567)	7.90 Min. (0.311) 10.9 Max. (0.429)
12mm	(12.992)	(0.059)	(0.512 ^{+0.020} _{-0.008})	(0.795)	(1.969)	12.4 ^{+2.0} (0.488 ^{+0.079})	18.4 (0.724)	11.9 Min. (0.469) 15.4 Max. (0.607)

Metric dimensions will govern.

English measurements rounded and for reference only.

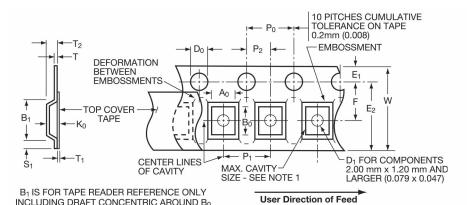
⁽¹⁾ For tape sizes 16mm and 24mm (used with chip size 3640) consult EIA RS-481 latest revision.

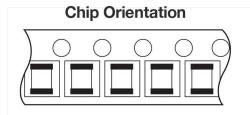


Embossed Carrier Configuration

4, 8 & 12mm Tape Only







4, 8 & 12mm Embossed Tape

Metric Dimensions Will Govern

CONSTANT DIMENSIONS

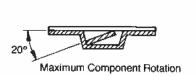
Tape Size	D _o	E ₁	P ₀	P ₂	S ₁ Min.	T Max.	T ₁ Max.
4mm	0.80±0.04	0.90±0.05	2.0±0.04	1.00±0.02	1.075	0.26	0.06
	(0.031±0.001)	(0.035±0.001)	(0.078±0.001)	(0.039±0.0007)	(0.042)	(0.010)	(0.002)
8mm	$1.50_{ -0.0}^{ +0.10} \\ (0.059_{ -0.0}^{ +0.004})$	1.75 ± 0.10	4.0 ± 0.10	2.0 ± 0.05	0.60	0.60	0.10
& 12mm		(0.069 ± 0.004)	(0.157 ± 0.004)	(0.079 ± 0.002)	(0.024)	(0.024)	(0.004)

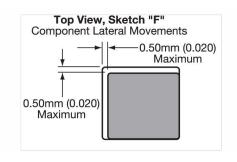
VARIABLE DIMENSIONS

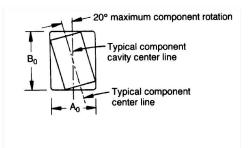
Tape Size	B ₁ Max.	D ₁ Min.	E ₂ Min.	F	P ₁ See Note 5	R Min. See Note 2	T ₂	W Max.	$A_0 B_0 K_0$
8mm	4.35 (0.171)	1.00 (0.039)	6.25 (0.246)	3.50 ± 0.05 (0.138 ± 0.002)	4.00 ± 0.10 (0.157 ± 0.004)	25.0 (0.984)	2.50 Max. (0.098)	8.30 (0.327)	See Note 1
12mm	8.20 (0.323)	1.50 (0.059)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	4.00 ± 0.10 (0.157 ± 0.004)	30.0 (1.181)	6.50 Max. (0.256)	12.3 (0.484)	See Note 1
8mm 1/2 Pitch	4.35 (0.171)	1.00 (0.039)	6.25 (0.246)	3.50 ± 0.05 (0.138 ± 0.002)	2.00 ± 0.10 (0.079 ± 0.004)	25.0 (0.984)	2.50 Max. (0.098)	8.30 (0.327)	See Note 1
12mm Double Pitch	8.20 (0.323)	1.50 (0.059)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	8.00 ± 0.10 (0.315 ± 0.004)	30.0 (1.181)	6.50 Max. (0.256)	12.3 (0.484)	See Note 1

NOTES:

- 1. The cavity defined by A0, B0, and K0 shall be configured to provide the following: Surround the component with sufficient clearance such that:
 - b) the component does not protrude beyond the sealing plane of the cover tape.
 - c) the component can be removed from the cavity in a vertical direction without mechanical restriction, after the cover tape has been removed.
 - d) rotation of the component is limited to 20° maximum (see Sketches D & E).
 - e) lateral movement of the component is restricted to 0.5mm maximum (see Sketch F).
- 3. Bar code labeling (if required) shall be on the side of the reel opposite the round sprocket holes. Refer to EIA-556.
- 4. B₁ dimension is a reference dimension for tape feeder clearance only. 5. If P_1 = 2.0mm, the tape may not properly index in all tape feeders.
- 2. Tape with or without components shall pass around radius "R" without damage.



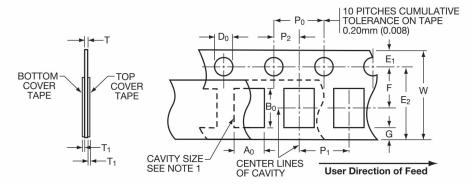




Paper Carrier Configuration

8 & 12mm Tape Only





4, 8 & 12mm Embossed Tape **Metric Dimensions Will Govern**

CONSTANT DIMENSIONS

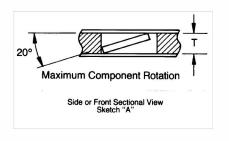
Tape Size	D _o	Е	P ₀	P ₂	T ₁	G. Min.	R Min.
8mm and 12mm	1.50 ^{+0.10} (0.059 ^{+0.004})	1.75 ± 0.10 (0.069 ± 0.004)	4.00 ± 0.10 (0.157 ± 0.004)	2.00 ± 0.05 (0.079 ± 0.002)	0.10 (0.004) Max.	0.75 (0.030) Min.	25.0 (0.984) See Note 2 Min.

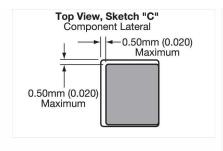
VARIABLE DIMENSIONS

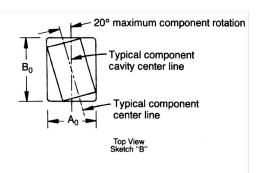
Tape Size	P ₁ See Note 4	E ₂ Min.	F	w	A ₀ B ₀	Т
8mm	4.00 ± 0.10 (0.157 ± 0.004)	6.25 (0.246)	3.50 ± 0.05 (0.138 ± 0.002)	8.00 ^{+0.30} -0.10 (0.315 ^{+0.012})	See Note 1	1.10mm (0.043) Max.
12mm	4.00 ± 0.10 (0.157 ± 0.004)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	12.0 ± 0.30 (0.472 ± 0.012)		for Paper Base Tape and
8mm 1/2 Pitch	2.00 ± 0.05 (0.079 ± 0.002)	6.25 (0.246)	3.50 ± 0.05 (0.138 ± 0.002)	8.00 ^{+0.30} (0.315 ^{+0.012} (0.315 -0.004)		1.60mm
12mm Double Pitch	8.00 ± 0.10 (0.315 ± 0.004)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	12.0 ± 0.30 (0.472 ± 0.012)		(0.063) Max. for Non-Paper Base Compositions

NOTES:

- 1. The cavity defined by A0, B0, and T shall be configured to provide sufficient clearance surrounding the component so that:
 - a) the component does not protrude beyond either surface of the carrier tape;
 - b)) the component can be removed from the cavity in a vertical direction without mechanical restriction after the top cover tape has been removed;
- c) rotation of the component is limited to 20° maximum (see Sketches A & B);
- d) lateral movement of the component is restricted to 0.5mm maximum (see Sketch C).
- 2. Tape with or without components shall pass around radius "R" without damage.
- 3. Bar code labeling (if required) shall be on the side of the reel opposite the sprocket holes. Refer to EIA-556.
- 4. If P₁ = 2.0mm, the tape may not properly index in all tape feeders.







Bar Code Labeling Standard

KYOCERA AVX bar code labeling is available and follows latest version of EIA-556





Basic Capacitor Formulas

I. Capacitance (farads)

English:
$$C = \frac{.224 \text{ K A}}{T_D}$$

Metric: $C = \frac{.0884 \text{ K A}}{T_D}$

II. Energy stored in capacitors (Joules, watt - sec)

$$E = \frac{1}{2} CV^2$$

III. Linear charge of a capacitor (Amperes)

$$I = C \frac{dV}{dt}$$

IV. Total Impedance of a capacitor (ohms)

$$Z = \sqrt{R_S^2 + (X_C - X_L)^2}$$

V. Capacitive Reactance (ohms)

$$x_C = \frac{1}{2 \pi fC}$$

VI. Inductive Reactance (ohms)

$$x_1 = 2 \pi fL$$

VII. Phase Angles:

Ideal Capacitors: Current leads voltage 90° Ideal Inductors: Current lags voltage 90° Ideal Resistors: Current in phase with voltage

VIII. Dissipation Factor (%)

D.F.=
$$\tan \delta$$
 (loss angle) = $\frac{\text{E.S.R.}}{\text{X}_{\text{C}}}$ = (2 π fC) (E.S.R.)

IX. Power Factor (%)

P.F. = Sine (loss angle) = $\cos \varphi$ (phase angle)

P.F. = (when less than 10%) = DF

X. Quality Factor (dimensionless)

Q = Cotan
$$\delta$$
 (loss angle) = $\frac{1}{D.F.}$

XI. Equivalent Series Resistance (ohms)

E.S.R. = (D.F.) (Xc) = (D.F.) / (2
$$\pi$$
 fC)

XII. Power Loss (watts)

Power Loss = $(2 \pi fCV^2)$ (D.F.)

XIII. KVA (Kilowatts)

 $KVA = 2 \pi fCV^2 \times 10^{-3}$

XIV. Temperature Characteristic (ppm/°C)

T.C. =
$$\frac{Ct - C_{25}}{C_{25} (T_t - 25)} \times 10^6$$

XV. Cap Drift (%)

C.D. =
$$\frac{C_1 - C_2}{C_1}$$
 x 100

XVI. Reliability of Ceramic Capacitors

$$\begin{array}{c} L_{o} = \left(\frac{V_{t}}{V_{o}} \right) X & \left(\frac{T_{t}}{T_{o}} \right) \end{array} \label{eq:loss_problem}$$

XVII. Capacitors in Series (current the same)

Any Number:
$$\frac{1}{C_T} = \frac{1}{C_1} + \frac{1}{C_2} - \frac{1}{C_N}$$
 Two: $C_T = \frac{C_1 C_2}{C_1 + C_2}$

XVIII. Capacitors in Parallel (voltage the same)

$$C_T = C_1 + C_2 --- + C_N$$

XIX. Aging Rate

A.R. = $\%\Delta$ C/decade of time

XX. Decibels

$$db = 20 \log \frac{V_1}{V_2}$$

METRIC PREFIXES

Pico	X 10 ⁻¹²
Nano	X 10 ⁻⁹
Micro	X 10 ⁻⁶
Milli	X 10 ⁻³
Deci	X 10 ⁻¹
Deca	X 10 ⁺¹
Kilo	X 10 ⁺³
Mega	X 10 ⁺⁶
Giga	X 10 ⁺⁹
Tera	X 10 ⁺¹²

SYMBOLS

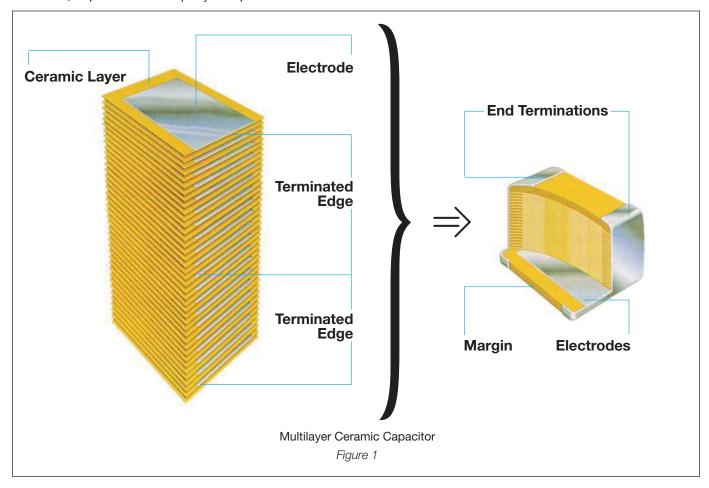
K = Dielectric Constant	f = frequency	L _t = Test life
A = Area	L = Inductance	V _t = Test voltage
T _D = Dielectric thickness	δ = Loss angle	V _o = Operating voltage
V = Voltage	φ = Phase angle	T _t = Test temperature
t = time	X & Y = exponent effect of voltage and temp.	T _o = Operating temperature
R _s = Series Resistance	L_{\circ} = Operating life	



General Description

Basic Construction - A multilayer ceramic (MLC) capacitor is a monolithic block of ceramic containing two sets of offset, interleaved planar electrodes that extend to two opposite surfaces of the ceramic dielectric. This simple structure requires a considerable amount of sophistication, both in material and manufacture, to produce it in the quality and quantities needed in

today's electronic equipment.



Formulations - Multilayer ceramic capacitors are available in both Class 1 and Class 2 formulations. Temperature compensating formulation are Class 1 and temperature stable and general application formulations are classified as Class 2.

Class 1 - Class 1 capacitors or temperature compensating capacitors are usually made from mixtures of titanates where barium titanate is normally not a major part of the mix. They have predictable temperature coefficients and in general, do not have an aging characteristic. Thus they are the most stable capacitor available. The most popular Class 1 multilayer ceramic capacitors are COG (NPO) temperature compensating capacitors (negativepositive 0 ppm/°C).

Class 2 - EIA Class 2 capacitors typically are based on the chemistry of barium titanate and provide a wide range of capacitance values and temperature stability. The most commonly used Class 2 dielectrics are X7R and Y5V. The X7R provides intermediate capacitance values which vary only ±15% over the temperature range of -55°C to 125°C. It finds applications where stability over a wide temperature range is required.

The Y5V provides the highest capacitance values and is used in applications where limited temperature changes are expected. The capacitance value for Y5V can vary from 22% to -82% over the -30°C to 85°C temperature range.

All Class 2 capacitors vary in capacitance value under the influence of temperature, operating voltage (both AC and DC), and frequency. For additional information on performance changes with operating conditions, consult KYOCERA AVX's software, SpiCap.



General Description

EIA and MIL Temperature Stable and General Table 1: **Application Codes**

EIA CODE Percent Capacity Change Over Temperature Range					
RS198	Temperature Range				
X7	-55°C to +125°C				
X6	-55°C to +105°C				
X5	-55°C to +85°C				
Y5	-30°C to +85°C				
Z5	+10°C to +85°C				
Code	Percent Capacity Change				
D	±3.3%				
E	±4.7%				
F	±7.5%				
Р	±10%				
R	±15%				
S	±22%				
Т Т	+22%, -33%				
U	+22%, - 56%				
V	+22%, -82%				

EXAMPLE - A capacitor is desired with the capacitance value at 25°C to increase no more than 7.5% or decrease no more than 7.5% from -30°C to +85°C. EIA Code will be Y5F.

MIL CODE						
Symbol	Tempera	Temperature Range				
Α	-55°C t	to +85°C				
В	-55°C to	o +125°C				
С	-55°C to +150°C					
Oh al	Cap. Change	Cap. Change				
Symbol	Zero Volts	Rated Volts				
R	+15%, -15%	+15%, -40%				
S	+22%, -22%	+22%, -56%				
W	+22%, -56%	+22%, -66%				
X	+15%, -15%	+15%, -25%				
Y	+30%, -70%	+30%, -80%				
l 7	+20%, -20%	+20%30%				

Temperature characteristic is specified by combining range and change symbols, for example BR or AW. Specification slash sheets indicate the characteristic applicable to a given style of capacitor.

In specifying capacitance change with temperature for Class 2 materials, EIA expresses the capacitance change over an operating temperature range by a 3 symbol code. The first symbol represents the cold temperature end of the temperature range, the second represents the upper limit of the operating temperature range and the third symbol represents the capacitance change allowed over the operating temperature range. Table 1 provides a detailed explanation of the EIA system.

Effects of Voltage - Variations in voltage have little effect on Class 1 dielectric but does affect the capacitance and dissipation factor of Class 2 dielectrics. The application of DC voltage reduces both the capacitance and dissipation factor while the application of an AC voltage within a reasonable range tends to increase both capacitance and dissipation factor readings. If a high enough AC voltage is applied, eventually it will reduce capacitance just as a DC voltage will. Figure 2 shows the effects of AC voltage.

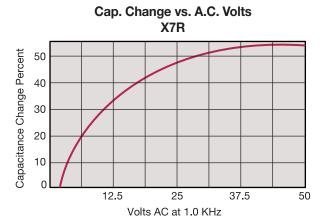


Figure 2

Capacitor specifications specify the AC voltage at which to measure (normally 0.5 or 1 VAC) and application of the wrong voltage can cause spurious readings. Figure 3 gives the voltage coefficient of dissipation factor for various AC voltages at 1 kilohertz. Applications of different frequencies will affect the percentage changes versus voltages.

D.F. vs. A.C. Measurement Volts X7R

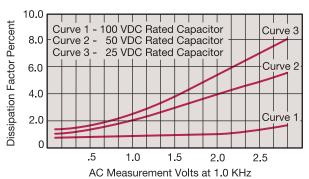


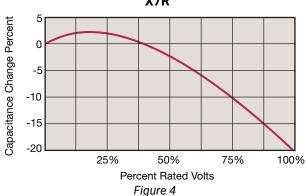
Figure 3

Typical effect of the application of DC voltage is shown in Figure 4. The voltage coefficient is more pronounced for higher K dielectrics. These figures are shown for room temperature conditions. The combination characteristic known as voltage temperature limits which shows the effects of rated voltage over the operating temperature range is shown in Figure 5 for the military BX characteristic.





Example Change vs. D.C. Volts X7R



Example Cap. Change vs. Temperature X7R

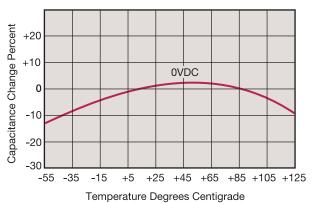


Figure 5

Effects of Time - Class 2 ceramic capacitors change capacitance and dissipation factor with time as well as temperature, voltage and frequency. This change with time is known as aging. Aging is caused by a gradual re-alignment of the crystalline structure of the ceramic and produces an exponential loss in capacitance and decrease in dissipation factor versus time. A typical curve of aging rate for semistable ceramics is shown in Figure 6.

If a Class 2 ceramic capacitor that has been sitting on the shelf for a period of time, is heated above its curie point, (125°C for 4 hours or 150°C for 1/2 hour will suffice) the part will de-age and return to its initial capacitance and dissi-pation factor readings. Because the capacitance changes rapidly, immediately after de-aging, the basic capacitance measurements are normally referred to a time period sometime after the de-aging process. Various manufacturers use different time bases but the most popular one is one day or twentyfour hours after "last heat." Change in the aging curve can be caused by the application of voltage and other stresses. The possible changes in capacitance due to de-aging by heating the unit explain why capacitance changes are allowed after test, such as temperature cycling, moisture resistance, etc., in MIL specs. The application of high voltages such as dielectric withstanding voltages also tends to de-age capacitors and is why re-reading of capacitance after 12 or 24 hours is allowed in military specifications after dielectric strength tests have been performed.

Example Curve of Aging Rate X7R

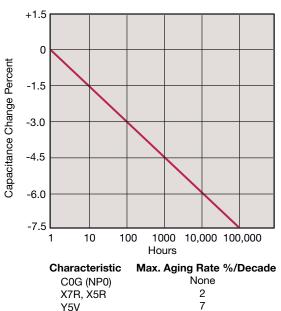


Figure 6

Effects of Frequency - Frequency affects capacitance and impedance characteristics of capacitors. This effect is much more pronounced in high dielectric constant ceramic formulation than in low K formulations. KYOCERA AVX's SpiCap software generates impedance, ESR, series inductance, series resonant frequency and capacitance all as functions of frequency, temperature and DC bias for standard chip sizes and styles. It is available free from KYOCERA AVX and can be downloaded for free from KYOCERA AVX website: www.kyocera-avx.com.



KYOCERa

General Description

Effects of Mechanical Stress - High "K" dielectric ceramic capacitors exhibit some low level piezoelectric reactions under mechanical stress. As a general statement, the piezoelectric output is higher, the higher the dielectric constant of the ceramic. It is desirable to investigate this effect before using high "K" dielectrics as coupling capacitors in extremely low level applications.

Reliability - Historically ceramic capacitors have been one of the most reliable types of capacitors in use today. The approximate formula for the reliability of a ceramic capacitor is:

$$\frac{L_o}{L_t} = \left(\frac{V_t}{V_o}\right) X \left(\frac{T_t}{T_o}\right) Y$$

where

L_o = operating life T_t = test temperature and L, = test life T_0 = operating temperature in °C V_t = test voltage

X,Y = see text V_0 = operating voltage

Historically for ceramic capacitors exponent X has been considered as 3. The exponent Y for temperature effects typically tends to run about 8.

A capacitor is a component which is capable of storing electrical energy. It consists of two conductive plates (electrodes) separated by insulating material which is called the dielectric. A typical formula for determining capacitance is:

$$C = \frac{.224 \text{ KA}}{t}$$

C = capacitance (picofarads)

K = dielectric constant (Vacuum = 1)

A = area in square inches

t = separation between the plates in inches (thickness of dielectric)

.224 = conversion constant (.0884 for metric system in cm)

Capacitance - The standard unit of capacitance is the farad. A capacitor has a capacitance of 1 farad when 1 coulomb charges it to 1 volt. One farad is a very large unit and most capacitors have values in the micro (10^{-6}), nano (10^{-9}) or pico (10^{-12}) farad level.

Dielectric Constant - In the formula for capacitance given above the dielectric constant of a vacuum is arbitrarily chosen as the number 1. Dielectric constants of other materials are then compared to the dielectric constant of a vacuum.

Dielectric Thickness - Capacitance is indirectly proportional to the separation between electrodes. Lower voltage requirements mean thinner dielectrics and greater capacitance per volume.

Area - Capacitance is directly proportional to the area of the electrodes. Since the other variables in the equation are usually set by the performance desired, area is the easiest parameter to modify to obtain a specific capacitance within a material group.

Energy Stored – The energy which can be stored in a capacitor is given by the formula:

$$E = \frac{1}{2}CV^2$$

E = energy in joules (watts-sec)

V = applied voltage

C = capacitance in farads

Potential Change - A capacitor is a reactive component which reacts against a change in potential across it. This is shown by the equation for the linear charge of a capacitor:

$$I_{ideal} = C \frac{dV}{dt}$$

where

I = Current

C = Capacitance

dV/dt = Slope of voltage transition across capacitor

Thus an infinite current would be required to instantly change the potential across a capacitor. The amount of current a capacitor can 'sink" is determined by the above equation.

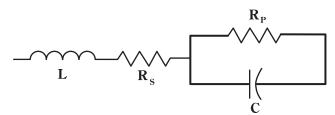
Equivalent Circuit - A capacitor, as a practical device, exhibits not only capacitance but also resistance and inductance. A simplified schematic for the equivalent circuit is:

C = Capacitance

L = Inductance

R_s = Series Resistance

R_n = Parallel Resistance



Reactance - Since the insulation resistance (Rp) is normally very high, the total impedance of a capacitor is:

$$Z = \sqrt{R_S^2 + (X_C - X_L)^2}$$

where

Z = Total Impedance

R_s = Series Resistance

X_c = Capacitive Reactance $\frac{1}{2\pi}$ fC

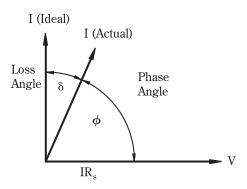
X₁ = Inductive Reactance

The variation of a capacitor's impedance with frequency determines its effectiveness in many applications.

Phase Angle - Power Factor and Dissipation Factor are often confused since they are both measures of the loss in a capacitor under AC application and are often almost identical in value. In a "perfect" capacitor the current in the capacitor will lead the voltage by 90°.

General Description





In practice the current leads the voltage by some other phase angle due to the series resistance RS. The complement of this angle is called the loss angle and:

> Power Factor (P.F.) = $\cos \varphi$ or $\sin \delta$ Dissipation Factor (D.F.) = $\tan \delta$

for small values of the tan and sine are essentially equal which has led to the common interchangeability of the two terms in the industry.

Equivalent Series Resistance - The term E.S.R. or Equivalent Series Resistance combines all losses both series and parallel in a capacitor at a given frequency so that the equivalent circuit is reduced to a simple R-C series connection.

Dissipation Factor – The DF/PF of a capacitor tells what percent of the apparent power input will turn to heat in the capacitor.

Dissipation Factor =
$$\frac{\text{E.S.R.}}{X_{\odot}}$$
 = (2 π fC) (E.S.R.)

The watts loss are:

Watts loss = $(2 \pi fCV^2)$ (D.F.)

Very low values of dissipation factor are expressed as their reciprocal for convenience. These are called the "Q" or Quality factor of capacitors.

Parasitic Inductance - The parasitic inductance of capacitors is becoming more and more important in the decoupling of today's high speed digital systems. The relationship between the inductance and the ripple voltage induced on the DC voltage line can be seen from the simple inductance equation:

$$V = L \frac{di}{dt}$$

The $\frac{di}{dt}$ seen in current microprocessors can be as high as 0.3 A/ns, and up to 10A/ns. At 0.3 A/ns, 100pH of parasitic inductance can cause a voltage spike of 30mV. While this does not sound very drastic, with the Vcc for microprocessors decreasing at the current rate, this can be a fairly large percentage.

Another important, often overlooked, reason for knowing the parasitic inductance is the calculation of the resonant frequency. This can be important for high frequency, bypass capacitors, as the resonant point will give the most signal attenuation. The resonant frequency is calculated from the simple equation:

$$f_{res} = \frac{1}{2\pi\sqrt{LC}}$$

Insulation Resistance - Insulation Resistance is the resistance measured across the terminals of a capacitor and consists principally of the parallel resistance RP shown in the equivalent circuit. As capacitance values and hence the area of dielectric increases, the I.R. decreases and hence the product (C x IR or RC) is often specified in ohm farads or more commonly megohm-microfarads. Leakage current is determined by dividing the rated voltage by IR (Ohm's Law).

Dielectric Strength - Dielectric Strength is an expression of the ability of a material to withstand an electrical stress. Although dielectric strength is ordinarily expressed in volts, it is actually dependent on the thickness of the dielectric and thus is also more generically a function of volts/mil.

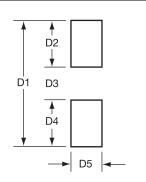
Dielectric Absorption – A capacitor does not discharge instantaneously upon application of a short circuit, but drains gradually after the capacitance proper has been discharged. It is common practice to measure the dielectric absorption by determining the "reappearing voltage" which appears across a capacitor at some point in time after it has been fully discharged under short circuit conditions.

Corona - Corona is the ionization of air or other vapors which causes them to conduct current. It is especially prevalent in high voltage units but can occur with low voltages as well where high voltage gradients occur. The energy discharged degrades the performance of the capacitor and can in time cause catastrophic failures.

MLC Chip Capacitors



REFLOW SOLDERING



Case Size	D1	D2	D3	D4	D5
0201	0.85 (0.033)	0.30 (0.012)	0.25 (0.010)	0.30 (0.012)	0.35 (0.014)
0402	1.70 (0.067)	0.60 (0.024)	0.50 (0.020)	0.60 (0.024)	0.50 (0.020)
0603	2.30 (0.091)	0.80 (0.031)	0.70 (0.028)	0.80 (0.031)	0.75 (0.030)
0805	3.00 (0.118)	1.00 (0.039)	1.00 (0.039)	1.00 (0.039)	1.25 (0.049)
1206	4.00 (0.157)	1.00 (0.039)	2.00 (0.079)	1.00 (0.039)	1.60 (0.063)
1210	4.00 (0.157)	1.00 (0.039)	2.00 (0.079)	1.00 (0.039)	2.50 (0.098)
1808	5.60 (0.220)	1.00 (0.039)	3.60 (0.142)	1.00 (0.039)	2.00 (0.079)
1812	5.60 (0.220)	1.00 (0.039)	3.60 (0.142)	1.00 (0.039)	3.00 (0.118)
1825	5.60 (0.220)	1.00 (0.039)	3.60 (0.142)	1.00 (0.039)	6.35 (0.250)
2220	6.60 (0.260)	1.00 (0.039)	4.60 (0.181)	1.00 (0.039)	5.00 (0.197)
2225	6.60 (0.260)	1.00 (0.039)	4.60 (0.181)	1.00 (0.039)	6.35 (0.250)

Dimensions in millimeters (inches)

Component Pad Design

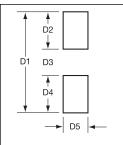
Component pads should be designed to achieve good solder filets and minimize component movement during reflow soldering. Pad designs are given below for the most common sizes of multilayer ceramic capacitors for both wave and reflow soldering. The basis of these designs is:

Pad width equal to component width. It is permissible to

decrease this to as low as 85% of component width but it is not advisable to go below this.

- · Pad overlap 0.5mm beneath component.
- · Pad extension 0.5mm beyond components for reflow and 1.0mm for wave soldering.

WAVE SOLDERING



				×	
Case Size	D1	D2	D3	D4	D5
0603	3.10 (0.12)	1.20 (0.05)	0.70 (0.03)	1.20 (0.05)	0.75 (0.03)
0805	4.00 (0.15)	1.50 (0.06)	1.00 (0.04)	1.50 (0.06)	1.25 (0.05)
1206	5.00 (0.19)	1.50 (0.06)	2.00 (0.09)	1.50 (0.06)	1.60 (0.06)

Dimensions in millimeters (inches)

Component Spacing

For wave soldering components, must be spaced sufficiently far apart to avoid bridging or shadowing (inability of solder to penetrate properly into small spaces). This is less important for reflow soldering but sufficient space must be allowed to enable rework should it be required.

Preheat & Soldering

The rate of preheat should not exceed 4°C/second to prevent thermal shock. A better maximum figure is about 2°C/second.

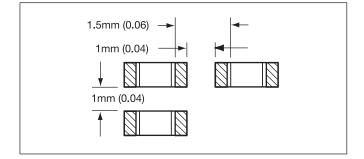
For capacitors size 1206 and below, with a maximum thickness of 1.25mm, it is generally permissible to allow a temperature differential from preheat to soldering of 150°C. In all other cases this differential should not exceed 100°C.

For further specific application or process advice, please consult KYOCERA AVX.

Cleaning

Care should be taken to ensure that the capacitors are thoroughly cleaned of flux residues especially the space beneath the capacitor. Such residues may otherwise become conductive and effectively offer a low resistance bypass to the capacitor.

Ultrasonic cleaning is permissible, the recommended conditions being 8 Watts/litre at 20-45 kHz, with a process cycle of 2 minutes vapor rinse, 2 minutes immersion in the ultrasonic solvent bath and finally 2 minutes vapor rinse.



Recommended Soldering Profiles



REFLOW SOLDER PROFILES

KYOCERA AVX RoHS compliant products utilize termination finishes (e.g.Sn or SnAg) that are compatible with all Pb-Free soldering systems and are fully reverse compatible with SnPb soldering systems. A recommended SnPb profile is shown for comparison; for Pb-Free soldering, IPC/ JEDECJ- STD-020C may be referenced. The upper line in the chart shows the maximum envelope to which products are qualified (typically 3x reflow cycles at 260°C max). The center line gives the recommended profile for optimum wettability and soldering in Pb-Free Systems.

Preheat:

The pre-heat stabilizes the part and reduces the temperature differential prior to reflow. The initial ramp to 125°C may be rapid, but from that point (2-3)°C/sec is recommended to allow ceramic parts to heat uniformly and plastic encapsulated parts to stabilize through the glass transition temperature of the body (~ 180°C).

Reflow:

In the reflow phase, the maximum recommended time > 230°C is 40secs. Time at peak reflow is 10secs max.; optimum reflow is achieved at 250°C, (see wetting balance chart opposite) but products are qualified to 260°C max. Please reference individual product datasheets for maximum limits

Cool down should not be forced and 6°C/sec is recommended. A slow cool down will result in a finer grain structure of the reflow solder in the solder fillet.

WAVE SOLDER PROFILES

For wave solder, there is no change in the recommended wave profile; all standard Pb-Free (SnCu/SnCuAg) systems operate at the same 260°C max recommended for SnPb systems.

Preheat:

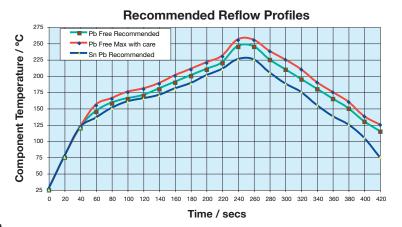
This is more important for wave solder; a higher temperature preheat will reduce the thermal shock to SMD parts that are immersed (please consult individual product data sheets for SMD parts that are suited to wave solder). SMD parts should ideally be heated from the bottom-Side prior to wave. PTH (Pin through hole) parts on the topside should not be separately heated.

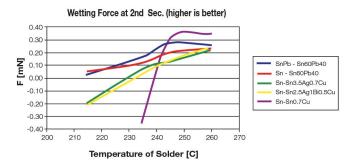
Wave:

250°C - 260°C recommended for optimum solderability.

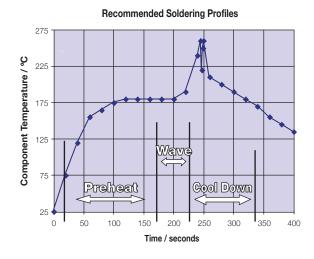
Cool Down:

As with reflow solder, cool down should not be forced and 6°C/sec is recommended. Any air knives at the end of the 2nd wave should be heated.





IMPORTANT NOTE: Typical Pb-Free reflow solders have a more dull and grainy appearance compared to traditional SnPb. Elevating the reflow temperature will not change this, but extending the cool down can help improve the visual appearance of the joint.



MLC Chip Capacitors



APPLICATION NOTES

Storage

The components should be stored in their "as received packaging" where possible. If the components are removed from their original packaging then they should be stored in an airtight container (e.g. a heat sealed plastic bag) with desiccant (e.g. silica gel). Storage area temperature should be kept between +5 degrees C and +30 degrees C with humidity < 70% RH. Storage atmosphere must be free of gas containing sulfur and chlorine. Avoid exposing the product to saline moisture or to temperature changes that might result in the formation of condensation. To assure good solderability performance we recommend that the product be used within 6 months from our shipping date, but can be used for up to 12 months. Chip capacitors may crack if exposed to hydrogen (H2) gas while sealed or if coated with silicon, which generates hydrogen gas.

Solderability

Terminations to be well soldered after immersion in a 60/40 tin/lead solder bath at 245°C +/- 5°C for 5 +0/-0.5 seconds.

Leaching

Terminations will resist leaching for at least the immersion times and conditions shown below.

Termination Type	Solder Tin/	Solder	Immersion	
	Lead/Silver	Temp °C	Time Seconds	
Nickel Barrier	60/40/0	260 ± 5	30 ± 1	

Lead-Free Wave Soldering

The recommended peak temperature for lead-free wave soldering is 250°C-260°C for 3-5 seconds. The other parameters of the profile remains the same as above.

The following should be noted by customers changing from lead based systems to the new lead free pastes.

- A. The visual standards used for evaluation of solder joints will need to be modified as lead free joints are not as bright as with tin-lead pastes and the fillet may not be as large.
- B. Lead-free solder pastes do not allow the same self alignment as lead containing systems. Standard mounting pads are acceptable, but machine set up may need to be modified.

General

Surface mounting chip multilaver ceramic capacitors are designed for soldering to printed circuit boards or other substrates. The construction of the components is such that they will withstand the time/temperature profiles used in both wave and reflow soldering methods.

Handling

Chip multilayer ceramic capacitors should be handled with care to avoid damage or contamination from perspiration and skin oils. The use of tweezers or vacuum pick ups is strongly recommended for individual components. Bulk handling should ensure that abrasion and mechanical shock are minimized. Taped and reeled components provides the ideal medium for direct presentation to the placement machine. Any mechanical shock should be minimized during handling chip multilayer ceramic capacitors.

Preheat

It is important to avoid the possibility of thermal shock during soldering and carefully controlled preheat is therefore required. The rate of preheat should not exceed 4°C/second and a target figure 2°C/second is recommended. Although an 80°C to 120°C temperature differential is preferred, recent developments allow a temperature differential between the component surface and the soldering temperature of 150°C (Maximum) for capacitors of 1210 size and below with a maximum thickness of 1.25mm. The user is cautioned that the risk of thermal shock increases as chip size or temperature differential increases.

Soldering

Mildly activated rosin fluxes are preferred. The minimum amount of solder to give a good joint should be used. Excessive solder can lead to damage from the stresses caused by the difference in coefficients of expansion between solder, chip and substrate. KYOCERA AVX terminations are suitable for all wave and reflow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

Natural cooling in air is preferred, as this minimizes stresses within the soldered joint. When forced air cooling is used, cooling rate should not exceed 4°C/second. Quenching is not recommended but if used, maximum temperature differentials should be observed according to the preheat conditions above.

Cleaning

Flux residues may be hygroscopic or acidic and must be removed. KYOCERA AVX MLC capacitors are acceptable for use with all of the solvents described in the specifications MIL-STD-202 and EIA-RS-198. Alcohol based solvents are acceptable and properly controlled water cleaning systems are also acceptable. Many other solvents have been proven successful, and most solvents that are acceptable to other components on circuit assemblies are equally acceptable for use with ceramic capacitors.

Prevention of Metallic Migration

Note that when components with Sn plating on the end terminations are to be used in applications that are likely to experience conditions of high humidity under bias voltage, we strongly recommend that the circuit boards be conformally coated to protect the Sn from moisture that might lead to migration and eventual current leakage.

When using Capacitor Arrays we recommend that there is no differential in applied voltage between adjacent elements.

MLC Chip Capacitors



POST SOLDER HANDLING

Once SMP components are soldered to the board, any bending or flexure of the PCB applies stresses to the soldered joints of the components. For leaded devices, the stresses are absorbed by the compliancy of the metal leads and generally don't result in problems unless the stress is large enough to fracture the soldered connection.

Ceramic capacitors are more susceptible to such stress because they don't have compliant leads and are brittle in nature. The most frequent failure mode is low DC resistance or short circuit. The second failure mode is significant loss of capacitance due to severing of contact between sets of the internal electrodes.

Cracks caused by mechanical flexure are very easily identified and generally take one of the following two general forms:

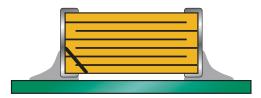
Mechanical cracks are often hidden underneath the termination and are difficult to see externally. However, if one end termination falls off during the removal process from PCB, this is one indication that the cause of failure was excessive mechanical stress due to board warping.

COMMON CAUSES OF MECHANICAL CRACKING

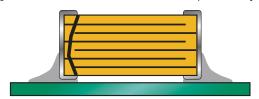
The most common source for mechanical stress is board depanelization equipment, such as manual breakapart, v-cutters and shear presses. Improperly aligned or dull cutters may cause torqueing of the PCB resulting in flex stresses being transmitted to components near the board edge. Another common source of flexural stress is contact during parametric testing when test points are probed. If the PCB is allowed to flex during the test cycle, nearby ceramic capacitors may be broken.

A third common source is board to board connections at vertical connectors where cables or other PCBs are connected to the PCB. If the board is not supported during the plug/unplug cycle, it may flex and cause damage to nearby components.

Special care should also be taken when handling large (>6" on a side) PCBs since they more easily flex or warp than smaller boards.



Type A: Angled crack between bottom of device to top of solder joint.

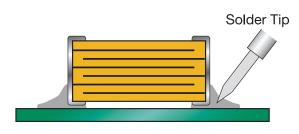


Type B: Fracture from top of device to bottom of device.

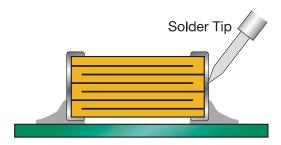
REWORKING OF MLCS

Thermal shock is common in MLCs that are manually attached or reworked with a soldering iron. KYOCERA AVX strongly recommends that any reworking of MLCs be done with hot air reflow rather than soldering irons. It is practically impossible to cause any thermal shock in ceramic capacitors when using hot air reflow.

However direct contact by the soldering iron tip often causes thermal cracks that may fail at a later date. If rework by soldering iron is absolutely necessary, it is recommended that the wattage of the iron be less than 30 watts and the tip temperature be <300°C. Rework should be performed by applying the solder iron tip to the pad and not directly contacting any part of the ceramic capacitor.



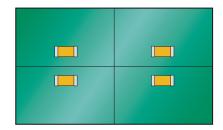
Preferred Method - No Direct Part Contact



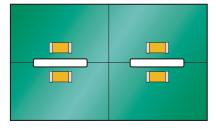
Poor Method - Direct Contact with Part

PCB BOARD DESIGN

To avoid many of the handling problems, KYOCERA AVX recommends that MLCs be located at least .2" away from nearest edge of board. However when this is not possible, KYOCERA AVX recommends that the panel be routed along the cut line, adjacent to where the MLC is located.



No Stress Relief for MLCs



Routed Cut Line Relieves Stress on MLC



KYDCERa | The Important Information/Disclaimer is incorporated in the catalog where these specifications came from or available online at www.kyocera-avx.com/disclaimer/ by reference and should be reviewed in full before placing any order.



FOLLOW US: O F in D

VISIT US AT WWW.KYOCERA-AVX.COM ▶

North America Tel: +1 864-967-2150

Europe Tel: +44 1276-697000

Asia Tel: +65 6286-7555

Central America Tel: +55 11-46881960

Japan Tel: +81 740-321250

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Capacitor Kits category:

Click to view products by Kyocera AVX manufacturer:

Other Similar products are found below:

1320838-1 DK0035T KITMS11111 DK0033T TS0002 ALU ENG KIT 07 GRM03-KIT-CLASS2-DE MKV250V-KIT-1-DE MKV250V-KIT-2-DE 744114 GCJ-KIT-X7-DE-A GJM022-KIT-TTOL-DE GRM02-KIT-DE ACCU-P0402KITL1 KITTYPE2100 LF KITMS08051 AY21-KIT-HF KIT3000UZ PPR ENG KIT 04 ALU ENG KIT 02 TAN ENG KIT 34 CER ENG KIT 36 ALU ENG KIT 01 VY2-KIT-MS TS0003 ACCU-P0201KITL2 FPCAP-SMD-KIT DK0009 885070 ALU ENG KIT 03 ALU ENG KIT 05 ALU ENG KIT 06 DK0008T DK0015 DK0036T DK0037T DK0081T DK0084T DK0060T ESRD-KIT9 MCF1000VKIT6 MICA-KIT1 MIN300VKIT1 HOTC-KIT-KH S-0402 S-0603 S-0805 S111DVE S111TVE S-1KV